THE CO-EVOLUTION OF MICROSTRUCTURE FEATURES IN SELF-ION IRRADIATED HT9 AT VERY HIGH DAMAGE LEVELS

by

Elizabeth Margaret Getto

A dissertation submitted in partial fulfillment of the requirements for the degree of Doctor of Philosophy (Nuclear Engineering and Radiological Sciences) in The University of Michigan 2016

Doctoral Committee:

Professor Gary S. Was, Chair Associate Research Scientist Zhijie Jiao Professor Amit Misra Adjunct Professor Roger Stoller Professor Lumin Wang Copyright © 2016 Elizabeth Margaret Getto

All rights reserved

To my family

ACKNOWLEDGEMENTS

I would first like to thank my thesis advisor, Dr. Gary Was. His insight, suggestions and input have been instrumental throughout my doctoral program. I would also like to thank my committee members, Dr. Roger Stoller, Dr. Lumin Wang, Dr. Zhijie Jiao and Dr. Amit Misra. Their input has greatly improved the quality of my thesis and has been invaluable.

I would like to thank the members of Was research group including Dr. Janelle Wharry, Dr. Anne Campbell, Dr. Mike McMurtrey, Dr. Cheng Xu, Dr. Gokce Gulsoy, Dr. Tyler Moss, Dr. Kale Stephenson, Dr. Shyam Dwaraknath, Stephen Raiman, Anthony Monterrosa, Justin Hesterberg, Stephen Taller, Gerrit Vancoervering, David Woodley, Drew Johnson, Rigel Hanbury and Rajan Bhambroo. The mentorship, help in the lab, moral support and camaraderie have been the best part of my graduate school experience. I especially would like to thank Gerrit Vancoervering for his aid in the modeling section of my dissertation. I am forever indebted to the staff at the Michigan Ion Beam Laboratory, Dr. Ovidiu Toader, Dr. Fabian Naab, Dr. Prabir Roy, Thomas Kubley and Dr. Ethan Uberseder, for support of many, many hours of ion irradiations and many emergency calls after midnight. I would also like to thank Dr. Kai Sun at the Michigan Center for Material Characterization and Dr. Zhijie Jiao for assistance in the microscopy required for both my research project and dissertation.

Without the support of Dr. Micah Hackett at TerraPower, LLC., this work would have never happened. Dr. Hackett's insights, support and ideas helped shape the irradiation program that led to my final dissertation. To Dr. Alexander Barashev and Dr. Stas Golubov at Oak Ridge National Laboratory, I am truly thankful for all your patient assistance helping me with the modeling section of my thesis. A special thanks as well to Dr. Frank Garner for many enjoyable and insightful conversations and discussions about void swelling and radiation effects over the last five years.

I am grateful for the support of the Beering Scholarship at Purdue University, which started me off on my higher education journey. I am also grateful to the National Science Foundation Graduate Research Foundation for the funding of my first three years of graduate school.

To my parents, Anne and David Beckett, thank you for the love and support throughout my whole life. I am forever gratefully for you encouraging me to follow my dreams and for your constant love and prayers. I cannot imagine this journey without your support. Anchors aweigh! To Rob, Lynn, Eleanor and Philip Beckett, thank you for your love and support and making me laugh when I need it the most.

Finally, to my husband Josh: thank you for your love for all these years, always being my biggest fan, knowing just what to say when I'm about to give up, making me a better person and for all those burritos delivered to the lab at all hours of the day or night.

The funding for this work as provided by TerraPower, LLC.

TABLE OF CONTENTS

DEDICATIO	DNii
ACKNOWL	EDGEMENTS iii
LIST OF TA	ABLES x
LIST OF FIG	GURES xii
LIST OF AF	PPENDICES xxvii
ABSTRACT	7xxviii
CHAPTER	1 INTRODUCTION
CHAPTER 2	2 BACKGROUND
2.1 Me	chanisms of Void Swelling2
2.1.1	Introduction to Void Swelling
2.2 Fer	ritic-Martensitic Alloys
2.2.1	Physical Metallurgy
2.3 Voi	id Swelling Experiments in Ferritic-Martensitic Alloys7
2.3.1	Void Swelling under Neutron Irradiation
2.3.2	Void Swelling under Ion Irradiation 12
2.3.3	Defect Partitioning
2.4 Dis	location Microstructure
2.4.1	Loop Character
2.4.2	Dislocation Microstructure under Irradiation
2.5 Pre	cipitation of Secondary Phases
2.5.1	Precipitate Types in HT9 19
2.5.2	Precipitate Behavior under Irradiation
2.6 Oth	ner Irradiation Effects
2.6.1	Radiation-Induced Segregation
2.6.2	Hardening

CHAPTER 3 OBJECTIVE	
CHAPTER 4 EXPERIMENTAL PROCEDURE	
4.1 Sample Preparation	
4.1.1 Sample Processing	
4.1.2 Sample Preparation	
4.2 Helium Preimplantation	
4.3 Fe ⁺⁺ Irradiations	
4.3.1 Irradiation Set-up	
4.3.1.1 Copper Stage with Indium	
4.3.1.2 Copper Stage with Indifoil	
4.3.1.3 Nickel Stage with Copper Foil	
4.3.2 Displacement Damage	
4.3.3 Damage Calculation	
4.3.4 Apertures and Beam Scanning	
4.3.4.1 Stage Aperture System	
4.3.4.2 Slit Aperture System	
4.3.5 Temperature Control	
4.3.5.1 Thermocouples	
4.3.5.2 Thermal Imager	
4.3.6 Irradiation Setup and Control	
4.4 5 MeV Fe ⁺⁺ Irradiation Results	
4.5 Post-Irradiation Sample Preparation and Microstructure C	Characterization67
4.5.1 TEM Specimen Preparation	
4.5.2 Void Swelling Measurement and Characterization	
4.5.2.1 Imaging Conditions	
4.5.2.2 Void Counting and Determination of Region of	Interest71
4.5.2.3 Error Analysis	
4.5.3 Precipitate Measurement, Characterization and Imag	ing76
4.5.4 Dislocation Imaging	
CHAPTER 5 RESULTS OF MICROSTRUCTURE EVOLUTION	ON UNDER ION
IRRADIATION	

5.1 U	Inirradiated Microstructure Characterization
5.2 V	Void Swelling Results
5.2.1	Determination of Valid Region of Interest
5.2.2	Damage Dependence at 440°C 117
5.2.3	Temperature Dependence at 188 dpa 118
5.2.4	Damage Dependence at 460°C 120
5.2	4.1 Grain to Grain Void Variation
5.2.5	High Swelling Correction
5.3 S	econdary Phase Results
5.3.1	G Phase
5.3.2	M ₂ X
5.4 D	Dislocation Microstructure
5.4.1	Dislocation Network
5.4.2	Dislocation Loops
CHAPTER	R 6 MODELING 192
6.1 N	Iodeling Methodology
6.1.1	Introduction to RIME Model
6.1.2	Description of Model Physics
6.1	2.1 Master Equations
6.1	2.2 Sink Strength Calculations
6.1	2.3 Defect Production Rates
6.1	2.4 Network Dislocation Evolution
6.1	2.5 Calculation of Radii/Swelling
6.1	2.6 Grouping Scheme
6.1	2.7 Consideration of Production Bias Model
6.1.3	Description of Main Sub Routines
6.1.4	Sensitivity Analysis
6.1.5	Input Parameter Selection
6.2 A	Adaptations to RIME Model for Void Growth-Dominated Microstructure 210
6.2.1	Pre-Existing Microstructure
6.2.2	Dislocation Treatment

6.2.3 Carbon-Vacancy Interactions	214
6.2.4 Precipitation	216
6.3 Development of Reference Cases	220
6.3.1 Comparison of Reference Cases to Experimental Data	221
6.3.1.1 Ref.0: Constant Network Density	221
6.3.1.2 Ref.1: Experimentally Input Dislocation Evolution	222
6.3.1.3 Ref.2: Dynamic Dislocation (DD) Evolution	223
CHAPTER 7 DISCUSSION: CO-EVOLUTION OF THE IRRADIATED	
MICROSTRUCTURE	257
7.1 Analysis Scope	257
7.1.1 Definitions of Modifications to Reference Cases	260
7.2 Effect of Dislocations on Voids	260
7.2.1 Summary of Dislocation and Void Evolution	262
7.2.2 Case Ref.0: Experimentally input network dislocations	263
7.2.3 Case Ref.1: Experimentally input network and loops	264
7.2.4 Case Ref.2: Dynamic Dislocation Treatment	265
7.2.5 Comparison of Model to Experiment	267
7.3 Effect of Precipitates on Voids	271
7.3.1 G Phase	271
7.3.2 M ₂ X	273
7.4 Effect of Precipitates on Dislocations	277
7.4.1 G Phase	277
7.4.2 M ₂ X	279
7.5 Carbon Trapping	283
7.6 Combined Impact of Microstructure Features on Voids and Dislocations	289
7.7 Alternate Considerations Regarding Overall Microstructure Co-evolution	292
7.7.1 Discussion of Other Possible Interaction Mechanisms	292
7.7.1.1 Lower Effective Bias	292
7.7.2 Reconsidering Swelling Rates from Experiment	293
CHAPTER 8 CONCLUSIONS	337
CHAPTER 9 FUTURE WORK	340

APPENDICES.	
REFERENCES	

LIST OF TABLES

Table 6.7:	Main changes in parameterization from FCC to BCC alloys
Table 6.8:	Concentration [10] and diffusion coefficients at 500°C for minor alloying elements in
	HT9
Table 6.9:	Definition of reference case input. Changes between each reference case highlighted
	in yellow
Table 7.1:	Description of flags denoting modification of reference cases with various
	microstructure treatments
Table 7.2:	Dislocation biases for interstitials reported in literature using a variety of approaches.
Table 7.3:	Description of reference cases with modifications used to match void and dislocation
	behavior to experiment
Table 7.4:	Summary of attempts to match microstructure behavior with precipitate and carbon
	treatments
Table 7.5:	Comparison of relative effect on final swelling values at 650 dpa of each
	microstructure treatment
Table 7.6:	Comparison of swelling rates calculated in the range of 188 to 650 dpa using nominal
	or fixed depth method [85]

LIST OF FIGURES

Figure 2.1: Expected swelling behavior as a function of damage. Adapted from [19] 29
Figure 2.2: Effect of chromium on the constitution of Fe-Cr-C alloys with 0.1% carbon.
$(CrFe)_4C$ is the $M_{23}C_6$ carbide [3]
Figure 2.3: Continuous cooling transformation (CCT) diagram for 12Cr-MoVNb martensitic
steel where A refers to austenite, K refers to carbide, Sp- δ refers to trace ferrite, M
refers to martensite, P =pearlite, A_{C1b} is the start of austenite formation upon heating,
A_{C1e} is the completion of austenite formation upon heating and λ is the cooling rate
(°C/min) from [3]
Figure 2.4: a) Schematic [32] and b) micrograph of typical HT9 microstructure prior to
irradiation [3]
Figure 2.5: Stress-free swelling of irradiated HT9 up to 165 dpa for 4 heat treatments. Heat 1 and
Heat 2 were subjected to the same heat treatment: 1038°C/5 min/air followed by
760°C/30 min/air cool. Heat 3 and 5 were subjected to 1100°C/2 min/air cool followed
by 650º/120 min/air cool [4]
Figure 2.6: Swelling in Fe-Cr alloys as a function of damage [33]
Figure 2.7: Adjustment of damage levels in EBR-II results by Garner et al. [8] to data collected
by Gelles [33]
Figure 2.8: Summary of HT9 and T91 irradiated in-reactor up to 208 dpa
Figure 2.9: a) Temperature dependence of void swelling in EM12 and HT9 irradiated to 150 dpa
b) Damage dependence of swelling of EM12 and HT9 up to at 500°C [14]
Figure 2.10: a) Temperature dependence of swelling in ferritic steel irradiated with 200 keV C^+
ions to 150 dpa and b) damage dependence of swelling in ferritic steels irradiated with
200 keV C ⁺ ions at 575°C [40]

Figure 2.11: a) Damage dependence of commercial alloys up to 600 dpa at 450 or 480°C. b)
Temperature dependence experiment at 100 dpa and 500 dpa on MA957 ODS ferritic
steel [15]
Figure 2.12: Summary of ion irradiations performed upon HT9 [14,15,40]
Figure 2.13: Q analysis for various neutron irradiations [34]
Figure 2.14 Temperature dependence of loop number density and diameter in 14 MeV Ni-
irradiated HT9 [35]. Note that loops of size of 800 nm would typically be classified as
an unfaulted network
Figure 2.15: A summary of dislocation loop results as a function of temperature in neutron and
ion irradiated HT9 [7,35]
Figure 2.16: HT9 irradiated to a) 4 dpa at 505° C b) 28 dpa at 384° C c) 155 dpa at 443° C [10]. 44
Figure 2.17: Formation of rod-like precipitates in 13 Cr-2Mo-TiO ₂ after Cr irradiation at 500° C to
a) 30 dpa and b) 150 dpa [38]
Figure 2.18: Representative stress/strain curves for Mod 9Cr-1Mo after irradiation in spallation
environment [56]46
Figure 2.19: Comparison of the behavior of martensitic steels in the tempered and as-quenched
conditions [59]
Figure 4.1: Unirradiated HT9 (Heat 84425) imaged in STEM-BF. Sample made via FIB liftout
method
Figure 4.2 Sample geometry following EDM. Only one face will be irradiated
Figure 4.3: Assembly used for electropolishing of samples. Samples polished in 90%
methanol/10% perchloric acid solution
Figure 4.4: The helium profile (blue) is overlaid on the damage rate (red) and implanted ion
concentration (green) for 5 MeV Fe ⁺⁺ in Fe-12Cr calculated from SRIM [64]
Figure 4.5 Schematic of irradiation stage and position of 2D thermal imager on beamline 88
Figure 4.6: a) Schematic of hold-down bars and b) view of hold-down bars on the stage [32] 89
Figure 4.7: a) "First generation stage" schematic where indium is used to ensure good thermal
contact and apertures were attached to the stage. b) "Second generation stage"
schematic where a combination of indium and graphite foil were utilized to ensure
good thermal conductivity and leak protection
Figure 4.8: Stage design as viewed from the top [32]

Figure 4.9: Completed stage after irradiation at 460°C to 130 dpa
Figure 4.10: a) Schematic and b) stage image for temperature uniformity test. c) Results of the
24-hour test on the beamline
Figure 4.11: Schematic of "third generation" stage configuration with a) stage and b) slit
apertures. Copper foil provided sufficient thermal contact and eliminated indium
leaks. Slit apertures eliminated danger of aperture shift, which could occur during
stage loading onto beamline94
Figure 4.12: Top view of stage design with slit aperture system. The aperture feedthrough was
replaced with an additional thermocouple feedthrough95
Figure 4.13: Schematic of tantalum aperture system
Figure 4.14: Schematic of benchtop alignment setup of stage apertures [32]
Figure 4.15: Path of raster scanned beam center across samples over irradiated area [13,32] 98
Figure 4.16: a) Schematic of raster scanned beam area after beam sizing procedure with ceramic.
b) Beam intensity profile due to Gaussian beam shape
Figure 4.17: Irradiation stage a) without and b) with alignment laser
Figure 4.18: 2D thermal image from 460°C, 130 dpa irradiation. Two AOIs per samples were
placed on 5 samples with two guide bars bookending the samples
Figure 4.19: Example temperature histogram for 5 MeV Fe ⁺⁺ irradiation of ACO3-460C-450dpa-
10He-021615 showing approximately normal distribution in both areas of interest (top
and bottom) on the sample and having 2σ well within $\pm 10^{\circ}$ C
Figure 4.20: a) Platinum deposited on the surface of the irradiated sample b) trenching around
the platinum protected surface c) under cut of the samples d) attaching the needle to
the lamella using platinum e) attaching the lamella to the copper grid f) thinning using
the Ga beam
Figure 4.21: Schematic of cross-sectional liftout and resulting image in HAADF STEM. The PT
layer and irradiated surface are at the top of the image. Voids are dark circles. Sample
irradiated at 460°C to 188 dpa with 10 appm He preimplanted104
Figure 4.22: Conventional BF (a) and STEM BF (b) images of voids in HT9 irradiated with 5
MeV Fe ⁺⁺ at 460°C to 375 dpa with 10 appm He preimplanted. Note that all voids are
in focus in (b) while conventional images show some voids in over or under focus. 105

Figure 4.23: STEM ADF (a) and BF (b) images of HT9 irradiated with 5 MeV Fe ⁺⁺ at 440°C to
140 dpa with 100 He preimplanted. Voids obscured by diffraction contrast in BF (b)
are clearly observed in ADF (a) as black circles
Figure 4.24: Example of STEM HAADF and BF images stitched together to show entire liftout.
(HT9, 440°C, 188 dpa, 10 appm He) 107
Figure 4.25: Depth profiles for void a) diameter b) number density and c) swelling in HT9
irradiated at 440°C to 140 dpa with 100 appm He preimplanted [12] 108
Figure 4.26: Error for diameter, number density and swelling as a function of average void
diameter109
Figure 4.27: Orientation and shapes of dislocation loops in FM alloys imaged along <001> axis
[32]110
Figure 5.1: As-received HT9 sample prepared via FIB liftout method showing representative
microstructure
Figure 5.2: Optical micrograph of as-received HT9 after etching. The etchant used was Vilellas's
reagent which includes 1 g picric acid with 5 mL of hydrochloric acid in a solution of
100 mL [63]
Figure 5.3: Indexed diffraction of bcc matrix of HT9
Figure 5.4: Void formation in the a) irradiated area and b) near surface in HT9 preimplanted with
10 appm He then irradiated with 5 MeV Fe ⁺⁺ to 188 dpa at 440° C 145
Figure 5.5: Void a) diameter b) number density c) and swelling profiles with depth in HT9
preimplanted with 10 appm He then irradiated with 5 MeV Fe^{++} to 188 dpa at 460°C.
Figure 5.6: Determination of location of onset of swelling increase after swelling peak near the
surface (from [12])
Figure 5.7: Determination of location of onset of in swelling decrease at depths of 700 nm or
greater (from [12])
Figure 5.8: HAADF images of HT9 preimplanted with 10 appm He then irradiated with 5 MeV
Fe^{++} at 440°C to a) 25 dpa b) 50 dpa c) 140 dpa and d) 188 dpa 149
Figure 5.9: a) Diameter and b) number density of voids in HT9 preimplanted with 10 appm He
then irradiated with 5 MeV Fe ⁺⁺ at 440°C up to 188 dpa

Figure 5.22: Damage rate (dpa/s) curve as a function of increasing damage due to void swelling.
Beam current is assumed to be constant for all irradiations so damage rate can be
directly compared163
Figure 5.23: a) Effective damage rate calculated from SRIM. b) Swelling vs. damage with fixed
depth correction164
Figure 5.24: Void diameter, number density and swelling depth profiles as well as void
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}
(ACO3) at 460°C, to 550 dpa with 10 appm He 165
Figure 5.25: Void diameter, number density and swelling depth profiles as well as void
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}
(ACO3) at 460°C, to 650 dpa with 10 appm He 166
Figure 5.26: G phase evolution with increasing damage irradiated at 460° C with 5 MeV Fe ⁺⁺ with
10 appm He preimplanted. Some G phase precipitates are marked by red arrows 167
Figure 5.27: APT analysis of two G phase precipitates observed at HT9 irradiated with 5 MeV
Fe ⁺⁺ at 440°C to 140 dpa with 10 appm preimplanted. APT confirms composition of
$Mn_6Ni_{16}Si_7$ by observation of expected concentrations in at% (55%Ni-24%Si-21%Mn)
in Precipitates b) 1 and c) 2168
Figure 5.28: STEM BF image of G phase with corresponding XEDS map. Ni is in red and Si in
blue
Figure 5.29: HRTEM BF image of G phase in the matrix. The much larger lattice parameter of G
phase (a=1.148 nm) relative the matrix a=0.286 nm. The incoherent interface is clearly
visible. The FFT pattern of the outlined region in the image (red frame) is inset in the
top left corner and demonstrates fcc crystallographic structure 170
Figure 5.30: Evolution of G phase precipitates in terms of diameter (blue), number density (red)
and volume fraction (green) at 460°C in HT9 irradiated with 5 MeV Fe ⁺⁺ after
preimplantation with 10 appm He171
Figure 5.31: Formation of M_2X precipitates in irradiated HT9 irradiated with 5 MeV Fe ⁺⁺ . (a)-(e)
are the low angle annular dark field images of M ₂ X, shown as light grey rods. (f)-(j)
present the corresponding high angle annular dark field images with voids as dark
circles and M_2X can faintly be observed as light grey plates

Figure 5.32: Orientation of M_2X within the matrix. The top view corresponds to what is imaged
in Figure 5.31
Figure 5.33: LAADF image of formation of M_2X precipitates in irradiated HT9 irradiated with 5
MeV Fe ⁺⁺ . Note precipitates form intragranularly
Figure 5.34: Bright field image (a) and corresponding jump ratios for Cr (b), C (c) and N (d) in
HT9 irradiated at 460°C to 550 dpa with 10 appm He preimplanted 175
Figure 5.35: EDX spectrum of M_2X confirming Cr_2C in HT9 irradiated at 460°C to 550 dpa with
10 appm He preimplanted 176
Figure 5.36: SAED patterns of M_2X in HT9 irradiated at 460°C to 450 dpa with 10 appm He
preimplanted with axis tilted to a) 0° b) 27° and c) 43°
Figure 5.37: a) HRTEM of M_2X b) FFT of precipitate from red box in (a), c) nanodiffraction
revealing M_2X (red) and Fe (green) matrix in HT9 irradiated at 460°C to 650 dpa with
10 appm He preimplanted 178
Figure 5.38: a) BF b) HR BF and c) HR HAADF images of M_2X irradiated to 650 dpa at 460°C.
Moiré fringes clearly visible and indicated misfit strain due to slight lattice mismatch,
consistent with coherency
$\label{eq:steps} \begin{tabular}{lllllllllllllllllllllllllllllllllll$
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < $1220 > M2X//< 100 > \alpha$, demonstrated by parallel lines.180
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growthrelationship < 1220 > $M2X//< 100 > \alpha$, demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated
$\label{eq:solution} \begin{array}{l} \mbox{consistent with coherency.} & \mbox{179} \\ \mbox{Figure 5.39: HR HAADF image of } M_2 X \mbox{(yellow) and matrix (red). FFT show same growth} \\ \mbox{relationship} < 1220 > M2X//< 100 > \alpha, \mbox{demonstrated by parallel lines.} & \mbox{180} \\ \mbox{Figure 5.40: a) } HR \mbox{-}HAADF \mbox{image of } HT9 \mbox{ irradiated at } 460^{\circ}\mbox{C to } 650 \mbox{ dpa. b) } FFT \mbox{ with simulated} \\ \mbox{SAED pattern overlaid indicating consistency of observed pattern with simulation} \\ \end{array}$
$ \begin{array}{l} \mbox{consistent with coherency.} & 179 \\ \mbox{Figure 5.39: HR HAADF image of } M_2X \mbox{ (yellow) and matrix (red). FFT show same growth } \\ \mbox{relationship < 1220 > } M2X//< 100 > \alpha, \mbox{ demonstrated by parallel lines.} & 180 \\ \mbox{Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated \\ \mbox{SAED pattern overlaid indicating consistency of observed pattern with simulation } \\ \mbox{ along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.} \\ \end{array}$
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > $M2X//<$ 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.181
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > $M2X//<$ 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.181Figure 5.41: Evolution of M2X precipitates in terms of length (blue), width (red), thickness181
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > $M2X//<$ 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.181Figure 5.41: Evolution of M2X precipitates in terms of length (blue), width (red), thickness (green), number density (yellow) and volume fraction (grey) in HT9 irradiated with 5
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > $M2X//<$ 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.181Figure 5.41: Evolution of M2X precipitates in terms of length (blue), width (red), thickness (green), number density (yellow) and volume fraction (grey) in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C after preimplantation of 10 appm He.182
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > $M2X//<$ 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.181Figure 5.41: Evolution of M2X precipitates in terms of length (blue), width (red), thickness (green), number density (yellow) and volume fraction (grey) in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C after preimplantation of 10 appm He.182Figure 5.42: Images of representative dislocation network used for characterization of line
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > M2X//< 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid. .181Figure 5.41: Evolution of M2X precipitates in terms of length (blue), width (red), thickness (green), number density (yellow) and volume fraction (grey) in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C after preimplantation of 10 appm He.182Figure 5.42: Images of representative dislocation network used for characterization of line density in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C with 10 appm He preimplanted.
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > M2X//< 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid. 181Figure 5.41: Evolution of M2X precipitates in terms of length (blue), width (red), thickness (green), number density (yellow) and volume fraction (grey) in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C after preimplantation of 10 appm He.Figure 5.42: Images of representative dislocation network used for characterization of line density in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C with 10 appm He preimplanted. Some dislocations pointed out with red arrows.
consistent with coherency.179Figure 5.39: HR HAADF image of M2X (yellow) and matrix (red). FFT show same growth relationship < 1220 > M2X//< 100 > α , demonstrated by parallel lines.180Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.

Figure 5.44: Dislocation network evolution under 5 MeV Fe ⁺⁺ irradiation at 460°C in HT9 185
Figure 5.45: Dislocation loop evolution with increasing damage irradiated at 460°C with 5 MeV
Fe ⁺⁺ . Some loops are marked by white circles
Figure 5.46: Quantification of dislocation loop diameter from 130 to 650 dpa at 460°C irradiated
with 5 MeV Fe ⁺⁺
Figure 5.47: Quantification of dislocation loop number density from 130 to 650 dpa at 460°C
irradiated with 5 MeV Fe ⁺⁺ 188
Figure 5.48: Dislocation loop line length in HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C from 130
to 650 dpa
Figure 5.49: Loop (blue), network (red) dislocation line length and total line (green) length in
HT9 irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 650 dpa
Figure 5.50: Summary of evolving microstructure with damage in HT9 irradiated with 5 MeV
Fe ⁺⁺ at 460°C
Figure 6.1: Main structure and sub routines in RIME model
Figure 6.2: Effect of changing bias at 20 dpa on swelling at 460°C using Ref.2
Figure 6.3: Effect of changing grain size at 20 dpa on swelling at 460°C using Ref.2
Figure 6.4: Absolute value of significance of damage rate, temperature, grain size and bias.
Treatment including with (Ref.2) and without unbiased G phase (Ref.2.G) are both
included as a function of damage in RIME at 21 and 100 dpa
Figure 6.5: Absolute value of significance of bias, interstitial migration energy, vacancy
migration and formation energy, recombination coefficient and cascade efficiency. DD
treatment (Ref.2) used with significance reported as a function of damage in RIME at
21 and 100 dpa from the start of the case run
Figure 6.6: Comparison of cascade efficiency and dislocation loop and network bias for
interstitials of 1% (solid lines), 2% (dashed lines) and 3% (dotted lines)
Figure 6.7: Measured a) void and b) loop fraction in HT9 irradiated with 5 MeV Fe^{++} at 460°C to
188 dpa
Figure 6.8: Experimental void distribution (blue columns) compared with RIME void
distribution input (red line) into each case
Figure 6.9: a) Radius and b) number density of dislocation loops in HT9 irradiated with 5 MeV
Fe ⁺⁺ from 188 to 650 dpa at 460°C. Interpolation is from experimental data 251 xix

Figure 6.10: a) Radius and b) number density of G phase in HT9 irradiated with 5 MeV Fe ⁺⁺
from 188 to 650 dpa at 460°C. Interpolation is from experimental data 252
Figure 6.11: a) Effective radius and b) number density of M ₂ X-phase in HT9 irradiated with 5
MeV Fe ⁺⁺ from 188 to 650 dpa at 460°C. Interpolation is from experimental data 253
Figure 6.12: Comparison of Ref.0 treatment (<i>zinet</i> =1.01) with experimental data in terms of a)
network sink strength and b) void diameter, number density and swelling
Figure 6.13: Comparison of Ref.1 treatment ($ziloop = zinet=1.01$) with experimental data in
terms of a) network and loop sink strength and b) void diameter, number density and
swelling
Figure 6.14: Comparison of Ref.2 treatment ($ziloop = zinet=1.01$) with experimental data in
terms of a) loop and network sink strength b) loop diameter and number density and c)
void diameter, number density and swelling
Figure 7.1: Schematic of relationships between precipitates, dislocations and voids explored in
depth using RIME
Figure 7.2: Comparison of Ref.0 (solid) and Ref.0.N (dashed) treatments (zinet=1.01) with
experimental data in terms of a) void and network sink strength and b) void swelling.
Figure 7.3: Comparison of Ref.0 (solid) and Ref.1 (dashed) treatments ($zilp = zinet=1.01$) with
experimental data in terms of a) network, loop and total dislocation sink strength and
b) void swelling
Figure 7.4: Comparison of Ref.1 (solid) and Ref.2 (dashed) treatments (zilp = zinet=1.01) in
terms of a) void, network, loop and total dislocation sink strength and b) void
swelling
Figure 7.5: Comparison of net vacancies absorbed at voids in Ref.1 (solid) and Ref.2 (dashed).
Total dislocation sink strength is included in red. Discontinuity in Ref.1 case at 550
dpa is due to the manual increase in network sink strength which decreases d_ic_i and
$d_{\nu}c_{\nu}$
Figure 7.6: Comparison of swelling response to initial dislocation network density varied from
0.3 to 30×10^{14} m ⁻² in a) Ref.2 and b) Ref.1

Figure 7.7: Comparison of experimentally input loop and network treatment (Ref.1: zilp =
zinet=1.01) with experimental data in terms of a) network/loop sink strength and b)
void diameter, number density and swelling
Figure 7.8: Comparison of 1% (solid lines: Ref.1) and 0.7% biased (dashed lines: Ref.1.1.007)
with experimental data in terms of void diameter, number density and swelling 311
Figure 7.9: Comparison of DD treatment (Ref.2: zilp = zinet=1.01) with experimental data in
terms of a) loop and network sink strength b) loop diameter and number density and c)
void diameter, number density and swelling
Figure 7.10: Effect of G phase on void a) sink strength and b) swelling when included in
experimentally determined levels as an unbiased sink. Dislocations are treated as
experimentally input network and loops with (Ref.1.G: dashed lines) and without G
phase (Ref.1: solid) with zilp = zinet=1.01
Figure 7.11: Comparison of experimentally input loop and network treatment with G phase
included (Ref.1G: $zilp = zinet=1.01$) with experimental data in terms of a) G phase,
loop and network sink strength and b) void diameter, number density and swelling.314
Figure 7.12: Comparison of evolution of void and M_2X a) diameter and length and b) number
density and volume fraction/swelling from 188 to 650 dpa. All irradiations performed
with 5 MeV Fe ⁺⁺ at 460°C with 10 appm He preimplanted. Lines guide the eye 315
Figure 7.13: Comparison of swelling behavior with increasing <i>Ebv</i> , <i>tr</i> using Ref.1.MR with
zilp = zinet=1.01
Figure 7.14: Comparison of swelling with M ₂ X treated as either variable bias (red) or
recombination centers (blue) with experimentally input network and loop with
zilp=zinet =1.01
Figure 7.15: Comparison of Ref.1.MV (<i>zilp=zinet</i> =1.01) with experimental data in terms of a)
M_2X , loop and network sink strength and b) void diameter, number density and
swelling. All irradiations performed with 5 MeV Fe ⁺⁺ at 460°C with 10 appm He
preimplanted
Figure 7.16: Effect of G phase on network and loop a) sink strength and b) loop number density
and diameter when included in experimentally determined levels as an unbiased sink.

Dynamic dislocation treatment used both with (Ref.2.G: dashed lines) and without G
phase (Ref.2: solid lines) with zilp = zinet=1.01
Figure 7.17: Comparison of Ref.2.G (zilp = zinet=1.01) with experimental data in terms of a) G
phase, loop and network sink strength and b) dislocation loop diameter and number
density
Figure 7.18: Loop and M_2X diameter/length compared with number density as a function of
damage. All irradiations performed with 5 MeV Fe^{++} at 460°C with 10 appm He
preimplanted. Lines guide the eye
Figure 7.19: Effect of M_2X phase on network and loop a) sink strength and b) loop number
density and diameter when included in experimentally determined levels as a variably
biased sink. Dynamic dislocation treatment used with (Ref.2.MV: dashed lines) and
without M_2X phase (Ref.2: solid lines) with zilp = zinet=1.01
Figure 7.20: Effect of changing number of interstitial cluster groups from 60 (solid) to 160
(dashed) with DD treatment (Ref.2.MV: $zilp=zinet = 1.01$). M ₂ X treatment as variable
bias sink was used
Figure 7.21: Comparison of Ref.2.MV (<i>zilp=zinet</i> =1.01) with experimental data in terms of a)
M_2X , loop and network sink strength and b) dislocation loop diameter and number
density
Figure 7.22: Accounting for carbon in HT9 in the as-received condition and at 450 dpa 325
Figure 7.23: Comparison of Ref.2 with Ref.2.C with 0 to 855 appm for a) network and loop sink
strength and b) swelling. Case run with 3940 appm terminated at 400 dpa. 0 and 1
appm lines are indistinguishable in b)
Figure 7.24: Comparison of Ref.1 (blue), Ref.1.C with 100 appm in solution (red) and 100 appm
in solution removed stepwise from 188 to 450 dpa (green) representing the
precipitation of M ₂ X
Figure 7.25: Comparison of Ref.1.C (blue) and Ref.2.C (red) with 100 appm of carbon in
solution removed stepwise from 188 to 450 dpa representing the precipitation of M_2X .
Figure 7.26: Comparison of void swelling with M ₂ X plus 100 appm of carbon in solution

removed stepwise from 188 to 450 dpa (Ref.1.MV.C: green), M₂X (Ref.1.MV: red)

and Ref.1 (blue). All M_2X treated as variably biased with experimentally input
dislocations
Figure 7.27: Comparison of DD treatment (Ref.2.C: zilp = zinet=1.01) with experimental data
in terms of a) loop and network sink strength b) loop diameter and number density and
c) void diameter, number density and swelling including 100 appm of carbon in
solution removed stepwise from 188 to 450 dpa
Figure 7.28: Comparison of experimentally input loop and network treatment (Ref.1.G.MV.C:
zilp = zinet=1.01) with experimental data in terms of a) network, loop, G phase and
M_2X sink strength and b) void diameter, number density and swelling including M_2X
(variable biased), G phase and stepwise removal of 100 appm of carbon in solution
from 188 to 450 dpa
Figure 7.29: Comparison of DD treatment (Ref.2.G.MV.C: zilp = zinet=1.01) with
experimental data in terms of a) network, loop, G phase and M ₂ X sink strength b) loop
diameter and number density and c) void diameter, number density and swelling
including M_2X (variable biased), G phase and stepwise removal of 100 appm of
carbon in solution from 188 to 450 dpa
Figure 7.30: Comparison of swelling curves with various microstructure treatments. All cases
run with experimentally input dislocations (Ref.1: zilp = zinet=1.01)
Figure 7.31: Comparison of experimentally input loop and network treatment with lower bias
(Ref.1.1.007.G.MV.C: $zilp = zinet=1.01$) with experimental data in terms of a)
network, loop, G phase and M_2X sink strength and b) void diameter, number density
and swelling including M_2X (variable biased), G phase and 100 appm C in solution
removed stepwise from 188 to 450 dpa
Figure 7.32: Comparison between swelling rate before and after 450 dpa (Ref.1.G.MV.C: zilp =
zinet=1.01). Dashed lines guide the eye to approximate swelling rates calculated from
RIME
Figure 7.33: Comparison of instantaneous swelling rate calculated from experiment using
parabolic regression before and after 450 dpa using a) uncorrected swelling and b)
fixed depth method [85]

Figure B. 1: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 440°C up to 140 dpa with 10	appm He
preimplanted	
Figure B. 2: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 440°C up to 25 dpa with 10 a	ppm He
preimplanted	
Figure B. 4: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 440°C up to 188 dpa with 10	appm He
preimplanted	350
Figure B. 5: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 480° C up to 188 dpa with 10	appm He
preimplanted	351
Figure B. 6: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 400°C up to 250 dpa with 0 as	ppm He
preimplanted	
Figure B. 7: HT9 (ACO3) irradiated with 5 MeV Fe^{++} at 460°C up to 188 dpa with 10	appm He
preimplanted	353
Figure B. 8: HT9 (ACO3) irradiated with 5 MeV Fe^{++} at 440°C up to 50 dpa with 10 as	ppm He
preimplanted	
Figure B. 9: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460° C up to 375 dpa with 10	appm He
preimplanted	355
Figure B. 10: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 130 dpa with 10) appm He
preimplanted	356
Figure B. 11: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 75 dpa with 10	appm He
preimplanted	
Figure B. 12: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 250 dpa with 10) appm He
preimplanted	358
Figure B. 13: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 350 dpa with 10) appm He
preimplanted	359

Figure B. 14: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 450 dpa with 10 appm He	Э
preimplanted	0
Figure B. 15: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 550 dpa with 10 appm He	Э
preimplanted	1
Figure B. 16: HT9 (ACO3) irradiated with 5 MeV Fe ⁺⁺ at 460°C up to 650 dpa with 10 appm He	Э
preimplanted	2
Figure C. 1: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 440°C, to 140 dpa with 10 appm He	4
Figure C. 3: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 440°C, to 25 dpa with 10 appm He	5
Figure C. 4: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 440°C, to 188 dpa with 10 appm He	6
Figure C. 5: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 480°C, to 188 dpa with 10 appm He	7
Figure C. 6: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 400°C, to 250 dpa with 10 appm He	8
Figure C. 7: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 460°C, to 188 dpa with 10 appm He	9
Figure C. 8: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 440°C, to 50 dpa with 10 appm He	0
Figure C. 9: Void diameter, number density and swelling depth profiles as well as void	
distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
(ACO3) at 460°C, to 375 dpa with 10 appm He	1

Figure C.	10: Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
	(ACO3) at 460°C, to 130 dpa with 10 appm He.	372
Figure C.	11: Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
	(ACO3) at 460°C, to 75 dpa with 10 appm He.	373
Figure C.	12: Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
	(ACO3) at 460°C, to 250 dpa with 10 appm He.	374
Figure C.	13 Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV $\mathrm{Fe^{++}}$	
	(ACO3) at 460°C, to 350 dpa with 10 appm He.	375
Figure C.	14: Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
	(ACO3) at 460°C, to 450 dpa with 10 appm He.	376
Figure C.	15: Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++}	
	(ACO3) at 460°C, to 550 dpa with 10 appm He.	377
Figure C.	16: Void diameter, number density and swelling depth profiles as well as void	
	distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV $\mathrm{Fe^{++}}$	
	(ACO3) at 460°C, to 650 dpa with 10 appm He.	378

LIST OF APPENDICES

Appendix A - Temperature Histograms	343
Appendix B - Void Images	347
Appendix C - Void Depth Profiles and Distributions	363

ABSTRACT

THE CO-EVOLUTION OF MICROSTRUCTURE FEATURES IN SELF-ION IRRADIATED HT9 AT VERY HIGH DAMAGE LEVELS

by Elizabeth Margaret Getto

Chair: Gary S. Was

The objective of this study was to understand the co-evolution of microstructure features in self-ion irradiated HT9 at very high damage levels. HT9 (heat 84425) was pre-implanted with 10 atom parts per million helium and then irradiated with 5 MeV Fe⁺⁺ in the temperature range of 440-480°C to 188 dpa. A damage dependence study from 75 to 650 dpa was performed at the peak swelling temperature of 460°C. The swelling, dislocation and precipitate evolution was determined using Analytic Electron Microscopes in both Conventional Transmission electron microscopy (CTEM) and Scanning Transmission Electron Microscopy (STEM) modes. Void swelling reached a nominally linear rate of 0.03%/dpa from 188 to 650 dpa at 460°C. G phase precipitates were observed by 75 dpa and grew linearly up to 650 dpa. M₂X was observed by 250 dpa and peaked in volume fraction at 450 dpa. Dislocation loop evolution was observed up to 650 dpa including a step change in diameter between 375 and 450 dpa; which correlated with nucleation and growth of M₂X. The experimental results were interpreted using a rate theory model, the Radiation Induced Microstructure Evolution (RIME), in the damage range from 188 to 650 dpa. A simple system of voids and dislocations was modeled in which the dislocations measured from experiment were used as input, or the dislocations were allowed to evolve dynamically, resulting in swelling that was overestimated by 63% relative to that observed experimentally. G phase had limited effect on the void or dislocation behavior. The behavior of M₂X within the microstructure was characterized as a direct effect as a coherent sink, and as an indirect effect in consuming carbon from the matrix, which had the largest impact on both void and dislocation behavior. A slowly monotonically increasing swelling rate was observed both experimentally and computationally, with swelling rates of ~0.025%/dpa and ~0.036%/dpa before and after 450 dpa. The agreement in void behavior between experiment and model when all effects (loops, network, G phase, M₂X formation and growth, and removal of carbon) are accounted for demonstrates the importance of characterizing the evolution of the full microstructure over a large dpa range.

CHAPTER 1 INTRODUCTION

The rapidly growing world population has increased the demand for natural resources including energy. Growing concerns about climate change have fueled a return to interest in nuclear power as a significant carbon-free base-load energy source. However, uncertainty about nuclear waste policy has led to increased focus on alternative reactor concepts that minimize waste. Generation (Gen) IV reactors are key in meeting the rapidly growing demand for energy now and in the future. The concerns about residual nuclear waste have thus created a demand for greater fuel utilization via increased burnup. Higher burnup will push the limits of reactor structural materials to damage levels not yet reached in the current light water reactor (LWR) fleet or fast reactors used in the past. Thus, understanding the behavior of core and structural materials under irradiation is paramount to the success of new reactor concepts including TerraPower's Traveling Wave Reactor (TWR) concept.

The main differentiator of the TWR from "traditional" breeder reactors is its unique core [1]. Fertile fuel assemblies consisting of depleted uranium (for breeding) and low enriched uranium fuel assemblies will be arranged within the core to enable both burning and breeding of fuel. What presents a unique materials challenge is that the core operates without refueling. Fuel shuffling is utilized to create either a traveling wave from the inside of the core to the outside or alternatively, a "standing wave" of breeding/burning that distinguishes this reactor design and gives it its name. The shuffle would simply move fuel assemblies of high burnup from the middle of the core to the outer rim, without reload, a significant deviation from traditional LWR operation leading to a much higher burnup and therefore more radiation damage to core materials. Damage levels are expected to reach at least 200 displacements per atom (dpa) and above in sodium fast reactors [2] and 600 dpa in TWRs after 60 years in operation [1,2], which presents a unique material challenge as this requires highly radiation tolerant materials. Furthermore, there is no existing database at such high damage levels for any type of steel under neutron irradiation. Finally, the push to higher burnup and damage is not unique to TWRs, but also to other Gen IV reactor designs including alternative sodium fast reactor concepts.

Ferritic-martensitic (FM) steel alloys are leading candidates for structural and cladding components in Gen IV designs. FM steels are candidates for fast reactors because of their compatibility with sodium, superior resistance to radiation damage such as void swelling and excellent thermal conductivity and thermal expansion coefficient [3]. It was first determined in the 1970s that austenitic stainless steels, given their susceptibility to both void swelling and creep, were unsuitable for both breeder-type reactors and fusion devices expected to reach very high damage levels. FM alloys, previously developed for applications in high temperature coal plants, have become an alternative to stainless steels. Initial testing at the Fast Flux Test Facility (FFTF), a sodium fast reactor in Hanford, Washington, showed promise in terms of increased radiation tolerance, especially in terms of void swelling resistance, and continued to motivate the transition from advanced stainless steels such as D9 to FM alloys.

FM steels are body centered cubic (bcc) iron alloys with major additions of chromium, typically with Cr concentrations of 7-15 wt% with most commercially available alloys having either 9 or 12 Cr wt% [3]. They have additions of other minor alloying elements, such as W, V, Mn, Ta, Ti and Mo, to add desirable material properties such as strength or ductility. FM alloys

are uniquely identified by their complex microstructure including laths, subgrains and secondary phases that form during heat treatment of the alloy or under irradiation, which typically leads to a much higher sink density than conventional austenitic stainless steels.

Under high damage irradiation, a number of microstructure features form, most of which are detrimental to material integrity and safety. Of primary interest to this thesis, formation of voids causes dimensional instability. In addition, formation and evolution of secondary phases and dislocation loops under irradiation can lead to increased hardening and embrittlement of the alloy.

Void swelling has been studied extensively in other alloys such as austenitic stainless steels, but very little systematic experimental work has been performed on void swelling in FM alloys due, in part, to the high degree of swelling resistance. Very few voids form at the relatively low damage levels examined. However, some limited results for neutron (up to 200 dpa) and ion irradiation (up to 600 dpa) do exist. Neutron irradiations performed in FFTF up to 200 dpa indicates that swelling remains below 3.2% in the temperature range 400-460°C [4–10]. However, the scarcity of data makes it difficult to determine whether or not swelling is in the so-called steady state swelling regime, which is characterized by void growth-dominated swelling and a linear or near linear swelling rate. If the highest neutron damage (165-200 dpa) irradiations are in the growth-dominated steady state swelling regime, then the linear swelling rate is expected to be ~0.01-0.02%/dpa [5,7,10,11].

More recently, ion irradiation has proven effective as a surrogate for neutron irradiations [2,12,13] resulting in more systematic studies of temperature and damage, but has yielded conflicting results. Smidt *et al.* [14] found swelling of up to 4.7% at 450°C and 250 dpa in HT9. Assuming swelling is linear by 250 dpa, the swelling rate is ~0.02%/dpa. In contrast, Toloczko *et*

al. [15] in irradiations performed with 1.8 MeV Cr^{3+} at 450°C determined a final swelling rate of 0.2%/dpa at damage levels of 400 dpa and above.

In addition to uncertainty of the high damage void swelling behavior, secondary phases have not been examined at commensurately high damage levels. The main precipitates observed in reactor or under ion irradiation in this temperature and damage regime are G phase, M₂X and α' [3]. Finally, there exists no systematic study of dislocation formation without stress beyond 10 dpa, but recent results from Gupta *et al.* [16] and Jiao *et al.* [17] suggest that dislocation loop diameter saturates by 10 to 20 dpa, well below the void growth-dominated swelling regime.

The limited and somewhat contradictory experimental results from both neutron and ion irradiations highlight the need for a systematic study of the evolution of void swelling and other microstructure features to a very high damage level in FM alloys. In particular, and especially relevant to this thesis, is that the so called terminal swelling rate of FM alloys is a subject of some debate. Consequently, there are no studies on the effect of other irradiation-induced features such as secondary phases and dislocations on voids at this high damage and high swelling rate.

The objective of this thesis is to understand the co-evolution of microstructure features at very high damage in self-ion irradiated HT9. This will be accomplished with a combination of ion irradiation experiments followed by post irradiation microstructure characterization and computational modeling. Chapter 2 will provide extended background from the literature relevant to this thesis. Chapter 3 will present the detailed objective and associated approach. Chapter 4 presents the experimental details and methodology utilized in ion experiments. Results from ion irradiation experiments and post-irradiation characterization will be presented in Chapter 5. Chapter 6 will present the modeling portion of the thesis, including additional background relevant to the computational model. Chapter 7 will present a discussion and analysis of the combined

experimental and modeling results. Chapter 8 will present final conclusions and finally, Chapter 9 will suggest possible future work.

CHAPTER 2

BACKGROUND

Cladding and structural components will be subject to a high fluence of fast neutrons in Generation IV reactors, especially in TerraPower's traveling wave reactor concept. Although there is a large database of knowledge of radiation effects on materials under light water reactor conditions, a limited amount of these results can be applied to next generation reactors since they are at relatively low damage (<100 dpa) levels. Nevertheless, significant materials degradation has occurred at these damage levels via radiation-induced segregation (RIS), nucleation and growth of dislocation loops, secondary phase formation causing hardening and embrittlement as well as dimensional changes such as creep and void swelling.

FM alloys are being considered as alternatives to stainless steels used in previous fast reactor designs because of improved radiation tolerance. However, the existing dataset is small and little to nothing is known about void swelling in the very high damage regime in these alloys, due to their high degree of swelling resistance and the low damage levels achievable in test reactors. Additionally, the coupling of temperature and flux makes systematic damage or temperature studies challenging.

This chapter will provide background necessary to place results of this thesis in context within the existing literature. First, void swelling will be introduced and mechanisms described in
a theoretical framework. Then, the existing experimental measurements of void swelling as well as other irradiation-induced phenomena that may influence void swelling will be presented.

2.1 Mechanisms of Void Swelling

Swelling is caused by the formation and growth of cavities under irradiation. The supersaturation of vacancies due to irradiation and biased sinks drives void nucleation and growth by vacancy agglomeration, which in turn causes bulk dimensional change. Although it is well understood in austenitic alloys that voids undergo a nucleation period followed by linear or "steady state" swelling rate of ~1%/dpa [8,18], there is little evidence that ferritic-martensitic alloys exhibit linear swelling behavior at any levels approaching 1%/dpa. Furthermore, the influence of other irradiation features on void swelling has not been studied systematically. An introduction to void swelling followed by a discussion of ferritic-martensitic alloys will be presented. The current void swelling results under neutron and ion irradiation will be reviewed.

The term cavity is inclusive of both bubbles, which by definition require helium to stabilize, whereas voids do not require helium to be stabilized. In other words, all voids are cavities but all cavities may not be voids. At large sizes (>20 nm), it is a safe assumption that all cavities are voids. Thus, for the swelling range examined in this study, it is safe to assume all cavities are in fact voids and for preference will be given to this nomenclature from here on.

2.1.1 Introduction to Void Swelling

Irradiation-induced void swelling in susceptible metals and alloys evolves through three different void behavior regions shown in Figure 2.1 [19]. In the *nucleation regime*, cavity embryos are nucleated then stabilized to form bubbles or small voids, which are resolvable by transmission electron miscopy (TEM) or scanning transmission electron microscopy (STEM) at ~1 to 2 nm.

Swelling increase in this regime is dominated by the nucleation of new stable bubbles or voids. There are two nucleation pathways for void formation under irradiation [18,20,21]. The first pathway is agglomeration of small vacancies or vacancy clusters that then reach a critical size; which is a mechanism that is dependent on stochastic fluctuations in the damaged microstructure. The second pathway is accumulation of small gas-stabilized bubbles (typically helium) until they reach a critical size beyond which gas accumulation is not needed for growth and they convert from bubbles to voids. Helium decreases the critical size necessary for a stable cavity by reducing the free energy barrier.

As these void embryos nucleate and stabilize, they start to accumulate vacancies and grow in size. At this point, the void distribution is centered at low diameters (<10 nm) and has a small full width half maximum, as growth is not yet the dominant process. In the *transition region*, there is simultaneous nucleation of new stable embryos while existing voids grow by vacancy agglomeration. Thus the void size distribution expands and the mean void diameter increases as stable voids grow. The increase in swelling is due to both nucleation of new voids as well as growth of already nucleated voids. After a period of time depending on the swelling resistance of the alloy in question, growth dominates and the swelling reaches the *growth-dominated regime*, which continues to very high damage levels and is characterized by a near constant swelling rate [19]. This has also been referred to as steady state swelling due to linear final swelling value observed in reactor for austenitic and pure alloys [8,22–24]. An alternative theory suggests that swelling may even saturate at sufficiently high swelling values, but this has only been shown to happen in AISI 316 at 260% swelling at 600 dpa [25]. Although void swelling is classified into these three regimes, the transition is not distinct as the regimes overlap in time. Void evolution is well documented in both FCC austenitic alloys [8,22,25] and pure metals [3,23,26], which are relatively susceptible to void swelling. The final linear swelling rate appears to be independent of heat treatment and temperature for austenitics [8,27] within the temperature region where metals/alloys are susceptible to void swelling ($T \approx 0.3T_m - 0.5T_m$) [20]. Although void swelling is well understood in austenitic alloy, there is limited data, particularly at high damage level, for ferritic-martensitic (FM) alloys, which are candidate materials for Gen IV fast reactors. The lack of swelling data in FM alloys is due to a combination of the swelling resistance of FM alloys, as well as their relatively limited use in reactors to date [4,6–8].

2.2 Ferritic-Martensitic Alloys

High chromium steels refer to those that contain 7-12% chromium. The first high chromium steel was developed in 1912 for steam turbine blades in Germany. British scientists then discovered that martensitic steels were rust resistant during unrelated experiments for gun barrel applications. Initial commercial applications included knives, tableware, razors and heat resistant bearings and tools [3]. High chromium steels continued to be developed for applications in chemical plants, aerospace technologies, electrical plants and gas turbine engines throughout the rest of the 20th century. There was renewed interest in high chromium FM steels during the fifties and sixties due to a large push to improve efficiencies of coal power plants [28]. Increased efficiency was accomplished by increasing the temperature and pressure of the steam, leading to a need for supercritical boilers, designed to operate to ever increasing temperatures and pressures. As a result, steels needed to be developed that operated with low thermal fatigue, high thermal conductivity and low thermal expansion. Austenitic steels, previously used in coal plants, did not possess sufficient thermal properties to operate safely and effectively under the new required operating conditions [28]. Interest continued to grow throughout the seventies and early eighties,

due to the energy crisis of the seventies and interest in first fast breeder then fusion applications [3].

It became apparent that austenitic steels were susceptible to both irradiation-induced creep and void swelling so scientists turned to the high chromium steels that were being utilized in fossil fuel applications. In 1974, scientists worldwide began an effort to optimize breeder reactors with a new type of steel, instead of the previously utilized AISI 316. Two FM alloys that were under consideration were HT9 and T91. HT9 was used in many fuel tests as primary core materials including duct and cladding as well as pressurized tubes used to study creep at the Fast Flux Test Facility (FFTF) in Hanford, Washington [4–7,11,29].

FM steels, in general, possess a number of useful properties [3]. These properties include high thermal conductivity, low thermal expansion and resistance to thermal fatigue; all of which are necessary for usage in high temperature fossil fuel plants as well as in high or very high temperature reactors. They also exhibit sufficient strength to be of practical use in power plants. 12Cr steel, in particular, exhibits excellent oxidation resistance. They show particular resistance to irradiation-induced creep and void swelling.

There are several limitations with FM steels. Body-centered-cubic (BCC) structures exhibit a ductile-brittle transition temperature (DBTT) that increases significantly with radiation [3]. Furthermore, radiation embrittlement and irradiation-induced creep will still be a consideration for FM steels. Finally, welding is much more difficult than for conventional austenitic stainless steels.

2.2.1 Physical Metallurgy

Processing of FM alloys involves three heat treatments: austenization, transformation to martensitic phase and tempering. The phase diagram relevant for FM alloy formation is given in

Figure 2.2 [3]. Typically, austenization occurs when the alloy is heated up to ~800-1450°C for 9-12 wt% Cr alloys. The austenizing temperature can be affected by the addition of austenite (γ) stabilizers, which typically lower the temperature required for complete austenization of the steel, but at the risk of the formation of MC carbides if C, the most commonly used and inexpensive austenite stabilizer is used. Thus, a higher temperature is desirable as it has the added effect of dissolving MC carbides resulting in coarser prior austenite grain (PAG) sizes and complete transformation to austenite before cooling. Austenization temperature for HT9 is typically around 1050-1100°C. Following cooling, all or most of the phase transforms to martensite, unless austenite or ferrite stabilizers such as nickel or chromium are added. In general, HT9 may consist of all three phases: austenite, martensite and δ ferrite, but an effort is made to minimize both retained austenite and ferrite. Initially, the austenite to martensite transformation yields a very brittle microstructure prone to brittle fracture due to the high dislocation density.

Martensite is formed in thick sections known as laths, due to inhibition of pearlite transformation and absence of bainite. A continuous cooling transformation (CCT) diagram is shown in Figure 2.3. Lathes tend to be low in carbon and are usually around 0.5-1 μ m by 5 μ m in length [30]. Upon cooling, the austenite phase normally transforms to martensite, but when the martensite start temperature is close to room temperature austenite is retained. In an ideal microstructure, PAG has packets of martensite laths that are parallel. Laths within a single pack occupy the same habit plane, have the same orientation and are often very closely aligned in terms of crystallography.

The final step, tempering, is required to improve toughness by refining the microstructure. Tempering causes formation of small precipitates such as $M_{23}C_6$, which improve toughness and reduce softening, and is performed at a temperature below austenization to avoid re-austenization. Typically, tempering is performed around 760-850°C for conventional FM alloys and 870-960°C for reduced activation steels [3]. The effect of tempering temperature is as follows:

- <350°C: M₃C precipitates form and grow into a dendrite morphology
- 450-500°C: Fine needles of M₂X precipitate nucleate on dislocations causing retardation of softening
- 500-550°C: M₇C₃ and M₂X phases coarsen and decrease hardness
- >550°C: Cr-rich M₂₃C₆precitiates nucleate on the martensite laths and PAG boundaries
- $>650^{\circ}$ C: M₂₃C₆ precipitates coarsen, reducing dislocation density
- >750°C: sub-cell within laths grow into equi-axed grains and continued growth of M₂₃C₆
 [3]

During tempering, the dislocation networks rearrange into a lower energy configuration with the lath forming small subgrains. Dislocation motion and rearrangement is caused by thermally-activated dislocation climb and glide and results in small grain orientation angles. The martensitic phase has lathes with high dislocation density, even after tempering and formation of subgrains. The resulting dislocation network density is on the order 10¹⁴-10¹⁵ m⁻² [3,31]. A schematic and typical microstructure is presented in Figure 2.4 [3,32].

Finally, tempering also results in precipitation of carbon out of the matrix, which then precipitate as carbides on the PAGB (prior austenite grain boundaries). They preferentially nucleate on PAGBs rather than lath or subgrain boundaries due to the increased diffusion rate along high angle boundaries [30,32].

2.3 Void Swelling Experiments in Ferritic-Martensitic Alloys

Although there is limited data at high (>100 dpa) or very high damage (>200 dpa) for void swelling in FM alloys, there exists a non-trivial dataset at lower damage levels that may approach the high damage/growth-dominated swelling regime. The following is a summary of both in-reactor (Section 2.3.1) and ion (Section 2.3.2) irradiations. A discussion of irradiation-induced defect partioning and its relation to void swelling is also included.

2.3.1 Void Swelling under Neutron Irradiation

Sencer *et al.* performed a study using neutron-irradiation at the Fast Flux Test Facility (FFTF) on HT9 [9,10]. A duct was irradiated under a variety of conditions at a temperature of 443°C up to 155 dpa. Swelling was calculated via TEM measurement of the voids and was 0.3% on average. However, it is unclear whether void growth-dominated swelling was reached or if the swelling was in the transition regime since average void diameter was ~30 nm. If the swelling was transient in nature, it would be expected that the swelling could increase at a faster rate at higher damage levels. Assuming linear swelling, the swelling rate could be as low as 0.002%/dpa. However, the results of this study do not provide enough data to support a prediction for swelling amount or rate, especially given the likelihood that the swelling is still exhibiting transient-type behavior. It is worth mentioning that this is the same heat (84425) as was examined in this thesis.

Gelles [7] performed microstructure examination of commercial alloys (HT9 and T91) irradiated at FFTF up to approximately 200 dpa. A single heat of HT9 (9607R2) with two different heat treatments was examined: RFFL (Heat 9607R2, 1000°C/20 h+1100°C/5 min+700°C/2 h) and RHFL (Heat 9607R2, 1050°C/5 min+760°C/0.5 h) and compared to a third heat/heat treatment of T91 designated as PTFL (Heat 30176, 1040°C/1h+760°C/1 h). Overall, the T91 (PTFL) swelled the most when measured via the density change method with 1.76% average swelling. Compared to the RHFL heat treatment of HT9, which swelled 1.02% and the RFFL heat treatment of HT9

that swelled by only 0.09%. This result indicates that heat treatment can be at least as important as alloy composition in terms of swelling resistance. Additional evidence is that the HT9-RHFL and T91-PTFL heat treatments, which swelled the most, also had the most similar heat treatments, with shorter tempering and austenization times. However, swelling in any of the 3 alloys/heats/heat treatments examined likely had not reached the growth-dominated swelling regime, so this was likely a measurement of the resistance to void nucleation rather than an examination of the growth regime. The observed void structures were consistent with expected void structures in martensitic steels; i.e. void arrays between lath boundaries and void denuded zones on and adjacent to boundaries. The HT9 microstructure had blockier carbide precipitation on boundaries and lower density of larger voids when compared to T91. Swelling was also found to be independent of Burgers vector distribution.

Toloczko and Garner [4,6] examined irradiated HT9 from the FFTF facility to examine creep and swelling behavior. Swelling behavior was examined at damage levels up to 165 dpa and temperatures in the range 384-427°C. Swelling remained under 1% for all HT9 heats up to 165 dpa at 400°C, without stress. Maximum swelling rate appeared to be ~0.01%/dpa. A comparison of incremental swelling with swelling rate is shown in Figure 2.5. Heat treatment as well as heat-to-heat variation are major factors in swelling and were found to cause orders of magnitude changes in swelling rate. Although the samples were nominally the same composition and heat treatment, the swelling variance was attributed to differences in production variables, which were not characterized by the authors.

Toloczko *et al.* [5] also examined HT9 at a damage level up to 208 dpa at ~400°C in FFTF. Swelling reached up to ~1% swelling at 208 dpa in the absence of a hoop stress. Assuming linear swelling, the swelling rate again was found to be less than ~0.01%/dpa. Swelling measured from 165-208 dpa did not increase substantially. It was also found that swelling was accelerated by hoop stress. A 9Cr-1Mo alloy was also examined and swelling was measured to be 0.8% at the same temperature and damage level.

The effect of the chromium composition was examined by Gelles [33] in neutron irradiations of up to 200 dpa at 425°C. Using previous irradiation data from EBR-II and results from FFTF, the void swelling and microstructures were characterized as a function of chromium composition. Swelling peaked between 6 and 9 Cr wt%. The maximum swelling of 7.4% was observed in the Fe-9Cr alloy. The Fe-12Cr alloy (similar chromium content as HT9) had swelling of 2.8%. Fe-18Cr and Fe-15Cr had the lowest swelling levels. For all chromium compositions, there appeared to be a slower swelling rate up to just under 150 dpa (presumed transient regime) and an accelerated swelling rate afterwards (Figure 2.6), indicating possible linear swelling behavior. However, very few damage levels were examined. The highest average swelling rate was estimated to be 0.1%/dpa for Fe-9Cr. However, irradiations were performed in two different reactors with two different neutron spectra and He/dpa ratios.

Another important value examined in this study is the sink density ratio (Q). Q is the ratio of the void sink strength to that of dislocations. Q analysis was developed by Mansur [34] to predict the damage dependence of swelling in austenitic alloys and ferritic-martensitic alloys to a limited extent. Q is defined as:

$$Q = \frac{Z_{i,v}^d \rho_d}{Z_{i,v}^c 4\pi r_c \rho_c}$$
(2.1)

where $z_{i,v}^d$ is the bias factor for either dislocations or cavities, ρ_d is the dislocation density including both network and loops, r_c is the cavity radius and ρ_c is the cavity density. Assuming bias factors are similar, the expression for Q can be simplified to the following:

$$Q = \frac{\rho_d}{4\pi r_c \rho_c} \tag{2.2}$$

The peak swelling rate is expected at values of $Q\sim1$, which was observed in this study at 200 dpa. The maximum swelling rate is likely to be synonymous with linear swelling [34]. The implications for Q will be further discussed in Section 2.3.3. Voids were homogeneously distributed throughout the microstructure except for the void denuded zones near grain boundaries [33]. Larger voids were imaged attached to needle-shaped precipitates in the 18Cr alloy only.

After the publication of Gelles' paper ([33]) on the effect of chromium content on swelling, Garner *et al.* [8] suggested an error had been made in the damage calculation and the dpa levels were adjusted. Garner *et al.* suggest that the calculated 0.06%/dpa swelling rate from 0-150 dpa was mistaken. A comparison of their corrections next to the original data from EBR-II is given in Figure 2.7. Assuming that the new damage is more accurate, this increases the swelling rate by approximately an order of magnitude. Additionally, it was suggested in Garner's study that the temperature dependence of swelling arises primarily by extension of the transient regime, rather than a difference in the swelling rate observed in the high damage level growth-dominated regime, which is still consistent with the bell-shaped curve predicted by swelling theory [20]. The author also suggested that final swelling could be as high as 0.5%/dpa, and could approach the swelling rate of austenitic steels; however, there was no experimental evidence of such a swelling rate.

A summary of void swelling results of neutron-irradiated HT9 is given below in Figure 2.8. Clearly, swelling varies greatly with heat treatment but in general tends to increase at a rate of 0.01%/dpa. In addition, there is no data beyond 208 dpa under neutron irradiation.

2.3.2 Void Swelling under Ion Irradiation

Kai and Kulcinski [35] investigated the effect of helium preimplantation on 14 MeV nickel irradiated HT9 in damage levels up to 200 dpa. There was no void formation in samples without helium preimplantation at 500°C to 200 dpa. However, the 200 dpa location was at the peak, where the injected interstitial has been shown to suppress void swelling [12,25,36]. At 30 dpa, voids did not form at temperatures other than 500°C. The highest swelling value (0.02%) reached was at 60 dpa, 500°C with 100 appm He preimplanted.

Comparisons between cold pre-injection of helium and simultaneous co-implantation was examined by Ayrault in a 9Cr-1Mo [37]; both damage dependence (5, 10 and 25 dpa) and temperature dependence (450, 500, 550 and 600°C) experiments were performed. Helium levels were 15 appm He/dpa and implanted using a degraded 0.83 MeV He⁺ ion beam at the Argonne National Lab Dual-Ion Beam Facility. 3.0 MeV Ni⁺ ions were used for the irradiation and damage rates were $3-4\times10^{-3}$ dpa/s. There was more cavity formation in the co-implanted samples then the pre-injected samples. It was also observed that there was a peak swelling temperature at 450°C, regardless of method of helium implantation. All swelling was below 0.05%, which is likely far below the onset of linear or growth-dominated swelling.

Smidt *et al.* [14] irradiated HT9 and EM12 steel with 2.8 MeV Fe⁺ ions up to 250 dpa preimplanted with 1 appm He. The primary objective of this study was to understand the relationship between temperature and swelling. The peak swelling temperature was determined to

be 500°C for HT9 and 550°C for EM12. Once peak swelling temperature was determined, a damage dependence study was performed up to 250 dpa. Temperature dependence for both steels is plotted in Figure 2.9a. Swelling was maximized at 500°C and 3.7% for HT9 at 150 dpa. The swelling curve as a function of damage is plotted in Figure 2.9b. The linear swelling rate was calculated to be 0.017%/dpa for HT9 and 0.011%/dpa for EM12. EM12 had a transient regime of approximately 10 dpa and HT9 appeared to have a higher swelling rate from 0-40 dpa, which does not agree with swelling theory. Swelling behavior was atypical and did not exhibit nucleation; the transient swelling followed what appeared to be a linear swelling rate. Swelling values were higher than those of neutron irradiated samples at similar temperatures and damage levels.

Borodin *et al.* [38] examined various 10-13% chromium-containing steels with heavy ions (3 MeV Cr⁺³) including 13Cr-2Mo-Nb-V-B, 13Cr-2Mo-TiO₂, 10Cr-6Mo-Nb-V and Fe-12Cr from 1 to 150 dpa. Maximum swelling of 0.5% was observed at 500°C, 150 dpa suggesting a peak swelling temperature of 500°C for the Fe-12Cr alloy. Swelling was examined in both ferrite and martensite phases and remained below 0.5%, regardless of grain type. Void behavior differed in each of the phases; for the ferrite phase, voids were distributed homogeneously and for the martensite phase, voids were highest near cell walls.

Ferritic steels irradiated with heavy ions were examined by Ward and Fisher [39]. Fe-10Cr and FV448 (10Cr with solute additions) were irradiated up to 50 dpa with helium preimplantation with 52 MeV Cr ions. Swelling in the Fe-10Cr was 4.6% and in the FV448 was 0.1%, indicating the improved swelling resistance of commercial alloys with solute additions. The swelling rate of the Fe-10Cr was the highest observed in an FM alloy at the time. Lower damage experiments showed that a dislocation network formed very quickly in the high purity metals, and slower in the

commercial alloys. Since a stable dislocation network is correlated to higher swelling rates, these results are consistent with expected swelling behavior.

Hide *et al.* [40] irradiated FM steels in a two-step process. Specimens were first injected with 42 keV helium ions and then irradiated with either carbon (200 keV) or nickel ions (3 MeV) up to 200 dpa with damage rates of 1×10^{-2} dpa/s. Irradiations were performed between 425-625°C. Maximum swelling was 0.3% at 575°C and 150 dpa. Larger cavities of around 17 mm were formed at 525°C and were homogeneously distributed. For all FM steels, swelling was very low and temperature and damage relationships are plotted in Figure 2.10. Estimated swelling rate was 0.001-0.003%/dpa at peak temperatures, suggesting void evolution had not proceeded to any great extent.

Toloczko *et al.* [15] examined swelling in Cr^{3+} -irradiated ODS ferritic alloy MA957, EP 450 and HT9 up to 600 dpa. Damage and temperature dependence experiments were performed. At 450°C, all three alloys were examined up to 600 dpa. The authors determined that steady state/linear swelling in HT9 was not reached until approximately 400-600 dpa and the swelling rate was determined to be approximately 0.2%/dpa, which was consistent with previous results from Garner *et al.* under neutron irradiation [8]. MA957 did not reach this high of a swelling rate, which the authors attributed to an extended nucleation regime. The temperature dependence results are shown in Figure 2.11b. Peak swelling temperature was determined to be 450°C at 500 dpa.

A summary of ion irradiations, analogous to Figure 2.8, is shown below in Figure 2.12. It highlights the conflicting results between different experiments. The overall results of this literature search show that void swelling evolution to high damage is not well understood in FM alloys. Specifically, neither the length of void incubation nor the high damage swelling rate has been determined to any degree of consistency because FM alloys have been shown to be highly

resistant to void swelling both in reactor [4–10] and by ion irradiation [15,35,37–40]. Since accessing the post-transition swelling regime requires high damage levels, there is little data in the literature at damage levels in excess of 100-200 dpa. Such damage levels have only recently become experimentally feasible due to recently improved ion source performance.

2.3.3 Defect Partitioning

Related to understanding void swelling, the evolution of various microstructure features with increased damage can be tracked by determining how the freely migrating defects are partitioned. In other words, at which sinks do they agglomerate, how many recombine, and how many annihilate at various other sinks. Defect absorption at sinks (i.e. microstructure features) is determined by the sink strength. Sink strength determines the affinity of a microstructure feature for defects. The simplest method to analyze defect partitioning is by a Q analysis, which uses void and dislocation sink strengths (i.e. defect partitioning) described in Section 2.3.1.

This model is simplistic in that it only takes into account dislocations and voids. Other features, such as coherent and incoherent precipitates, grain boundaries and lath boundaries also act as sinks, which are not addressed in this analysis. An additional simplification is the assumption that bias factors are approximately equal. Since swelling is bias driven, this makes little physical sense for large values of bias. Ferritic-martensitic alloys are expected to have low values of bias (<10%) [8,41–43], especially when compared to austenitic stainless steels. Finally, Q analysis has only been applied at limited damage levels and correspondingly low swelling values. However, a summary of the available results is presented in Figure 2.13. A more sophisticated defect partitioning analysis via modeling of individual defect behavior at various sinks including precipitates, dislocations and voids would be both more useful and applicable to the physical behavior under irradiation.

2.4 Dislocation Microstructure

Dislocation analysis in FM alloys has primarily been studied within the context of mechanical properties such as creep [30,44], fatigue [45,46] or tensile deformation [47], but limited data is available for FM alloys not under stress. The interaction between biased loops and voids is critical. The bias for interstitials enables the free vacancies necessary for void swelling to initiate and continue. The dislocation network also makes a significant contribution to irradiation hardening, which will be discussed later in this chapter, for completeness but will not be analyzed in this work.

2.4.1 Loop Character

Prior to irradiation, lathes in FM alloys [3] contain dislocations with a Burgers vector of a/2 < 111> and a density typically around 10^{14} m⁻². This is large when compared to typical dislocation densities in pure metals or solution annealed stainless steel alloys that have not been cold worked. Under irradiation below $0.3T_m$ (where T_m is the melting temperature of the alloy), interstitials are much more mobile than vacancies, leading to formation interstitial-type dislocation loops. Vacancy loops, nucleated by collapse of depleted zones within the cascade, are theoretically possible but have not been observed in ferrite and as such are not expected in FM alloys [3].

Dislocation loops form under irradiation with two possible Burgers vector orientations: a cube edge-loop with \mathbf{a} <100> or glissile edge loops with \mathbf{a} /2<111> Burgers vectors on {111} habit planes. Loops tend to vary in size from 10 to ~40-50 nm in size. They can be formed by shearing from a common \mathbf{a} /2<110> nucleus. The high stacking fault energy in high-Cr FM alloys means that loops unfault very early by shear in one or two directions [47] and faulted loops are not observed.

Interactions between dislocations form a complex dislocation network. $\mathbf{a} < 100 > 100$ have strong interstitial bias and it has been theorized that the $\mathbf{a}/2 < 111$ > network has less of a bias [3,48]. Assuming this theory is correct, it means that $\mathbf{a}/2 < 111$ > are essentially neutral sinks whereas $\mathbf{a} < 100$ > are more biased sinks. Thus, the formation of a stable $\mathbf{a} < 100$ > 100p population instead of the preexisting $\mathbf{a}/2 < 111$ > network has been correlated with the extended nucleation regime for void swelling as the bias increases with the growth of loops as a function of damage [41]. Under irradiation, loops have been observed to be primarily of $\mathbf{a} < 100$ > character while the network still tends to consist of dislocations with Burgers vector $\mathbf{a}/2 < 111$ > as in the unirradiated microstructure.

2.4.2 Dislocation Microstructure under Irradiation

The dislocation microstructure of commercial FM alloys and binary Fe-Cr model alloys irradiated at 420°C to nominally 200 dpa were characterized by Gelles [7,11,33]. HT9 exhibited a dislocation microstructure dominated by $\mathbf{a}/2 < 111$ > network with a low density of $\mathbf{a} < 100$ > loops. Loop sink strength (0.83×10^{14} m⁻²) was approximately an order of magnitude lower than the network (9.8×10^{14} m⁻²) in Fe-12Cr [33]. Similar behavior was observed in T91 irradiated under the same conditions; with the loop population dominated by $\mathbf{a} < 100$ > type loops and network of $\mathbf{a}/2 < 111$ > character. The dominance of the $\mathbf{a}/2 < 111$ > network was attributed to the subgrain structure in the as-received condition.

Binary alloys were also irradiated to similar conditions (420°C, 200 dpa) and will be considered, as there is a shortage of dislocation data in commercial FM alloys. At 200 dpa, [11,33] model Fe-12Cr alloys exhibited small (~15 nm) \mathbf{a} <100> loops and both \mathbf{a} <100> and \mathbf{a} <111> lines in the network. In terms of morphology, there were fewer dislocations with Burgers vectors of \mathbf{a} <100> located at or near subgrain boundaries, which is likely a result of the tempering step. The behavior of Fe-9Cr was the same in terms of the character of the loops and the network. FM alloys examined by Dubuisson *et al.* [49] showed formation of dislocation loops from 400-450°C as well as a large dislocation network with small unfaulted loops at high temperatures of 500°C and above. There was little dislocation evolution with increasing damage levels up to 100 dpa, but no quantitative results were given.

Kai and Kulcinski characterized the dislocation microstructure of 14 MeV Ni-irradiated HT9 [19,35]. A high density of dislocation loops was found after irradiation in the temperature range of 300-600°C. Loops were interstitial in nature with $\mathbf{b}=\mathbf{a}<100>$. The high network density prior to irradiation was replaced by irradiation-induced loops. Damage dependence was not examined. Dislocation loop diameter increased while number density decreased with temperature as shown in Figure 2.14 and there was virtually no difference in dislocation microstructure after irradiation at 600°C.

The dislocation microstructure after irradiation in FFTF was also characterized by Sencer *et al.* [9,10]. At 384°C and 28 dpa, loops of type \mathbf{a} <100> of average size of approximately 14 nm were observed in densities of around 9.3×10²⁰ m⁻³. At 443°C and 155 dpa, the total loop and line density was ~3×10¹⁵m⁻³ and was dominated by a network of \mathbf{a} /2<111> with a network density of 2.2×10¹⁵ m⁻². Dislocation loops of type \mathbf{a} <100> increased in size to an average of 18 nm while the loop number density decreased to 5×10²⁰ m⁻².

Under low damage irradiation (<10 dpa), loops have been shown to nucleate and grow until saturation has been reached. Systematic studies by Gupta *et al.* [16] and Jiao *et al.* [17] on T91 suggest that loop size and density increase as a function of irradiation damage until reaching saturation by 10 dpa, regardless of temperature. However, the regime above 10 dpa was not considered and still remains unexamined.

A summary of dislocation loop data is given below in Figure 2.15 and Table 2.1. Throughout all data examined, loop density tended to decrease with increased temperature while the average diameter increased with temperature until the loops became large enough to form a network, usually around 500°C. In addition to the limited data for dislocations at low damage levels in FM alloys not subjected to stress under irradiation, the coupling of temperature and flux in reactor makes a systematic study of either temperature or damage dependence difficult. In addition, there is a distinct lack of characterization of the evolution of these dislocations above 10 dpa to high damage levels of 150 dpa or higher.

2.5 **Precipitation of Secondary Phases**

The formation of secondary phases, either enhanced or induced by irradiation, is considered for several reasons. First, formation of secondary phases may lead to embrittlement or hardening of the materials. Second, and more important to the objective of this thesis, the formation of secondary phases provides alternative sinks for defects and thus could affect swelling behavior.

2.5.1 Precipitate Types in HT9

Many types of precipitates can form under irradiation in the temperature range considered for this thesis. Below is a summary of types of precipitates that may form under ion irradiation in the relevant temperature range.

<u>α'</u>

 α' is a chromium-rich ferrite radiation-enhanced precipitate. It is a BCC phase that is usually produced in the tempered martensite phase by spinoidal decomposition [3]. It is coherent with the iron matrix. Sizes of the precipitate vary from 2 to 20 nm. α' precipitate is highly resistant to coarsening. An interesting effect of α' composition is that it is very difficult to directly observe because of its chemical similarity to the bulk steel as well as small size [50]. α' precipitation is enhanced by irradiation and is a contributor to embrittlement. It is one of the most undesirable precipitates enhanced by irradiation because it increases hardness, yield strength and tensile strength while decreasing corrosion resistance, elongation, ductility and impact resistance [50]. Although the α' phase has been observed in irradiated alloys with 12-13% Cr content, it has not been observed in 9Cr-1Mo (T91). Thus, it was hypothesized that there is a critical bulk Cr concentration (>12 wt%) for the formation of α' precipitates [3].

χ

 χ is a BCC intermetallic phase. The most common composition is Fe₃₆Cr₁₂Mo₁₀ [3]. It only occurs in Fe-Cr-Mo ternary systems and Fe-Cr-Ni-Mo and Fe-Cr-Ni-Ti quaternary systems. It increases susceptibility to intergranular stress corrosion cracking and may also be enriched in silicon and nickel under irradiation. A minimum molybdenum content, which is dependent on temperature, is needed for precipitation; for instance, 2 wt% at 600°C is required for precipitation [50].

<u>M₆X (η)</u>

 $M_6X(\eta)$ is a diamond cubic phase in the form of fine and coarse precipitates in martensitic steels with >0.3 wt% nickel composition. η phase is primarily observed in thermally aged highchromium steels. Under irradiation, it may become enriched in Si and Ni similar to χ -phase [3].

 $M_{23}C_6$

 $M_{23}C_6$ precipitates, also known as τ -phase, are chromium rich carbides that nucleate on the martensite lath and PAG boundaries. These precipitates are a primary cause of intergranular stress corrosion cracking [3].

<u>M₂X (ε)</u>

M₂X precipitates are predominately Cr₂N, but can also form as carbides. They are structured as fine needles. They generally precipitate on dislocations within martensite laths [3]. M₂X is a contributor to embrittlement under irradiation [51]. Large (100 to 1000 nm) needles of can be formed during thermal processing. Conversely, M₂X can form under irradiation, typically as a platelike precipitate of length below 100 nm [3,38].

Laves

Laves phase is an irradiation-enhanced phase, and also is found after prolonged thermal aging. The composition is Fe₂Mo. Enhancement of this phase was not observed in HT9 at irradiation temperatures between 300 to 615°C, which include applicable temperature ranges for this research [3].

σ

 σ -phase can occur in austenitic, ferritic and duplex steels. It is an intermetallic with a tetragonal crystal structure precipitate with 30 atoms per unit cell composed of Fe-Mo-Cr. It causes loss of toughness and can cause depletion of Cr and Mo from the matrix. Generally, σ -phase replaces the ferrite portion of the microstructure. Higher chromium and molybdenum content tend to lead to quicker precipitation of this phase [3,50].

<u>G phase</u>

G phase has been observed in irradiated HT9 steels. G phase is a complex FCC silicide of the form $M_6Mn_{16}Si_7$ where M = Ni typically [3]. Precipitates are around 10 nm in size and occur on grain boundaries, but can be somewhat bigger when occurring within subgrains. Irradiation hardening is attributed in part to this phase [51].

2.5.2 Precipitate Behavior under Irradiation

After irradiation, α' -phase [49], G phase [10], M₆C and χ -phases [49], σ -phase and the Fe₂Mo type Laves phase have been reported in FM alloys.

The microstructure stability of the ACO3 duct was examined by Sencer *et al.* [9,10]. At 4 dpa and an irradiation temperature of 505°C, the microstructure was essentially unchanged from the unirradiated microstructure, meaning that large blocky carbides ($M_{23}C_6$) were observed on the martensite lath boundaries and carbides were distributed on or near the subgrain boundaries. After 28 dpa and 384°C, there was enhancement of the carbides on the subgrain boundaries. In addition, G phase developed within grains and on lath boundaries. No voids were observed. At 155 dpa and 443°C, there was an enhancement of carbide size and density on and around the subgrain boundaries. Radiation enhanced precipitation was clearly observed and was dominated by G phase and η -phase at 155 dpa Smaller precipitates were obscured but were presumed to be α' . A comparison of these microstructures is given in Figure 2.16. It was theorized that the precipitates may act as sinks for the vacancies, which elongates the transient regime of swelling and could decrease the final swelling rate.

Gelles [7] identified G phase formation in HT9 and T91 irradiated in FFTF via neutron irradiation to 200 dpa at 420°C. The 700°C heat treated HT9 had well developed precipitate arrays decorating the subgrain lath boundaries, non-uniform void arrays within the laths and fine

precipitates on and within the boundaries. There were no phases observed that were not visible at lower radiation damage levels. Precipitated G phase that had a diameter of 10 nm formed within laths, but larger precipitates formed on prior austenite grain boundaries (PAGBs) and on packet boundaries.

Recent results from Z. Jiao and G.S. Was [51] suggest that precipitate behavior (specifically Ni/Si G phase) continues to evolve at high damage levels (>100 dpa). Increased diameter and decreased number density of Ni/Si/Mn and copper rich precipitates was observed up to 500 dpa in Fe⁺⁺-irradiated HCM12A suggested coarsening behavior up to high damage levels. However, the volume fraction of the precipitates decreased at damage levels beyond 7 dpa, an unexpected result that suggests that precipitates continue to evolve as a function of dpa.

Coarsening or dissolution of carbides [51] ($M_{23}C_6$) was observed at low damage levels in the temperature range of 420-460°C in unalloyed 12% Cr steels. However, this effect was only observed in high alloy grades. α ' precipitation has been observed in temperatures at or below 400°C or for high Cr (17%) FM alloys. G phase was also shown to be closely correlated with strong radiation-induced segregation (RIS) to point defect sinks, such as carbides and dislocations. Prior to more recent results, there had been a debate of whether G phase actually formed, as it was only observed in samples irradiated above 20 dpa, so it may be classified as a "high damage phenomenon" and primarily nucleated on dislocation networks.

Although the predominant mode of precipitation in FM alloys is formation of G phase or α' , other modes have been observed. σ phase (Fe-Cr intermetallic) was observed in the temperature range of 420-460°C [3]. It precipitated as large sheets and thin ribbons surrounding carbides, primarily in the ferritic portion of 9-13Cr steels. The Laves phase [3] formed prior to irradiation

upon thermal ageing in some high Cr martensitic steels, but was suppressed upon irradiation in the temperature range of 300-615°C.

 M_2X (ϵ) [38,52] were observed by Borodin *et al.* after ion irradiation at 500°C to 30 dpa and 150 dpa. Irradiations were performed with 3 MeV Cr ions on 13Cr-2Mo-TiO₂. Rod-like precipitates formed by 30 dpa and grew in size up to 150 dpa, shown in the Figure 2.17. Similar M_2X precipitates were also observed by Maziasz [53] in 12Cr-1MoVW (HT9) irradiated in HFIR at 500°C to 38 dpa with 87 appm He co-generated, indicating that the phase forms both in neutron and ion irradiation.

Although precipitate formation in FM alloys has been observed and reported at a number of different damage levels and in in a large temperature range, there has been no systematic study of precipitate evolution with high damage, especially in excess of 100 to 200 dpa.

2.6 Other Irradiation Effects

The addition of irradiation to the microstructure has been shown to also affect mechanical properties. Other irradiation effects not central to the scope of this thesis are presented below. Specifically, radiation-induced segregation and hardening behavior will be briefly summarized, but will not be examined in this study.

2.6.1 Radiation-Induced Segregation

Radiation-induced segregation, or RIS, can contribute to the formation of precipitates. Jiao and Was [54] irradiated FM alloys (T91, HCM12A, and HT9) with protons and heavy ions to 7 and 100 dpa, respectively. For HCM12A, the focus of the study, silicon, nitrogen and phosphorous were enriched at the grain boundaries. Chromium enrichment/depletion was highly variable and

different at each of the grain boundaries analyzed. It was theorized that enrichment levels were affected by the competing mechanism of solute precipitation. Copper enrichment at the grain boundaries was lower than expected. It was also theorized, much like for chromium, that copperrich precipitates decrease enrichment levels by diverting Cu atoms. Molybdenum and manganese concentration remained constant or slightly increased at the grain boundaries. Tungsten depleted, which was expected due to its large size. Segregation to dislocations was also observed in HCM12A. Solute segregation to dislocations was similar to segregation at the grain boundaries.

Wharry and Was [55] also examined RIS in FM alloys irradiated with protons up to 10 dpa. Under irradiation in the temperature range of 300-600°C, they observed chromium, nickel and silicon enrichment at grain boundaries. A damage dependence study in a 9 Cr model alloy suggested that Cr enrichments saturates between 7-10 dpa, whereas T91 enrichment reached a peak at 7 dpa and decreased beyond that damage. A similar trend was observed in Ni and Si, and it was suggested that the lattice parameter in the vicinity decreased with the addition of undersized solutes, which decreased the migration energy of Cr, thus decreasing enrichment. Higher damage levels were not examined.

2.6.2 Hardening

Irradiation-induced microstructural and microchemical changes contribute to the macroscopic effect of irradiation-induced hardening. Hardening then increases the yield stress and ultimate tensile strength of the examined material, while decreasing the uniform and total elongation. This can be observed in changes in the stress-strain curve of the alloy after irradiation. Representative stress-strain curves are shown in Figure 2.18 [56]. Irradiation of a metal causes strengthening by source hardening and friction hardening. The formation of defect clusters, voids, precipitates and dislocation loops impede the motion of dislocation lines [20]. In general, the

magnitude of irradiation hardening decreases with temperature and disappears between 400 and 500°C, likely due to annealing of radiation-induced defect clusters at higher temperatures [56].

Yield strength ($\Delta \sigma_{v}$) is related to hardening ΔH_{V} via the following equation:

$$\Delta \sigma_y = 3.06 \Delta H_V \tag{2.3}$$

for FM alloys [57].

Gelles and Schäublin [58] tensile tested irradiated F82H samples and examined the post deformation microstructures. F82H samples were irradiated to 2.57 dpa at 327°C. Deformation only occurred <0.5 mm from the failure site. Yield strength increased to an average of 619 MPa compared to 540 MPa, prior to irradiation. Hardening was attributed to the small loops which formed near preexisting dislocation microstructure. In a similar study, de Carlan *et al.* [59] also surveyed a variety of types of steels and compared post-irradiation tensile behavior. Austenitic, martensitic and ODS FM steels were irradiated up to 9.5 dpa in the Osiris reactor in France. All steels exhibited irradiation hardening and increases in yield strength. Hardening and ductility for all the steels appeared to saturate by 9 dpa. Saturation of yield strength was observed in Figure 2.19 for a variety of FM alloys. HT9 exhibited brittle behavior and intergranular failure mode, especially relative to ODS alloy MA 957, which showed more ductile fracture.

Radiation damage at high damage levels is a dynamic process where the resultant defect flow is complex and there are many possible mechanisms for interactions between the various radiation-induced microstructure features. Defect clusters form and are annealed. Dislocation loops form, grow and climb and glide. Solutes segregated to and away from grain boundaries and sinks. Secondary phases form and provide additional sinks. Finally, vacancies agglomerate into void nuclei and grow into voids. The scope of this thesis will be limited to the interactions of voids, secondary phases and the dislocation loops and network.

Alloy	Irradiation Temperature (°C)	Damage (dpa)	Dislocation Character	Loop Number Density (m ⁻²)	Loop Diameter (nm)	Loop Line Density (m ⁻²)	Туре	Reference
HT9	420	200	a/2<111> network and a<100> loops			Not Reported		[33]
Fe-12Cr model	420	15	small and large a[001] segments; a/2<111> network			4.70E+14	Total	[33]
		21	small and large a[001] segments; a/2<111> network			6.80E+13	Total	[33]
		200	small and large a[001] segments; a/2<111> network			8.30E+13	a/2<111>	[33]
						4.11E+14	a<100>	[33]
						4.90E+14	Total	[33]
HT9	450	10-100	loops +network			Not Reported		[49]
	500	10-100	network + small unfaulted loops			Not Reported		[49]
	300	40	a<100>	1.00E+22	8	2.51E+14	a<100>	[35]
	400	40	a<100>	8.00E+21	25	6.28E+14	a<100>	[35]
	500	40	a<100>	6.00E+19	800	1.51E+14	a/2<111> network	[35]
	384	28	a<100> loops	9.30E+20	14	4.09E+13	a<100>	[9,10]
	443	155	a/2<111> network and a<100> loops			2.20E+15	a/2<111> network	[9,10]
	443			5.00E+20	18	8.00E+14	a<100>	[9,10]
						3.00E+15	total	[9,10]
	505	4	Microstructure unchanged with irradiation			Not Reported		[9,10]

Table 2.1: Summary of observed dislocation behavior in FM alloys.



Figure 2.1: Expected swelling behavior as a function of damage. Adapted from [19].



Figure 2.2: Effect of chromium on the constitution of Fe-Cr-C alloys with 0.1% carbon. (CrFe)₄C is the $M_{23}C_6$ carbide [3].



Figure 2.3: Continuous cooling transformation (CCT) diagram for 12Cr-MoVNb martensitic steel where A refers to austenite, K refers to carbide, Sp- δ refers to trace ferrite, M refers to martensite, P=pearlite, A_{C1b} is the start of austenite formation upon heating, A_{C1e} is the completion of austenite formation upon heating rate (°C/min) from [3].



Figure 2.4: a) Schematic [32] and b) micrograph of typical HT9 microstructure prior to irradiation [3].



Figure 2.5: Stress-free swelling of irradiated HT9 up to 165 dpa for 4 heat treatments. Heat 1 and Heat 2 were subjected to the same heat treatment: 1038°C/5 min/air followed by 760°C/30 min/air cool. Heat 3 and 5 were subjected to 1100°C/2 min/air cool followed by 650°/120 min/air cool [4].



Figure 2.6: Swelling in Fe-Cr alloys as a function of damage [33].



Figure 2.7: Adjustment of damage levels in EBR-II results by Garner *et al.* [8] to data collected by Gelles [33].



Figure 2.8: Summary of HT9 and T91 irradiated in-reactor up to 208 dpa.



Figure 2.9: a) Temperature dependence of void swelling in EM12 and HT9 irradiated to 150 dpa b) Damage dependence of swelling of EM12 and HT9 up to at 500°C [14].


Figure 2.10: a) Temperature dependence of swelling in ferritic steel irradiated with 200 keV C⁺ ions to 150 dpa and b) damage dependence of swelling in ferritic steels irradiated with 200 keV C⁺ ions at 575°C [40].



Figure 2.11: a) Damage dependence of commercial alloys up to 600 dpa at 450 or 480°C. b) Temperature dependence experiment at 100 dpa and 500 dpa on MA957 ODS ferritic steel [15].



Figure 2.12: Summary of ion irradiations performed upon HT9 [14,15,40].



Figure 2.13: Q analysis for various neutron irradiations [34].



Figure 2.14 Temperature dependence of loop number density and diameter in 14 MeV Ni-irradiated HT9 [35]. Note that loops of size of 800 nm would typically be classified as an unfaulted network.



Figure 2.15: A summary of dislocation loop results as a function of temperature in neutron and ion irradiated HT9 [7,35].



Figure 2.16: HT9 irradiated to a) 4 dpa at 505°C b) 28 dpa at 384°C c) 155 dpa at 443°C [10].



Figure 2.17: Formation of rod-like precipitates in $13Cr-2Mo-TiO_2$ after Cr irradiation at $500^{\circ}C$ to a) 30 dpa and b) 150 dpa [38].

Stress/Strain Curves for Mod 9Cr-1Mo



Figure 2.18: Representative stress/strain curves for Mod 9Cr-1Mo after irradiation in spallation environment [56].



Figure 2.19: Comparison of the behavior of martensitic steels in the tempered and asquenched conditions [59].

CHAPTER 3 OBJECTIVE

The objective of this thesis is to understand how microstructure features co-evolve in the high damage level, growth-dominated swelling regime of self-ion irradiated HT9. The hypothesis is that continued defect absorption at precipitate and dislocations maintains the supersaturation of vacancies necessary for linear swelling to continue to high damage levels.

A combination of ion irradiation, microstructure characterization and computational modeling will be used to understand how voids evolve in the high damage regime where growth rather than nucleation of voids dominates the swelling behavior. Three sub-objectives have been identified.

First, Sub Objective 1 will determine the temperature and damage regime relevant to void swelling. Prior to this work, the majority of analysis of the microstructure has been performed in the incubation and transition regime. Although void swelling is postulated between $0.3 - 0.5 \frac{T}{T_m}$, void formation in this high swelling resistant alloy only occurs at high damage. Thus, identifying the peak swelling temperature will be key to reaching the growth dominated swelling regime.

Second, Sub Objective 2 will determine microstructure (void, dislocation, precipitate) evolution at the peak swelling temperature after the onset of linear swelling in the growth regime using a combination of ion irradiation and post-irradiation microstructure characterization. Specifically, a damage dependence experiment at the peak swelling temperature will be performed

then characterized via STEM imaging. The high damage level set of experiments will determine the damage evolution for all features of interest (voids, dislocations, precipitates), which will isolate the *onset of growth-dominated swelling regime* (in terms of damage). The characterized *microstructure at the onset of growth-dominated swelling* will be used as an input for a cluster dynamics/rate theory model and will provide a database of microstructure results with which to 1) use as input into the model in the linear swelling regime 2) use to verify model results are reasonable and finally 3) use to track the defect partitioning to various sinks at high damage levels.

The third sub-objective will be to adapt and utilize the Radiation Induced Microstructure Evolution (RIME) model to understand how precipitates, dislocations and voids co-evolve in HT9. The sub-objective is to understand the processes by which voids, dislocations and precipitates co-evolve at high damage, with the focus being on the interactions between the microstructure features rather than benchmarking the code explicitly to the database. The interdependencies will be determined by examining how *defect partitioning evolves with increasing damage* in the growth regime. Thus, the model will be able to track the *evolution of defect absorption at sinks*. It is expected that the voids will continue to grow in both sink strength as well as the relative amount of defect absorption at sinks, but the focus of the modeling effort will be on analyzing how the dislocation and precipitate microstructure affect defect partitioning. The combination of defect behavior in the bulk and at sinks can then be used to determine what, if any, *interdependencies/interactions between voids, precipitates and dislocations* occurred. Thus, the results of Sub Objective 1-3 will demonstrate both how the microstructure evolves and why it evolves in such a way.

CHAPTER 4

EXPERIMENTAL PROCEDURE

The chapter will describe experimental techniques used in this thesis. It is organized into the following sections: sample preparation, ion irradiations and post-irradiation sample preparation and microstructure characterization.

4.1 Sample Preparation

The focus of this thesis is on the ion irradiation-induced microstructure evolution of HT9a FM alloy.

4.1.1 Sample Processing

The commercial alloy chosen for this study was HT9, which is an iron based alloy with major additions of Cr and minor additions of Mo, V, and W. The heat number is 84425 and has the composition shown in Table 4.1. HT9 was heat treated first with a 1065°C/30 min/air cooling to room temperature (RT) austenization step followed by a 750°C/60min/air cooling to RT tempering step [29,60]. A number of publications of data from this duct reflect different heat treatment parameters [9,10,29,31,60–62], but a propriety certification from Carpenter verified that this was the correct heat treatment [63]. The heat treatment results in a transformation from austenite to martensite lathes with carbides forming primarily at the grain boundaries during the tempering step, shown in Figure 4.1. There were also retained grains of δ -ferrite. The heat was

formed into ducts and irradiated in the Fast Test Flux Facility [9,10] as well as under ion irradiation [2,13]. The duct removed from FFTF and analyzed was designated as ACO3.

Samples were cut from archive duct material into $1.5 \times 1.4 \times 18$ mm TEM bar specimens by electrical discharge machining (EDM). EDM, also known as spark machining, is a manufacturing process where a voltage applied between an electrode wire and the block results in high frequency sparks. These sparks, across a distance of 10-100 µm cause material removal near the wire, which is placed at the desired cut area. Overall, the EDM process results in a sample cut without cold working, which is induced by traditional machining techniques. The schematic of the samples post-EDM is shown in Figure 4.2.

4.1.2 Sample Preparation

After samples have been machined, they were then subjected to a series of polishing steps, starting with mechanical polishing followed by a final finish of vibratory polishing and/or electropolishing. A flat, aluminum polishing block or disk was heated to a sufficiently high temperature to melt Crystalbond[™] resin wax. The samples were placed on the block in the configuration that they would be mounted onto the irradiation stage. Upon cooling, the resin wax bonded the samples to the block. Samples were placed in this configuration to ensure a planar surface, which resulted in good thermal contact between the samples and the hold down bars. When resin wax is fully cooled, the samples were wet polished using Buehler® SiC paper, beginning with grit #240 and working up to grit #4000.

The back surface (opposite to irradiation surface) was polished up to grit #4000, after which the samples were cleaned ultrasonically in acetone, flipped over, remounted with Crystalbond[™] and the irradiated surface was mechanically polished with SiC paper up to grit #4000. After that, samples were mechanically polished using a diamond solution from 9 μ m to 0.25 μ m ensuring a very smooth surface. A final mechanical polishing step using 0.02 μ m silica solution was performed either by hand or on a vibratory polisher.

To ensure that no plastic deformation remains after mechanical polishing, some samples were then electropolished. An electropolishing study was performed to select optimum electropolishing conditions such that the samples had a mirror finish, with no observable pitting or etching.

A 1000 ml beaker containing a solution of 500 ml of 90% methanol and 10% perchloric acid was immersed in a bath of methanol and dry ice. The temperature of the solution was maintained between -40 and -50°C. A square platinum mesh cathode with sides approximately 70 mm and in length and 40 mm in height was placed in the bottom of the beaker. During electropolishing, individual samples were held at one end with alligator clips and placed, upright, centered vertically in the solution-containing beaker. Samples were electropolished for 20 seconds with an applied potential of 35 V between the sample and the platinum mesh cathode, measured by a voltmeter. A magnetic stirring bead rotating with a frequency of approximately 650 rpm created a circular flow inducing a vortex of 0.75 inches in the polishing solution. The sample face to be irradiated was immersed in the vortex so that oxygen bubbles would be agitated off from the sample surface, which reduced pitting. A schematic of this electropolishing assembly is shown in Figure 4.3. After electropolishing, the samples were rinsed in acetone, followed by methanol, followed by ethanol; after rinsing, a final ultrasonic cleaning with ethanol was performed. Samples were stored in membrane boxes until the time of irradiation.

4.2 Helium Preimplantation

To more accurately account for helium formed in-reactor by (n, α) reactions, preimplantation of helium was performed prior to irradiation of the samples. A 400 keV National Electrostatics Company (NEC) ion implanter was used. Helium pre-injection was performed at energies of 80, 140, 220, 310 and 420 keV, to yield an approximately flat distribution of helium $(\pm 10\%)$ over a depth range of 300-1000 nm from the surface shown in Figure 4.4. In this thesis, 10 appm He was determined to be sufficient to enhance nucleation of voids without unduly suppressing the growth of the voids [12]. For preimplantation, samples were mounted to the implanter stage in the configuration that they would be mounted onto the irradiation stage. Preimplantation were performed at room temperature, with no heating from the He beam or cooling from the stage assembly.

4.3 Fe⁺⁺ Irradiations

This section covers all the relevant experimental details and techniques utilized for iron irradiations. Samples were irradiated in either a 1.7 MV General Ionex Tandetron accelerator or a 3 MV National Electrostatics Company (NEC) Pelletron accelerator at the Michigan Ion Beam Laboratory. During the course of this thesis, based upon increased user experience, a number of experimental improvements were implemented. Additionally, a renovation of the laboratory that resulted in improvements to the experimental setup and the switch to a new accelerator; all experimental set-ups will be described later. To perform a successful iron irradiation, a specialized irradiation set-up including stage design, aperture systems, temperature measurement, experimental monitoring and optimal vacuum conditions were utilized.

4.3.1 Irradiation Set-up

Irradiations were performed under high vacuum conditions. The entire accelerator beam line was maintained at pressures ranging from approximately 10⁻⁷ torr near the accelerator to below 10⁻⁷ torr near the stage. The stage was outgassed prior to the start of each irradiation, ensuring that experiments only started after the pressure dropped below 10⁻⁷ torr after stage. To improve vacuum further, a second cryopump was added directly below the stage to minimize any oxide formation due to the high energy incident iron ions at high temperature.

Samples were mounted on an irradiation stage, which was attached to the accelerator beam line. Two stages were used in these experiments, both of identical design, but constructed using two different metals (Cu and Ni). The "first generation" stage, made of copper, was used initially when irradiations were performed using liquid indium to ensure good thermal contact between the sample and stage. The prevalence of indium leaks with this configuration lead to design of an intermediate "second generation" stage configuration using a combination of indium and graphite foil to mitigate leaks. Due to concerns about vacuum quality, a final "third generation" stage configuration was implemented which utilized a nickel stage with copper foil for heat conduction. Regardless of stage or stage configuration used, a combination of resistive heating and air cooling monitored by an in-situ 2D infrared thermal imager was used to ensure excellent temperature control, further explained in Section 4.3.5.2. Figure 4.5 shows a side view of the beam line at the stage showing the relative position of the 2D infrared thermal imager. The following are descriptions of each of the three stage configurations used for this thesis.

4.3.1.1 Copper Stage with Indium

First, a stainless steel shim was placed on the copper stage. In the center of the shim, an opening of 16 or 10 mm (length) by 10 mm (width) which was filled with an indium foil. The shim

was 0.65 mm in height and was filled with an approximately 0.60 mm of indium foil(s), which was sufficient to fill the reservoir upon melting. Samples were then placed on top of the stage and centered over the indium reservoir. Indium was used to ensure good thermal conductivity between the copper stage and steel samples. TEM bar samples were placed on top of the stage between two guide bars. Guide bars were included to 1) ensure uniform irradiation across the width of the stage and to 2) provide a surface to attach thermocouples for calibration of the 2D thermal imager.

Samples and guide bars were held in place with hold-down bars, shown in Figure 4.6. The hold down bars fit tightly over the samples to ensure good, uniform thermal contact and the "half-moon" shape minimizes thermal reflections to the thermal imager (Figure 4.6a). They were secured with 4 set screws which were tightened slowly to maintain even pressure on the samples (Figure 4.6b). This stage configuration was designated as "first generation" and a schematic is given in Figure 4.7a. J-type thermocouples were spot-welded to guide bars for use in calibration of the 2D thermal imager and will be further described in Section 4.3.5. Lastly, a tantalum aperture assembly for beam alignment was mounted onto the stage using isolating ceramic standoffs immediately adjacent to the stage. A schematic view from the top is shown in Figure 4.8 and Figure 4.9 shows a completed stage. Stage and slit aperture systems will be further described in detail in Section 4.3.4.

Indium melts at 156°C, and was originally used to maintain thermal contact, which is especially necessary for higher flux proton irradiations that result in high beam heating. This stage design was only used with stage apertures. However, temperature cycling due to frequent iron source failures led to indium leaks, which limited damage levels that could be reached in each irradiation. Thus, the stage configuration was improved to mitigate the possibility of indium leaks.

4.3.1.2 <u>Copper Stage with Indifoil</u>

To limit indium leaks and the subsequent detrimental effect on sample surface, a graphite foil was placed in between the indium and the samples on the stage (Figure 4.7b), colloquially known as "indifoil." The effect of the graphite foil was twofold. First, it maintained the necessary thermal contact to ensure uniform temperature across the samples. Second, it eliminated leaks entirely, even with thermal cycling due to interruptions during irradiation to rebuild the iron source or replace the iron target. The graphite foil used was a 0.1 mm thick, high thermal conductivity pyrolytic graphite sheet. The stage design was used for a limited period (two experiments presented: 480°C, 188 dpa and 400°C, 250 dpa) before it was replaced with the final stage configuration that was used for the majority of the experiments in this thesis. Again, this stage design was only used with stage apertures.

4.3.1.3 <u>Nickel Stage with Copper Foil</u>

Concerns about the formation of a surface oxide prompted a final stage configuration change. Despite the low ($<10^{-7}$ torr) vacuum near the stage, a surface oxide formed under irradiation. To minimize this oxide, the graphite foil was removed because water vapor and other light molecules can adsorb to the graphite foil and decrease vacuum quality. Thus, two changes were made. First, the nickel stage was machined flat. Second, the indium and graphite foil were removed entirely from the stage and replaced with a 0.25 mm copper foil (Figure 4.11a). Given the low current of Fe⁺⁺, very little beam heating ($<10^{\circ}$ C) was observed and a copper foil maintained good enough thermal contact ensure uniform heating across samples.

Prior to irradiation, the temperature uniformity was assessed. Four FM samples (T91) were polished and loaded onto the stage. Eight thermocouples were welded to the stage (Figure 4.10a-

b). On the benchtop, the stage was heated to 200°C and 6 of the 8 TCs were within 200±3°C. Upon cooling, it was found that the welds of the two thermocouples that were not within 3°C of 200°C were loose. The loose thermocouples were re-welded and the stage was loaded onto the beamline and heated up to 500°C. It was found that 6 of the 8 thermocouples were within 4°C for a period of 20 hours (Figure 4.10c), with a brief interruption due to a power outage. Upon unloading, the two thermocouples that had readings outside of the 4°C window were again loose. These results were deemed sufficient to demonstrate temperature uniformity. However, this experiment also highlighted limitations in thermocouple welding and the procedure for spot welding thermocouples was improved as a result, to minimize loosening of thermocouples.

The copper foil stage design was used with both stage (Figure 4.11a) and slit apertures (Figure 4.11b). After the upgrade to slit apertures, the stage was fitted with 2 thermocouple feed-throughs, which allowed up to 8 thermocouples to be used per stage. (Figure 4.12)

4.3.2 Displacement Damage

Displacement damage of the incident 5 MeV Fe⁺⁺ is calculated with the Stopping and Range of Ions in Matter (SRIM) 2010TM program [64]. The SRIM program outputs a number of displacements produced per unit length per ion (displacements/Å-ion), which is depth dependent. For this thesis, the SRIM calculations were calculated using the "quick" Kinchin-Pease approximation, which has been shown to be more appropriate for calculating damage levels of ion experiments [65], when they are compared to damage calculated in neutron irradiations by the Norgett, Robinson and Torrens (NRT) method [66]. 100,000 incident ions were used to improve counting statistics, which provides an accurate and smooth damage curve. Displacement energy for each element was defined in the SRIM calculation. For this work, the input composition was 88% Fe and 12% Cr. For both Fe and Cr, 40 eV was used as the displacement energy for both elements, per the recommendation offered by ASTM E 521-89 [67]. Figure 4.4 shows both the damage curve (red) as well as the implanted ion fraction (green) overlaid on the preimplanted helium concentration (blue). As shown, the damage curve is highly peaked so a specific depth was chosen to avoid both surface and damage peak effects. Peak damage due to Fe⁺⁺ was at 1.3 μ m, but nominal damage was measured and recorded at 0.6 μ m. The damage rate was calculated to be 0.355 displacements/Å-ion.

4.3.3 Damage Calculation

The irradiation damage is related to the current of iron ions on the stage, so accurate measurement of the current throughout the irradiation is paramount to reaching the appropriate damage level. 5 MeV Fe⁺⁺ ions incident on a metal surface cause electron showers, [68] which means that the current cannot be read accurately unless the measurement was actively electronically suppressed. Thus, *in situ* monitoring of the current on the stage was not possible, as with proton irradiations [32,69,70]. Current was measured with a suppressed Faraday cup either before or after the apertures every 45-60 minutes, depending on source stability. Installation of slit aperture system allowed the current to be measured immediately before the samples. The damage level (dpa) is calculated using the following equation:

$$dpa = \frac{\left(\sum t_i(minutes) * f_1\left(\frac{s}{minute}\right) * i_{stage}(\mu A) * R_D\left(\frac{displacement}{A-ion}\right) * f_2\left(\frac{A}{cm}\right)\right)}{N\left(\frac{at}{cm^3}\right) * Q\left(\frac{c}{ion}\right) * f_3\left(\frac{\mu C}{c}\right) * A(cm^2)}$$
(4.1)

where $\sum t_i$ is the total time under irradiation, f_1 is the conversion factor from seconds to minutes, *i*_{stage} is the time-averaged stage current, R_D is the displacement rate from SRIM, f_2 is the conversion factor from angstroms to centimeters, *N* is the atomic density, *Q* is the charge per Fe^{++} , f_3 is conversion factor from micro-coulombs to coulombs and *A* is the area receiving full irradiation (i.e. aperture opening). A summary of these terms and their typical values is given in Table 4.2.

4.3.4 Apertures and Beam Scanning

The aperture system provided a method for both aligning and sizing the beam. Two different methods of beam scanning were used throughout this thesis. First, apertures attached to the stage were used. Although stage apertures have been effective in previous proton and iron irradiations, the apparatus could shift upon loading to the beamline, which changes the area of the samples that is irradiated. Shifting of the apertures and consequently the irradiated area was mitigated by an upgrade to an *in situ* slit aperture system.

4.3.4.1 <u>Stage Aperture System</u>

The stage aperture system consisted of four tantalum plates, which were electrically isolated from each other. They were mounted to the stage using ceramic standoffs to ensure that they were electrically isolated from the stage as well. The stage aperture system is shown in Figure 4.13. Aperture sizes were adjusted using the screws to reach the desired irradiated area. Typically, the aperture size was 12 mm in x by 5 mm in y, though it varied depending on the number of samples; typically, 4 to 6 samples plus 2 guide bars per stage. Each aperture piece was individually connected with a wire to a feedthrough that output current to a monitoring computer. The relative current on each aperture was then used to balance the beam on desired irradiated area.

Aperture alignment was performed *ex situ*. The alignment was performed on the benchtop with the stage oriented on its side as it would be on the beamline. A laser pen was positioned ~20 feet away from the irradiation stage. The laser is aligned to the center of the aperture then diffused with a thin plastic sheet to mimic a raster-scanned beam. The aperture was adjusted with screws so that the irradiated area was clearly illuminated by the laser. The alignment assembly is shown in Figure 4.14.

Before starting an irradiation, the focused iron beam was measured for size in a beam profile monitor. The beam size was verified to be at most 3 mm. The beam was then raster-scanned across the samples at a frequency of 255 Hz in x and 2061 Hz in y, corresponding to 3.92 and 0.48 ms cycle time in the x and y directions, respectively. The ratio of these cycles was not an integer, which results in an offset of the beam between scan cycles, ensuring uniform irradiation. A schematic is shown in Figure 4.15.

The raster-scanned beam must overlap onto all the aperture pieces to ensure full, uniform irradiation for all samples. One full beam diameter, or 3 mm must overlap onto each aperture piece during raster-scanning. The size of the aperture opening sets the size of the beam. For a 12 mm x 5 mm aperture with a 3 mm beam diameter, the beam must be scanned 18 mm x 11 mm. The desired irradiation area was drawn on a ceramic, which was the loaded in the target chamber before the stage. When the Fe⁺⁺ beam hits the ceramic, it fluoresced so the beam was able to be scanned to an appropriate size. After sizing, the ceramic was moved out of the incident beam so the beam is allowed to reach the aperture and irradiated area. A schematic of the appropriately sized beam is shown in Figure 4.16a.

To measure i_{Stage} , the Faraday cup was inserted periodically (~45-60 minutes) into the beam. The value of i_{Stage} was recorded and time averaged. However, since the current was being monitored before the slits, an additional factor was required to calculate the current at the stage. That factor was calculated by following the center of the beam as it rastered, even though the scanned area is 3 mm in each direction, the center of the beam only travels 1.5 mm off each direction. The result of this beam path was demonstrated by the beam intensity curve plotted in Figure 4.16. Thus, the percentage of current on the stage using Equation 4.2 below:

$$\frac{i_{stage}}{i_{total}} = \frac{x * y}{(x + \frac{d_{beam}}{2})(y + \frac{d_{beam}}{2})}$$
(4.2)

where i_{stage} is the current on stage, i_{total} is the current before the slits, x is the aperture width, y is the aperture height and d_{beam} is the beam diameter. Considering the nominal case of x = 5 mm, y=12 mm and $d_{beam}=3$ mm, the percentage of current on the stage is 50%. Thus, this factor can be multiplied by the total current before slits to calculate i_{stage} , which is used to calculate damage.

4.3.4.2 <u>Slit Aperture System</u>

The stage aperture system had several drawbacks. First, the slit size was manually adjusted and measured with calipers. Second, the alignment took place *ex situ*, which had the disadvantage of not being adjustable once the stage was loaded. In addition, the assembly was prone to shifting or translation during the loading process, which was only discovered upon completion of the irradiation. For the purposes of re-irradiating samples, this was a major concern. Thus, with the renovation of the ion irradiation beam line, slit apertures were included so alignment could be performed *in situ*.

The slit aperture system contains 4 tantalum plates attached to independent motors. The plates were electrically isolated so current can be read off of each plate (X+, X-, Y+, and Y-). The slit system was 24 inches in front of the stage. An alignment laser had been installed and was aligned from the magnet to the stage. It was a green laser diffuse enough so that entire irradiated region of interest (maximum of 20 mm x 20 mm) can be observed. After the stage had been loaded, the alignment laser before the magnet is turned on. Slits were opened to the desired irradiation size (for most cases, 12 mm x 5 mm). The laser was turned on and the stage was adjusted, if necessary, by physically adjusting the stage holder. An image of the aligned stage is presented in Figure 4.17.

The beam sizing procedure described previously had the disadvantage of being dependent on 1) the florescence of the beam on the ceramic, and 2) visual inspection of the size of the beam scanned area from a distance of ~18 inches. With the upgrade to the slit aperture system, and the installation of Faraday cups before and after the slits, a more precise beam sizing procedure was developed. First, the slits were closed to 3 mm x 3 mm and the beam was maximized in the stage Faraday cup using the magnet and quadruples, ensuring the beam was approaching the stage head on, and also minimized the size of the beam. After this focusing step, the beam was typically ≤ 2 mm, measured by the beam profile monitor. The slits were then opened to the desired irradiated area (usually 12 mm x 5 mm). The maximum ratio of beam to be transmitted through the slits to the stage was calculated using Equation 4.2 mentioned previously. Similarly, for a 12 mm by 5 mm aperture, 50% of the beam is on the stage and 12.5% is on each aperture. It should be noted that this ratio was identical to what was used to calculate the damage on the stage in the stage aperture method. Beam raster-scanning was adjusted in x and y directions such that these parameters were measured when the irradiation was ready to commence.

4.3.5 Temperature Control

Temperature control of the irradiation status was accomplished by a combination of heating and cooling. A Watlow FIREROD ® resistance cartridge was inserted to the stage base. The heater cartridge was 4 cm in length with a 1 cm diameter and was rated up to 760°C, which was well above desired irradiation temperature, which varied from 400-480°C. Cooling lines ran through the stage and air cooling removed heat during or after completion of irradiations. The combination of heating and cooling was ideal for minimizing temperature variations.

4.3.5.1 <u>Thermocouples</u>

Four J-type thermocouples were spot welded to the guide bars or portions of the sample not under irradiation on the stage. These were used upon start up to calibrate the 2D infrared thermal imager, which was used for monitoring the temperature during irradiations. The thermal infrared imager will be discussed in Section 4.3.5.2.

J-type thermocouples have an operating temperature of up to 750°C, well within what was necessary for these experiments. They were made from 0.0013 mm iron and constantan wires, which were insulated with ceramic beads to ensure that there were no shorts between the wires, other thermocouples or with the stage. Four thermocouples were used as a redundant check on temperature and to verify that there were no non-uniformities across the stage between the unique samples.

Thermocouples were attached to the samples using a spot weld at the "cross" of the two wires. The thermocouple beads and wire cross on the sample are shown in Figure 4.9 on the irradiation stage. Since repeated thermal cycling and irradiation can embrittle the wire, they were made separately for each irradiation. A fifth coated probe J-type thermocouple from Omega®

was inserted into a port on the back of the stage, which was used to monitor the temperature of the back of the stage throughout the irradiation.

4.3.5.2 <u>Thermal Imager</u>

Prior to sending the iron beam onto the samples, the samples were heated to irradiation temperature using the resistance heater. They were allowed to stabilize at the desired irradiation temperature, measured by the thermocouples. At this point, the 2D infrared thermal imager was calibrated to the thermocouples readings. Shown in Figure 4.5, an IRCON thermal imaging system was positioned outside the irradiation chamber. Areas of interest (AOIs) were created on each TEM bar sample; each corresponded to 5 pixels or 1 mm in diameter. At least 2 AOIs per sample were monitored and the resulting image is shown in Figure 4.18. Each AOI was calibrated to the thermocouples by adjusting the emissivity, which was dependent on the angle of imaging as well as surface condition and material. Beam heating was measured by the thermal imager and was typically between 2-8°C, depending on current density from the source.

Some experiments were run entirely, or partially, with previously irradiated samples. Since annealing of irradiation damage was a major concern, the sample temperature, measured in the AOIs from the 2D thermal image, was not calibrated prior to starting the irradiation. The samples were out-gassed, typically overnight at 150°C. When the beam was ready, the samples were heated up (with the beam on the stage from 350°C to the irradiation temperature). The AOI temperatures were then calibrated to the thermocouples with the irradiation already started. Calibration of the AOIs typically took less than 5 minutes to complete, once the temperature was stabilized.

4.3.6 Irradiation Setup and Control

Once the samples were at temperature and the AOIs calibrated, the beam was allowed to reach the samples. The temperature was maintained with a combination of resistive heating and air cooling, which maintained the temperature within $\pm 10^{\circ}$ C. With iron irradiations, this was typically much lower and closer to within $\pm 5^{\circ}$ C on average. With the beam sent through, the current was balanced using the beam steerer, which set the horizontal and vertical positions. If the beam scanning has not already been set, it was then set to the appropriate ratio between stage and apertures calculated in Section 4.3.4.

Temperature (from both the AOI output from the thermal imager as well as from the thermocouples) and current were monitored throughout the duration of the irradiation. Each AOI temperature was collected once per second then averaged over a 15 second period and that value was recorded in LabVIEWTM. The thermocouple temperature, including the back thermocouple, was recorded once every 30 seconds. The current was recorded manually by insertion of the Faraday cup into beam line every 45-60 minutes. The aperture current and pressure were also recorded once per 15 seconds. Data acquisition was performed using LabVIEWTM program.

The monitoring frequencies were set to high frequency (every 15 and 30 seconds for AOI and thermocouple temperature, respectively) to ensure the highest quality irradiations in terms of temperature control and current monitoring, without being unduly disruptive to the experiment. If any of the AOI temperatures drifted outside of the acceptable $\pm 10^{\circ}$ C an alarm sounded, alerting the experimenter. Similarly, the aperture currents were monitored so if the beam drifted an alarm sounded alerting the experimenter that the steerer needed to be adjusted.

4.4 5 MeV Fe⁺⁺ Irradiation Results

Sample designations have been developed to ensure easy identification. Each irradiated bar was designated as 'heat name-temperature-damage-helium-date.' For instance, 'ACO3-460C-350dpa-10He-011215' refers to a bar of the ACO3 heat of HT9 preimplanted with 10 appm He irradiated on 01/12/15 at 460°C up to a final damage of 350 dpa. If a specific liftout is referenced, then the designation also includes the grid post and date of liftout taken as well ('alloy-temperature-damage-helium-irradiation date-grid post-liftout date'). For instance, a liftout on grid post B from the previously mentioned 350 dpa irradiation would be referred to as ACO3-460C-350dpa-10He-011215-Grid B-011715. A list of bar samples used in this thesis is given in Table 4.3. A total of 15 irradiations were performed for this thesis to fulfill the requirements of Sub Objectives 1 and 2.

This section will report on irradiations performed using consistent and appropriate experimental techniques. For any type of ion irradiation, there were three key parameters that were defined: temperature, damage and damage rate. Temperature and final damage level were of primary concern. Regarding damage rate, an effort was made to ensure the highest possible damage rate, while still maintaining stable irradiation parameters. Practically speaking, this varied between $0.5-1\times10^{-3}$ dpa/s for the majority of irradiations. Within an irradiation, the ion current and as a consequence, the instantaneous damage rate, was maintained within a factor of 2. An attempt was also made to ensure all damage rates were within a factor of 2-3 between irradiations.

A summary of all the irradiations conducted is provided in Table 4.4. All irradiations reached ± 0.5 dpa of the target damage level. The damage rate varied between $0.27 - 1.20 \times 10^{-3}$ dpa/s. The lower damage rates were prior to replacement of the 1.7 MV Tandem accelerator with a 3 MV Pelletron accelerator, which had increased beam transmission by approximately a factor of two. After this upgrade, the damage rates were within a factor of two for the irradiation campaign from

0-650 dpa referred to as part of Sub Objective 2 described in Chapter 3. Irradiation temperature was calibrated with J type thermocouples; the average temperature is shown in Table 4.4. Prior to irradiation, at least 3 thermocouples varied less than $<5^{\circ}$ C from the target irradiation temperature. Irradiations only commenced upon the pressure reaching 9.9×10^{-8} torr, ensuring a high vacuum environment.

The irradiation temperature, measured by at least two AOIs on each sample, is also shown in Table 4.4. All samples have been irradiated within <4°C of the target irradiation temperature. The frequency of temperature measurements has been plotted as a series of histograms and the temperature distribution for each irradiation was normally distributed with a target $2\sigma <\pm 10^{\circ}$ C. Presented in Table 4.4, most 2σ values were considerably lower and averaged around $\pm 5^{\circ}$ C. Temperature histograms for AOIs on all samples included in this thesis are available in "Appendix A: Temperature Histograms", but an example is also shown in Figure 4.19.

4.5 **Post-Irradiation Sample Preparation and Microstructure Characterization**

Following iron irradiation, the samples were removed from the stage for preparation of TEM specimans using the focused ion beam (FIB) in-situ liftout method. The procedures for this technique are discussed in this section.

4.5.1 TEM Specimen Preparation

The shallow penetration depth of Fe⁺⁺ ions into the irradiated sample presented a unique challenge. In addition, magnetic materials such as HT9 distort the TEM electron beam. A practical solution to both of these challenges is to limit the volume of examined material to the near surface, which was accomplished using the FIB in-situ lift-out technique to create cross-sectional TEM specimens.

The dual beam FIB system used consists of a low energy ($\leq 30 \text{ keV}$) electron beam and a gallium beam oriented 52° from the e-beam. It also included a tilting stage so that the stage can be tilted so it was orthogonal to the e-beam (0° tilt) or orthogonal (52° tilt) to the gallium beam. Lift-outs prepared for this thesis were made using the FEI Company's Helios NanoLabTM DualBeamTM, Nova NanoLabTM DualBeamTM or QuantaTM 200 3D Focused Ion Beam Workstation. TEM specimens were prepared in the following way.

First, the stage was tilted normal to the ion beam (52°) . A gas injector was inserted and a low current ion beam (~0.1-0.23 nA) was used to deposit platinum (Figure 4.20a) onto the sample surface. The gallium beam, at a higher current (~7-9 nA), was then used to mill away trenches surrounding the area of interest, known as a lamella (Figure 4.20b). The sample was then tilted back normal to the e-beam (0° tilt). The gallium beam, still at a high current, was used to cut the bottom of the lamella, so it was held only on one side (Figure 4.20c). At this point, a micromanipulator (Ominoprobe) was inserted and positioned on the side of the lamella and was then jointed to the lamella with platinum (Figure 4.20d). The lamella was then totally free from the surrounding materials by further cutting and was lifted out of the trench by moving up the Ominoprobe. The lamella was then transferred on the micromanipulator to a copper half grid (Figure 4.20e). Once it was jointed to the grid, the micromanipulator was cut away using the gallium beam. The grid was then tilted such that the sample surface was orthogonal to the ion beam. Thinning was performed using low current ion beam in stages until the TEM specimen was electron transparent (Figure 4.20f). A final cleaning was performed with 5 keV ion energy. Liftouts were usually 100-150 nm in thickness. A schematic of the cross sectional liftout is shown in Figure 4.21.

4.5.2 Void Swelling Measurement and Characterization

The objective of this thesis is to determine how microstructure features co-evolve. Thus, a systematic and careful characterization of microstructure features was essential. There are a number of challenges in imaging voids in particular. First, the irradiation area is limited to the first 1.6 µm and there were many gradients in terms of both helium and damage. Second, HT9 is swelling resistant and void nucleation is highly heterogeneous. Thus, it was expected that there would be a low density of voids nucleated over large areas making statistical significance a challenge. Third, FM alloys such as HT9 are very complex and include many features including dislocation loops, lines, as well as small grain and lath sizes. These features have the potential to obscure voids, particularly those that are small (<5-10 nm).

4.5.2.1 Imaging Conditions

Void imaging was performed using either a JEOL 2100F Cs Corrected Analytic Electron Microscope (AEM) located at the Michigan Center for Materials Characterization (MC²), formerly the Electron Microbeam Analysis Laboratory (EMAL) at the University of Michigan, or a JEOL 2010F AEM. The JEOL 2100F operates only in scanning transmission electron microscopy (STEM) mode. The JEOL 2010F operates in either CTEM or STEM mode. Both microscopes were operated using an accelerating voltage of 200 kV. Specimens were loaded on either a single-JEOL or double-tilt Gatan holder, operated at room temperature. The Digital Micrograph® software package was used for STEM and CTEM image acquisition. It was also used for energy-dispersive X-ray spectroscopy (XEDS), a technique utilized to obtain microchemical data collection and analysis when imaging secondary phases.

Void imaging was performed using STEM mode. The entire liftout was imaged in both high angle annular dark field (HAADF) and in bright field (BF) modes. Traditionally, void

imaging has been performed using CTEM with the through focus technique, meaning that voids were over and under focused in a series of imaging conditions. There are several issues with this technique. First, although conventional BF has better resolution than BF STEM, the voids varied in size with depth, since not all voids were in focus at a single objective focus value. Second, the BF imaging suffers diffraction contrast effect causing voids to be obscured by BF imaging under strong Bragg scattering conditions. Since HAADF imaging in STEM has Z contrast (Z is atomic number here) in nature, the void size can be accurately measured irrespective of the position of the void in the lamella and most voids were in focus as long as the a smaller beam convergent angle used and the specimen is not too thick, shown in Figure 4.22. So, HAADF is optimal for imaging voids, as there is less diffraction contrast in HAADF relative to that observed in BF; thus, voids that were obscured by diffraction contrast in BF (Figure 4.23b) were clearly visible in HAADF (Figure 4.23a).

Void images in STEM HAADF and STEM BF modes were taken across the entire liftout at a magnification of 50,000x and were then "stitched" together to show the whole area. An example of this is shown in Figure 4.24, where both HAADF and BF images clearly show the void distribution within the sample. In addition, as it is hard to reach a "pure Z-contrast" imaging condition experimentally, if diffraction contrast was still visible in HADDF, the stage was then tilted so that all grains can be clearly illuminated without much diffraction contrast.

Specimen thicknesses was measured using Electron Energy Loss Spectroscopy (EELS) low loss method. The EELS spectrum, which was performed in conjunction with STEM imaging, measures the loss in energy of electrons penetrating the samples using an energy filter here a Gatan Imaging Filter (GIF). The lenses for STEM imaging were set to give a probe size of ~ 1nm with an EELS collection angle about 38 mrad. The EELS low loss method used to

determine specimen thickness has an error of 10% [71], which was determined by calculating the error in logarithmic fit of the inelastic mean free path of electrons through the sample. The specimen thickness was measured at a depth of 500-700 nm, corresponding to the depth of interest for void data, in at least 2 locations per liftout.

4.5.2.2 Void Counting and Determination of Region of Interest

After imaging of the liftout was complete, the voids were counted from HAADF images. Features that appeared to be voids were confirmed by examining the same image in BF to ensure that the feature was in fact a void and not a precipitate or defect cluster. Counting was performed using ImageJ software. Micrographs were opened in the program. Using the length measurement tool, the experimenter drew straight lines across the voids to measure the diameter. Voids were counted in 100 nm depth increments, or "bins," starting from the surface and proceeding to a depth of at least 1000 nm up to 1300 nm, depending on if there were any voids at greater depths, which occurred at high damage/swelling. After an image was counted, the experimenter repeated the process with the next image, taking care not to double count voids that may overlap in both of the images. Swelling was calculated using the following equation:

$$\frac{\Delta V}{V} = \frac{\frac{\pi}{6} \sum_{i=1}^{N} d_i^3}{A * \delta - \frac{\pi}{6} \sum_{i=1}^{N} d_i^3} * 100$$
(4.3)

where *A* is the image area, δ is the sample thickness, *d_i* is the void diameter and *N* is the number of voids. Sink strength for voids is calculated below:

$$k_v^2 = 4\pi \frac{d_{avg}}{2} \rho_V \tag{4.4}$$

where ρ_V is the void number density.

Swelling rate $(\frac{\Delta v}{v})$ was calculated from a linear regression using either linear or parabolic least squares regression line from the swelling vs. dpa curve where

$$\frac{\Delta \dot{V}}{V} = \frac{\sum (\Phi_i - \bar{\Phi})(\frac{\Delta V}{V_i} - \frac{\Delta V}{V})}{\sum (\Phi_i - \bar{\Phi})^2}$$
(4.5)

where Φ is the damage level in dpa for a linear least squares regression. Swelling rate for the linear swelling regime is calculated with all values from 188 to 650 dpa unless otherwise marked. Least squares regression can also be applied to polynomial fits. In this case, the instantaneous swelling rate is taken as the tangent of least squares polynomial fit of n=2:

$$\frac{\Delta \dot{V}}{V} = \frac{d}{d\Phi} (a_0 + a_1 \Phi + a_2 \Phi^2) = a_1 + 2a_2 \Phi$$
(4.6)

where a_0 , a_1 and a_2 are the polynomial coefficients calculated in Excel.

A typical result of depth profiling is shown in Figure 4.25. Several effects can be observed. Figure 4.25a-b shows that there was a high density of small voids near the surface, which was observed in the majority of conditions, regardless of temperature or presence of helium, which resulted in relatively high values of swelling in the near surface region. A similar result was observed by Shao *et al.* [72] Enhanced nucleation of voids within 300 nm of the surface where the dpa increases from 0 to 68% and the He concentration is below the nominal level of the nominal value (Figure 4.4) indicates that some mechanism is increasing the damage efficiency in this region. Furthermore, this effect was found to be independent of nominal helium concentration. Thus, it is likely caused by the close proximity of the surface. In addition, at depths greater than 700 nm a decrease in number density (Figure 4.25b) was observed and found to be coincident with the increase of the injected interstitial [73].

A full discussion of these atypical effects is in Section 5.2.1, and the valid region for void analysis was determined to lie between 300 and 700 nm. While the He concentration was constant in this region, the damage varied substantially, increasing from 68 to 117% of the nominal damage across this 400 nm region. Swelling was analyzed in either the region from 300 to 500 nm or from 500 to 700 nm, which limited the damage variation over the analyzed area while still maintaining a larger enough area to capture the microstructural variations and to ensure statistically significant numbers of voids. The creation of two regions of interest effectively doubled the damage levels that could be analyzed in each sample, assuming there were statistically significant numbers of voids in both regions. However, it should be noted that there will be a different damage rate in each region.

4.5.2.3 Error Analysis

A variety of measurement errors and inherent variations in void formation and measurement contributed to uncertainty regarding the void diameter, number density and overall swelling. Measurement errors were treated separately from variations. For the purposes of this analysis, fractional error (μ_X) is denoted as the following:

$$\mu_X = \frac{\sigma_x}{X} \tag{4.7}$$

where σ is the measurement error and X is the measured quantity. Fractional error is typically presented as a percentage. There are two types of measurement error to be considered: TEM Resolution and EELS Measurement Error.
The resolution of the image is 0.7 nm/pixel and using line measurement, the error would involve at least one pixel on each end. So the error in resolution (σ_{Res}) is ~1nm, regardless of void size. This error should be void diameter dependent according to the following equation:

$$\mu_{\text{Res}} = \frac{1nm}{D} \tag{4.8}$$

where μ_{Res} is the fractional error from TEM Resolution and D is the average diameter. Measurement error contributes to the diameter and swelling, since it affects the diameter of the voids, used in calculating average diameter as well as swelling.

The EELS zero loss method has inherent measurement error of 10% or fractional error of 0.1, due to the error in the logarithmic fit of inelastic mean free path of electrons through the sample. Fractional error in thickness (μ_{EELS}) contributed to error in number density and swelling, only.

$$\mu_{EELS} = 0.1 = 10\% \tag{4.9}$$

For diameter, the only measurement in error under consideration is that from TEM resolution. Applying Equation 4.8 to voids from size of 2 nm up to 50 nm results in a void size dependent error shown in Figure 4.26. Thus, the appropriate for diameter can be selected from this graph. For void density, the error is constant regardless of void diameter and is 10%, which is also plotted on Figure 4.26.

Since swelling includes error contributions from TEM resolution as well as EELS measurement, it is necessary to apply linear propagation to determine the swelling error. Linear propagation for multiplication of quantities is shown below in Equation 4.10.

$$\mu = \frac{\sigma_u}{u} = \sqrt{\left(\frac{\sigma_x}{x}\right)^2 + \left(\frac{\sigma_y}{y}\right)^2} \tag{4.10}$$

For the case of void swelling, swelling is proportional to the number density and diameter (D) via the following formula:

$$\frac{\Delta V}{V} \propto N_D * \left(\frac{D}{2}\right)^3 \tag{4.11}$$

For the case of error propagation with quantities raised to power (diameter in this case), μ_D can be calculated as:

$$\mu = n * \frac{\sigma_D}{D} \tag{4.12}$$

where n is the exponent. For swelling, combining Equations 4.10 and Equation 4.12 results in the following error for swelling:

$$\mu_{\Delta V} = \sqrt{\left(\frac{\sigma_{N_D}}{N_D}\right)^2 + \left(n * \frac{\sigma_D}{D}\right)^2} = \sqrt{\mu_{N_D}^2 + (3 * \mu_D)^2}$$
(4.13)

Thus, swelling error is dependent on void diameter and is also plotted in Figure 4.26.

An additional consideration is the high degree of spatial heterogeneity of the void distribution, common to FM alloys. Variation in void nucleation behavior adds an additional uncertainty into the volume averaged void swelling, which is dependent on the volume of

material characterized. To report for such variability, the number of voids counted and the area counted is provided for all void results presented in this thesis. An effort was made to examine at least 100 voids per irradiation condition in at least 2 liftouts, or nominally 2 μ m² of 120 nm thickness to minimize the effect of the heterogeneity.

4.5.3 Precipitate Measurement, Characterization and Imaging

Two major types of irradiation-induced precipitates were observed in this study. G phase precipitates were imaged, either in CTEM or STEM mode. G phase were imaged at magnifications of up to 50,000x. Thickness of the sample was again measured by the EELS low loss method described in Section 4.5.2.1. Either XEDS maps or diffraction patterns were used to confirm the formation of the G phase. XEDS was used to verify that precipitates too small for a usable diffraction pattern were in fact Ni/Si rich. Diffraction patterns were used on larger precipitates. M₂X precipitates were imaged in low angle annular dark field (LAADF) STEM mode analog to the dark-field imaging in CTEM at magnifications of 50,000x. Compositions were confirmed using EELS and diffraction patterns were also taken in conventional mode. The calculation for sink strength for spherical, unbiased precipitates (G phase) is shown below.

$$k_{ppt}^2 = 4\pi \frac{d_{ppt}}{2} \rho_{ppt}$$
(4.14)

where d_{ppt} is the precipitate diameter and ρ_{ppt} is the precipitate number density. When precipitates are planar with l>>w as in the case of M₂X, a more rigorous calculation is required to account for the acicular shape. The calculation for non-spheroid precipitate sink strength is shown below in Equation 4.15.

$$k_{ppt}^2 = 4\pi r_p \rho_{ppt} \frac{\kappa}{r_p} = 4\pi \kappa \rho_{ppt}$$
(4.15)

where r_p is the effective radius and κ is the capacitance for a precipitate such that $w \approx t$.

$$r_p = \sqrt[3]{lwt} \tag{4.16}$$

$$\kappa = \frac{\sqrt{l^2 - t^2}}{\ln\left[\left(\frac{l}{t}\right)^2 + \sqrt{\left(\frac{l}{t}\right)^2 - 1}\right]}$$
(4.17)

4.5.4 Dislocation Imaging

Both dislocation loops and lines are present after irradiation. Dislocation loop imaging in FM alloys is challenging, especially where there is a high population of voids, which can obscure the dislocation loops. Mentioned in Chapter 3, two loop types exist in FM alloys: cube-edge loops with b<100> on [100] planes and glissile edge loops with $\frac{1}{2}b<111>$ on [111] planes [3]. The simplest way to image all loops is by tilting to the <001> axis, so <001> loops will appear circular, the <100> and <010> appear as ovals perpendicular to each other and $\frac{1}{2}<111>$ appear as ovals at an angle of 45° to the <100> loops. Imaging was performed in CTEM with weak 2 beam imaging conditions. A diagram of this is shown in Figure 4.27. Loop diameter and number density were measured and from these values, a dislocation loop line length may be calculated.

Dislocation lines were measured and counted using TEM BF imaging at a magnification of 50,000x, which resulted in the average dislocation line length. Sample thickness used in this calculated line length was measured using the EELS low loss method described in Section 4.5.2.1. The method for determining dislocation network was developed by Smith *et al.* [74] and utilized in T91 recently by Xu [70]. Using an equidistant circular grid, intersections between the grid and dislocation lines can be used to obtain a planar density. Consider p, a probability of a randomly oriented line segment that intersects a grid which is defined by line segment L_i and grid spacing of d_c .

$$p = \frac{2}{\pi} \frac{L_i}{d_c} \tag{4.18}$$

If $L_i \ll d_c$ and L is made up of M segments of L_i , the number of intersection will be pM thus Equation 4.18 becomes the following:

$$N = \frac{2}{\pi} \frac{L}{d_c} \tag{4.19}$$

The 2D planar density is the total line length divided by the effective area of the grid:

$$\rho_{2D} = \frac{L}{A} \tag{4.20}$$

Considering a circular grid with a number of concentric lines n_c that were spaced d_c apart, the effective density is thus:

$$A = \pi (n_c d_c)^2 \tag{4.21}$$

Combing these equations results in a planar density with units of m⁻¹.

$$\rho_{2D} = \frac{N}{2n_c^2 d_c} \tag{4.22}$$

Since TEM specimans have a finite thickness, this can be translated into a volumetric density. The length of the projection of a dislocation line in a TEM image is related to the actual length by a factor of $2/\pi$, when added to the area density results in a dislocation line density (length) of:

$$\rho_{3D} = \frac{N\pi}{4n_c^2 d_c t} \tag{4.23}$$

Thus, this equation was used for calculation of network dislocation line density of either the asreceived or irradiated sample.

The equation for calculation of sink strength for dislocation loops and network are given below.

$$k_{loop}^2 = 4\pi \frac{d_{loop}}{2} \rho_{loop} \tag{4.24}$$

$$k_{network}^2 = \rho_{network} \tag{4.25}$$

Element	Chemical composition (wt%)				
Fe	85.1				
Cr	11.8				
Ni	0.51				
Мо	1.03				
Mn	0.50				
С	0.21				
Ti	<0.01				
V	0.33				
W	0.24				
Si	0.21				
Al	0.03				
S	0.003				
Р	0.008				
N	0.006				

Table 4.1 Chemical composition of HT9 in wt% [9].

Variable	Meaning	Origin	Value		
Σt_i	Total irradiation time	Measured	Irradiation dependent		
İstage	Time averaged stage current	Measured	Irradiation dependent		
А	Area receiving full irradiation	Measured	Irradiation dependent		
f_{I}	Conversion from minutes to seconds	Constant	60 s/min		
f_2	Conversion from angstroms to centimeters	Constant	10 ⁸ Å/cm		
f3	Conversion from micro- coulomb to coulomb	Constant	10 ⁶ µC/C		
R _D	Damage rate calculated from SRIM	Constant	0.355 displacement/Å- ion		
N	Atomic density	Constant	$\frac{8.34\times10^{22}}{\text{atoms/cm}^3}$		
Q	Charge per ion	Constant	3.204×10 ¹⁹ C/ion		

Table 4.2: Variables used in calculation of damage under 5 MeV Fe⁺⁺ irradiation.

Sample Designation	Alloy: Heat	Target Irradiation Temperature (°C)	Target Irradiation Damage (dpa)	Final Intended Damage (dpa)	Preimplanted Helium (appm)	Date of Irradiation
ACO3-440C-140dpa-10He-032812	HT9:84425	440	140	140	10	3/28/2012
ACO3-440C-25dpa-10He-081412	HT9: 84425	440	25	25	10	8/14/2012
ACO3-440C-188dpa-10He-091312	HT9: 84425	440	188	188	10	9/13/2012
ACO3-480C-188dpa-10He-111312	HT9: 84425	480	188	188	10	11/13/2012
ACO3-400C-250dpa-10He-011913	HT9: 84425	400	250	250	10	1/19/2013
ACO3-460C-188dpa-10He-062413	HT9: 84425	460	188	188	10	6/24/2013
ACO3-440C-50dpa-10He-090413	HT9: 84425	440	50	50	10	9/4/2013
ACO3-460C-188dpa-10He-111313	HT9: 84425	460	188	375	10	11/13/2013
ACO3-460C-130dpa-10He-092214	HT9: 84425	460	130	130	10	9/22/2014
ACO3-460C-75dpa-10He-102914	HT9: 84425	460	75	75	10	10/29/2014
ACO3-460C-120dpa-10He-120814	HT9: 84425	460	120	250	10	12/8/2014
ACO3-460C-100dpa-10He-011215	HT9: 84425	460	100	350	10	1/12/2015
ACO3-460C-100dpa-10He-021615	HT9: 84425	460	100	450	10	2/16/2015
ACO3-460C-100dpa-10He-030515	HT9: 84425	460	100	550	10	3/5/2015
ACO3-460C-100dpa-10He-050715	HT9: 84425	460	100	650	10	5/7/2015

Table 4.3: List of samples utilized in this thesis, including target irradiation temperature, damage and date.

Irradiation	Temperature	Incremental	Final	Damage	Stage	Apertures	Thern	Thermocouple at Calibration			Pressure at
Date	(°C)	Damage	Damage	Rate (10 ⁻³	Configuration			(°C)			Start
		(dpa)	(dpa)	dpa/s)			1	2	2	4	(10^{-6} torr)
							1	2	3	4	
3/28/2012	440.5±8.8	140.1	140.1	0.40	Cu+In ¹	Stage	444	n. r ²	440	441	9.7
8/14/2012	443.8±5.7	25.5	25.5	0.50	Cu+In	Stage	443	419	n. r	440	5.6
9/13/2012	440.8±7.3	186.8	186.8	0.27	Cu+In	Stage	444	438	440	n. r	5.3
11/13/2012	480.0±5.9	187.5	187.5	0.53	Cu+InF ³	Stage	n.r.	483	480	481	5.3
1/19/2013	401.3±7.2	250.1	250.1	0.40	Cu+InF	Stage	404	395	402	n. r	8.8
6/24/2013	460.7±7.4	187.5	187.5	0.35	Ni+CuF ⁴	Stage	456	459	458	460	5.6
9/4/2013	442.0±10.7	50.0	50.0	0.40	Ni+CuF	Stage	443	442	440	439	9.9
11/13/2013	461.4±7.5	187.5	375	0.34	Ni+CuF	Stage	n. r	460	458	463	8.7
9/22/2014	460.2±4.4	127.6	127.6	0.57	Ni+CuF	Slit	458	460	461	n. r	5.7
10/29/2014	460.2±7.7	75.0	75.0	0.37	Ni+CuF	Slit	n. r	462	459	461	5.9
12/8/2014	462.4±3.9	122.4	250.0	11.5	Ni+CuF	Slit	456	460	458	n. r	4.7
1/12/2015	462.2±5.2	100.0	350.0	0.93	Ni+CuF	Slit	456	460	458	459	5.9
2/16/2015	461.1±5.8	100.0	450.0	11.9	Ni+CuF	Slit	457	460	n. r	459	4.9
3/5/2015	461.6±3.9	100.0	550.0	0.63	Ni+CuF	Slit	457	459	n. r	460	4.8
5/7/2015	461.9±3.1	100.0	650.0	085	Ni+CuF	Slit	n. r	463	459	460	2.9

Table 4.4: Summary of irradiation data from 5 MeV Fe⁺⁺ irradiations referred to in this thesis.

- ³ Cu+InF: Copper Stage with Indiphoil ⁴ Ni+CuF: Nickel Stage with Cooper foil

¹ Cu+In: Copper Stage with Indium ² N.R.: Not recorded



Figure 4.1: Unirradiated HT9 (Heat 84425) imaged in STEM-BF. Sample made via FIB liftout method





Figure 4.2 Sample geometry following EDM. Only one face will be irradiated.



Figure 4.3: Assembly used for electropolishing of samples. Samples polished in 90% methanol/10% perchloric acid solution.



Figure 4.4: The helium profile (blue) is overlaid on the damage rate (red) and implanted ion concentration (green) for 5 MeV Fe⁺⁺ in Fe-12Cr calculated from SRIM [64].



Figure 4.5 Schematic of irradiation stage and position of 2D thermal imager on beamline.



Figure 4.6: a) Schematic of hold-down bars and b) view of hold-down bars on the stage [32].



Figure 4.7: a) "First generation stage" schematic where indium is used to ensure good thermal contact and apertures were attached to the stage. b) "Second generation stage" schematic where a combination of indium and graphite foil were utilized to ensure good thermal conductivity and leak protection.



Figure 4.8: Stage design as viewed from the top [32].



Figure 4.9: Completed stage after irradiation at 460°C to 130 dpa.



Figure 4.10: a) Schematic and b) stage image for temperature uniformity test. c) Results of the 24-hour test on the beamline.



Figure 4.11: Schematic of "third generation" stage configuration with a) stage and b) slit apertures. Copper foil provided sufficient thermal contact and eliminated indium leaks. Slit apertures eliminated danger of aperture shift, which could occur during stage loading onto beamline.







Figure 4.13: Schematic of tantalum aperture system.



Figure 4.14: Schematic of benchtop alignment setup of stage apertures [32].



Figure 4.15: Path of raster scanned beam center across samples over irradiated area [13,32].



Figure 4.16: a) Schematic of raster scanned beam area after beam sizing procedure with ceramic. b) Beam intensity profile due to Gaussian beam shape



Figure 4.17: Irradiation stage a) without and b) with alignment laser.



^{0.0} Figure 4.18: 2D thermal image from 460°C, 130 dpa irradiation. Two AOIs per samples were placed on 5 samples with two guide bars bookending the samples.



Figure 4.19: Example temperature histogram for 5 MeV Fe⁺⁺ irradiation of ACO3-460C-450dpa-10He-021615 showing approximately normal distribution in both areas of interest (top and bottom) on the sample and having 2σ well within $\pm 10^{\circ}$ C.



Figure 4.20: a) Platinum deposited on the surface of the irradiated sample b) trenching around the platinum protected surface c) under cut of the samples d) attaching the needle to the lamella using platinum e) attaching the lamella to the copper grid f) thinning using the Ga beam.



Figure 4.21: Schematic of cross-sectional liftout and resulting image in HAADF STEM. The PT layer and irradiated surface are at the top of the image. Voids are dark circles. Sample irradiated at 460°C to 188 dpa with 10 appm He preimplanted.



Figure 4.22: Conventional BF (a) and STEM BF (b) images of voids in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C to 375 dpa with 10 appm He preimplanted. Note that all voids are in focus in (b) while conventional images show some voids in over or under focus.



Figure 4.23: STEM ADF (a) and BF (b) images of HT9 irradiated with 5 MeV Fe⁺⁺ at 440°C to 140 dpa with 100 He preimplanted. Voids obscured by diffraction contrast in BF (b) are clearly observed in ADF (a) as black circles.



Figure 4.24: Example of STEM HAADF and BF images stitched together to show entire liftout. (HT9, 440°C, 188 dpa, 10 appm He)



Figure 4.25: Depth profiles for void a) diameter b) number density and c) swelling in HT9 irradiated at 440°C to 140 dpa with 100 appm He preimplanted [12].



Figure 4.26: Error for diameter, number density and swelling as a function of average void diameter.


Figure 4.27: Orientation and shapes of dislocation loops in FM alloys imaged along <001> axis [32].

CHAPTER 5

RESULTS OF MICROSTRUCTURE EVOLUTION UNDER ION IRRADIATION

This chapter will describe results of the experimental portion of the thesis. There are two sections; the results of the 5 MeV Fe⁺⁺ irradiation experiments followed by the post-irradiation microstructure characterization. The first part of the chapter will verify that irradiations were performed at the targeted conditions in terms of temperature, damage, and pressure. The second part of the chapter will present all relevant microstructure results, which will serve as both inputs and a baseline comparison for the modeling section of the thesis in Chapters 6 and 7.

5.1 Unirradiated Microstructure Characterization

Prior to irradiation, FIB liftouts of the as-received alloy were prepared and characterized to establish a baseline microstructure for comparison to the irradiated microstructure. Measurements of the grain sizes, precipitate ($M_{23}C_6$ carbides) size and density and dislocation line length are presented in this section.

Grain size (measured as lath length and width), precipitate diameters and densities as well as dislocation lines were measured from STEM bright field images. The precipitate observed in the as-received microstructure was $M_{23}C_6$, which primarily decorate grain boundaries. An example as-received microstructure is shown in Figure 5.1. The as-received characterization of this alloy is quantified in Table 5.1. Laths in HT9 have, on average, a length of 880 nm and width of 317 nm. At least 50 grains were measured. Grain boundary sink strength requires calculation of an effective grain size parameter d. d is calculated by mathematically equating the rectangular lath area to an equivalent square area, shown in Equation 5.1, where l is the lath length and w is the lath width.

$$d = \sqrt{l * w} \tag{5.1}$$

The effective grain width can be used to calculate grain boundary sink strength using Equation 5.2.

$$k_{gb}^{2} = \begin{cases} \frac{6k}{d}, d > 10^{-5} m \\ \frac{24}{d^{2}}, d < 10^{-5} m \end{cases}$$
(5.2)

where *k* is the sum of all other sink strengths, which in this case was approximately $k=2\times10^{14} \text{ m}^{-2}$ [20]. Using *d*, which was calculated as 528 nm, the grain boundary sink strength was calculated to be $8.6\times10^{13} \text{ m}^{-2}$.

Finally, retained δ -ferrite due to incomplete tempering was observed. Metallography of the as-received HT9 was performed and a representative micrograph is shown in Figure 5.2. Several δ -ferrite are marked with yellow arrows. δ -ferrite is marked by a characteristically "clean" matrix, free of M₂₃C₆. The fraction of retained δ -ferrite was measured to be approximately 8% by area. A comparison of the void behavior in each grain type is further discussed in Section 5.2.4.1.

A copy of the indexed diffraction pattern is given in Figure 5.3 using selected area electron diffraction (SAED) along the [001] zone axis, which was consistent with body centered structure. No asymmetry was noted between the a and c, which indicates that HT9 is body centered cubic

(BCC) rather than body centered tetragonal (BCT) with *a*=0.282 nm. (The calculated c/a ratio was 1.002, which was within TEM error). The classification of HT9 as BCC is consistent with a well establish observation in the literature that martensite has BCC structure when carbon levels are below 0.6 wt% [75–78]. (The concentration of carbon in HT9 heat 84425 is 0.2 wt%). These results are also consistent with recent X-ray diffraction (XRD) results of the c/a ratio of 1.0003 in T91, a similar alloy [79].

 $M_{23}C_6$ carbides were observed primarily decorating the grain boundaries and were determined to be on average, 47.7 nm in diameter with a density of 1.66×10^{19} m⁻³ yielding a sink strength of 4.96×10^{12} m⁻³, an order of magnitude lower than the sink strength of the grain boundaries.

The dislocation network was also measured. The as-received alloy had a network dislocation line length of 2×10^{14} m⁻², which precisely corresponds to its sink strength. From the unirradiated characterization, it was clear that the dislocation network was the strongest sink contributor by an order of magnitude and dominated the calculated total sink strength of 2.50×10^{14} m⁻² of the as-received alloy.

5.2 Void Swelling Results

The focus of this thesis is on the co-evolution of the microstructure with particular focus on the behavior of voids under self-ion irradiation. Before analytic void results in terms of void diameter, number density and swelling can be determined, several unique effects due to the ion irradiation must be considered to determine a "valid" depth region of interest. These atypical effects include the shallow depth penetration (less than 1.6 μ m in the sample surface), proximity to the surface as well as the implantation of iron ions, referred to as the "injected interstitials."

5.2.1 Determination of Valid Region of Interest

A meaningful characterization of void swelling requires that the extrinsic factors previously mentioned be properly characterized. A complete analysis was performed and presented in [12]; for completeness, a summary is included here. First, a representative void image is shown in Figure 5.4a from a sample irradiated at 460°C up to 188 dpa with 10 appm He preimplanted. By visual inspection, a high density of mostly small voids near the irradiated surface was observed (Figure 5.4b). With increasing depth, it was also observed that there was a second band of larger voids from approximately 400 to 1000 nanometers from the surface. Finally, the diameter increased with depth into the bulk. The void distribution with depth was characterized using the method described in Chapter 4 and the results for void diameter, number density and swelling as a function of depth are presented in Figure 5.5a-c. Quantitative comparisons verify the qualitatively observed trends regarding void density; a peak near the surface and a decrease in void density beyond 700 nm.

Small voids near the surface were observed in a majority of irradiated conditions, regardless of temperature or presence of helium, which resulted in relatively high values of swelling in the near surface region, especially at low damage levels. The enhanced nucleation cannot be attributed to radiation damage; within the first 300 nm, the damage increased from up to 68% of the nominal calculated damage and the helium concentration was below the nominal level, shown in Figure 4.4. Furthermore, this effect was found to be independent of nominal helium concentration. (The effect of helium on void behavior is outside the scope of this thesis, but relevant to the discussion at hand and was addressed in [12].) Thus, it was assumed that this is a surface effect.

To quantify the surface effect, swelling depth profiles were examined for fourteen conditions of varying helium, damage and temperature. The depth at which the swelling began to increase is plotted in Figure 5.6, which shows that the onset of the swelling increase was most commonly at a depth of 400 nm, demonstrating that the surface effect was confined to the first 300 nm. The surface effect was also observed by Shao et al. [72], who attributed this effect to a defect imbalance near the surface. A vacancy-rich region forms near the surface because of the preferential loss of interstitials due to their higher mobility. The surface effect was modeled by Xu et al. [80] in molybdenum irradiated in the TEM with 1 MeV Kr⁺. The ratio of mono-vacancies to mono-interstitials was always larger near the surface of the examined foil rather than near the middle of the foil. This ratio varied from 1.81×10^{11} at the surface to 3.89×10^{10} at 30 nm from the surface in a TEM foil with thickness of 60 nm under 1 MeV Kr⁺ irradiation at fluence of 4.8×10¹³/cm² at 80°C. In addition, MD simulation of 100 keV Fe⁺ irradiated iron performed by Stoller [81] compared surviving defects after cascades near the surface and the bulk. It was found that 0.48 vacancies per NRT survived cascades versus 0.33 for interstitials near the surface. In the bulk, there was no difference in survival efficiency between vacancies and interstitials. There was also an increase in vacancy clustering near the surface relative to the bulk. The vacancy/interstitial imbalance promotes void nucleation by stabilization of vacancy clusters and void embryos. Regardless of the mechanism, the surface affected void formation within the first 300 nm.

Figure 5.5c also showed a decrease in void swelling at depths greater than 700 to 900 nm due primarily to a decrease in number density, with little to no effect on diameter. The damage in this region was 80% above the nominal damage level measured at 600 nm, which should result in increased void swelling. The decrease was likely due to the presence of injected interstitials, which have been shown throughout the literature [36,73,82] to suppress swelling. A similar decrease in

number density at increasing depth/damage was also observed by Yamamoto *et al.* [83] in irradiations performed with 6.4 MeV Fe³⁺ ions. They performed a similar depth profiling study up to 1.6 μ m in dual ion-irradiated MA957 and PM2.

For the results considered in this analysis, the depth at which the apparent decrease in void swelling occurred is plotted in Figure 5.7. Fifteen different cases varying in temperature, damage and helium implantation level were examined. Irrespective of temperature, helium or damage, the drop in swelling occurred between 700 and 900 nm. A rate theory calculation of void swelling by Brailsford and Mansur determined that excess interstitials decrease void growth by less than 10% when the ratio of interstitials to dpa was $\leq 2.5 \times 10^{-4}$ when modeling 4 MeV Ni⁺ irradiation of pure Ni at 450°C [82]. Between the depths of 700 to 900 nm, the ratio of implanted ions to dpa in this experiment varied between 5.26×10^{-6} and 5.45×10^{-5} . The rate theory calculation pertains to the growth-dominated swelling regime. Since most of the data in this analysis was in the nucleation or transition regimes, the primary effect of the injected interstitial was on void nucleation. The decrease in swelling was due to a decrease in the void number density over a variety of damage, temperature and helium conditions. Fifteen temperature conditions that were examined in Figure 5.7 for the depths at which there was an apparent swelling decrease were then compared to the locations where diameter and number density decreased. It was found that the decrease in swelling was due to a decrease in void number density in 7 cases, a decrease in void diameter in 2 cases and a decrease in both number density and diameter in 3 conditions. There was no correlation in the remaining 3 cases.

After accounting for the effects of the surface and the implanted interstitial, the valid region for void analysis was determined to lie between 300 and 700 nm. While the He concentration was constant in this region, the damage varied substantially, increasing from 68 to 117% of the nominal

damage across this 400 nm region. Swelling and void characteristics for the rest of this thesis were analyzed in either the region from 300 to 500 nm or from 500 to 700 nm, which limited the damage variation over the analyzed area while still maintaining a large enough area to capture microstructural variations and to ensure statistically significant numbers of voids; effectively doubling the number of damage levels that can be analyzed in each sample, assuming there were statistically significant numbers of voids in both regions. However, it should be noted that there was a different damage rate and He/dpa ratio in each region and preference was given to analyzing voids in the 500 to 700 nm region.

5.2.2 Damage Dependence at 440°C

Using the characterization method outlined in Chapter 4 combined with the region of interest selected in Section 5.2.1, void results were analyzed for each of the damage and temperature combinations outlined in the approach in Chapter 3. Representative images for each examined condition are included in this chapter, and Appendix B: Void images, presents images of an entire liftout from each examined condition. Void depth profiles for each irradiation condition are included in Appendix C: Void Depth Profiles.

The first damage dependence study was performed at 440°C from 25-188 dpa with 10 appm He preimplanted. The primary motivation of this damage series was to determine 1) where void swelling occurred in terms of damage level and 2) what damage level was sufficiently high enough to provide a large enough void population to perform a statistically significant temperature dependence experiment. The temperature, 440°C, was chosen because 440°C was believed to be the approximate peak swelling temperature in reactor irradiations of the same heat of HT9 [9,10]. Due to the high sink density of HT9, temperature shift theory from Mansur [34] suggested that there would not likely be a large temperature shift with accelerated damage rates reached by ion irradiations. Thus, 440°C was chosen on the assumption that voids may be observed at similar damage levels as those reached in reactor at 443°C, 155 dpa [9].

Representative images from each damage level at 440°C are presented in Figure 5.8. No voids were observed at 25 or 50 dpa (Figure 5.8a-b). By 140 dpa (Figure 5.8c), a few isolated voids were observed. By 188 dpa (Figure 5.8d), a significant population of voids were observed from 0 to 1000 nm.

Using both the 300 to 500 and 500 to 700 nm depth regions described previously, the diameter and number density as a function of damage are plotted in Figure 5.9 and tabulated in Table 5.2. Figure 5.9a showed a modest increase in diameter with damage from 92-188 dpa. A larger relative increase was observed in number density (Figure 5.9b) from 0.214×10^{20} m⁻³ to 5.60×10^{20} m⁻³ at damage levels from 140 to 188 dpa. The resulting effect of increased diameter and number density is plotted in Figure 5.10. A clear increase in overall swelling was observed. For a simple comparison, the final swelling rate was calculated using linear regression Equation 4.5 from a damage of 140 (with 0.03% swelling) and 188 dpa (with 0.22% swelling) and was determined to be 0.004%/dpa. This swelling rate was low compared to the swelling rates observed in reactor at similar damage levels, (~0.01%/dpa) [7,9,10] indicating that linear, growth-dominated swelling may not have yet been reached. However, given that there was significant void swelling by 188 dpa (0.22% measured from 179 voids counted in the region of interest), 188 dpa was deemed a sufficiently high enough damage level at which to perform a temperature dependence experiment.

5.2.3 Temperature Dependence at 188 dpa

Following the 440°C damage dependence experiment, additional temperatures (460 and 480°C at 188 dpa) were examined to verify that 440°C was the peak swelling temperature or alternatively, to determine where swelling peaks as a function of temperature. Representative images from the temperature dependence experiment are included in Figure 5.11. Qualitatively, the results were striking. At 460°C, there was a higher number density of voids with a larger diameter than those at 440°C, which was strong evidence suggesting that 460°C was the peak swelling temperature. At 480°C, the voids were larger than those at 440°C, but not at 460°C. They also appeared to have a smaller number density than any other temperature.

These results are quantified in Figure 5.12 and Figure 5.13. The void diameter (Figure 5.12a) variation with temperature was highly peaked, which did not agree with previous observations from the literature. The literature [14,15] suggests that diameter increases with temperature until it becomes thermodynamically unfavorable to maintain void stability due to thermal emission from vacancy clusters [20]. The number density (Figure 5.12b) also peaked at 460°C, and sharply dropped off by 480°C by two orders of magnitude. Previous results from neutron and ion irradiation [10,14,15] suggested that number density should decrease with temperature. The results from this study did not reflect the expected diameter and number density behavior. The reason for this is that at 188 dpa, the different temperatures examined may not be in the same swelling regime i.e. transition versus void growth-dominated. To demonstrate this, the damage evolution of all three temperatures is plotted in terms of diameter and number density in Figure 5.14. Dashed lines were added to extrapolate the expected damage evolution at 440°C and 480°C to higher damage levels. At 188 dpa (marked by a black line), 460°C is at the beginning of the void growth dominated regime whereas new voids are likely being nucleated in 440 and 480°C. At higher dpa, such as the 300 dpa marked by a black line, all three temperatures will likely be in the void growth-dominated regime with the diameter directly proportional to temperature and number density inversely proportional temperature. In other words, the period of sudden growth at 460°C from 130 to 188 dpa was not yet observed in either 440 or 480°C. Thus, a better comparison of temperature dependence is if all three were in the void growth-dominated regime.

Regardless of the observed diameter and number density behavior, swelling exhibited the expected bell-shaped curve, which was consistent with theory [20] and literature [10,14,15], despite the inconsistency in the diameter and number density trends. Smidt *et al.* [14] observed a similar swelling peak in both HT9 and EM12, which was centered at 500°C rather than 460°C as in this study. These irradiations were performed with 2.8 MeV Fe⁺ with a damage rate of 6×10^{-2} dpa/s up to 150 dpa with 1 appm He preimplanted. The full width at tenth maximum (FWTM) for alloy HT9 in Smidt's experiment was approximately 100°C. Toloczko [15] recently reported on the temperature dependence on swelling of MA957, in which the FWTM was ~90°C. Toloczko's irradiations were performed on MA957 with 1.8 MeV Cr⁺ at 1×10^{-2} dpa/s up at 100 and 500 dpa. However, these results differed in that the swelling peak was narrower than that reported in the literature [14,15]. A FWTM value of ~30°C was observed in this study. The cause of this difference was unclear but may be in part due to improvements in temperature control under ion irradiation. Regardless, the peak swelling temperature was quite clearly demonstrated to be 460°C.

5.2.4 Damage Dependence at 460°C

A damage dependence experiment was then performed at 460°C; the motivation was previously described in Chapter 3, but is repeated here. The peak swelling temperature was chosen for several reasons. First, the focus of this thesis is on the high damage, void growth-dominated regime. To this end, it was desirable to reach the growth-dominated swelling regime as quickly as possible in terms of damage/time. Damage levels examined were from 75-650 dpa for the purpose of mapping out void evolution from nucleation, through transition and into growth-dominated regime. A summary of all void results following irradiation at 460°C is presented in Table 5.3. Due to the large amount of swelling and small amount of helium, "cavities" are hereafter referred to as "voids" for the rest of these results.

No voids were observed at 75 dpa in the 500 to 700 nm region. Figure 5.15 shows micrographs of the self-ion irradiated HT9 from 130 to 650 dpa. The lowest damage at which voids were observed was 130 dpa, where there was a large population of small voids (Figure 5.15a). As the damage increased, the void diameter also increased (Figure 5.15b-f). In general, the void diameter increased with increasing depth into the sample, but decreased in number density at depths greater than 700 to 1000 nm.

Voids were characterized as a function of depth for each irradiation damage level, previously described in Chapter 4 and also in Appendix C: Void Depth Profiles. Void diameter from the 500 to 700 nm region of interest is shown in Figure 5.16. Diameter increased as a function of damage up to and including 650 dpa. The void diameter growth rate was determined to be nearly 0.1nm/dpa (0.063nm/dpa from 188 to 650 dpa) from 188 dpa and above. A constant or near constant void diameter growth rate was a strong indication that linear swelling had been achieved. Figure 5.17 presents the number density as a function of damage. Number density was approximately constant throughout the damage levels examined until 450 dpa. The decrease was attributed to void coalescence as voids grew large enough for agglomeration to occur. Atypical void shapes, meaning those not circular or faceted, provided additional evidence of void coalescence.

Figure 5.18 shows the swelling as a function of damage. Consistent with the damage behavior demonstrated in Figure 5.16, there was linear swelling from approximately 188 dpa up

to 650 dpa. A swelling rate was determined to be ~0.033%/dpa, measured from 188 to 650 dpa using Equation 4.5, and this will be compared to the literature as it serves as a useful metric. Smidt *et al.* [14] determined a linear swelling rate of ~0.02%/dpa up to 250 dpa for HT9 under 2.8 MeV Fe⁺⁺-irradiated at 500°C with 1 appm He preimplanted. Toloczko *et al.* [15] determined a final swelling rate of 0.2%/dpa from 1.8 MeV Cr³⁺ at 450°C from 400 to 600 dpa. For this study, recall that 10 appm He was purposefully chosen to accelerate the void swelling evolution. In spite of this, the approximate swelling rate remained an order of magnitude lower at a higher damage when compared to Toloczko's results. The swelling rates at 460°C were more consistent with Smidt's results and those of the HT9/T91 in-reactor database showing swelling rates of 0.01%/dpa up to 208 dpa shown in Figure 2.8.

The inconsistency in void response between these results and [15] at high damage levels need to be addressed. Toloczko's irradiation were performed using a lower ion energy resulting in void data that was taken much closer to the surface (from 100 to 200 nm compared to 500 to 700 nm in this study); the surface has previously been shown to promote an atypical void response [12,72,83]. Furthermore, the differences in sample preparation and characterization methods (conventional BF vs. STEM ADF) could account for some of the variability. Samples in Toloczko's study made using electropolishing have more variability in terms of isolating the exact depth of the sample. Finally, electropolishing could also have artificially increased the size of the voids in the examined samples, especially at higher swelling values.

Linear regression analysis, calculated from Equation 4.5, has classically been used to determine the so-called "steady state" swelling rate. An alternative interpretation is that of a strictly monotonically increasing swelling rate i.e. swelling modeled by a parabolic curve with a slowly increasing instantaneous swelling rate, rather than as linear. The comparison of regression

analyses is shown in Figure 5.19. Both regression types are within error bars, which indicates that either was appropriate for describing the overall swelling curve shape, though the parabolic fit has a slightly better fit measured by the R^2 (0.99 vs 0.97). Despite the fact that both regression methods are within error bars, a parabolic fit indicates that the "linear" swelling observed may actually indicate a very slowly increasing swelling rate cannot be discounted and will be considered in Chapter 7.

5.2.4.1 Grain to Grain Void Variation

The void results reported here are representative to the average behavior across a number of grains. Typically, at least 2 or 3 liftouts with lengths of 8 to 12 μ m were examined with approximately 15-20 grains per samples. Examining the void behavior of 30 to 50 represents an appropriate average microstructure, which will then be applicable to the modeling mean field approach that will be discussed in Chapters 6 and 7.

However, it was observed in Figure 5.2 that there was measureable retained δ -ferrite (approximately 8% by area measured by metallography). δ -ferrite has been correlated with high levels of local swelling [15,49,84]. For comparison, a δ -ferrite grain is compared to a typical martensite grain in Figure 5.20 at both 130 and 450 dpa. At 130 dpa, voids appear to be more homogeneous in the image of the ferrite grain (Figure 5.20a) relative to the image of the martensite grains (Figure 5.20b). At 450 dpa, the voids are also much more homogenously distributed in the ferrite (Figure 5.20c) relative to the martensite (Figure 5.20d). These results are quantified in Figure 5.21. At both damage levels, nucleation was higher in the ferrite grain. The void diameter between grain types was within error bars and the swelling was higher in ferrite rather than martensite as a result. The effect of ferrite was stronger at 130 dpa, which is likely due to the fact that HT9 at 130 dpa is within the nucleation dominated regime rather than void

123

growth-dominated regime, as for 450 dpa. However, it is difficult to determine if grain boundaries in the martensite are influencing the observed void inhomogeneity. It cannot be discounted that the decrease in nucleation was due to the larger proportion of void denuded zones in martensite as in ferrite. However, qualitatively it was observed at all damage levels there are always voids in a ferrite grain but there are not always voids in a martensite grain. Thus, the results from this study are still consistent with results in the literature that suggest that δ -ferrite is more susceptible to void swelling than martensite [15,49,84]; in this case, by enhanced void nucleation.

5.2.5 High Swelling Correction

To verify that there were no atypical effects from ion irradiation, an additional analysis was performed to determine whether there was a significant effect of increased porosity due to void swelling in terms of the ion damage curve. Void swelling decreased the effective density of the material. Thus, ions are able to penetrate further into the bulk altering the dpa versus depth curve. A full analysis is available in [85], but a summary is presented here.

After void depth profiling, SRIM was used to calculate the damage in HT9 specimens. Figure 4.4 shows the damage vs. depth profile and the implanted ion distribution for 5 MeV Fe⁺⁺ in HT9. After voids were profiled in depth, the resulting swelling profile was used to recalculate the damage profile at each of the 6 damage levels at which voids were observed. Using the swelling profiles, the SRIM calculation was adapted for the change in material density as a result of void swelling at each nominal damage level. The updated densities were input into SRIM as discrete layers of 100 nm thickness. The effective density is then given by:

$$\rho_{effective} = \left(1 - \frac{\Delta V}{V}\right) * \rho_{HT9}$$
(5.3)

where $\rho_{effective}$ is the effective density, $\frac{\Delta v}{v}$ is the fractional change in volume (measured swelling) and ρ_{HT9} is the density of HT9. The results of this calculation, i.e. the effective damage rate under ion irradiation with voids were used to determine an appropriate method for correction of the damage curve.

Using the effective densities calculated from the depth profiles in Appendix C as input into the SRIM calculation described in Chapter 4, the damage rate vs. depth are directly compared at each nominal damage level in Figure 5.22. The beam current was assumed to be constant regardless of irradiation to directly compare damage rates measured in dpa/s. With increasing dpa and hence, swelling, the range of the ions increased due to increased porosity from void swelling. The effect of porosity became significant at nominal damage levels of 450 dpa. Between 550 and 650 dpa, peak swelling remained approximately the same at ~23% at 900 nm; however, at 650 dpa, the swelling prior to the peak (300 to 700 nm) continued to increase. Related to this, at any given depth (before the damage peak) the damage rate decreased with increasing nominal damage level. Finally, all of these effects were exacerbated at high swelling (>10%) of 550 dpa and above.

Figure 5.23a shows the results of the SRIM calculation with effective density of the irradiated HT9. The decrease in damage rate at 600 nm with damage was marked by a black arrow. Since this correction method maintains the same 500 to 700 nm area of interest, the damage must then be corrected with the results of the SRIM calculation. For instance, at 450 dpa, the effective damage rate was 0.91×10^{-3} dpa/s instead of 1.00×10^{-3} dpa/s, for a decrease of

9%. The 100 dpa increment from 350 to 450 dpa was actually a 91 dpa increment, if the worst case swelling profile was used. A more realistic application uses the average damage rate from $350 \text{ dpa} (0.94 \times 10^{-3} \text{ dpa/s})$ and 450 dpa $(0.91 \times 10^{-3} \text{ dpa/s})$, which was calculated as 0.92×10^{-3} dpa/s, for a decrease in 8% of the total damage. The resulting swelling curves are plotted in Figure 5.23b, which includes both the average and the "worst case scenario" corrections. Up to 450 dpa, there was almost no difference between the nominal swelling and the damage corrected swelling, but the effect became non-negligible from 450 to 650 dpa. For the fixed depth method, one downside was that the actual damage rate changed from irradiation to irradiation. However, the change in damage rate was ~20% at 650 dpa when compared to the unirradiated damage rate. The effect of damage rate on swelling was therefore minimal.

Another interesting result was that the difference between the "average" and "worst case" swelling profile was almost negligible, even up to 650 dpa. The relative consistency was likely because the largest amounts of swelling were at 600 nm or greater as shown in Figure 5.24 and Figure 5.25, meaning that the largest effect of the increased swelling was at greater depth where there was a greater cumulative effect of the porosity. The cumulative effect of increased swelling also increases with each subsequent irradiation. The resultant swelling rates from the two cases were very close for damage levels up to 650 dpa. The swelling rate was also within the error bars when compared to the nominal swelling rate.

This "fixed depth" method has the benefit of maintaining a usable void distribution, which was useful for examining void growth behavior. The correction was based upon a relatively simple SRIM calculation only. It was also the most similar to the previous correction methods used by Odette *et al.* [86] and Johnston *et al.* [87]. Finally, and perhaps most importantly, maintaining the same region of interest ensured that there are no complicating effects from the injected interstitial deeper in the sample.

A key observation was that there was little variation in the ion damage profile in irradiations below 450 dpa or ~10% swelling. Thus, the method was most useful in the high swelling regime. It was expected that the correction methodology will be even more important at even higher swelling values of 20% or more, assuming a reactor design can accommodate that level of void swelling. The depth correction method would be especially relevant for higher swelling materials such as austenitic stainless steels. Nevertheless, even at lower swelling amounts, the value of the method was that it provides more accurate data to swelling model development to high damage levels. Thus, these results were convincing evidence that even with the most liberal correction, the calculated linear swelling rate remained more or less constant and the reported swelling rate remains approximately 0.033%/dpa from 188 to 650 dpa.

5.3 Secondary Phase Results

In this section, the formation of secondary phases (precipitates) with irradiation will be discussed and characterized as a function of damage.

5.3.1 G Phase

Previously mentioned in Chapter 2, G phase is a complex FCC silicide of the form $M_6Mn_{16}Si_7$ where M = Ni typically. Images of G phase observed from 130 to 650 dpa are shown in Figure 5.26. Atom probe analysis was used to confirm the composition of G phase in samples irradiated at 440°C to 140 dpa (Figure 5.27). For the M=Ni type precipitates observed, the expected concentration (at%) of elements is 55%Ni-24%Si-21%Mn. This was consistent with Figure 5.27b and Figure 5.27c, which show two precipitates that have concentrations of nearly 55% Ni, 24% Si

and 21% Mn, within error bars. There was some uncertainty in exact composition due to how atom probe analyses are performed, but these compositions are close enough to be appropriate in identifying these precipitates as G phase. These results are also consistent with representative a XEDS image from HT9 irradiated to 130 dpa at 460°C that is shown in Figure 5.28, confirming that these are Ni/Si rich since APT analysis of all irradiation results was not feasible. γ' , also a Ni Si rich precipitate with no Mn was not observed in this study nor in any other irradiations of FM alloys [3].

A representative HRTEM image of G phase at 460°C, 650 dpa is presented in Figure 5.29. Analysis of the image verifies that G phase has an fcc cubic structure and a lattice parameter of a=1.148 nm. Furthermore, the cubic-on-cubic growth relationship to the surrounding matrix was verified to be $(001)_{G}/(001)_{\alpha}$, $(110)_{G}/(110)_{\alpha}$, and $(111)_{G}/(111)_{\alpha}$, which was consistent with results from Mateo *et al.* [88] and Vitek *et al.* [89].

G phase was observed in self-ion irradiated HT9 by 75 dpa and G phase diameter, number density and volume fraction are plotted as a function of damage in Figure 5.30 and are included in Table 5.4. Initially, G phase formed at a high number density of 2.38×10^{21} m⁻³ and a small average diameter of 7.2 nm. The number density was approximately constant from 75-130 dpa, and then decreased to ~ 8.5×10^{20} m⁻³ between 188 and 650 dpa as the diameter increased approximately linearly. Since the number density was more or less constant, the increasing growth in diameter led to an overall linear increase in volume fraction beyond 188 to 650 dpa. Two key observations are emphasized: first, the continuing evolution of the G phase precipitates up to very high damage levels of 650 dpa was consistent with recent results from Jiao and Was that suggest that the several types of precipitates continue to evolve up to very high damage levels [51]. Second, the constant number density and linear diameter growth rate resulted in an evolution similar to that of the voids.

G phase is an incoherent precipitate, meaning that it acts as an unbiased sink in terms of defect absorption behavior similar to voids [20].

5.3.2<u>M₂X</u>

In addition to the formation of G phase under irradiation, another irradiation-induced secondary phase was first observed at 250 dpa. Using low angle annular dark field (LAADF), oriented precipitates were observed in low number densities at 250 dpa up to 650 dpa. Figure 5.31 shows both the HAADF and LAADF images of the precipitates formed from 250 up to 650 dpa. M_2X are planar type precipitates. With damage, there was a clear increase in number density and with size up to 450 dpa.

Intragranular precipitation was observed and was consistent with previous observations of M_2X formation from Borodin *et al.*, Wang *et al.* and Maziasz [3,38,53,90]. M_2X -denuded zones were observed near grain boundaries, which is shown in Figure 5.33. Several authors have suggested that M_2X forms on a<100> dislocation loops, which is further supported by evidence that the habit plane is the same [3,38]. M_2X was not observed to precipitate on grain boundaries. In ferritic-martensitic alloys, Cr enriches at the grain boundaries has been observed [54], yet the enrichment does not result in precipitation. This observation is not surprising since in austenitic alloys, Ni and Si have been observed to strongly enrich at grain boundaries, but rarely results in precipitation [54,69,91,92]. In Figure 5.26, most Ni/Si precipitated within the grains as well.

The orientation relationship with respect to the miller indices is shown in a schematic in Figure 5.32. As it was determined that these are oriented on the {001} family of planes along the

<001> direction. The schematic shows the top view that corresponds with Figure 5.31a-e, and also defines the dimensions of M₂X with respect to the miller indices.

Additional characterization of the irradiation-induced M_2X was performed to verify the composition, structure, and coherency. EFTEM imaging (Figure 5.34) was used to verify that they are rich in chromium and carbon, and that the stoichiometric composition was Cr_2C . This was further confirmed with an EDX spectrum taken on M_2X that had been polished to <50 nm in thickness to perform HRTEM, which is shown in Figure 5.35.

Selected area electron diffraction (SAED) was performed at three different tilt angles to deterime the lattice parameter of M2X, shown in Figure 5.36. The diffraction patter was consistent with hexagonal crystal structure (HCP). This was later confirmed with HRTEM in HT9 irradiated to 650 dpa. Figure 5.37a shows the bright field HRTEM image. Figure 5.37b shows the fast Fourier transform (FFT) from the HRTEM images. This pattern was identical with that in Figure 5.36. Lattice parameters for M₂X are a=0.271 nm and c=0.452 nm, consistent with [90].

M₂X was determined to be semi-coherent with the matrix. To prepare specimens for HRTEM imaging of the M₂X phase free from the interference of the matrix, a FIB liftout was flash electropolished yielding specimen thicknesses less than 50 nm (Figure 5.38). The orientation relationship between the precipitate and the matrix is $[100]_{M_2X}//[100]_{\alpha}$ or $[11\overline{2}0]_{M_2X}//[100]_{\alpha}$; $(\overline{1}20)_{M_2X}//(0\overline{1}0)_{\alpha}$ ($\overline{1}\overline{1}20$)_{$M_2X}//(<math>0\overline{1}0$)_{α}, shown in Figure 5.39. The semi-coherency and growth directions of M₂X were consistent with recent results from Wang *et al.* in FM alloy CNS II, a Fe-12Cr analogue to HT9 that was irradiated at 460°C up to 450 dpa with 5 MeV Fe⁺⁺ [93].</sub>

To further explore coherency in the [011] direction, FFTs from the HRTEM image in Figure 5.40a the simulated SAED patterns (Figure 5.40b) were overlaid on the FFT shown in Figure 5.40c. From the simulated SAED pattern, it can be shown that $[0\bar{2}0]$ spot from the Fe matrix had d=0.141 nm and coincident with the $[\bar{1}20]_{M_2X}$ spot from M₂X, which had d=0.136 nm. Furthermore, the d[10 $\bar{1}$] from matrix and d[100] from M₂X precipitate were coincident with d=0.202 nm and d=0.235 nm, respectively, indicating a 16% mismatch, which is consistent with semi-coherency. The orientation relationship between the precipitate and the matrix along the [011] direction is thus $[001]_{M_2X}//[10\bar{1}]_{\alpha}$ or $[0001]_{M_2X}//[10\bar{1}]_{\alpha}$; $(100)_{M_2X}//(10\bar{1})_{\alpha}$ or $(11\bar{2}0)//(10\bar{1})_{\alpha}$. The orientation relationship is also consistent with results from [94,95].

There are differences in both the *a* lattice parameter (*a*=0.28 nm for matrix, *a*=0.271 nm for M₂X) and the *c* lattice parameter, which is 0.452 nm in M₂X. Since, by definition, if any direction is semi-coherent the precipitate must be classified as semi-coherent, therefore M₂X is semi-coherent. Furthermore, semi-coherency is much more plausible than coherency because of the differing crystal structure (hcp versus bcc) and the much larger *c* lattice parameter of M₂X. Furthermore, the growth directions of [010] and [101] determines in Figure 5.39 and Figure 5.40 explains the platelike shape on the {100} family of planes as M₂X forms from growth inside the matrix along the [010] and [101].

To further quantify the precipitate response to increasing damage, Figure 5.41 and Table 5.4 present the length, width, thickness, number density and volume fraction as a function of dpa. Similar to what was observed by visual inspection in Figure 5.31, the length, width and thickness saturated with damage by ~450 dpa. The number density peaked at 450 dpa, then decreased leading to a corresponding decrease in the volume fraction.

5.4 Dislocation Microstructure

A systematic characterization of the dislocation network and loop microstructure is essential since swelling and dislocation microstructure are linked through the interstitial bias of the dislocations, which provides vacancy supersaturation and drives defect partitioning. The following is a discussion of the dislocation lines and loops as a function of damage level.

5.4.1 Dislocation Network

Dislocation lines were characterized at each damage level in the manner described in Chapter 4 using representative bright field STEM images shown in Figure 5.42 and tabulated in Table 5.5. A representative area was chosen for each damage level. Several higher magnification images are also presented in Figure 5.43 so that the network is more clearly visible. The Burgers vector was $\mathbf{a}/2 < 111$ > type network. Very little evolution of the line network was observed, evidenced by Figure 5.44. The initial network density was 2×10^{14} m⁻². By 130 dpa, the network line length was $\sim 3 \times 10^{14}$ m⁻², which was consistent (same order of magnitude) with results from Gelles [7,11] and Kai [19], but was an order of magnitude lower than that of Sencer observed in the same heat of HT9 [9]. Variations in results may be due to different imaging conditions and counting methods.

5.4.2 Dislocation Loops

Dislocation loops were characterized in the weak 2 beam condition described in Chapter 4 using BF conventional TEM or STEM imaging. An effort was made to examine loops only in the approximate depth range of 500 to 700 nanometers, reflecting the nominal damage. No loops were observed in the unirradiated condition, which was expected [20]. A summary table is available in Table 5.5 and micrographs are presented in Figure 5.45.

Loops were first characterized at 130 dpa. Loops formed primarily were of \mathbf{a} <100> character with very few observed \mathbf{a} /2<111>, which was consistent with literature [3,10]. Since so few \mathbf{a} /2<111> loops were observed, all results reported are from \mathbf{a} <100> loops only. A high density of relatively small loops formed at the lowest damage imaged. Loops had an average diameter of ~22 nm. With damage, the loop diameter increased up to 30 nm and remained relatively constant up to 375 dpa varying between 23-32 nm, which is shown in Figure 5.46. Between 375 to 450 dpa, there was a sudden increase in dislocation loop diameter growth rate resulting in loops of the unusual size of 78 nm at 450 dpa up to a final loop diameter of 92 nm at 650 dpa.

Figure 5.47 presents the loop number density from 130 to 650 dpa. At the lowest damage, the highest number density of loops $(9.7 \times 10^{20} \text{m}^{-3})$ was observed. As damage increased, the number density dropped off precipitously from 130 to 188 dpa and more slowly to 450 dpa. Given the typical uncertainty inherent in loop number density due to the difficulty in imaging loops in ferritic-martensitic alloys, it was appropriate to conclude that the loop number density remains approximately constant from 450 to 650 dpa.

The combined effect of the increasing diameter and decreasing number density, in general, resulted in a dynamic evolution of the loop line length. Figure 5.48 presents the loop line length as a function of damage. Due to the high density of loops, the loop line length, analogous to sink strength, was the highest at 130 dpa. With the drop off in number density, line length decreased before it recovered to the previously maximum value via increased diameter growth. The loop line length at 250 dpa did not quite follow this trend due to its higher observed number density, but in general the trend was still consistent. Another key observation was that even though the loop line

length did not vary significantly with damage, the character of the loops (i.e. diameter and number density) evolved consistently up to high damage.

Calculation of the loop line length can be directly compared with the network line length shown in Figure 5.49. The striking result of this comparison was that the dislocation behavior was dominated by the network rather than the loops by approximately an order of magnitude. Regardless of the dynamic nature of loop evolution, defect accumulation was likely dominated by network behavior, rather than the loops.

The increase in network line length from 450 to 550 dpa could be explained by the observed decrease in loop number density in which the large loops join the network. Since no loops were observed experimentally above 100 nm, it is a good assumption that loops are joining the network at approximately 100 nm. A measurable decrease $(2 \times 10^{20} \text{ m}^{-3})$ in loop number density from approximately 4 to $2 \times 10^{20} \text{ m}^{-3}$ (reflecting the decrease in number density from approximately 250 to 550 dpa) was observed. Assuming 100 nm loops have left the network at $2 \times 10^{20} \text{ m}^{-3}$, this corresponds to an increase in sink strength of $7 \times 10^{13} \text{ m}^{-2}$. The measured sink strength at 550 dpa was $1 \times 10^{14} \text{ m}^{-2}$ higher than at 450 dpa. Given the large error inherent in measuring loop number density and network line length, this difference is well within error.

Recall that loops observed are $\mathbf{a} < 100$ > whereas the network is $\mathbf{a}/2 < 111$ >. Some authors have theorized that a secondary population of $\mathbf{a}/2 < 111$ > loops may form and rapidly climb to grow the network [94], which could account for the increase in the dislocation network from the asreceived case (2×10¹⁴ m⁻²) to 130 dpa (3×10¹⁴ m⁻²), but likely would not account for the increase from 450 to 550 dpa from 3 to 4×10¹⁴ m⁻².

Interactions between $\mathbf{a} < 100 > 100$ and the $\mathbf{a}/2 < 111 > 10$ network have been proposed in the literature. Eyre and Bullough proposed a mechanism where dislocation loops of both $\mathbf{a} < 100 > 100$ and $\mathbf{a}/2 < 111 > 100$ type could form from an aggregate of self-interstitials through shear reactions, resulting in the formation of a network [95]. More recently, possible interaction mechanisms between $\mathbf{a} < 100 > 100$ type loops and $\mathbf{a}/2 < 111 > 100$ network were proposed by Terentyev *et al.* on the basis of MD simulations and offer an explanation of how the loops observed may grow the network from 450 to 550 dpa by absorption of $\mathbf{a} < 100 > 100$ loops into the $\mathbf{a}/2 < 111 > 100$ network. Interaction of any type of $\mathbf{a} < 100 > 100$ with $\mathbf{a}/2 < 111 > 100$ resulted with absorption into the network by the formation of "superjogs" or segments that are pinned then absorbed in the network with a resulting change in burgers vector. Thus, it is reasonable to assume that the loops are growing the network despite the difference in loop character.

One of the most significant results from this study was the continuing evolution and growth of loops at damage levels beyond 200 dpa. The most comparable study of dislocation evolution with damage for comparison was performed on binary Fe-9Cr and Fe-12Cr alloys irradiated in FFTF by Gelles from 15 to 200 dpa [33]. Gelles observed that total dislocation density increased from 2 to 10.8×10^{14} m⁻² in Fe-9Cr and from 4.7 to 4.9×10^{14} m⁻² in Fe-12Cr. The relatively stable network in Fe-12Cr was consistent with these results, as total dislocation density increased from 3.6×10^{14} m⁻² at 130 dpa up to 4.5×10^{14} m⁻² at 650 dpa.

A second finding was that the dislocation line length of the loops was an order of magnitude lower than that in the network $(0.4 \times 10^{14} \text{ m}^{-2} \text{ versus } 3 \times 10^{14} \text{ m}^{-2}, \text{ respectively at } 250 \text{ dpa})$. In Fe-Cr alloys irradiated in FFTF at 420°C to 130 dpa, Katoh [96] observed dislocation line length of loops and networks to be of similar value in Fe-12Cr (~1×10¹⁴ m⁻² and 0.8×10¹⁴ m⁻² for loops and lines,

respectively), but a much smaller loop contribution to overall dislocation density in Fe-9Cr binary alloys ($\sim 0.2 \times 10^{14} \text{m}^{-2}$ and $0.8 \times 10^{14} \text{m}^{-2}$ for loops and lines, respectively).

Figure 5.50 presents a summary of the co-evolution of the microstructure at 460°C. As damage increased beyond 188 dpa, which is referred to as the nucleation regime, both void swelling and G phase volume fraction increased linearly up to 650 dpa. M_2X formed at 250 dpa and increased up to 450 dpa then decreased in terms of volume fraction. Dislocation microstructure evolution was dominated by the network, while loops continued to grow up to 650 dpa. This complete data set thus provides a database for modeling of this microstructure evolution, which will be discussed in Chapter 6. The results also provide insights into the interaction mechanisms between the voids, dislocations and precipitates, which will be further explained using the RIME model and discussed in Chapter 7.

Alloy	HT9 (84425)
Damage (dpa)	0
Sample Preparation Method	FIB liftout
Lath Length (nm)	880
Lath Width (nm)	317
Lath size, d (nm)	528
Sink Strength of Grain Boundaries (m ⁻²)	8.6×10 ¹³
M ₂₃ C ₆ Diameter (nm)	47.7
$M_{23}C_6$ Density (m ⁻³)	1.7×10^{19}
$M_{23}C_6$ Sink Strength (m ⁻²)	5.0×10^{12}
Dislocation Network Line Density (m ⁻²)	2.0×10^{14}
Dislocation Network Sink Strength (m ⁻²)	2.0×10^{14}
Total Sink Strength (m ⁻²)	2.5×10^{14}

Table 5.1: As-received microstructure characterization of HT9 (84425).

Temperature (°C)	Damage (dpa)	He (appm)	Number of TEM Samples Analyzed Per Condition	Number of Voids	Area Examined (µm)	Void Diameter (nm)	Void Density (10 ²⁰ m ⁻³)	Swelling (%)
440	25	10	2	0	2.0	0	0	0
440	50	10	2	0	2.0	0	0	0
440	140	10	2	11	3.8	12.9±1.0	0.214±0.021	0.0029 ± 0.0005
440	188	10	2	179	1.4	17.7±1.0	5.60±0.56	0.22±0.04
480	188	10	2	17	3.4	21.3±1.0	0.393±0.039	0.033±0.005
460	188	10	2	343	2.1	29.8±1.0	12.00±1.2	2.9±0.4

Table 5.2: Void results from damage dependence study at 440°C and temperature dependence study at 188 dpa.

Temperature (°C)	Damage (dpa)	He (appm)	Number of TEM Samples Analyzed Per Condition	Number of Voids	Area Examined (µm ²)	Void Diameter (nm)	Void Density (10 ²⁰ m ⁻³)	Swelling (%)
460	75	10	2	0	2.3	N.O. ⁵	N.O.	N.O.
	130	10	2	829	3.6	15.0±1.0	13.7±1.4	0.38±0.05
	188	10	2	343	2.1	29.8±1.0	12.0±1.2	2.90±0.5
	250	10	3	733	5.3	33.0±1.0	11.8±1.2	3.35±0.4
	350	10	2	437	3.9	40.8±1.0	10.4±1.0	6.00±0.7
	375	10	2	549	2.8	39.9±1.0	14.1±1.4	8.36±1.0
	450	10	3	742	5.5	45.1±1.0	11.9±1.2	8.81±1.1
	550	10	3	396	4.1	55.2±1.0	8.4±0.8	13.3±1.6
	650	10	3	502	5.3	59.8±1.0	7.1±0.7	16.0±2.0

Table 5.3: Summary of void data from damage dependence experiment performed at 460°C.

⁵ N.O.: Not observed

Experimental Conditions		G Phase			M_2X					
Temperature (°C)	Damage (dpa)	Diameter (nm)	Number Density (10 ²⁰ m ⁻³)	Volume Fraction (%)	# of ppts	Length (nm)	Width (nm)	Thickness (nm)	Number Density (10 ²⁰ m ⁻³)	Volume Fraction (%)
460	75	7.9±0.8	2.4±0.2	0.060 ± 0.01	N.O.	N.O.	N.O.	N.O.	N.O.	N.O.
	130	7.2±0.7	2.5±0.3	0.05 ± 0.008	N.O.	N.O.	N.O.	N.O.	N.O.	N.O.
	188	11.0±1.1	7.9±0.8	0.052 ± 0.01	N.O.	N.O.	N.O.	N.O.	N.O.	N.O.
	250	13.2±1.3	10.5±1.0	0.132±0.02	26	50.3±5.0	12.2±1.2	10.0±1.0	8.0±0.8	0.5 ± 0.07
	350	12.3±1.2	7.4±0.7	0.072 ± 0.02	47	65.2±6.5	19.6±2.0	10.1±1.0	11.9±1.2	1.6±0.3
	375	12.0±1.2	9.4±0.9	0.077 ± 0.02	0. ⁶	О.	Ο	О.	О.	0
	450	12.0±.12	8.2±0.8	0.19±0.03	65	93.6±9.4	20.5±2.1	15.0±1.5	15.9±1.6	4.8±0.7
	550	15.3±1.5	9.9±1.0	0.23±0.03	51	89.1±8.9	21.0±2.1	17.3±1.7	8.7±0.87	2.8±0.4
	650	19.4±2.0	6.6±0.7	0.29±0.04	46	99.4±10.0	22.4±2.2	19.1±1.9	7.5±0.75	3.2±0.5

Table 5.4: Summary of G phase and M₂X behavior from damage dependence experiment performed at 460°C.

⁶ O. Observed-not quantified

Temperature (°C)	Damage (dpa)	Number of Loops Counted	Loop Diameter (nm)	Dislocation Loop Density (10 ²⁰ m ⁻³)	Dislocation Loop Line Length (10 ¹³ m ⁻²)	Dislocation Network Line Length (10 ¹⁴ m ⁻²)	Total Dislocation Line Length $(10^{14}m^{-2})$
460	130	76	22±2	9.7±2.0	6.7±1.4	3.0±0.8	3.7±0.9
	188	39	30±3	1.7±0.3	1.6±0.3	3.0±0.8	3.2±0.9
	250	51	32±3	4.9±1.0	5.0±1.0	3.0±0.8	3.5±0.9
	350	19	29±3	1.8±0.4	1.7±0.3	3.0±0.8	3.2±0.9
	375	42	23±2	3.8±0.8	2.8±0.4	3.0±0.8	3.3±0.9
	450	22	78±8	2.1±0.4	5.2±1.1	3.0±0.8	3.5±0.9
	550	26	78±8	2.4±0.5	5.8±1.2	4.0±0.8	4.6±1.0
	650	19	92±9	1.8±0.4	5.3±1.1	4.0±0.9	4.5±1.0

Table 5.5: Summary of dislocation microstructure data from damage dependence study performed at 460°C.



Figure 5.1: As-received HT9 sample prepared via FIB liftout method showing representative microstructure.



Figure 5.2: Optical micrograph of as-received HT9 after etching. The etchant used was Vilellas's reagent which includes 1 g picric acid with 5 mL of hydrochloric acid in a solution of 100 mL [63].



Figure 5.3: Indexed diffraction of bcc matrix of HT9.







Figure 5.4: Void formation in the a) irradiated area and b) near surface in HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ to 188 dpa at 440° C.


Figure 5.5: Void a) diameter b) number density c) and swelling profiles with depth in HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ to 188 dpa at 460°C.



Figure 5.6: Determination of location of onset of swelling increase after swelling peak near the surface (from [12]).



Figure 5.7: Determination of location of onset of in swelling decrease at depths of 700 nm or greater (from [12]).



Figure 5.8: HAADF images of HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ at 440°C to a) 25 dpa b) 50 dpa c) 140 dpa and d) 188 dpa.



Figure 5.9: a) Diameter and b) number density of voids in HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ at 440°C up to 188 dpa.



Figure 5.10: Void swelling in HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ at 440°C up to 188 dpa. Swelling values are indicated above the data points.



Figure 5.11: HAADF images of HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ at a) 440 °C b) 460 °C and c) 480°C to 188 dpa.



Figure 5.12: Void a) diameter and b) number density (red) in HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ to 188 dpa between 440 to 480°C.



Figure 5.13: Swelling in HT9 preimplanted with 10 appm He then irradiated with 5 MeV Fe⁺⁺ to 188 dpa between 440 and 480°C. Micrographs of typical voids are included for each temperature.



Figure 5.14: a) Diameter and b) number density as a function of damage for 440°C (red), 460°C (blue) and 480°C (green). Dashed lines extrapolated expected damage evolution at 440°C and 480°C resolving peak diameter and number density observed at 460°C, 188 dpa. At 300 dpa, it is expected that diameter will increase with temperature and number density will decrease as is predicted by theory since all three will be in void growth-dominated regime.



Figure 5.15: Void evolution as a function of damage in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C after preimplantation with 10 appm He. Voids are the dark circles and marked with red arrows. Orange rectangles denote the 500 to 700 nm region.



Figure 5.16: Void diameter as a function of damage in HT9 irradiated with Fe^{++} at $460^{\circ}C$ with 10 appm He preimplanted.



Figure 5.17: Void number density as a function of damage in HT9 irradiated with Fe^{++} at 460°C with 10 appm He preimplanted.



Figure 5.18: Void swelling as a function of damage in HT9 irradiated with Fe^{++} at 460°C with 10 appm He preimplanted.



Figure 5.19: Comparison of linear or parabolic regression analysis applied to void swelling resulting from HT9 irradiated with Fe⁺⁺ at 460°C with 10 appm He preimplanted.



Figure 5.20: Representative images of δ -ferrite (a, c) and martensite (b, d) at 130 and 450 dpa.



Figure 5.21: Comparison of diameter, number density and swelling in ferrite and martensite grains compared at a) 130 dpa and b) 450 dpa.



Figure 5.22: Damage rate (dpa/s) curve as a function of increasing damage due to void swelling. Beam current is assumed to be constant for all irradiations so damage rate can be directly compared.



Figure 5.23: a) Effective damage rate calculated from SRIM. b) Swelling vs. damage with fixed depth correction.



460°C-550dpa-10.10He-030515

Figure 5.24: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 550 dpa with 10 appm He.



Figure 5.25: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 650 dpa with 10 appm He.



Figure 5.26: G phase evolution with increasing damage irradiated at 460°C with 5 MeV Fe⁺⁺ with 10 appm He preimplanted. Some G phase precipitates are marked by red arrows.



Figure 5.27: APT analysis of two G phase precipitates observed at HT9 irradiated with 5 MeV Fe⁺⁺ at 440°C to 140 dpa with 10 appm preimplanted. APT confirms composition of $Mn_6Ni_{16}Si_7$ by observation of expected concentrations in at% (55%Ni-24%Si-21%Mn) in Precipitates b) 1 and c) 2.



Figure 5.28: STEM BF image of G phase with corresponding XEDS map. Ni is in red and Si in blue.



Figure 5.29: HRTEM BF image of G phase in the matrix. The much larger lattice parameter of G phase (a=1.148 nm) relative the matrix a=0.286 nm. The incoherent interface is clearly visible. The FFT pattern of the outlined region in the image (red frame) is inset in the top left corner and demonstrates fcc crystallographic structure.



Figure 5.30: Evolution of G phase precipitates in terms of diameter (blue), number density (red) and volume fraction (green) at 460°C in HT9 irradiated with 5 MeV Fe⁺⁺ after preimplantation with 10 appm He.



Figure 5.31: Formation of M₂X precipitates in irradiated HT9 irradiated with 5 MeV Fe⁺⁺. (a)-(e) are the low angle annular dark field images of M₂X, shown as light grey rods. (f)-(j) present the corresponding high angle annular dark field images with voids as dark circles and M₂X can faintly be observed as light grey plates.



Figure 5.32: Orientation of M_2X within the matrix. The top view corresponds to what is imaged in Figure 5.31.



Figure 5.33: LAADF image of formation of M_2X precipitates in irradiated HT9 irradiated with 5 MeV Fe⁺⁺. Note precipitates form intragranularly.



Figure 5.34: Bright field image (a) and corresponding jump ratios for Cr (b), C (c) and N (d) in HT9 irradiated at 460°C to 550 dpa with 10 appm He preimplanted.



Figure 5.35: EDX spectrum of M₂X confirming Cr₂C in HT9 irradiated at 460°C to 550 dpa with 10 appm He preimplanted.



Figure 5.36: SAED patterns of M_2X in HT9 irradiated at 460°C to 450 dpa with 10 appm He preimplanted with axis tilted to a) 0° b) 27° and c) 43°.



Figure 5.37: a) HRTEM of M_2X b) FFT of precipitate from red box in (a), c) nanodiffraction revealing M_2X (red) and Fe (green) matrix in HT9 irradiated at 460°C to 650 dpa with 10 appm He preimplanted.



Figure 5.38: a) BF b) HR BF and c) HR HAADF images of M_2X irradiated to 650 dpa at 460°C. Moiré fringes clearly visible and indicated misfit strain due to slight lattice mismatch, consistent with coherency.



Figure 5.39: HR HAADF image of M₂X (yellow) and matrix (red). FFT show same growth relationship $< 12\overline{2}0 >_{M_2X} // < 100 >_{\alpha}$, demonstrated by parallel lines.



Figure 5.40: a) HR-HAADF image of HT9 irradiated at 460°C to 650 dpa. b) FFT with simulated SAED pattern overlaid indicating consistency of observed pattern with simulation along [011] direction of matrix, c) FFT with no simulated diffraction pattern overlaid.


Figure 5.41: Evolution of M_2X precipitates in terms of length (blue), width (red), thickness (green), number density (yellow) and volume fraction (grey) in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C after preimplantation of 10 appm He.



Figure 5.42: Images of representative dislocation network used for characterization of line density in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C with 10 appm He preimplanted. Some dislocations pointed out with red arrows.



Figure 5.43: High magnification images of dislocation lines/network in HT9 irradiated with 5 MeV Fe⁺⁺ at 440°C with 10 appm He preimplanted to a) 140 and b) 188 dpa.



Figure 5.44: Dislocation network evolution under 5 MeV Fe⁺⁺ irradiation at 460°C in HT9.



Figure 5.45: Dislocation loop evolution with increasing damage irradiated at 460°C with 5 MeV Fe⁺⁺. Some loops are marked by white circles.



Figure 5.46: Quantification of dislocation loop diameter from 130 to 650 dpa at 460° C irradiated with 5 MeV Fe⁺⁺.



Figure 5.47: Quantification of dislocation loop number density from 130 to 650 dpa at 460°C irradiated with 5 MeV Fe⁺⁺.



Figure 5.48: Dislocation loop line length in HT9 irradiated with 5 MeV Fe $^{++}$ at $460^{\rm o}C$ from 130 to 650 dpa.



Figure 5.49: Loop (blue), network (red) dislocation line length and total line (green) length in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C up to 650 dpa.



Figure 5.50: Summary of evolving microstructure with damage in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C.

CHAPTER 6

MODELING

The chapter will describe the Radiation Induced Microstructure Evolution (RIME) model. A summary of modifications made to the model and reference case definitions will also be included. The modeling efforts in this Chapter will demonstrate that reference cases capture the majority of microstructure evolution, which will be further discussed in Chapter 7. Thus, the behavior of the microstructure in the RIME model in response to mechanistic changes will be correlated to and used to explain the experimental results.

6.1 Modeling Methodology

The modeling effort is based upon a mean field approach to a cluster dynamics model. The primary purpose of this section is to describe the modeling approach and perform a sensitivity analysis to verify that the underlying physics is captured as expected. Second, the input parameter selection process will be described including the selection of appropriate values relevant to BCC ferritic-martensitic steels. Third, modifications to the RIME model relevant to discussing significant findings from the experimental results will be described (Section 6.2) and finally, the reference cases for analysis will be presented. (Section 6.3)

6.1.1 Introduction to RIME Model

The RIME model utilizes a mean field approach, where cluster evolution is treated using the master equation (ME) that summarizes a large number of differential equations [97,98]. To achieve realistic treatment of cluster evolution up to high damage and high temperature, the large number of equations makes a purely numerical solution computationally difficult or impossible. As such, a grouping scheme was developed to reduce the number of equations to a solvable level. An early grouping scheme was proposed by Kiritani [99]. This and other schemes were later shown to be inadequate [97] because they created an artificial dependence on the group width, leading to unphysical results. An alternative grouping scheme developed by Golubov *et al.* [97] demonstrated much less sensitivity to the group widths and better agreement with analytical results. This scheme approximated the size distribution within a group using a linear function, rather than a single average value as in most other methods. This linear approximation enables the simultaneous conservation of both the total number of clusters and total number of point defects in clusters. This framework was also extended to permit integration of 2-D MEs, which account for both vacancies and helium gas atoms so that bubbles could be accurately modeled.

For the purpose of this thesis, helium treatment is neglected because helium is pre-injected in the experiment while the regime of modeling interest is at high damage levels (188 dpa and beyond), where there was no simultaneous co-injection of helium, and the major effect of helium was likely on void nucleation [12]. Furthermore, there is no way to experimentally track where He migrates or coalesces in the first 188 dpa.

After adapting the RIME model for bubble kinetics under aging or irradiation in model austenitic alloys [97], the RIME method was further refined by integration of a model for dislocation evolution originally developed by Stoller and Odette [18,100]. A brief overview of the equations follows and a description of key subroutines is at the end of this section.

The generalized model accounts for helium effects and is performed in the (x, m) phase space where x is number of vacancies and m is the number of gas atoms in a cavity, respectively. Since helium is not related in this thesis, equations will only represent calculation/integration in x space, which treats only the vacancies in a given void. For the purpose of this section, the superscript *i* refers to interstitials and the superscript *v* refers to vacancies, not voids. Superscript *V* refers to voids and superscript *L* refers to voids and loops.

6.1.2 Description of Model Physics

The following section will detail the relevant equations used in calculation of swelling and dislocation results. Since He is not included, all cavities are referred to as voids in keeping with the preferred nomenclature.

6.1.2.1 <u>Master Equations</u>

The size distribution of voids, f_x , accounts for reactions of voids with vacancies and interstitials in the following equation.

$$\frac{df_x}{dt} = G_x - P_x^i f_x + P_{x+1}^i f_{x+1} - P_x^v f_x + P_{x-1}^v f_{x-1} - Q_x^v f_x + Q_{x+1}^v f_{x+1}$$
(6.1)

where G_x is the generation rate of *x* clusters in cascades from dpa. Association, *P*, and dissociation, *Q*, for vacancies and interstitials with voids containing *x* vacancies are defined below:

$$P_x^J = w_x D_j C_j \tag{6.2}$$

$$Q_x^v = w_x D_v \exp\left(-\frac{E_x^v}{k_{BT}}\right) \tag{6.3}$$

where

$$w_x = \frac{4\pi r_x}{\Omega} \tag{6.4}$$

where Ω is atomic volume and the void radius r_x is can thus be calculated as:

$$r_x = \sqrt[3]{\frac{3\Omega x}{4\pi}} \tag{6.5}$$

Additionally, D_j and C_j are the diffusion coefficients (m²/s) and concentrations (site fractions) of *j*-type defects, E_x^v is the binding energies of vacancy with a cavity of *x* vacancies, *T* is the absolute temperature, k_B is the Boltzmann constant. Diffusion coefficients are calculated using migration energy E_m^j , and pre-exponential D_{j0} :

.

$$D_j = D_{j0} \exp\left(-\frac{E_m^j}{k_B T}\right) \tag{6.6}$$

A second similar ME is used for calculation of size distribution of interstitial loops. For clarity, the superscript L is used to differentiate this ME from that presented in Equation 6.1.

$$\frac{df_x^{iL}}{dt} = G_x^{iL} - P_x^i f_x^{iL} + P_{x+1}^v f_{x+1}^{iL} - P_x^v f_x^{iL} + P_{x-1}^i f_{x-1}^{iL}$$
(6.7)

where

$$P_x^J = w_x D_j C_j \tag{6.8}$$

 $w_x = \frac{2\pi r}{\Omega}$ is calculated for loops. The loop radius is calculated below in Equation 6.9:

$$r_x = \sqrt{\frac{\Omega x}{\pi b}} \tag{6.9}$$

b is the burgers vector. Vacancy loops are included as an option in the code and have a similar formalism, but not treated in this thesis. The conversion of loops to the network is discussed in Section 6.1.2.4.

Concentrations for each defect species are shown below in Equation 6.10 and Equation 6.11.

$$\frac{dC_i}{dt} = G_i - \mu D_i C_i C_v - (z_i^d \rho_d + z_i^L k_L^2 + z_i^{GB} k_{GB}^2 + k_b^2) D_i C_i - 2w_l D_i C_i^2 + (P^v f_L)_{x=2} + P_{FP}$$
(6.10)

$$\frac{dC_v}{dt} = G_v - \mu D_i C_i C_v - \left(z_i^d \rho_d + z_i^L k_L^2 + z_i^{GB} k_{GB}^2 + k_b^2 \right) D_v (C_v - C_v^e) - 2w_l D_v C_v^2 + (Q^v f)_{x=2}$$
(6.11)

where μ is the recombination constant, ρ_d is the dislocation density, k_L^2 is the sink strength for interstitial loops, k_{Gb}^2 is the sink strength for grain boundaries and k_b^2 is the sink strength for the bubbles. z_j^{GB} are capture efficiencies from grain boundary, z_j^d is the bias for each defect species, G_j are the defect generation rates and C_v^e is the thermal-equilibrium vacancy concentration calculated as

$$C_{\nu}^{e} = C_{\nu 0}^{e} \exp\left(-\frac{E_{f}^{\nu}}{k_{B}T}\right)$$
(6.12)

where C_{v0}^{e} is the pre-exponential.

6.1.2.2 Sink Strength Calculations

The sink strength of voids is calculated as the integral of the overall total number of vacancy clusters in the grouping scheme:

$$k_b^2 = \sum_x \frac{4\pi r_x}{\Omega} f_x(\mathbf{x}) \Delta_x^V \tag{6.13}$$

where Δ_x^V is the width of the groups. For planar loops, sink strength is approximated by

$$k_{iL}^2 = \sum_x \frac{2\pi r_x}{\Omega} f_x^{iL}(x) \,\Delta_x^{iL} \tag{6.14}$$

Again, Δ_x^{iL} is the group width.

6.1.2.3 Defect Production Rates

The point defect production rates are equivalent to those in the NRT standard damage rate [66], with a correction for fractions of defects recombined in cascades ε_r and the fraction of defects clustered in cascades, ε_v and ε_i are shown in Equation 6.15 and Equation 6.16.

$$G_i = G^{NRT} (1 - \varepsilon_r) (1 - \varepsilon_i)$$
(6.15)

$$G_i = G^{NRT} (1 - \varepsilon_r) (1 - \varepsilon_v)$$
(6.16)

The generation rate of vacancy and interstitial clusters is given below in Equation 6.17.

$$G_x^j = A^j x^{-k_j} (6.17)$$

6.1.2.4 <u>Network Dislocation Evolution</u>

Network dislocations were allowed to evolve or remain static based upon user choice. For the dynamic network treatment, the network decreases due to annihilation reactions and increases due to large loops reaching a specified radius and join the network.

$$\frac{d\rho_d}{dt} = G_d - \rho_d (\tau_{irr}^{-1} + \tau_{th}^{-1})$$
(6.18)

 τ_{irr} is the average lifetime of a dislocation for annihilation, from dislocation climb, calculated as

$$\tau_{irr} = \frac{b_d}{\sqrt{\pi\rho_d}} \left[z_i^d D_i C_i - z_v^d D_v (C_v - C_v^e) \right]^{-1}$$
(6.19)

The thermal contribution is described by:

$$\tau_{th} = \left[\frac{A' 2\pi^{\frac{2}{3}}}{\ln\left[\frac{(\pi\rho_d)^{-\frac{1}{2}}}{2b_d}\right]} \frac{\Omega G D_v C_v^e}{k_b T} \rho_D \right]^{-1}$$
(6.20)

where A' is the modified back stress term and the generation term. The generation term has two contributions: first, the Bardeen Herring dislocation source and second, growth of loops into the network with radius greater than r_{max} . The loop generation term is described by Equation 6.21 and r_{max} is a code input calculated from the number of interstitial groups *mil* and the group spacing *dri*.

$$G_d = \left(\frac{2\pi r_{max}}{\Omega}\right)^2 z_i^{iL} D_i C_i \tag{6.21}$$

 z_i^{iL} is the bias of loop for interstitials.

6.1.2.5 <u>Calculation of Radii/Swelling</u>

Size distributions must be converted from x space, where cluster size, x, is defined as the number of vacancies in a given cluster, to R space, where the cluster size is defined as the radius R of the cluster. This is performed using the following relationship:

$$f_x dx = f_R dR \tag{6.22}$$

For voids, this becomes

$$f_R = \frac{4\pi R^2}{\Omega} f_x \tag{6.23}$$

For dislocation loops, this becomes

$$f_R = \frac{2\pi Rb}{\Omega} f_x \tag{6.24}$$

where b is the loop Burgers vector. Swelling (S) is calculated by integrating the size distribution of voids similar to sink strength calculation:

$$S = \sum_{x} x f_x \Delta_x^{\nu} \tag{6.25}$$

6.1.2.6 Grouping Scheme

Previously mentioned, a grouping scheme was developed to conserve number of defects and clusters. Size distributions are represented by a linear function within each group

$$f_x = a + b(x - \langle x \rangle)$$
 (6.26)

where $\langle x \rangle$ is the group mean values and *a* and *b* are constant unique to each group. The coefficient *a* is the mean cluster concentration in each group $\langle f_x \rangle$ while the mean value of vacancy in clusters of the group are calculated from

$$\langle f_x x \rangle = a \langle x \rangle + bD_x \tag{6.27}$$

where

$$D_j = \langle j^2 \rangle - \langle j \rangle^2 \tag{6.28}$$

 D_i are the dispersions for each group, not diffusivity, in this case.

Time integration is performed using the FORTRAN subroutine Livermore Solver for Ordinary Differential Equations (DLSODE) from Hindmarsh [101] and is coded in FORTRAN 90.

6.1.2.7 <u>Consideration of Production Bias Model</u>

The production bias model (PBM) has been used to effectively explain behavior or pure metals with low dislocation densities [98]. The PBM includes the production of point defect clusters as well as one dimensional (1D) diffusion, which has been suggested as a better treatment of in-cascade clustering [98,102–105]. However, this model is not considered here because of several limitations of the model. The PBM predicts swelling saturation at a certain void radius, which is inconsistent with the void results from Figure 5.16 and Figure 5.18, which do not show diameter or swelling saturation. This swelling saturation is due to the change in reaction cross section being proportional to R for 3D diffusion and R² for 1D diffusion, which can cause negative vacancy flux. Furthermore, if the PBM model is applied without 1D diffusion, the system is at risk for the so-called Singh-Foreman catastrophe which is the result of a high density of sessile interstitial clusters completely dominating the microstructure [102]. For these reasons, the PBM is not considered as an appropriate modeling methodology for this application.

6.1.3 Description of Main Sub Routines

The overall structure of the code is quite complex, with 9 categories of 38 sub routines. Categories refer to groups of sub routines, which have the same function. For instance, the s00 category includes all sub routines providing inputs and definitions required at the start of each case run. A full description of all sub routines and adaptations made in this thesis is given in Table 6.1. The main 11 sub routines relative to this work will be described in this section.

s00_rime.main.f: This is the main do loop, which calls functions for each time step. In addition, it calls the solver for each time step and calls intermediate results to both the screen and files.

 $s00_preexistm.f$: This sub routine is a new addition and reads in microstructure data with which to start an irradiation. Meaning, the void and dislocation distribution can be read in at t_0 , to mimic an already irradiated microstructure. For the purposes of this study, this was the microstructure observed at 460°C, 188 dpa. More information on the preexisting microstructure sub routine is in Section 6.2.1.

s02_a_void.f, s02_a_iloop.f: These sub routines define the vacancy and interstitial grid for voids and interstitial type loops, respectively, for cases not including the effect of helium. Reaction rate constants and binding energies are calculated in this section. Generation rates of vacancy and SIA clusters in cascade are also calculated.

s03_sd_void.f, s03_sd_iloop.f: Calculates the size distribution, in terms of number of voids for either voids or interstitial loops.

s04_treatment: This sub routine treats the overall results. It calls upon sub routines to determine size distributions with which to calculate results relevant to experimental data such as radii and number density. It also tallies defect absorption at various sinks.

s04_rt_void.f, s04_trt_iloop.f: This routine takes the cluster distribution calculated from s03 sub routines and translates the outputs into cavity or loop radii, number density and swelling.

s05_read_continue.f: This routine reads in data for continuation of irradiation, which allows parameters to be changed at a user determined damage level.

s06_write_screen.f: This routine prepares intermediate results from each time step to be written to either the screen or files at each examined dpa.

s07_mobile_defects.f: This routine provides derivatives of the concentration of freely migrating defects including SIAs and vacancies to and from solver.

s08_dlsode.f: This is the sub routine containing the ordinary differential equation solver used for this model.

s09_fexjex.f: This routine calculates time derivatives output from the solver; it also calls calculations for size distributions and includes treatment of the precipitates.

A flow chart with the main structure and sub routines is provided in Figure 6.1.

For each case run, desired experimental conditions must be included in an input file. A table summarizing a generic input file is shown in Table 6.2. Parameters that are not used for this thesis are highlighted in red. Parameters that have been modified or added to the code are highlighted in yellow. A parameterization was performed based upon the results from [2,12] to verify that void and loop behavior was behaving in line with experimental results. This determination of key migration and formation energies for BCC FM alloys will be further discussed in Section 6.1.5.

Given the complexity of this code and the varied applications, there are many data outputs that fully describe the microstructure evolution. A full list of outputs is available in Table 6.3 with the main outputs described below. The relevant output files will be described below.

zm_swss.dat: Main output file used in for this analysis. This output file contains a summary of key swelling, loop, network, precipitate results and includes the sink strengths as well.

zm_liz.dat: Summary of void and loop diameter, number density. Swelling, sink strengths for network, loops, void and precipitates.

z_sdw3.dat: This file contains the size distribution of voids as a function of damage level.

z_sdil.dat: This file contains all relevant results regarding interstitial loop evolution.

zm_dens.dat: This file includes number densities for voids and loops as a function of damage level.

zm_radi.dat: This file includes radii for voids and loops as a function of damage level.

zm_conc.dat: This file includes concentrations of mobile defects as a function of damage level.

This section has provided a very brief introduction to the development and utilization of the RIME model. Prior to implementation, a sensitivity analysis was performed 1) to understand the significance of several key experimental parameters and 2) to verify that the model was responding to perturbations of input in a physical way.

6.1.4 Sensitivity Analysis

The RIME model requires input of a large number of parameters, which control defect behavior in the system, in turn controlling the swelling behavior of the system. In this section, a sensitivity analysis was performed to identify input parameters that have the greatest effect on the model output. Output in this case will be measured by swelling/swelling rate. Furthermore, changing various parameters will verify that the essential physics are captured by the RIME model and that no unphysical responses are observed.

Model sensitivity is defined as the derivative of the swelling or swelling rate as a function of a given input parameter. The sensitivity was approximated as the ratio of the change in swelling or swelling rate relative to a change in the input parameter value. This is calculated as below:

$$\frac{\frac{\partial\Delta V}{V}}{\partial P} \approx \frac{\frac{\delta\Delta V}{V}}{\delta P} = \frac{\frac{\Delta V}{V} - \frac{\Delta V}{V}}{P' - P_{reference}}$$
(6.29)

where $\frac{\Delta V}{V}$ refers to the swelling and $\frac{\Delta \dot{V}}{V}$ refers to the swelling rate, both of which will be a calculated as part of this study. $P_{reference}$ is the reference input parameter, P' is the varied parameter and $\frac{\Delta V'}{V}$ is the resulting swelling from P'.

Sensitivity is best expressed as significance, which is the fractional change in swelling/swelling rate relative to the fractional change in input parameter. Significance is calculated as:

$$S_{p}^{\frac{\Delta V}{V}} = \frac{\frac{\Delta V}{V} - \frac{\Delta V}{V}_{reference}}{P' - P_{reference}} * \frac{P_{Reference}}{\frac{\Delta V}{V}_{reference}}$$
(6.30)

The parameters with the highest significance values most strongly impact resulting swelling.

To isolate changes in each of the parameters, a reference case (Ref.2) was run to 20 dpa. (Ref.2 parameters will be further described in Section 6.3.1.) At 20 dpa, the parameter of interest was changed (for instance, bias was perturbed) and the resulting swelling and swelling rate were measured at 21 and 100 dpa, to calculate significance at each bias. The change in parameter was performed at 20 dpa to mitigate instability in dislocation microstructure at the beginning of the irradiation. The main input parameters used in this study are given in Table 6.4 and the irradiated microstructure at 188 dpa was used. This will be further discussed in Section 6.2.1. A sample significance graph for bias is shown in Figure 6.2 and for grain size is shown in Figure 6.3. The significance results for both swelling and swelling rate are shown in Table 6.5 and Figure 6.4.

First, the overall trends matched what was expected. With increasing bias, the swelling rate increased, indicating a higher preference of loops/network for interstitials in turn promoting excess vacancy population. Second, increased grain size also increased swelling due to the lower grain boundary sink strength, which acted as an alternate neutral sink for defects. Third, with increased temperature, the swelling slightly increased. It was not expected to have a large effect, since the pre-voided microstructure was used in this study. Examining the void characteristics revealed an increased void size with decreased number density with temperature, exactly as expected. Finally,

with increasing damage rate the swelling rate decreased slightly. This was expected as lower damage rates are expected to promote void swelling [8].

Figure 6.4 demonstrates the magnitude of each significance. A few key observations were noted. Parameter change affected swelling rate more so than swelling. Clearly, bias was the controlling feature in terms of void swelling. The next most significant value was temperature and grain size followed by damage rate. Bias as the controlling parameter is reasonable as bias directly affects defect flow as opposed to the other parameter changes, with have more indirect effects. Therefore, choosing an appropriate bias was key in modeling this system. A final observation is that there is little change in significance with the addition of unbiased precipitates into the system, indicating that key physics was still captured with precipitation treatment.

A second significance study was performed to address other input parameters including cascade efficiency, recombination coefficient, vacancy migration and formation energies and interstitial migration energy. The methodology was identical to that used for the results presented in Table 6.5. The results are included in Table 6.6 and Figure 6.5. Of these features considered, the next most significant was the cascade efficiency, which has a significance of -2.0. The next more significant was the interstitial migration energy followed by vacancy migration and formation energies and recombination coefficient was the least significant. Bias was also included for comparison and was again shown to be the most significant feature. The low significance of these other input values gives confidence that input chosen from literature, described in the next section, will be appropriate.

6.1.5 Input Parameter Selection

The previous section showed that variation of some parameters such as bias can highly influence void behavior within the RIME model. The major challenge with any rate theory model is determining an appropriate parameter set. Many of these cannot be directly measured and may only be inferred in *post hoc* experimental analyses. In addition, for more complex alloys such as HT9, there are many microchemical or microstructural variations which cannot be accounted for just by varying binding energies and assorted inputs. In this section, the reference input values will be discussed in modeling HT9 as Fe-Cr binary values. Suitable input values were taken from a variety of sources. In Table 6.2, values highlighted in red are those that are not relevant for this study and were thus not utilized. Parameters in yellow are those that were changed as a result of the transition from modeling FCC to BCC, were added as part of the additional capabilities of the RIME model or were used as a flag to include a more complex microstructure treatment (such as the treatment of precipitates). The non-highlighted features are those that were not changed as part of this work. A summary of the main changes is given in Table 6.7 showing the changes from FCC [97] to BCC. The main change was an increase in dislocation density. The unirradiated dislocation density was measured to be 2×10^{14} m⁻² with only a modest increase up to 3×10^{14} m⁻² by 188 dpa. Grain diameter was characterized prior to irradiation with lathes being ~800 to 1000 nm on average and a lath width of ~350 nm. Since lathes are the smallest dimension, and as a consequence the strongest grain sink strength, the lath dimension is used in lieu of the prior austenite grain diameter. For simplicity, a 1 µm lath was assumed. Vacancy and interstitial formation and migration energies are key in capturing appropriate defect kinetics. These formation, migrations and diffusion preexponentials were taken from [106–109]. The chosen cascade efficiency (η), also referred to as point defect survival fraction, was 0.33 based upon molecular dynamics results [110,111]. (In RIME, this input value is reported as ε_{R} which is the fraction of point defects recombined rather

than survived where $\eta = 1 - \varepsilon_R$, which is the more accepted nomenclature in the literature.) In general, for mean theory applications, any value between 0.1 to 0.3 is appropriate, with object kinetic Monte Carlo (OKMC) typically reporting higher efficiencies (0.2) than atomistic kinetic Monte Carlo (AKMC) cascade efficiency (0.1), which was attributed to lack of inclusion of atomistic interactions in OKMC [112,113]. Finally, bias was found to be a key parameter in determining is swelling behavior in Section 6.1.4. As a result, a range of values from 1.01-1.3 was found in the literature for BCC iron/iron alloys [8,41–43,114,115], with a majority varying from 1.01-1.05. As such, bias variations were limited between these values. A more in depth discussion of bias is found in Section 7.2.

The generally accepted range for cascade efficiency (η) for mean field rate theory applications is from 0.1 to 0.33 and the range for dislocation biases for interstitials (z_L^i) is from 1 to 3%. A comparison of the effect of cascade bias and dislocation bias in these ranges is presented in Figure 6.6. Low cascade efficiency combined with low bias decreases swelling while swelling increases in proportion to increased cascade efficiency and dislocation bias, in general. The majority of these values ranges from final swelling values at 650 dpa of 23-33% with the lowest swelling from the ε =0.1, $z_i^{loop} = z_i^{net}$ =1% case and the highest swelling from the ε =0.33, $z_i^{loop} =$ z_i^{net} =3% case, resulting in final swelling of 9% and 80%, respectively. Thus, the chosen reference values of ε =0.33, $z_i^{loop} = z_i^{net}$ =1% (in blue) are reasonable within the range of swelling behavior presented in Figure 6.6.

6.2 Adaptations to RIME Model for Void Growth-Dominated Microstructure

To aid in more complete analysis of the irradiated microstructure, a number of microstructure options were added into the existing RIME model. These are isolated into four categories. First, since the focus of this thesis is on the void growth-dominated microstructure rather than any treatment of nucleation, an option for the existing void and dislocation loop distribution were included. Second, an explicit dislocation loop treatment was developed. Third, a treatment of carbon as a trapping site was included. Finally, treatment for precipitates as unbiased, biased or variable biased sinks or as recombination centers was also included.

6.2.1 Pre-Existing Microstructure

The study of void nucleation is an open question in the study of radiation effects. As such, this thesis is confined to examining the effect of microstructure features on voids in the growthdominated swelling regime. In Chapter 5, the onset of linear swelling was determined to be 188 dpa at 460°C. At this damage level, there is a well characterized void (Figure 6.7a) and loop (Figure 6.7b) distribution in addition to a characterized network dislocation density. Thus, a model option to start irradiations at 188 dpa is needed and a formalism for starting at a "pre-irradiated microstructure" was developed. Prior to development of the sub routine, an approximate distribution was calculated as input for the code. (Figure 6.8) The actual input used was idealized relative to the experimental distribution, to limit statistical variation.

The basic method was as follows: 1) Determine an appropriate grouping vector to reflect the observed void and loop distribution in s02a_void.f. 2) Read in an approximate void and loop dislocation distribution (Figure 6.8) 3) Use this distribution as the arbitrary t_0 . The void distribution was idealized, but based upon the actual experimentally observed distribution.

<u>S02a_void.f</u>

This sub routine determines the vacancy grid. The vacancy grid was determined in terms of x space, meaning each number of vacancies corresponds to a radius of voids for each cluster of size x. For instance, a cluster of size 1 has a radiations of 0.1408 nm. Previously, the grouping size was determined based upon increasing x space, which did not yield a systematic increase in radius. This was adapted such that

dxv

$$= \begin{cases} 1 & x < 30\\ dint(xw(i-1) * 3.0 * drvv) + 1.0 & x < 363, drvv = 0.12\\ \frac{4\pi}{3\Omega * 10^{27}} * (rwh^3 - rwh(i-1)^3) & x > 363, drvv = 1 \end{cases}$$
(6.31)

where dxv is the change in group size, *dint* is a FORTRAN function that converts a double to integer, xw is a vector of the x grid sizes, drvv is the change in radius size and Ω is the atomic volume. Essentially, this converts the vacancy grid from being controlled by x to controlled by r at sizes greater than 1 nm so that the void distribution can be more accurately input. The practical results of this alternate grouping scheme is that the change in each radius group above 1 nm is 1 nm. Dislocation loop grouping scheme is adapted similarly.

SO0_preexistm.f

With the grid properly defined, an additional subroutine was developed to read in an input file (zz_microst.dat) for loop and void distributions. A flag *"iliz"* was added into the input file as

well. When iliz=1, the s00_preexistm.f subroutine was called so that the radius and void distribution fraction (*f*) at a given radius. *f* was calculated from

$$f = b + a(x - \bar{x}) \tag{6.32}$$

where *b* is the group vacancy fraction, *a* is the slope from the group fraction of the previous group to the next and \bar{x} is the average number of vacancies. For the purpose of this calculation $a\approx 0$. *b* is calculated as:

$$b = \frac{N\Omega}{x_{max} - x_{min}} \tag{6.33}$$

where N is the number density of voids in each group, taken from the experimental void distribution. This process is repeated similarly for interstitials as part of the interstitial loop treatment.

Finally, if the *iliz* flag is chosen, the void and loop distribution will not only be read in, but then sent to the subroutine *initfors* in s01_exchange.f which determines the initial y(i) that is sent to the DLSODE solver, effectively starting the irradiation at 188 dpa.

6.2.2 Dislocation Treatment

The original RIME model included two dislocation treatments. The first was assuming a constant network density that was set at the beginning of the case run. The user inputs the desired

network sink strength, which can be changed manually at any time during the irradiation by using the continue option in subroutine s05_write_continue.f.

The second dislocation treatment already incorporated into RIME, hereafter referred to as dynamic dislocation (DD) treatment, allows the dislocation loops and network to evolve based upon the initial experimental input. The existing dislocation treatment was previously described in Section 6.1.2 based upon modeling results from [18,100].

To more accurately represent the overall experimental dislocation microstructure evolution, a formalism for explicit treatment of loops was added. Functions defining the dislocation loop radius and number density evolution with damage were determined and are shown in Figure 6.9. These equations were read in from the input file.

After the number density and radius of loops are read in, the sub routine $s09_fexjex.f$ was updated to provide an additional biased sink strength, with the bias defined by the user input z_i^{lp} . In $s09_fexjex.f$, the variables ss_lpi and ss_lpv were added to track the sink strength of interstitials and vacancies, respectively, of the loops. Values for vacancy and interstitial cluster sizes are called from the DLSODE solver. Then, each radius and number density was updated for each time step. That sink strength is then used in $s07_mobile_defects.f$ to calculate the reaction rate coefficients for loops, which were used in determining the number of defects that are absorbed at the loops. This is identical to how the dislocation network was treated, when network density is assumed to remain constant. One limitation is that the sink strength evolution of the loops is prescribed, so the evolution is a function of the input and does not react to the absorbed defects.

6.2.3 Carbon-Vacancy Interactions

Carbon is an undersized interstitial solute in steel. A number of studies have posited that carbon may act as a point defect trap for either interstitials or vacancies [116–122]. Free carbon interstitials can trap either vacancies or interstitials by raising the migration energy leaving them less mobile. This also serves the purpose of having trapping sites that form recombination centers, leave the freely migrating defect population smaller. In this case, carbon is treated as traps for vacancies with a binding energy of ~0.4-0.8 eV [123–125] will be considered. To model this mechanism, an effective vacancy diffusion coefficient due to formation of the C-v complexes is calculated via the following equation:

$$D_{v}^{eff} = \frac{D_{v}}{1 + \alpha C_{s} \exp(\beta E_{vs}^{b})} \approx \frac{D_{v0}}{\alpha C_{s}} \exp[-\beta (E_{v}^{m} + E_{vs}^{b})]$$
(6.34)

where α =coordination number for BCC interstitials, C_s is the concentration of vacancy traps in appm, $\beta = 1/k_bT$. Thus, both an appropriate binding energy and concentration of solute trap sites can be used as an input.

Carbon is considered as the primary solute available to trap dislocations and also to trap vacancies. Theoretically, other solutes could operate in a similar way. A table including all minor alloying elements with concentrations and approximate diffusion coefficients is provided in Table 6.8. Although some data suggests that other small interstitial solutes like N may provide similar trapping, the concentration is too low for consideration. Larger solutes such as Cr, Ni, Mn, Si, P and S have limited diffusivity in iron. Therefore, due to its small size, relatively large concentration and demonstrated precipitation out of solution C is likely as the major solute effect in the model.

6.2.4 Precipitation

The original RIME model did not include precipitate behavior. A full model of precipitation behavior would include microchemical effects and is outside the scope of this thesis. However, an explicit treatment of precipitation behavior can be used to determine how the introduction of precipitates as sinks may affect void or dislocation behavior as defect partitioning is altered. Further, the precipitate dataset presented in Chapter 5 was systematic enough that equations describing the behavior of both G phase and M₂X could be determined and input into the RIME model.

First, G phase is considered. G phase was determined to be an incoherent, unbiased sink in Section 5.3.1. The evolution as a function of dpa was determined for the radius and number density in Figure 6.10. The radius increases linearly at a slope of 0.008 nm/dpa (Figure 6.10a). The number density remains roughly constant throughout this dpa range and so was assumed to be constant at 8.5×10^{20} m⁻³. (Figure 6.10b)

Second, M_2X is considered. M_2X was determined to be coherent in Section 5.3.2, and likely acts as a coherent sink in terms of defect absorption. Regardless of its sink characteristic, the effective radius and number density need to be determined as a function of dpa. Since M_2X is a rectangular plate, the effective radius needs to be calculated according to the equations developed by Brailsford and Mansur [126].

$$r_P = (LMN)^{\frac{1}{3}} \tag{6.35}$$

where r_p is the effective radius and L, M, N refer to the length, width and thickness respectively. The results of this calculation are shown in Figure 6.11. These equations can then be used to calculate the sink strength as a function of dpa in the code.

The radii and number densities for each precipitate type are updated according to the predetermined equations (Figure 6.10 and Figure 6.11) in the *fex* sub routine similar to the experimentally input dislocation loop treatment. Values for vacancy and interstitial cluster sizes are called from the DLSODE solver. Then, each radius and number density was updated as a function of dpa. From here, the sink strengths are also calculated according to sink type and the total vacancy and interstitial populations absorbed at the precipitates are calculated. Defects absorbed are calculated via the following equation:

$$i_U = D_i C_i * SS_U * dt \tag{6.36}$$

where i_U refers to the interstitials (or vacancies) captured by unbiased precipitates, D_i is interstitial diffusion constant and C_i is interstitial concentration, SS_U is the unbiased sink strength and dt is the time step. For biased precipitates, a factor is included in calculation of sink strength but otherwise remains the same.

The RIME model was updated to treat M_2X precipitates as either unbiased, biased, variable biased or as recombination centers. These different treatments will be compared in Chapter 7, but are described here. A variable in the input file (*zipptB*) is read in and used as a flag to determine whether the precipitates are treated as unbiased (*zipptB*=1), biased (*zipptB*=1.005, for instance) or variable biased (*zipptB*=10). Note that for coherent precipitates, the bias is not 10, but this is used
as a convenient flag to start the variable biased treatment described below. An alternate flag *itrap* can flag use of the recombination treatment.

For unbiased sinks, there is no preference for vacancies or interstitials and the sink strength remains as calculated in $s09_fexjex.f$. In the biased treatment, sink strength is multiplied by the bias for interstitials (*zipptB*). Finally, variable biased sinks are treated according to the Brailsford and Bullough formalism [127] shown below. The sink strength for interstitials *i* and vacancies *v* for a coherent precipitate is calculated below using Equation 6.37 and Equation 6.38, respectively.

$$k_{\nu CP}^2 = 4\pi R_{CP} \rho_{CP} Y_{\nu} \tag{6.37}$$

$$k_{iCP}^2 = 4\pi R_{CP} \rho_{CP} Y_i \tag{6.38}$$

 Y_i is a factor which measures the bias for interstitials and vacancies respectively, that changes as a function of dpa. Y_i is calculated below:

$$Y_i = \frac{D_v C_v}{D_i C_i} Y_V \tag{6.39}$$

and Y_v is calculated as:

$$Y_v = 1 + (z - 1)f_0 + (z - 2)\delta f$$
(6.40)

where z is the coordination number and

$$\delta f = \frac{1}{z+1} \left[1 - \frac{k_v^2}{k_i^2} \right]$$
(6.41)

which represents the change in capacity for either vacancies or interstitials based upon the sink strength and

$$f_{\nu} = \left(\frac{\overline{K}_{\nu}c_{\nu}}{\alpha_{s}}\right)^{\frac{1}{2}}$$
(6.42)

 f_v is a recombination term at the coherent precipitates, \overline{K}_v is the reaction rate constant, c_v is the vacancy concentration, α_s is the bulk recombination coefficient.

The final possible treatment for coherent precipitates is as recombination centers. M_2X is in a state of compressive stress relative to the matrix, making it preferential to trapping vacancies, due to its slightly smaller lattice parameter. Once vacancies are trapped at the precipitate-matrix interface, they are "held" until an anti-defect (i.e. an interstitial) diffuses to the trap site. When the flag itrap is used (*itrap*=1), a recombination term for interstitials at the trapped vacancies (*recomt*) is calculated from the sink strength, analogous to surface area, and a trap efficiency (*rotrp*), set by the user. (Previous literature suggests that coherent precipitates may not act as 100% efficient sinks, so this was included as an option [128].)

$$recomt = 4.0 * \pi * R_{ppt} * \rho_{ppt} * D_i C_i * rotrp$$
(6.43)

where R_{ppt} and ρ_{ppt} are the radius and number density, respectively.

Trapping and de-trapping reaction rate coefficients are calculated using Equation 6.44 and Equation 6.45 below. These reaction rates are then used to update dcv (the overall derivative of vacancy concentration, which is sent to the solver. *Recomt* also updates the derivative of interstitials in a similar way.

$$rtrap = 4.0 * \pi * R_{ppt} * \rho_{ppt} * D_v C_v * rotrp$$
(6.44)

$$rdtrap = 4.0 * \pi * R_{ppt} * \rho_{ppt} * \exp\left(-\frac{E_b^{trap,v}}{kT}\right) * D_v C_{vt} * rotrp$$
(6.45)

where $E_b^{trap,v}$ is the binding energy at the precipitate interface.

6.3 Development of Reference Cases

Having updated the RIME model with the required formalisms to treat the experimental results from this thesis, reference cases were developed to track the effects of introducing experimental values of precipitates, carbon traps and preexisting microstructure into the model. Since there are a number of perturbations that must be analyzed, three reference cases are presented. Since the preexisting microstructure treatment is used, the damage reported in RIME (Φ_{RIME}) starts at "0 dpa" even though the input microstructure is irradiated, but is related to the total, or true, damage (Φ_{T}).

$$\Phi_{RIME} = \Phi_T - 188 \, dpa \tag{6.46}$$

For clarity and ease of interpretation, all graphs will be plotted as a function of true dpa so that the RIME results and experimental results reflect the same damage level. For the purposes of benchmarking, only void and dislocation behavior is considered, as it represents the most fundamental interaction relevant to the study of void swelling.

Three reference cases will be compared to experimental data. Ref.0 is the simplest case with constant network density and no loops. Ref.1 includes the experimentally input network and loop evolution. Ref.2 includes the dynamic dislocation (DD) treatment. The input files for each reference case are presented in Table 6.9. Changes in input between reference cases are highlighted in yellow. Unless explicitly mentioned, the loop and network bias for all model cases was 1.01. A parametric analysis revealed that bias was the dominant parameter in determining void swelling behavior. A literature search shows expected bias in a range from 1.01-1.3 for BCC iron/iron alloys [8,41–43,114,115], with a majority varying from 1.01-1.05. As such, bias of 1.01 was deemed to be reasonable.

6.3.1 Comparison of Reference Cases to Experimental Data

Three reference cases will be discussed below and compared to the experimental data below to provide a baseline before incorporation of the more complex microstructure interactions including precipitates and solute effects.

6.3.1.1 <u>Ref.0: Constant Network Density</u>

The most fundamental interaction is simply the interaction between dislocations and voids. The simplest treatment in RIME was to assume a constant dislocation network density. This will be designated as Ref.0 (input in Table 6.9). Ref.0 will be used 1) to verify that the swelling behavior was exhibiting reasonable behavior and 2) to provide a baseline for further comparisons of more complex dislocation and precipitate treatments. Figure 6.12a compares the constant network density with the experimentally observed network density. The assumption of constant network density was quite reasonable, as the only variation between Ref.0 and the experiment was from 550 to 650 dpa, where a small increase to 4×10^{-14} m⁻² was observed.

The results of Ref.0 compared to experimental results are shown in Figure 6.12b. The overall diameter was higher than that observed in the experiment, but was fairly reasonable within 10 nm. (Figure 6.12b) The number density matched quite well for all damage levels. Finally, the swelling was overestimated as a result of the enhanced diameter. The final swelling value at 650 dpa was 21% relative to the experimental value of 16%.

6.3.1.2 <u>Ref.1: Experimentally Input Dislocation Evolution</u>

The second reference case matches the experimentally observed dislocation evolution. The explicit loop treatment, detailed in Section 6.2.2, was used in conjunction with manual adjustment of the network density from 3 to 4×10^{14} m⁻² at 550 dpa, performed using the irradiation continuation option of RIME also described in Section 6.1.2.7. This case will be designated as Ref.1 (input in Table 6.9). Ref.1 will be used to provide an exact comparison to the experimentally observed dislocation evolution. The results of Ref.1 compared to experimental results are shown in Figure 6.13. Figure 6.12a compares the Ref.1 with the experimentally observed network density and loop line length. The explicit treatment is quite accurate in capturing the overall loop and network behavior, as was expected.

The overall void diameter was higher than that observed in the experiment, but was fairly reasonable within 15 nm. (Figure 6.13b) The number density matched quite well for all damage

levels. Finally, the swelling was overestimated as a result of the enhanced diameter. The final swelling value at 650 dpa was 26% relative to the experimental value of 16% and Ref.0 values of 21%.

6.3.1.3 <u>Ref.2: Dynamic Dislocation (DD) Evolution</u>

The final reference case uses the dynamic dislocation treatment, which was based upon the physics from [18,100] and detailed in Section 6.1.2. Ref.2 is also compared to experimental data in Figure 6.14. The network density (Figure 6.14a) was representative of what was observed experimentally, but loop sink strength was higher than expected by an order of magnitude. Figure 6.14b shows the dislocation loop behavior, which explains the higher than expected loop sink strength observed in Figure 6.14a. The number density of loops was an order of magnitude higher and diameter was approximately the average of overall loop diameter from experiment. Loop sink strength was overestimated.

Figure 6.14c shows the resulting void behavior. Again, the number density was accurately captured but the diameter/diameter growth rate was too high. Again, the void swelling was higher than expected, indicating that some other mechanism or microstructure features was not taken into account.

Given the similarity of the DD treatment to the experimentally observed behavior as well as Ref.1, DD is especially appropriate as a reference case. It can then be used for model cases where the dislocations must be allowed to respond to changes in microstructure; for instance, to determine the effect of precipitates on dislocations.

A comparison between all three of these reference case will be detailed in Chapter 7. The reference cases are consistent in that they overpredicted the void swelling relative to that observed

experimentally. As such, Chapter 7 will focus on understanding where this behavior comes from and what mechanism results in the observed microstructure co-evolution.

Category	File	Description	Changes/Notes
s00	s00_rime_main.f90	Main do loop used to call functions for appropriate time steps. Calls solver for each time step. Writes intermediate results for each time step in files and to screen.	Changed output files to reflect new outputs including precipitates and impurity traps.
s00	s00_modes.f90	Initialize variables and prior to reading input data.	Added in additional inputs and variable definitions to reflect explicit dislocation loops, precipitates and impurity traps.
s00	s00_initialize.f90	Defines ODE system for new, continued or expanded problem. Calls preexisting microstructure.	Calls preexisting microstructure
s00	s00_preexistm.f	Reads in input file describing starting microstructure in terms of dislocation loop and void distribution.	Sub routine to call inputs for preexisting microstructure.
s01	s01_constants.f	Calculates constants based upon input data including Berger's vector, diffusion coefficients. Initializes counters for calculation of point defect flows.	
s01	s01_exchange.f	Initializes values for solver. Passes derivative calculations to and from solver.	
s01	s01_tolerance_change.f	Increases vectors/matrices sizes as cluster sizes increases.	
s02	s02_a_bubble.f	Defines vacancy and helium grid for cases including effect of helium. Calculates reaction rate constants. Outputs grid sizes to z_grid-wv.dat.	
s02	s02_a_void.f	Defines vacancy grid for cases not including effect of helium. Calculates reaction rate constants and binding energies.	Updated to pre-determine group sizes variation with increasing void size.
s02	s02_a_iloop.f	Defines interstitial grid for cases including interstitial type loops. Calculates reaction rate constants and binding energies as well as generation rates of sessile SIA clusters in cascades.	Updated to pre-determine group sizes variation with increasing loop size.
s02	s02_v_iloop.f	Defines vacancy grid for cases including interstitial type loops. Calculates reaction rate constants and binding energies as well as generation rates of sessile SIA clusters in cascades.	Not used for this analysis.
s02	s02_compressibility.f	Calculation of compressibility (Z) of a bubble for a given gas/vacancy ratio (x) using modified Carnahan-Starling Correction.	Not used for this analysis.
s03	s03_sd_bubble.f	Calculates size distribution of gas bubbles.	Not used for this analysis.
s03	s03_sd_iloop.f	Calculates size distribution of sessile interstitial loops.	
s03	s03_sd_iloop_ik.f	Interaction of SIA loops/clusters with 3D mobile SIA clusters. Also includes interaction of voids with 3D mobile SIA clusters.	
s03	s03_sd_vloop.f	Calculates size distribution of vacancy loops.	Not used for this analysis.
s03	s03_sd_void.f	Calculates size distribution of voids.	
s04	s04_total_sink_strength	Calculation of sink strength of voids, dislocation loops and lines, grain boundaries.	Not used for this analysis.
s04	s04_treatment.f	Treatment of results. Includes defect tallies for precipitates, gas accumulation at features. Calculation of swelling rate.	Precipitate treatment added in

Table 6.1: Summary of sub routines in RIME model. Updates, changes and notes are included in the last column.

Category	File	Description	Changes/Notes		
s04	s04_trt_bubble.f	Treatment of size distribution of bubbles.	Not used		
s04	s04_trt_iloop.f	Treatment of size distribution of interstitial loops.			
s04	s04_trt_vloop.f	Treatment of size distribution of vacancy loops.			
s04	s04_trt_void.f	Treatment of size distribution of voids. Calculates void concentration and radii.			
s04	s04_vickers.f	Calculation relating MPa to Vickers hardness values.	Not used		
s05	s05_correct_input.f	Correct input values for certain specific experiment types including thermal aging, TEM foils, and thermal neutron irradiation.	Not used		
s05	s05_read_continue.f	Reads data saved for continuation of irradiation or aging.			
s05	s05_read_input.f	Reads in input file.	Explicit loops, precipitate data and impurity traps have been added.		
s06	s06_w_open_files.f	Opens files and formats headers for output data files.	Headers adjusted for new outputs.		
s06	s06_write_continue.f	Saves data for continuation.			
s06	s06_write_generation.f	Writes generation rates of He and dpa with time.			
s06	s06_write_head.f	Writes headers for screen outputs.			
s06	s06_write_screen.f	Writes intermediate results to screen including swelling, sink strength and other key parameters. Also writes intermediate data to output files for each dpa.	Outputs changed to reflect new precipitate data.		
s06	s06_write_sd.f	Writes size distributions in own size distribution files for loops, voids and bubbles as a function of dpa.			
s07	s07_gb_sink_strength.f	Calculates grain boundary sink strengths.			
s07	s07_mobile_defects.f	Derivatives of concentration of freely migrating SIAs, vacancies, crowdions.	Calculates defect annihilation at precipitates.		
s08	s08_dlsode.f	Livermore Solver for Ordinary Differential Equations. DLSODE solves the initial-value problem for stiff or nonstiff systems of first-order ODE's, $dy/dt = f(t,y)$, or, in component form, $dy(i)/dt = f(i) = f(i,t,y(1),y(2),,y(N))$, $i=1,,N$.			
s09	s09_fexjex.f	Calculation of time derivatives. Calculates radius and sink strength of precipitates.	Explicit loops, Precipitate treatment is calculated here.		
s10	s10_euler.f	Euler solution method	Not used		

Table 6.1: Summary of sub routines in RIME model. Updates, changes and notes are included in the last column.

Reference	Variable	Variable		
Value	(RIME)	(symbol) ⁷	Unit	Description
RefO	name			Output Directory Name: 12 char max
0	key			0-Volume 1-Surf 2-Surf no denos
1	keyai			Aging -0: Irradiation -1
0	keye			Calculation: New-0: Cont-1
1	idm			-1 check cell size using criterion:
1 00E 06	ratmay			may ratio hubble/cell size allowed
1.00E-00	keyNucl			-1 no void nucleation: $v \pm v$ and $v \pm Gas$
0	keyNuclI			-1 no v-loop nucleation: v+v and v+Gas
$1.00E \pm 10$	dttt1		-	I SODE INTERNAL may timesten
1.00E+10	dt0		5	Initial timesten out
1.00E-00	time1		5	Time < time1: rio1
5.00E+03	timem		5	Time < timem: riom: if >: constant
1	riol		5	OUT timesten dt-dt0 + t/rio1
10	riom			OUT Timestep dt=dt previous + t/riom
10	nsorn			N stars for writing to screen k files
1	nromm		-	N steps for saving to continue
1	nwrit		-	N steps for writing SDs and 3 d graph
0	mfaular		-	FULER -1 I SODE -0. Only 0 is used
1	nround		-	EULER -1, LSODE -0. Only 0 is used
1	nstons		-	EULER EULER n of steps dt_integ = dt/nsteps
1	listeps		- Flags and Dimensions I	Defining System
0	iHe			Flag for treatment of Helium gas
1	iVac		-	Flag for treatment of vacancies
1	iInt		-	Flag for treatment of interstitials
1	init		-	Flag for treatment of interstitials
0			-	Flag for treatment of crowdions
1	1 V 010		-	Flag for treatment of voids/bubbles
0	1 V 100p		-	Flag for treatment of vacancy loops
0	11100p		-	Flag for treatment of interstitial loops
0	iDisi		-	Flag for treatment of unsocations
120	Пар		-	Initial # of vegeness groups in veide/hubbles
120	IIIVV		-	Initial # of vacancy groups in voids/bubbles
120	mil		-	# of interstitial loop groups
8	myl		-	# of merstillar loop groups
10	ievpnd		-	# of groups added when expanding cell
10	lexplid		_	# of groups added when expanding cen
			Tolerances for in	tegration
10	ntol		-	for all derivatives: atolD=atolV/ntol
1.0d-4	rtol		_	relative tolerance for all values
1.0d ⁻¹ 5	atsia		at ⁻¹	initial abs tolerance for SIAs
1.0d-7	atvac		at ⁻¹	initial abs tolerance for vacancies
1.0d-7	atcro		at ⁻¹	initial abs tolerance for crowdions
1.0d ⁻¹ 7	atgas		at ⁻¹	initial abs tolerance for gas atoms
1.0d ⁻¹ 2	atbub		at-1	initial abs tolerance for bubbles
1.0d ⁻¹ 6	atlns		at ⁻¹	initial abs tolerance for interstitial loops
1.0d ⁻¹ 6	atVL		at ⁻¹	initial abs tolerance for vacancy loops
1.0d+9	atdis		m ⁻²	initial abs tolerance for dislocation
1.0d+9	rspec		m	bubble radius: > not used in fmax
1.0477	Tspee		III	Conditions
				Conditionio

⁷ Symbols included for variables used in the text.

or changed. Variable Reference Variable Unit Description (symbol) Value (RIME) 4.50E+05 time Irradiation/Aging TIME t s 1.00E-03 rknrt φ Mean NRT generation rate dpa/s Defect fraction recombination in cascades 0.67 Epsr ε _ 0 SIA fraction in sessile clusters epsis _ 0 SIA fraction in crowdions _ 0 Vacancy fraction in sessile clusters _ 0.3 Vacancy fraction in micro-voids epsw 460 T °C Temperature, degree Celsius tc 0.00E+00 cg0 Initial gas-atom site fraction m⁻² 3.0d+14 rod0 Initial VOLUME dislocation density ρ_D 1.0d-8 rotrp at-1 Density of vacancy trapping sites m⁻² 1.0d+19 GB dislocation density (if key>0) 5.00d-7 rgr d Grain radius m 5.0d-0 Foil thickness for crowdions Μ -Thermal Neutrons-----0 key: 0- exclude; 1- include key_th 1.132d+9 Irradiation time time_th s 5.38d-8 dpa/s NRT generation rate for fast neutrons rknrt 0.9 Defect fraction recombination in cascades epsr_th -0 epsis_th -SIA fraction in sessile clusters 0 epsig_th -SIA fraction in crowdions 0 epsv_th -Vacancy fraction in sessile clusters 0 epsw-th Vacancy fraction in micro-voids -----He atom production------0.00d-08 s^{-1} He atom generation rate rkhe s-1 0.00d-13 He atom gen' rate from thermal neutrons 0.00d+18 Flux n/m² Thermal neutron flux 0.7 Initial Ni58 fraction (0.68077 of all) CNi 8.254dm⁻² SAlpha 59Ni(n,alpha) cross section 28 2.137d-**S**Gamma m⁻² 58Ni(n,gamma) (1 barn = 10-28 m-2)28 43.20dm⁻² **S**Total 59Ni total absorption cross section 28 -----Material-----

Table 6.2: Parameters used in a complete input file. Highlighted boxes in red are not used for the purpose of this work. Highlighted boxes in yellow have been adapted

2 N at. in unit cell 2-BCC 4-FCC type1 2.86d-10 Μ Lattice parameter: bcc Fe=2.87, fcc=3.61 а а h 1 Nbv _ Dislocation Burgers V: 1-S3/2; 2-0.5; 3-1/S3 Loop Burgers V: 1-S3/2; 2-0.5; 3-1/S3 3 NbvL _ 2.3 gamma0 J/m² Surface energy defined as γ (gama*gamma0-gamtc*tc)/1.6e-19 which is in eV 1 gama 0.0 γ J/m^2 gamtc 1.75e-3 0 J/m² Stacking-fault energy for vacancy loops gammaVI 0.33 Poisson ratio for vacancy loops poisson -1 rvinf nm join radius for Evb for vacancy loops 1.79 E_f^v eV evf Vacancy formation energy 0.63 evm E_m^v eV Vacancy migration energy

0.63evmeff $E_{m,eff}^{i}$ eVEffective vacancy migration energy (same if no trops)0.22eim E_m^{i} eVSIA migration energy0.22sgmeVCrowdon migration energy0.7ehmeVGasatom migration energy1evel $C_{0,r}^{i}$ -2.24-7c0v $C_{0,m}^{i}$ $m^{2/s}$ 9.44-7c0i $m^{2/s}$ Pre-exp for SIA migration9.44-7c0i $m^{2/s}$ Pre-exp for gas atom migration10.14 $m^{2/s}$ $m^{2/s}$ ik c012 Pre-exp mig10.15 $z_{1,m}^{i}$ -Loops capture efficiency for SIAs1.01 zi $z_{1,m}^{i}$ -1.01 zi $z_{2,m}^{i}$ - <tr< th=""><th>Reference Value</th><th>Variable (RIME)</th><th>Variable (symbol)⁷</th><th>Unit</th><th>Description</th></tr<>	Reference Value	Variable (RIME)	Variable (symbol) ⁷	Unit	Description
0.22cim E_m^l eVSIA migration energy0.22cgmeVCrowdion migration energy0.07chm eV Gasatom migration energy1evel $C_{0,m}^{r}$ -8.24.7c0v $C_{0,m}^{r}$ m^2/s 9.44.7c0i $C_{0,m}^{r}$ m^2/s 9.44.7c0i $C_{0,m}^{r}$ m^2/s 9.44.7dig m^2/s Pre-exp for SIA migration9.44.7dig m^2/s Pre-exp for gas atom migration0.04.22Still m^2/s Pre-exp for gas atom migration0.04.122Still m^2/s Pre-exp for gas atom migration1.011 eV ik cin2 SIA 2-4i mig energy1.6.6.4 m^2/s ik c02 Pre-exp for SIAs1.01zicl z_L^i -1.01zicl z_L^i 1.01zicl z_L^i 1.02 z_R^i -1.03zicl z_R^i 1.04zicl z_R^i 1.05congrue efficiency for SIAs1zygzin1.01zizlzin1.02zizl z_R^i 1.03zizlzizl2.04-0.05genute efficiency for gas atoms1zyg-	0.63	evmeff	$E_{m,eff}^{v}$	eV	Effective vacancy migration energy (same if no
0.22cguteVCrowdion migration energy0.07dmieVGas-atom migration energy1evel $C_{b,f}^{n}$ -Pre-exp for vacancy formation8.24.7edv $C_{0,m}^{n}$ m²/sPre-exp for vacancy formation9.44.7edv $C_{0,m}^{n}$ m²/sPre-exp for sIA migration9.44.7edgm²/sPre-exp for sIA migration9.44.7dbgm²/sPre-exp for gas atom migration9.44.7dbgm²/sPre-exp for gas atom migration0.04+22Sdislm²Bardeen-Herring disl' source density0AprimeA'-Modified back stress term, Roger=0.0510.11eVik einz SIA 2-4i mig energy16.54.8m²/sik einz SIA 2-4i mig energy101zix $z_{f_{1}}^{i}$ -101zix $z_{g_{2}}^{i}$ -101zix $z_{g_{2}}^{i}$ -101zix $z_{g_{2}}^{i}$ -102zix $z_{g_{2}}^{i}$ -103zix $z_{g_{2}}^{i}$ -104zix $z_{g_{2}}^{i}$ -105zix $z_{g_{2}}^{i}$ -101zix $z_{g_{2}}^{i}$ -102zix $z_{g_{2}}^{i}$ -103zix $z_{g_{2}}^{i}$ -104zix $z_{g_{2}}^{i}$ -105zix $z_{g_{2}}^{i}$ -103zix $z_{g_{2}}^{i}$ -11zix <td>0.22</td> <td>eim</td> <td>Fi</td> <td>eV</td> <td>SIA migration energy</td>	0.22	eim	Fi	eV	SIA migration energy
0.07 2 chain c_V	0.22	egm	<i>Lm</i>	eV	Crowdion migration energy
0.000.010.010.011cve0 C_{0d}^{0} -Pre-exp for vacancy formation9.44.7c0i C_{0dm}^{0} $m^{7/s}$ Pre-exp for stancy formation9.44.7c0i C_{0m}^{0} $m^{7/s}$ Pre-exp for gas anom migration9.44.7c0g $m^{7/s}$ Pre-exp for gas anom migration0.04-22Stisl m^{3} Bardeen-Herring disf source density0AprimeA'-Modified back stress term, Roger-0.0510.11ieVik einergyik c0i2 Pre-exp mig10.54.8m^{2/s}ik c0i2 Pre-exp mig10.1zi z_{in}^{i} -10.1zi z_{in}^{i} -10.2zi z_{in}^{i} -10.3zi z_{in}^{i} -10.4zig z_{in}^{i} -10.5zig10.6zigzig-10.7zig z_{in}^{i} -10.8zig11zig z_{in}^{i} -21zigzig-22<	0.22	ehm		eV	Gas-atom migration energy
1Cveo $C_{0,m}^{*}$ T^{*}	0.07	ava0	C^{v}	C V	Dro. over for vocency formation
8.20-7 COV $C_{0,m}^{*}$ Pre-exp for SIA migration 9.44-7 coi $C_{0,m}^{*}$ m ^{7/s} Pre-exp for SIA migration 9.44-7 coi $C_{0,m}^{*}$ m ^{7/s} Pre-exp for SIA migration 4.0d-7 db0 m ^{7/s} Pre-exp for gas atom migration 0.0d+22 Sdiat m ³ Bardeen-Herring disl' source density 0 Aprine A' - Modified back stress term, Roger-0.05 10.11 eV ik icm 2SIA 2-4i mig energy ik coi2 Pre-exp mig 10.1 zicl z_L^i - Loops capture efficiency for SIAs 1.01 zicl z_L^i - Dislocation capture efficiency for gas atoms 1.01 zi z_M^i Zi Dislocation capture efficiency for Gas atoms 1.01 zi z_M^i - OB capture efficiency for Gas atoms 1.02 zigl - GB capture efficiency for SIAs - 1 zigl zigl - GB capture efficiency for SIAs - 1 zigl zigl - GB capture efficiency for SIAs -	1	cveo	$C_{0,f}$	- 2/	Pre-exp for vacancy formation
9.44-7 cbit C_{0m}^{*} m*/s Pre-exp for crowdion migration 4.04-7 dbit m²/s Pre-exp for gas atom migration 0.0d+22 Statu m³ Bardeen-Hering disl'source density 0 Aprune A' - Modified back stress term, Roger=0.05 10.11 eV ik cinz SIA Z-4i mig energy 1.6.5d-8 m²/s ik c012 Pre-exp for SIAs 1.01 zicl z_L^i - 1.01 zicl z_L^i Z_i 1.01 zicl z_L^i - 1.01 zicl z_L^i - 1.01 zicl z_L^i - 1.01 zicl z_L^i - 1.02 zgd - Dislocation capture efficiency for SIAs 1 zig z_{an}^i - GB capture efficiency for vacancies 0 zgd - GB capture efficiency for vacancies - 1 zig z_{an}^i - GB capture efficiency for vacancies 0 zgd - GB capture efficiency for vacancie	8.2d-/	cOv	$L_{0,m}^{\circ}$	m²/s	Pre-exp for vacancy migration
9.44.7 cbp m²/s Pre-exp for gas atom migration 0.04+22 Sdisl m² Bardeen-Herring disl' source density 0 Apmine A' - Modified back stress term. Roger=0.05 10.11 eV ik elin2 SIA 2-4i mig energy 1 f.5d-8 m²/s ik elin2 SIA 2-4i mig energy 1.01 zicl z_1^i - Loops capture efficiency for SIAs 1.01 zicl z_N^i z Dislocation capture efficiency for SIAs 1 zi z_N^i - Dislocation capture efficiency for SIAs 0 zgd - GB capture efficiency for SIAs 1 zig z_{ag}^i - GB capture efficiency for SIAs 1 zvg z_{ag}^i - GB capture efficiency for Gas atoms 1.00E+00 rava - Fraction of sites for gas at from dislocation 1.6 dabb eV Emission energy for gas at from dislocation 1.6 dabb eV Emission energy for gas at from dislocation 1.6 dabb eV Emission energy for vacance-trap complex	9.4d-7	c0i	$C_{0,m}^{\iota}$	m²/s	Pre-exp for SIA migration
4.00.7 db0 m²/s Pre-exp or gas atom migration 0.0d+22 Satisi m³ Bardeen-Herring disl'source density 0 Aprime A' - Modified back stress term, Roger=0.05 1 0.11 eV ik cin2 SIA 24 imig energy 1 6.5d-8 m²/s ik c02 Pre-exp mig	9.4d-7	c0g		m²/s	Pre-exp for crowdion migration
0 Aprime A' - Modified back stress term, Roger-0.05 1 0.11 eV ik eim2 SIA 2-4i mig energy 1 6.54.8 m ⁷ /s ik c02 Pre-exp mig	4.0d-7	dh0		m²/s	Pre-exp for gas atom migration
0AprimeA'-Modified back stress term, Roger=0.0510.11eVik eim2 SIA 2-4 mig energy10.11zicl z_h^I -1.01zicl z_h^I -1.01zicl z_h^I -1.01zicl z_h^I -1.01zicl z_h^I -1.01zicl z_h^I -0.02-9rivoidmVoid capture efficiency for Vacancies0.04-9rivoidmVoid capture efficiency for vacancies0.04-9zgd-Dislocation capture efficiency for vacancies1zig Z_{LB}^I -GB capture efficiency for Vacancies1zig Z_{LB}^I -GB capture efficiency for slAs1zyg Z_{LB}^I -GB capture efficiency for slas dislocation1.00E+00raya-Fraction of sites for gas at filocation2.25edgeeVEmission energy for gas at from dislocation1.6elpibbeVEmission energy for gas at from dislocation1.6elpibb-EOS:1-Roger:(2 Carnahan-S:3?Manzke-T) *(1)0.3e2vV-crow: =1-pure 1D; =0-preferential1keybb-EOS:1-Roger:(2 Carnahan-S:3?Manzke-T) *(1)0.42-9sigma-Sigma for crowdions1.00Dnevf1keyat1keyat1keyat1keyat<	0.0d+22	Sdisl		m-3	Bardeen-Herring disl' source density
10.11eVik einz SIA 2-4i mig energy16.5d-8 m^2/s ik c0i2 Pre-exp mig1.01zicl z_k^{\dagger} -1.01zicl z_k^{\dagger} 21.01zi z_k^{\dagger} 21.01zi z_k^{\dagger} 21.02zy z_k^{\dagger} 20.04-9rivoidmVoid capture efficiency for SIAs1zv z_k^{\dagger} -0.04-9rivoidmVoid capture efficiency for gas atoms1zig z_{bg}^{\dagger} -0zgd-GB capture efficiency for gas atoms1zig z_{bg}^{\dagger} -0zgg-GB capture efficiency for gas atoms1.00E+00rava1.25edgeeVEmission energy for gas at fislocation2.25edgeeVEmission energy for gas at fom dislocation2.35edgeeVEmission energy for gas at fislocation1.6edgebeVEmission energy for gas at fislocation2.0d+21rec η m²/s1rkk-V+crow: =1-pure 1D; =0-preferential1keybb-EOS:1-Rogert/2 Carnahan-Starting EOS1keybb-Sigma for canduan-Starting EOS1keybb-Include punching of i from bubbles2.3egyeVGas atom-bubble binging energy0.4.7m-Notifer correction1keyat-Include punching of	0	Aprime	Α'	-	Modified back stress term, Roger=0.05
1 6.5d-8m ² /sik c0i2 Pre-exp migReaction cross-sections	1 0.11			eV	ik eim2 SIA 2-4i mig energy
Relaction cross-sections	1 6.5d-8			m ² /s	ik c0i2 Pre-exp mig
1.01zicl z_L^i -Loops capture efficiency for SIAs1.01zi z_M^i z_L^i Dislocation capture efficiency for vacancies0.0d-9rivoidmVoid capture efficiency for vacancies0zgd-Dislocation capture efficiency for yacancies1zig z_{GR}^i -GB capture efficiency for stast1zig z_{GR}^i -GB capture efficiency for stancies0zgg-GB capture efficiency for stancies1zvg z_{GR}^v -GB capture efficiency for Gas atoms1.00E+00nva-Fraction of sites for gas at dislocation2.25edgeeVEmission energy for gas at from GBs0.5ebtrv E_{BAT}^v eVEmission energy for vacancy-trap complex2.0d+21rec η m²/sRecombination constant1rkk-V+crow: =1-pure ID: =0-preferential1keybb-EOS:1-Roger;(2 Carnahan-S;3?Manzke-T) *(1)0.24-9sigma-Sigma for Carnahan-S;3?Manzke-T) *(1)0.24-9sigma-ibslocation capture radius for crowdions3.0d*l0nevf-ibslocation capture radius for crowdions3.0d*l0higgmSIA cance starter or wiginal1keyant-el include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.54-7rmmSIA loop capture radius for crowdions3.0d*l0h			-	Reaction cross-	sections
1.01zi $z_k^{i_k}$ $z_k^{i_k}$ Dislocation capture efficiency for SIAs1 zv $z_k^{j_k}$ -Dislocation capture efficiency for vacancies0.0d-9rivoidmVoid capture distance for SIA0 zgd -Dislocation capture efficiency for SIAs1 zig $z_{cB}^{i_k}$ -GB capture efficiency for SIAs1 zvg $z_{cB}^{i_k}$ -GB capture efficiency for Vacancies0 zgg GB capture efficiency for Gas atoms1.00E+00rava-Fraction of sites for gas at dislocation2.25edgeeVEmission energy for gas at from GBs0.5ebtrv $E_{b,tr}^{i_k}$ eVEmission energy for gas at from GBs0.5ebtrv $E_{b,tr}^{i_k}$ eVEmission energy for vacancy-trap complex2.0d+21rcc η m ² /sRecombination constant1rkk-V+crow: =1-pure 1D; =0-preferential1keybb-EOS1-Roger;(2 Carnahan-S3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-S3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-S3?Manzke-T) *(1)1keyatt-=1keyatt-=1keyatt-=2.3eggeVGas atom-bubble bing energy0.5d-7roomDislocation capture radius for crowdions0.0d-9roomSIA loop capture radius for crowdions<	1.01	zicl	Z_L^i	-	Loops capture efficiency for SIAs
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1.01	zi	z_N^i	z_L^i	Dislocation capture efficiency for SIAs
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1	ZV	Z_N^v	-	Dislocation capture efficiency for vacancies
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	0.0d-9	rivoid		m	Void capture distance for SIA
1zig z_{bB}^{i} -GB capture efficiency for SIAs1zvg z_{bB}^{i} -GB capture efficiency for vacancies0zgg-GB capture efficiency for Gas atoms1.00E+00nava-Fraction of sites for gas at dislocation2.25edgeeVEmission energy for gas at from GBs0.5ebtrv $E_{b,tr}^{y}$ eVEmission energy for vacancy-trap complex2.0d+21rec η m²/sRecombination constant1rkk-V+crow: =1-pure ID; =0-preferential1keybb-EOS:1-Roger;(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3e2v-v-v binding energy for modifier correct-1wolfn-Wolfer corr: original10000nevf-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7romDislocation capture radius for crowdions3.0d ⁻¹⁰ higmSIA loop capture radius for crowdions3.0d ⁻¹⁰ higmcascade size for restricting C.V. Joops0keyhd-key for generation original1iliz-key for generation rate correction1iliz-key for generation of impurity atoms !Eliz0.04-9racemcascade size for restricting C.V. Joops0keyhd-key for generation of impurity atoms !Eliz <td< td=""><td>0</td><td>zgd</td><td></td><td>-</td><td>Dislocation capture efficiency for gas atoms</td></td<>	0	zgd		-	Dislocation capture efficiency for gas atoms
1zvg Z_{GB}^{ν} -GB capture efficiency for vacancies0 Z_{2G}^{ν} -GB capture efficiency for Gas atoms1.00E+00rava-Fraction of sites for gas at dislocation2.25edgeeVEmission energy for gas at from dislocation1.6ebgbbeVEmission energy for gas at from GBs0.5ebtrv $E_{b,tr}^{\nu}$ eVEmission energy for yacancy-trap complex2.0d+21rec η m²/sRecombination constant1rkk-V+crow: =1-pure 1D; =0-preferential1kkybb-EOS:1-Roger(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3e2v-v-v binding energy for Wolfer correct-i wolfn-Wolfer corr: original10000nevf-Elos:1-Roger(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3e2vv-v binding energy for Wolfer correctinclude punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d ⁻¹⁰ hilgmSIA loop capture radius for crowdions3.0d ⁻¹⁰ hilgmCasacde size for restricting C_V_loops0key rk-key for high-density corrections0.0d-9resemcascade size for restricting C_V_	1	zig	Z_{GB}^{i}	-	GB capture efficiency for SIAs
0zgg-GB capture efficiency for Gas atoms1.00E+00rava-Fraction of sites for gas at dislocation2.25edgeeVEmission energy for gas at from dislocation1.6ebgbbeVEmission energy for gas at from GBs0.5ebtrv $E_{b,tr}^y$ eVEmission energy for vacancy-trap complex2.0d+21rec η m²/sRecombination constant1rkk-V+crow: =1-pure 1D; =0-preferential1keybb-EOS:1-Roger(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3e2vv-v binding energy for Wolfer correct-1wolfn-Wolfer corr: original10000nevf-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d+0hitgmVacancy loop capture radius for crowdions3.0d+0hitgmcacade size for restricting C_V_loops0key tik-key for high-density corrections0key tik-key for high-density atoms1iliz-key for high-density corrections0key tik-key for high-density corrections0key tik-key for high-density corrections0key tik-key for high-density corrections0key tik-ke	1	zvg	Z_{GB}^{v}	-	GB capture efficiency for vacancies
1.00E+00rava-Fraction of sites for gas at dislocation2.25edgeeVEmission energy for gas at from dislocation1.6ebgbbeVEmission energy for gas at from dislocation1.6ebgbbeVEmission energy for yacancy-trap complex2.0d+21rec η m²/sRecombination constant1rkk-V+crow: =1-pure 1D; =0-preferential1kkybb-EOS:1-Roger;(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3e2vv-v binding energy for Wolfer correct-1wolfn-Wolfer corr: original10000nevf-i>levef then Ev_binding=evf1keyart-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d+10hilgmVacancy loop capture radius for crowdions0.0d-9reasemcascade size for restricting C_V_loops0keyld-key for generation rate correctionkey for generation rate correction1iliz-key for generation rate correction0.0d-2Ccarbon C_s at^10.0d-2Ccarbon C_s at^10.0d-2Ccarbon C_s at^11iliz-coordination number !Eliz1iliz<	0	zgg	<u>UD</u>	_	GB capture efficiency for Gas atoms
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	1.00E+00	rava		-	Fraction of sites for gas at dislocation
1.6ebgbbeVEmission energy for gas at from GBs0.5ebtrv $E_{b,tr}^{v}$ eVEmission energy for vacancy-trap complex2.0d+21rec η m²/sRecombination constant1rkk-V+crow: =1-pure 1D; =0-preferential1keybb-EOS:1-Roger;(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-V-v binding energy for Wolfer correct-1wolfn-Wolfer corr: original10000nevf-i>nevf then Ev_binding=evf1keyart-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rtomDislocation capture radius for crowdions3.0d-10hilgmSIA loop capture radius for crowdions3.0d-10hilgmVacancy loop capture radius for crowdions0.0d-9reasemcascade size for restricting C_V_loops0keyhd-key for high-density corrections1iliz-key in correction1iliz-key for generation rate correction0key k-leag of the state of inpurity atoms !Eliz0.0d-2Ccarbon C_s at ¹ 0.12bulk concentration of inpurity atoms !Eliz1iliz-cordination number !Eliz0.5 <td< td=""><td>2.25</td><td>edge</td><td></td><td>eV</td><td>Emission energy for gas at from dislocation</td></td<>	2.25	edge		eV	Emission energy for gas at from dislocation
0.5ebtrv $E_{b,tr}^{\nu}$ eVEmission energy for vacancy-trap complex2.0d+21rec η m^2/s Recombination constant1rkk-V+crow: =1-pure 1D; =0-preferential1keybb-EOS:1-Roger;(2 Carnahan-S;3?Manzke-T) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3 $e2v$ 1wolfn-Wolfer corr: original10000nevf-i>nevf then Ev_binding=evf1keyart1keyart1keyart1keyart2.3eegeVGas atom-bubble binging energy0.54-7romDislocation capture radius for crowdions3.0d-10hilgmSIA loop capture radius for crowdions3.0d-10hvlgmVacancy loop capture radius for crowdions0keyhd-key for high-density corrections0keyhd-key for ligh-density corrections1iliz-key for ligh-density correction0.55Ebcv $E_b^{C,V}$ eVimpurity atoms: Eliz0.54K.y.rk-coordination number !Eliz0.55Ebcv $E_b^{C,V}$ eVimpurity-vacancy binding energy !Eliz0.55Ebcv $E_b^{C,V}$ eVimpurity atoms: !Eliz1.50.5Ebcv $E_b^{C,V}$ e	1.6	ebgbb		eV	Emission energy for gas at from GBs
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	0.5	ebtrv	E_{htr}^{v}	eV	Emission energy for vacancy-trap complex
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	2 0d+21	rec	n	m ² /s	Recombination constant
1rkk11<	1	11	,	11175	
1Reybe-EDS:1-Roger;(2 Carnahan-S; 3:Manzke-1) *(1)0.2d-9sigma-Sigma for Carnahan-Starling EOS0.3 $e2v$ -v-v binding energy for Wolfer correct-1wolfn-Wolfer corr: original10000nevf-i>nevf then Ev_binding=evf1keyart-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d ⁻¹⁰ hilgmSIA loop capture radius for crowdions3.0d ⁻¹⁰ hilgmVacancy loop capture radius for crowdions0.0d-9rcasemcascade size for restricting C_V_loops0key_nt-key for high-density corrections0key_nt-key for generation rate correction	1	ľKK Israelska		-	V+crow: =1-pure 1D; =0-preferential
0.2d-9sigma-Sigma for Carnanan-starting EOS0.3e2v-v-v binding energy for Wolfer correct-1wolfn-Wolfer corr: original10000nevf-i>nevf then Ev_binding=evf1keyart-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d-10hilgmSIA loop capture radius for crowdions3.0d-10hvlgmVacancy loop capture radius for crowdions0.0d-9rcasemcascade size for restricting C_V_loops0keyhd-key for high-density corrections0key frk-key for generation rate correction1iliz-key for generation of impurity atoms1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at^-10.0d-2Ccarbon C_s at^-11iliz-coordination number !Eliz1iliz-coordination number !Eliz0.5Ebcv $E_b^{C,v}$ eV1 N_{-} U; ρ_U N_U: number of and N_pptU coefficients !Eliz1 N_{-} U; r_U : number of and R_pptU coefficients !Eliz	1	. Keybb		-	EOS:1-Roger;(2 Carnanan-S;3?Manzke-1) *(1)
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	0.20-9	sigma		-	Sigma for Carnanan-Starling EOS
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	0.5	e2v		-	V-V binding energy for woher correct
10000nevr-I>nevr then $Ev_{_{_{_{_{_{}}}}}$ inding=evr1keyart-=1 include punching of i from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d ⁻¹⁰ hilgmSIA loop capture radius for crowdions3.0d ⁻¹⁰ hvlgmVacancy loop capture radius for crowdions0.0d-9rcasemcascade size for restricting C_V_loops0keyhd-key for high-density corrections0key_rk-key for generation rate correction1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at ⁻¹ 0.0d-2Ccarbon C_s at ⁻¹ 0.5Ebcv $E_b^{C,P}$ eV1iliz-coordination number !Eliz1 z_{1} p_U N_U: number of and N_pptU coefficients !Eliz1 $h_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{$	-1	wolfn		-	wolfer corr: original
1keyart-=1 include punching of 1 from bubbles2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d ⁻¹⁰ hilgmSIA loop capture radius for crowdions3.0d ⁻¹⁰ hvlgmVacancy loop capture radius for crowdions0.0d-9rcascmcascade size for restricting C_V_loops 0keyhd-key for high-density corrections0key_rk-key for generation rate correction1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at ⁻¹ 0.5Ebcv $E_b^{C,v}$ eV1 10.5 $Ebcv$ $E_b^{C,v}$ 1 12 -coordination number !Eliz1 $1-0c20$ $N_LU;$ ρ_U N_U: number of and N_pptU coefficients !Eliz2+0e-09 $R_LU;$ r_U _U: number of and R_pptU coefficients !Eliz	10000	nevi		-	i>nevi then Ev_binding=evi
2.3eegeVGas atom-bubble binging energy0.5d-7rromDislocation capture radius for crowdions3.0d-10hilgmSIA loop capture radius for crowdions3.0d-10hvigmVacancy loop capture radius for crowdions0.0d-9rcasemcascade size for restricting C_V_loops0keyhd-key for high-density corrections0key_rk-key for generation rate correction1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at ⁻¹ 0.5Ebcv $E_b^{C,v}$ eV1 z -coordination number !Eliz0.5 $Ebcv$ $E_b^{C,v}$ eV1 z -coordination number !Eliz0.5 $Ebcv$ $E_b^{C,v}$ eV1 z -coordination number !Eliz0.5 $Ebcv$ $E_b^{C,v}$ eV1 z -coordination number !Eliz1 z -coordination number !Eliz0.5 $Ebcv$ $F_b^{C,v}$ eV1 z -coordination number !Eliz1 z -coordination number !Eliz0.5 $Ebcv$ $F_b^{C,v}$ eV1 z -coordination number !Eliz1 z -coordination number !Eliz1 z -coordination number !Eliz1 z z -1 z	1	keyart		-	=1 include punching of 1 from bubbles
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	2.3	eeg		ev	Diele action control and in fan anoudiene
3.0d $\cdot 0$ HingmSIA loop capture radius for crowdions3.0d $\cdot 0$ hvlgmVacancy loop capture radius for crowdions0.0d-9reasemcascade size for restricting C_V_loops0keyhd-key for high-density corrections0key_rk-key for generation rate correction1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at \cdot^1 0.5Ebcv $E_b^{c,v}$ eV1 \cdot_{b} -1 z -1iliz-0.5Ebcv $E_b^{c,v}$ eV impurity-vacancy binding energy !Eliz8znnz1 +0e20 $N_{-}U$; $N_{-}pptU$ ρ_U 2 +0e-09 $R_{-}U$; $R_{-}U$; r_U 2 +0e-12RpptU r_U	0.50-7			m	Dislocation capture radius for crowdions
3.0d '0HVigmVacancy loop capture radius for crowdrons0.0d-9reasemcascade size for restricting C_V_loops0keyhd-key for high-density corrections0key_rk-key for generation rate correctionPrecipitates and impurity atoms1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at ⁻¹ bulk concentration of impurity atoms !Eliz0.5Ebcv $E_b^{c,v}$ eVimpurity-vacancy binding energy !Eliz8znnz-coordination number !Eliz1 +0e20 $N_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{_{$	3.00 10	niig		m	STA loop capture radius for crowdions
0.0d-9reasemcaseade size for restricting C_V_loops0keyhd-key for high-density corrections0key_rk-key for generation rate correction1iliz-key: and impurity atoms1iliz-key: and impurity atoms1iliz-key: and impurity atoms0.0d-2Ccarbon C_s at ⁻¹ 0.0d-2Ccarbon C_s at ⁻¹ 0.5Ebcv $E_b^{C,v}$ eVimpurity-vacancy binding energy !Eliz8znnz-1 +0e20 $N_{_{_{_{D}}}ptU}$ ρ_U N_U: $number of and N_pptU coefficients !Eliz2 +0e-09R_{_{_{_{D}}}U;}r_U+0e-12RpptUImpute of and R_pptU coefficients !Eliz$	3.00 0	nvig		m	vacancy loop capture radius for crowdions
0keynd-key for high-density corrections0key_rk-key for generation rate correction1iliz-key: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at ⁻¹ bulk concentration of impurity atoms !Eliz0.5Ebcv $E_b^{C,v}$ eVimpurity-vacancy binding energy !Eliz8znnz-coordination number !Eliz1 +0e20 $N_{_}U$; $N_{_}pptU$ ρ_U N_U: number of and N_pptU coefficients !Eliz2 +0e-09 $R_{_}U$; $+0e-12r_Ur_U_U: number of and R_pptU coefficients !Eliz$	0.00-9	rcasc		m	cascade size for restricting C_V_loops
0Rey TK-Rey for generation rate correction0-Rey for generation rate correction1iliz-1iliz-0.0d-2Ccarbon C_s at ⁻¹ bulk concentration of impurity atoms !Eliz0.5Ebcv $E_b^{c,v}$ eVimpurity-vacancy binding energy !Eliz8znnz1 +0e20 N_{-U} ; N_{-pptU} ρ_U N_U: number of and N_pptU coefficients !Eliz2 +0e-09 R_{-U} ; $+0e-12$ r_U RpptU r_U	0	<u>keynd</u>		-	key for high-density corrections
1ilizPrecipitates and impurity atoms1iliz- $0.0d-2$ Ccarbon C_s $0.0d-2$ Ccarbon C_s 0.5 Ebcv $E_b^{c,v}$ eV impurity-vacancy binding energy !Eliz 8 znnz $1 + 0e20$ $NU;$ $NpptU$ ρ_U $1 + 0e20$ $RU;$ $NpptU$ r_U $1 + 0e20$ $RU;$ $NpptU$ r_U $1 + 0e20$ $RU;$ $RU;r_U1 + 0e20RU;RDU;r_U1 + 0e20RU;RDU;r_U1 + 0e20RU;RDU;r_U1 + 0e20RU;RDU;r_U$	0	кеу_rк			key for generation rate correction
1IIIZ-Rey: =1 change pre-existing microstructure !Eliz0.0d-2Ccarbon C_s at ⁻¹ bulk concentration of impurity atoms !Eliz0.5Ebcv $E_b^{c,v}$ eVimpurity-vacancy binding energy !Eliz8znnz-coordination number !Eliz1 +0e20 $N_{_}U;$ $N_{_}pptU$ ρ_U N_U: number of and N_pptU coefficients !Eliz2 +0e-09 $R_{_}U;$ $+0e-12r_Ur_U$	1	.1.		Precipitates and imp	burity atoms
$0.0d-2$ Ccarbon C_s at 'bulk concentration of impurity atoms !Eliz 0.5 Ebcv $E_b^{c,v}$ eV impurity-vacancy binding energy !Eliz 8 znnz-coordination number !Eliz $1 + 0e20$ N_U ; N_pptU ρ_U N_U: number of and N_pptU coefficients !Eliz $2 + 0e-09$ R_U ; $+0e-12$ r_U r_U	1		C		key: =1 change pre-existing microstructure !Eliz
0.5Ebcv E_b^{m} eVimpurity-vacancy binding energy !Eliz8znnz-coordination number !Eliz1 +0e20 $N_{_}U;$ $N_{_}pptU$ ρ_U N_U: number of and N_pptU coefficients !Eliz2 +0e-09 $R_{_}U;$ $+0e-12$ r_U r_U	0.0d-2	Ccarbon	L_s		buik concentration of impurity atoms !Eliz
8 znn z $-$ coordination number !Eliz $1 + 0e20$ N_U ; N_pptU ρ_U N_U : number of and N_pptU coefficients !Eliz $2 + 0e - 09$ R_U ; $+ 0e - 12$ r_U r_U	0.5	Ebcv	$E_b^{b,r}$	eV	impurity-vacancy binding energy !Eliz
$1 + 0e20$ N_U ; N_pptU ρ_U N_U : number of and N_pptU coefficients !Eliz $2 + 0e-09$ R_U ; $+ 0e-12$ r_U r_U L_U : number of and R_pptU coefficients !Eliz	8	Znn	Z	-	coordination number !Eliz
2 +0e-09 R_U ; r_U +0e-12 R_{pptU} r_U	1 +0e20	N_U; N_pptU	$ ho_U$		N_U: number of and N_pptU coefficients !Eliz
	2 +0e-09 +0e-12	R_U; RpptU	r_U		_U: number of and R_pptU coefficients !Eliz

Reference	Variable	Variable	Unit	Description		
value	(RIME)	(symbol)		-		
4 + 0.0		$ ho_{CP}$				
+0e+19 -	N_B;			N B: number of and N pntB coefficients Eliz		
0e+16 +-	N_pptB			rt_b. humber of und rt_pptb coefficients .bhb		
e13						
3 + 0.0	R_B;	R _{CP}		_B: number of and R_pptB coefficients !Eliz		
+0e-1	K_ppptB					
1.0	ZIPPTB		-	Ppts_B capture effic for SIAs !Eliz		
1	rotrp			I rap effciency		
0 + 0e + 20	ilpnum,	$ ho_L$		ilpnum: number of and num_lp coefficients !Eliz		
-0017	num_ip					
0 + 0e - 8 - 0e - 10		r_L				
00-10	Ilpr, r_lp			ilpr: number of and r_lp coefficients		
+0e-12 - 0e - 15						
06-13			Correlation screening of voids	from 1 d SIA clusters		
1.0d+10	phice()		dagEAS	T min damage for starting screening		
1.0d+10 1.0d+01	phicso		dpaFAS dpaFAS	T may damage for complete screening		
1.00+01	rwheor		upar AS	smallest void screened [nm]		
0	Twitcol		Voids: vacan	cies		
9	mwm		-	Max size for generation $(< myxy)$		
1 94	nnw			Exponent: gener rate $\sim i^{**}(-pnw)$		
30	mvxv			i > myxy: groups		
0.12	drvy		nm	dr or dr/r for groups see below		
2	igryac		-	=1 - dr; =2 - dr/r for above choice		
1	ifac		-	Factor: increase size of last group		
358	nvv		-	Min i visible		
	Bubbles: gas atoms					
10	mvxb		-	j > mvxb: groups		
0.12	drvb		nm	dr or dr/r for groups see below		
2	igrgas		-	=1 - dr; =2 - dr/r for above choice		
50	nvb		-	Min j visible		
4.5	g00		-	Definition for upper boundary		
2	g11		-	for Gas atom area: $g < g00+g11*(x^{-1})$		
100	iimax		-	N of vacancypoints to write E_bin & emis		
100	ijmax		-	N of gas points to write E_bin & emis		
			Interstitial lo	pops		
10	mim		-	Max size for generation (<= mixl)		
1	pni		-	Exponent: gener rate ~ i**(-pni)		
20	mixl		-	i > mixl: groups		
6.0d-10	dri		m	dr in groups		
20	nli		-	Min i visible		
-			Vacancy loo	ops		
9	mvm		-	Max size for generation (< mvxl)		
1	phv		-	Exponent: gener rate ~ 1**(-pnv)		
10	mvxl		-	1 > mvx1: groups		
20			111	Min i visible		
20		L		μ IVIIII I VISIDIe		
80.0d±00	oshear		Pa	Shear modulus for v-loop hinding F		
240	sigma		MPa	Initial stress yield		
135	hard0		Vikers	Initial bardness		
2	fsht		-	Shmidt-Taylor factor		
2.7	sihard		Vikers	Sigma to hardness coefficient		
1	ali		-	Dimensionless coefficients		
1	alv		-	for estimation of hardening		
·						

Reference Value	Variable (RIME)	Variable (symbol) ⁷	Unit	Description
1	alc		-	due to i and v loops and cavities

File Name	Variable	Description
z_bevl.dat	vacancy - vacancy loop binding energy	
z_bewc.dat	vacancy - void binding energy	
z_bew3.dat	vacancy-bubble binding energy for 3D graph	
	xgas	number of gas atoms
	xvac	number of vacancies
	Eb (eV)	binding energy of a vacancy with a bubble
z_bewb.dat	vacancy-bubble binding energy [eV]	
	vac	number of vacancies
	g0, g1	corresponding 0, 1 gas atoms
z_emig.dat	gas emission rates from bubbles [s ⁻¹]	
	vac	number of vacancies
	g0, g1	corresponding 0, 1 gas atoms
z_emiv.dat	vacancy emission rates from bubbles [s ⁻¹]	
	vac	number of vacancies
	g0, g1	corresponding 0, 1 gas atoms
z_grid-wg.dat	gas axis grid for bubbles	
	N	index of the array element (group)
	x_def	number of defects (gas or vacancies) in bubble
	R_nm	bubble radius [nm]
z_grid-wv.dat	vacancy axis grid for bubbles	
	N	index of the array element (group)
	x_def	number of defects (gas or vacancies) in bubble
	R nm	bubble radius [nm]
z_hard.dat	hardening	
z_harv.dat	hardening in Vickers	
z_pcil.dat	production rates of interstitial loops in cascades	
	n_int	number of interstitials
	Rate	production rate [s ⁻¹]
z_pcvl.dat	production rates of vacancy loops in cascades	
	n_int	number of vacancies
	Rate	production rate [s ⁻¹]
z_pcwv.dat	production rates of micro-voids in cascades	
	n_int	number of vacancies
	Rate	production rate [s ⁻¹]
z rezz.dat	Input data read from input file to check reading	
z_sdif.dat	final size distribution of interstitial loops	
	R_nm	interstitial loop radius [nm]
	abs_f(R)	abs of size distribution to present in log scales
	f(R)	size distribution in R space [m ⁻³ nm ⁻¹]
	n_def	mean (over group) number of defects in a cluster
	f(n_vac)	size distribution in x space [at ⁻¹]
	slope	slope of x-space size distribution in group [at ⁻¹]
z_sdil.dat	all size distributions of interstitial loops	
	R_nm	interstitial loop radius [nm]
	abs_f(R)	abs of size distribution to present in log scales
	f(R)	size distribution in R space [m ⁻³ nm ⁻¹]
	n def	mean (over group) number of defects in a cluster
	f(n vac)	size distribution in x space [at ⁻¹]
	slope	slope of x-space size distribution in group [at ⁻¹]
z sdw3.dat	final size distribution of bubbles for 3D plot	
	N gas	number of gas atoms
	R nm	bubble radius [nm]
	$\overline{f(b)}$	bubble density in R-space [m ⁻³ *nm ⁻¹]
z sdwf.dat	R nm	void/bubble radius [nm]
	abs f(R)	abs of size distribution to present in log scales
	n vac	mean (over group) number of vacancies in a cluster
-	f(n vac)	size distribution in x space [at ⁻¹]
í	-\	

Table 0.5. Output the descriptions from RIME Model.	Table 6.3:	Output file	descriptions	from	RIME Model.
---	------------	-------------	--------------	------	-------------

File Name	Variable	Description
	slope	slope of x-space size distribution in group [at ⁻¹]
	m/x	number of gas atoms to number of vacancies ratio
	P_GPa	gas pressure [GPa] averaged over group
	Z	gas compressibility, characteristic gas non-ideality
	r/RWZ	bubble radius/Wigner-Zeitz radius
z_sdws.dat	2-D: gas-vacancy size distribution of bubbles for a	different damage levels
	two-dimensional size distributions in x space f	for different
	irradiation damage levels; the number of gas a	toms increases from top to
	bottom and the vacancy numbers increases fro	m left to right; the
	densities are in [at ⁻¹]	
z_sdwv.dat	all size distributions of bubbles/voids	
	R_nm	void/bubble radius [nm]
	abs_f(R)	abs of size distribution to present in log scales
	n_vac	mean (over group) number of vacancies in a cluster
	f(n_vac)	size distribution in x space [at ⁻¹]
	slope	slope of x-space size distribution in group [at ⁻¹]
	m/x	number of gas atoms to number of vacancies ratio
	P_GPa	gas pressure [GPa] averaged over group
	Z	gas compressibility, characteristic gas non-ideality
	r/RWZ	bubble radius/Wigner-Zeitz radius
z_sdvf.dat	final size distribution of vacancy loops	
	R_nm	vacancy loop radius [nm]
	abs_f(R)	abs of size distribution to present in log scales
	f(R)	size distribution in R space [m ⁻³ nm ⁻¹]
	n_def	mean (over group) number of defects in a cluster
	f(n_vac)	size distribution in x space [at ⁻¹]
	slope	slope of x-space size distribution in group [at ⁻¹]
z_sdvl.dat	all size distributions of vacancy loops	
	R_nm	vacancy loop radius [nm]
	abs_f(R)	abs of size distribution to present in log scales
	f(R)	size distribution in R space [m ⁻³ nm ⁻¹]
	n_def	mean (over group) number of defects in a cluster
	f(n_vac)	size distribution in x space [at ⁻¹]
	slope	slope of x-space size distribution in group [at ⁻¹]
zm_conc.dat	concentrations of mobile defects	
	Damage /Time	either irradiation damage [dpa] or time in [s]
	Ci	interstitial concentration [at ⁻¹]
	Cv	vacancy concentration [at ⁻¹]
	CGas	gas atom concentration [at ⁻¹]
	Ccrow	crowdion concentration [at ⁻¹]
zm_dens.dat	densities of extended defects [m ⁻³]	
	Damage /Time	either irradiation damage [dpa] or time [s]
	N_i_loop	number density of interstitial loops bigger than 2i
	Nn_i_loop	number density of visible interstitial loops
	N_v_loop	number density of vacancy loops bigger than 2v
	Nn_v_loop	number density of visible vacancy loops
	N_void	number density of voids bigger than 2v
	Nn_void	number density of visible voids
zm_gasA.dat	gas atoms at different sinks	
	Damage /Time	either irradiation damage [dpa] or time [s]
	CGas	freely migrating gas [at ⁻¹]
	Gas_bubb	in bubbles [at ⁻¹]
	Gas_dsl	at dislocations [at ⁻¹]
	Gas_GB	at grain boundaries [at ⁻¹]
	GB_Cover	grain boundary coverage with gas atoms,
	G_Gas_s ⁻¹	generation rate [s ⁻¹]
	<mgas></mgas>	mean number of gas at per bubble

Table 6.3:	Output fi	le descri	ptions fro	m RIME Model.

File Name	Variable	Description
zm_gasB.dat	all information on bubbles	
	Damage /Time	either irradiation damage [dpa] or time [s]
	N_m ⁻³	bubble number density [m ⁻³]
	R_nm	bubble mean radius [nm]
	Swelling_%	swelling due to bubbles [%]=[100.*at ⁻¹]
	SS_m-2	bubble sink strength for freely-migrating SIAs [m-2]
	Nn_m ⁻³	number density of visible bubbles [m ⁻³]
	Rn_nm	mean radius of visible bubbles [nm]
	<mgas></mgas>	mean number of gas atoms at per bubble
	DenZ_nm	mean distance between bubbles [nm]
zm_intL.dat	all information on interstitial loops	
	Damage /Time	either irradiation damage in dpa or time [s]
	N_m ⁻³	loop number density [m ⁻³]
	R_nm	loop mean radius [nm]
	SNdeff	total defects accumulated in loops [at ⁻¹]
	SS_m-2	sink strength for freely-migrating SIAs [m-2]
	Nn_m ⁻³	number density of visible loops [m ⁻³]
	Rn_nm	mean radius of visible loops [nm]
zm_radi.dat	radii of extended defects [nm]	
	Damage / Time	either irradiation damage in dpa or time [s]
	K_1_100p	mean radius of nicible interstitiel loops
	RII_1_100p	mean radius of visible interstitiat loops
	R_v_loop	mean radius of visible vacancy loops
	R void	mean radius of voids/bubbles bigger than 2y
	Rn void	mean radius of visible voids/bubbles
	RWZ void	Wigner-Zeitz cell radius for 3-D migrating defects
zm_swss.dat	swelling and sink strengths	Wigher Zeitz een rudius for 5 D highung dereets
	Damage /Time	either irradiation damage in dpa or time [s]
	I in loops	total number of interstitial in loops [at ⁻¹]
	V_in_loop	total number of vacancies in loops [at ⁻¹]
	Swelling_%	swelling [%]=[100.*at ⁻¹]
	SW_GB	no description yet
	SSi_i_lps	sink strength of interstitial loops for SIAs [m-2]
	SSi_v_lps	sink strength of vacancy loops for SIAs [m-2]
	SSi_voids	sink strength of voids/bubbles for SIAs [m-2]
	rod_m-2	dislocation density [m-2]
	MFP3d_nm	mean-free path of freely-migrating defects [m]
	S_dot_%/dpa	swelling rate [at ⁻¹ /dpa]
zm_vacL.dat	all information on vacancy loops	
	Damage /Time	either irradiation damage in dpa or time [s]
	N_m ⁻³	loop number density [m ⁻³]
	K_nm SNJ-ff	100p mean radius [nm]
		total defects accumulated in loops [at ']
	55_m-2	sink strength for freely-migrating SIAs [m-2]
	INII_III	multipler defisitly of visible loops [m ⁻]
zm liz det	Ni_iiii	mean diameter of visible loops [nm]
ZIII_IIZ.uai	Nn m ⁻³	number density of visible loops [m ⁻³]
<u> </u>	Swelling %	swelling [%]=[100 *at-1]
	S dot %/dpa	swelling rate [at ⁻¹ /dna]
	Si voids	sink strength of voids/bubbles for SIAs [m-2]
	Dn i loop	mean diameter of visible interstitial loops
<u> </u>	Nn i loop	number density of visible interstitial loops
	SSi i lps	sink strength of interstitial loops for SIAs [m-2]
	rod_m-2	dislocation density [m-2]
	ss_pptU	Sink strength for G phase

Table 6.3: Output file descriptions from RIME Model.

File Name	Variable	Description
	ss_pptB	Sink strength for M2X
	ss_loop_exp	Loop sink strength for explicit loop treatment
zz_age_ct.dat	aging continuation	this file is needed to continue previous aging calculation
zz_igr_ct.dat	continuation of surface irradiation after bulk	
	irradiation (not in use)	
zz_irr_ct.dat	irradiation continuation	this file is needed to continue previously performed
		irradiation

Table 6.3: Output file descriptions from RIME Model.

Parameter	Value	Reference
Case Name	100dpa	N.A
Void Distribution	Input (188 dpa)	From experiment
Loop Distribution	Input (188 dpa)	From experiment
Number of Starting Void Groups	120	N.A
Number of Loop Groups	120	N.A
Precipitate Evolution?	No	N.A
C-V traps?	No	N.A
Initial Dislocation Density [m ⁻²]	3×10 ¹⁴	N.A
Grain Diameter [m]	1×10 ⁻⁶	N.A
Helium Generation Rate [appm/dpa]	0	N.A
Di-Vacancy Binding Energy[eV]	0.3	[106]
Vacancy Formation Energy [eV]	1.79	[107]
Vacancy Migration Energy [eV]	0.63	[109]
Interstitial Migration Energy [eV]	0.22	[109]
Helium Migration Energy [eV]	N.A	N.A
Vac. Diffusion Pre-exponential [m ² /s]	8.2×10 ⁻⁷	[106]
Int. Diffusion Pre-exponential [m ² /s]	9.4×10 ⁻⁷	[106]
He Diffusion Pre-exponential [m ² /s]	N.A	N.A
Dislocation Loop /Network Bias for	1.01	[8,41-43,114,115]
Interstitials		

Table 6.4: Main input parameters used in sensitivity analysis. These inputs correspond to Ref.2 shown in Table 6.9.

	Swelling			Swelling Rate				
	21	dpa	100 dpa		21 dpa		100 dpa	
Parameter	Without PPT	With PPT	Without PPT	With PPT	Without PPT	With PPT	Without PPT	With PPT
Bias (Increase)	1.5	1.4	62	61	108	108	120	119
Grain Size (Increase)	0.01	0.01	0.15	0.15	0.29	0.29	0.29	0.29
Temperature (Increase)	0	0	0.33	0.22	0.392	0.366	0.47	0.43
Damage Rate (Decrease)	-0.0087	-0.00781	-0.0829	-0.0969	-0.090	-0.107	-0.11	-0.12

Table 6.5: Significance calculated for swelling and swelling rate at 460°C, 21 and 100 dpa with and without the addition of unbiased precipitates at experimental levels observed for G phase. (Ref.2)

	Swe	lling	Swelling Rate		
Parameter	21 dpa	100 dpa	21 dpa	100 dpa	
Cascade Efficiency (ε)	-0.014	-1.019	-1.901	-1.977	
Recombination Coefficient (μ)	0.000	-0.006	-0.012	-0.012	
E_f^v	0.088	0.038	0.066	0.061	
E_m^{v}	0.018	0.038	0.066	0.074	
E_m^i	0.002	-0.454	-0.015	-0.357	
Bias (z_L^i)	1.51	108	62	119	

Table 6.6: Significance of key input parameters in RIME model.

Parameter	Value	Reference
Dislocation Density [m ⁻²]	3×10 ¹⁴	Measured
Grain Diameter [m]	1×10 ⁻⁶	Measured
Di-vacancy Binding Energy [eV]	0.3	[106]
Vacancy Formation Energy [eV]	1.79	[107]
Vacancy Migration Energy [eV]	0.63	[109]
Interstitial Migration Energy [eV]	0.22	[109]
Vac. Diffusion Pre-exponential [m ² /s]	8.2×10 ⁻⁷	[106]
Int. Diffusion Pre-exponential [m ² /s]	1.1×10 ⁻⁷	[106]
He Diffusion Pre-exponential [m ² /s]	4×10 ⁻⁷	[108]
Cascade Efficiency	0.3	[110,111]
Dislocation Bias for Interstitials	1.01-1.25	[8,41– 43,114,115]

Table 6.7: Main changes in parameterization from FCC to BCC alloys.

Element	wt%	Approximate	Reference
		Diffusion	
		Coefficient	
Cr	11.8	3.70E-20	[129]
Ni	0.51	1.00E-19	[130]
Si	0.21	1.00E-20	[131]
Mn	0.5	5.00E-18	[132]
Mo	1.03	2.70E-21	[133]
С	0.21	5.00E-13	[109,119]
Р	0.008	5.00E-20	[134]
S	0.003	1.00E-17	[134]
Ν	0.01	1.00E-12	[109]
W	0.5	1.80E-21	[135]
V	0.33	2.00E-20	[136]

Table 6.8: Concentration [10] and diffusion coefficients at 500°C for minor alloying elements in HT9.

Categories	Description	Variable	Ref.0	Ref.1	Ref.2
Run Parameters	Output Directory Name: 12 char. max	name	Ref.0	Ref.1	Ref.2
	0=Volume, 1=Surf., 2=Surf. no depos	key	0	0	0
	Aging =0; Irradiation =1	keyai	1	1	1
	Calculation: New=0; Cont=1	keyc	0	0	0
	=1 check cell size using criterion:	idm	1	1	1
	max ratio bubble/cell size allowed	ratmax	1.00E-06	1.00E-06	1.00E-06
	=1 no void nucleation: v+v and v+Gas	keyNucl	0	0	0
	=1 no v-loop nucleation: v+v	keyNuclL	0	0	0
	LSODE INTERNAL max timestep	dttt1	1.00E+10	1.00E+10	1.00E+10
	Initial timestep out	dt0	1.00E-06	1.00E-06	1.00E-06
	Time <time1: rio1<="" td=""><td>time1</td><td>1.00E+03</td><td>1.00E+03</td><td>1.00E+03</td></time1:>	time1	1.00E+03	1.00E+03	1.00E+03
	Time <timem: if="" riom;="">: constant</timem:>	timem	5.00E+04	5.00E+04	5.00E+04
	OUT timestep dt=dt0 $+$ t/rio1	rio1	1	1	1
	OUT Timestep dt=dt_previous + t/riom	riom	10	10	10
	N steps for writing to screen & files	nscrn	1	1	1
	N steps for saving to continue	nremm	1	1	1
	N steps for writing SDs and 3-d graph	nwrit	1	1	1
	EULER =1, LSODE =0. Only 0 is used	mfeuler	0	0	0
Flags and	Flag for treatment of vacancies	iVac	1	1	1
Dimensions	Flag for treatment of interstitials	iInt	1	1	1
	Flag for treatment of voids/bubbles	iVoid	1	1	1
	Flag for treatment of interstitial loops	iIloop	0	0	1
	Flag for treatment of dislocations	iDisl	0	0	1
	Flag for explicit treatment of vacancy	iTrap	0	0	0
	Initial # of vacancy groups in voids/bubbles	mvv	120	120	120
	Initial # of helium groups in bubbles	mvb	120	120	120
	# of interstitial loop groups	mil	120	120	120
	# of groups added when expanding cell	iexpnd	10	10	10
Tolerances for	for all derivatives: atolD=atolV/ntol	ntol	10	10	10
integration	relative tolerance for all values	rtol	1.0d-4	1.0d-4	1.0d-4
	initial abs tolerance for SIAs	atsia	1.0d-15	1.0d-15	1.0d ⁻¹ 5
	initial abs tolerance for vacancies	atvac	1.0d-7	1.0d-7	1.0d-7
	initial abs tolerance for interstitial loops	atlps	1.0d ⁻¹ 6	1.0d ⁻¹ 6	1.0d ⁻¹ 6
	initial abs tolerance for dislocation	atdis	1.0d+9	1.0d+9	1.0d+9
Irradiation	Irradiation/Aging TIME	time	4.50E+05	4.50E+05	4.50E+05
	Defect fraction recombination in cascades	IKIIIt	0.67	0.67	0.67
	SIA fraction in sessile clusters	opsis	0.07	0.07	0.07
	Vacancy fraction in sessile clusters	opsis	0	0	0
	Vacancy fraction in micro-voids	epsv	03	03	03
	Tomporature, degree Coloius	to	460	460	460
	Initial gas atom site fraction	200	400 0.00E+00	400 0.00E+00	400 0.00E+00
	Initial VOLUME dislocation density	rod0	3.0d+14	3.0d+14	3.0d+14
	Density of vacancy trapping sites	rotro	1.04.8	1.04.8	1.04.8
	GP dislocation density (if kapo)	rode	1.04-10	1.04+19	1.04+10
	Grain radius	ror	5.004.7	5 004 7	5 004.7
Material	N at in unit cell 2-BCC 4-ECC	type1	2	2	2
wiaterial	Lattice parameter: bcc Fe=2.87 fcc=3.61	3	2 86d-10	2 86d-10	2 86d-10
	Dislocation Burgers V: 1-\$3/2: 2-0.5: 3-1/\$2	a Nhy	1	1	1
	Loon Burgers V: 1-53/2, 2-0.5, 5 /55	NbvI	3	3	3
	Surface energy	gamma0	23	23	23
	(gama*gamma)_gamta*ta)/1.6e_10	gama	1	1	1
	gamma in eV	gamte	0.0 1 75e ⁻³	0.0 1 75e ⁻³	0.0 1 75e ⁻³
1	o	Sume	0.0 1.750	0.0 1.750	0.0 1.750

Table 6.9: Definition of reference case input. Changes between each reference case highlighted in yellow.

Categories	Description	Variable	Ref.0	Ref.1	Ref.2
	Vacancy formation energy	evf	1.79	1.79	1.79
	Vacancy migration energy	evm	0.63	0.63	0.63
	Effective vacancy migration energy (same if	evmeff	0.63	0.63	0.63
	SIA migration energy	eim	0.22	0.22	0.22
	Pre-exp for vacancy formation	cve0	1	1	1
	Pre-exp for vacancy migration	c0v	8.2d-7	8.2d-7	8.2d-7
	Pre-exp for SIA migration	c0i	9.4d-7	9.4d-7	9.4d-7
	Bardeen-Herring disl' source density	Sdisl	0.0d+22	0.0d+22	0.0d+22
	Modified back stress term, Roger=0.05	Aprime	0	0	0
	ik eim2 SIA 2-4i mig energy		1 0.11	1 0.11	1 0.11
	ik c0i2 Pre-exp mig		1 6.5d-8	1 6.5d-8	1 6.5d-8
Reaction cross	Loops capture efficiency for SIAs	zicl	1.01	1.01	1.01
section	Dislocation capture efficiency for SIAs	zi	1.01	1.01	1.01
	Dislocation capture efficiency for vacancies	ZV	1	1	1
	Void capture distance for SIA	rivoid	0.0d-9	0.0d-9	0.0d-9
	Dislocation capture efficiency for gas atoms	zgd	0	0	0
	GB capture efficiency for SIAs	zig	1	1	1
	GB capture efficiency for vacancies	zvg	1	1	1
	Emission energy for vacancy-trap complex	ebtrv	0.5	0.5	0.5
	Recombination constant	rec	2.0d+21	2.0d+21	2.0d+21
	V+crow: =1-pure 1D; =0-preferential	rkk	1	1	1
	EOS:1-Roger;(2 Carnahan-S;3?Manzke-T)	keybb	1	1	1
	Sigma for Carnahan-Starling EOS	sigma	0.2d-9	0.2d-9	0.2d-9
	v-v binding energy for Wolfer correct	e2v	0.3	0.3	0.3
	Wolfer corr: original	wolfn	-1	-1	-1
	i>nevf then Ev_binding=evf	nevf	10000	10000	10000
	=1 include punching of i from bubbles	keyart	1	1	1
Precipitates and	key: =1 change pre-existing microstructure	iliz	1	1	1
impurity atoms	bulk concentration of impurity atoms !Eliz	Ccarbon	0.0d-2	0.0d-2	0.0d-2
	impurity-vacancy binding energy !Eliz	Ebcv	0.5	0.5	0.5
	coordination number !Eliz	znn	8	8	8
	N_U: number of and N_pptU coefficients	N_U; N_pptU	0 +0e20	0 +0e20	0 +0e20
	_U: number of and R_pptU coefficients	R_U; RpptU	0 +0e-09 +0e-	0 +0e-09 +0e-	0 +0e-09 +0e-
	N_B: number of and N_pptB coefficients	N_B; N_pptB	0 +0.0	0 +0.0	0 +0.0
	B: number of and R_pptB coefficients	R_B;	0 +0.0 +0e-1	0 +0.0 +0e-1	0 +0.0 +0e-1
	Ppts B capture effic' for SIAs !Eliz	zipptB	1	1	1
	Trap effciency	rotrp	1	1	1
	ilpnum: number of and num_lp	ilpnum,	0 +0e+20 -	2 3.13e+20 -	0 +0e+20 -
	ilpr: number of and r_lp coefficients	llpr, r_lp	0 +0e-8 -0e-10 +0e-12 -0e-15	4 +1.68e-8 - 1.58e-10 1.20e- 12 -1.57e-15	0 +0e-8 -0e-10 +0e-12 -0e-15
Correlation-	T min damage for starting screening	phics0	1.0d+10	1.0d+10	1.0d+10
screening of voids	T max damage for complete screening	phicsm	1.0d+01	1.0d+01	1.0d+01
from 1-d SIA	smallest void screened [nm]	rwhcor	6	6	6
Voids: vacancies	Max size for generation (< mvxv)	mwm	9	9	9
	Exponent: gener rate ~ i**(-pnw)	pnw	1.94	1.94	1.94
	i > mvxv: groups	mvxv	30	30	30
	dr or dr/r for groups see below	drvv	0.12	0.12	0.12
	=1 - dr; =2 - dr/r for above choice	igrvac	2	2	2
	Factor: increase size of last group	ifac	1	1	1
	Min i visible	nvv	358	358	358
Interstitial loops	Max size for generation (<= mixl)	mim	10	10	10
	Exponent: gener rate ~ i**(-pni)	pni	1	1	1
	i > mixl: groups	mixl	20	20	20
	dr in groups	dri	6.0d-10	6.0d-10	6.0d-10
	Min i visible	nli	20	20	20

Table 6.9: Definition of reference case input. Changes between each reference case highlighted in yellow.



Figure 6.1: Main structure and sub routines in RIME model.



Figure 6.2: Effect of changing bias at 20 dpa on swelling at 460°C using Ref.2.



Figure 6.3: Effect of changing grain size at 20 dpa on swelling at 460°C using Ref.2.



Figure 6.4: Absolute value of significance of damage rate, temperature, grain size and bias. Treatment including with (Ref.2) and without unbiased G phase (Ref.2.G) are both included as a function of damage in RIME at 21 and 100 dpa.



Figure 6.5: Absolute value of significance of bias, interstitial migration energy, vacancy migration and formation energy, recombination coefficient and cascade efficiency. DD treatment (Ref.2) used with significance reported as a function of damage in RIME at 21 and 100 dpa from the start of the case run.



Figure 6.6: Comparison of cascade efficiency and dislocation loop and network bias for interstitials of 1% (solid lines), 2% (dashed lines) and 3% (dotted lines).



Figure 6.7: Measured a) void and b) loop fraction in HT9 irradiated with 5 MeV Fe⁺⁺ at 460°C to 188 dpa.



Figure 6.8: Experimental void distribution (blue columns) compared with RIME void distribution input (red line) into each case.



Figure 6.9: a) Radius and b) number density of dislocation loops in HT9 irradiated with 5 MeV Fe⁺⁺ from 188 to 650 dpa at 460°C. Interpolation is from experimental data.



Figure 6.10: a) Radius and b) number density of G phase in HT9 irradiated with 5 MeV Fe⁺⁺ from 188 to 650 dpa at 460°C. Interpolation is from experimental data.



Figure 6.11: a) Effective radius and b) number density of M_2X -phase in HT9 irradiated with 5 MeV Fe⁺⁺ from 188 to 650 dpa at 460°C. Interpolation is from experimental data.


Figure 6.12: Comparison of Ref.0 treatment (z_i^{net} =1.01) with experimental data in terms of a) network sink strength and b) void diameter, number density and swelling.



Figure 6.13: Comparison of Ref.1 treatment ($z_i^{loop} = z_i^{net} = 1.01$) with experimental data in terms of a) network and loop sink strength and b) void diameter, number density and swelling.



Figure 6.14: Comparison of Ref.2 treatment ($z_i^{loop} = z_i^{net} = 1.01$) with experimental data in terms of a) loop and network sink strength b) loop diameter and number density and c) void diameter, number density and swelling.

CHAPTER 7

DISCUSSION: CO-EVOLUTION OF THE IRRADIATED MICROSTRUCTURE

The following analysis discusses the results from ion irradiation experiments in the high damage/void growth-dominated swelling regime within the context of the cases from the Radiation Induced Microstructure Evolution (RIME) cluster dynamics model to understand how dislocations, voids and precipitates co-evolve at very high damage levels beyond 188 dpa.

7.1 Analysis Scope

The RIME model itself and this analysis in particular include a number of inherent assumptions, which limit the understanding of the co-evolution of the microstructure. The first limitation of the RIME model is that the model utilizes a mean field approach, which means that it is unable to treat variations in the microstructure from grain to grain and instead presents mean or aggregate results from the overall microstructure. The microstructure data measured and reported in Chapter 5 is representative of an overall microstructure by examining a large number of grains in order to obtain average results. (For instance, at least 30-50 grains were examined for void data at a given damage level.) Thus, both RIME output and the reported measurements reflect the mean or aggregate microstructure features and do not capture local variations or heterogeneity that is common to FM alloys.

Second, the code does not have the capability to model precipitate nucleation or growth; the experimentally determined evolution of the precipitates is provided as input to the code. The precipitate radius and density are parameterized by equations that describe their respective behaviors as a function of dpa. (Figure 6.10, Figure 6.11) The resulting sink strength is calculated in RIME and used to determine how defects are partitioned to the sinks according to the calculated sink strength, as well as how the defects at sinks are treated (as unbiased, biased or variable biased sinks or as recombination centers). However, the addition of defects to the sink does not alter the precipitate evolution, and they cannot be influenced by any of the other microstructure features in the model. Hence, precipitates can influence evolution of dislocations and voids, but not the reverse.

Third, the dislocation microstructure is treated as either experimentally input to the code (Ref.0 or Ref. 1) or is allowed to evolve dynamically by a model for dislocation loop and network growth provided in RIME (Ref.2). The experimentally input treatment can be described in two ways: either with network only or with network and loops as input. In one case, the dislocation network sink strength is set by the code and remains constant throughout the irradiation and the contribution of loops is neglected (Ref.0). In a second case, the loop radius and number density can be calculated from the experimental data and are included as an experimental input along with the network, thus prescribing the entire dislocation evolution (Ref.1). Therefore, Ref.1 allows the precisely observed dislocation loop and network behavior to be modeled. The third case, hereafter referred to as dynamic dislocation (DD) treatment, allows the dislocation loops and network to evolve according to models in the code [18,100], with the microstructure at 188 dpa serving as input (Ref.2). Void evolution is modeled in the code and is able to respond to dislocation and precipitate evolution.

Lastly, the microstructure evolution is only considered at damage levels from 188 to 650 dpa, where void growth dominates the swelling behavior, resulting in linear or near linear swelling. Starting with the already irradiated microstructure at a higher damage level avoids void nucleation effects reflecting void growth-dominated regime. Therefore, a sub routine "s01_preexist.f" was developed such that the network density, dislocation loop and void distributions, measured experimentally at 188 dpa (Figure 6.7), could be used as the starting microstructure at time t_o . Thus, each model case starts at 188 dpa. Although cases are run from nominally "0 dpa" in RIME, damage levels reported will reflect the total damage Φ_T , which is consistent with the experimental damage reported.

Another way to understand the various relationships that can be explored is shown in Figure 7.1. Precipitates serve as the independent variable, voids as the dependent variable and dislocations can serve as either. Given these conditions and assumptions, the following relationships are explored in depth:

- effect of dislocations on voids,
- effect of precipitates on voids,
- effect of precipitates on dislocations and
- combined effect of dislocations and precipitates on voids.

The discussion is organized in the following way: 1) for each microstructure relationship, the experimental data will be summarized. 2) Each modification in RIME from the reference case will be compared to cases Ref.1 or Ref.2. 3) The resulting behavior will be compared back to the experimental observations to understand how the microstructure behavior influenced evolution of the other features being studied.

The majority of this thesis has referred to voids and cavities interchangeably, with preference given to the "void" nomenclature. Given the high damage levels discussed, it is appropriate to describe all cavities as voids in this chapter, especially since there is no helium treatment included in the RIME cases.

7.1.1 Definitions of Modifications to Reference Cases

To aid in identifying specific cases, a system of flags for each microstructure treatment was created to denote modification from the reference cases. Inputs for each reference case were defined in Table 6.9. Table 7.1 presents a list of the flags and their meanings. Each flag is added to its respective reference case and multiple flags may be added to a single case. For instance, the inclusion of G phase to the experimentally input dislocation treatment is denoted "Ref.1.G." The inclusion of both G phase and M₂X to the dynamic dislocation treatment is denoted "Ref.2.G.MV." Thus, each case's input can be quickly and easily identified.

7.2 Effect of Dislocations on Voids

Examining the effect of dislocations on voids in the absence of precipitates represents the simplest model system and the most fundamental microstructure interaction when considering void swelling, which is driven by the dislocation bias for interstitials. Identifying appropriate values for the dislocation bias for interstitials was not a straightforward task. To date, no experimental methodology has been developed to measure the dislocation bias for interstitials. Typically, there are two approaches to selecting an appropriate bias. There are a number of analytic solutions based upon a variety of methodologies, including, for example, the stationary drift-diffusion equation

[137–139], atomistic interaction energy maps [48] or finite element analyses [137]. Second, and most commonly used in the literature, rate theory models tend to treat bias as an input parameter where it is estimated and used as a tuning parameter; the model results are then benchmarked to experimental results [18,27,41,114]. This approach is similar to the bias sensitivity study presented in Figure 6.2.

To further complicate bias selection, bias is expected to have a weak dependence on temperature, a stronger dependence on dislocation density and the strongest dependence on crystal structure [48]. In fact, it has been theorized that a lower dislocation bias is responsible for the swelling resistance of bcc steels versus fcc steels [41,140]. As such, results from the literature in the bcc iron system are given preference in this analysis.

Table 7.2 gives the ranges for each of the dislocation bias determination approaches. The largest variation in calculated bias is from analytic solutions which vary from 1.01-1.25. The wide range of bias values is due to bias calculated for different types of dislocation loops along different planes as was demonstrated by [48]. Chang *et al.* found bias for interstitials that ranged from negligible (nearly 1.0) for screw type dislocations up to 1.05 for edge <111> dislocations. Finally, rate theory biases are lower than all first principles calculations and nearly all analytic solutions, in both ferritic and austenitic steels [8,41–43,114,115]. For this application, and based upon the experimental observation of predominantly <100> loops (Figure 5.45) and Chang's results, a bias input range between 1.01-1.04 was deemed to be reasonable.

Furthermore, a parametric analysis of bias (Figure 6.2) revealed that swelling was highly sensitive to the bias. With this consideration, a default bias of 1.01 was chosen because of its

consistency with the literature, including the most relevant analytic solution from Chang *et al.* [48] as well as preliminary comparisons of the resulting swelling to observed experimental data (Figure 6.2).

7.2.1 Summary of Dislocation and Void Evolution

All experimental data for this analysis was performed at 460°C from 188 to 650 dpa and was previously presented in Chapter 5. To summarize, both the loop (Figure 5.47) and void number density (Figure 5.17) were nearly constant from 188 to 650 dpa. The loop number density (~2 to $3 \times 10^{20} \text{ m}^{-3}$) was consistently lower than that of the voids (~ $10 \times 10^{20} \text{ m}^{-3}$). The diameter of the voids grew linearly (~0.06 nm/dpa shown in Figure 5.16) as a function of damage whereas the loop diameter was nearly constant at approximately 25 nm from 188 to 375 dpa and then underwent a period of rapid growth, tripling in size (~90 nm) by the final damage level of 650 dpa (Figure 5.46). There appeared to be no direct correlation between loop and void diameter behavior. Loop sink strength was an order of magnitude (10^{13} m^{-2}) lower than that for either the network or voids (10^{14} m^{-2}), suggesting that loops might not be the controlling feature in terms of void behavior due to the low sink strength. The network and total dislocation sink strength (Figure 5.49) were very similar to the void sink strength, varying between 3 to $4 \times 10^{14} \text{ m}^{-2}$ from 188 to 650 dpa. All three sink strengths exhibited very slow increases over the void growth-dominated swelling regime, indicating a very stable system in pseudo-equilibrium.

Before results for the simple system of dislocations and voids are analyzed, the pre-existing microstructure, which provides the overall swelling environment prior to irradiation, must be considered as more fundamental. The main features of the overall unirradiated microstructure,

discussed in Section 5.1, are the preexisting dislocation network from processing, the grain boundaries and the $M_{23}C_6$ carbides, with corresponding sink strengths of 2×10^{14} , 8×10^{13} and 5×10^{12} m⁻², respectively. Clearly, the dislocation network is the dominant feature and will be analyzed in more detail in this section. The other feature to be considered from an overall microstructure view of swelling rate is the grain boundaries. (Carbides are not considered due to low sink strength.) Although changing the grain size and as a consequence, the grain sink strength, was shown to have a measurable impact on void behavior in the significance study in Figure 6.3, a change of grain size of 20% led to swelling decrease of less than 5% relative that from Ref.2. Furthermore, grain size is stable throughout the irradiation which precludes it from having an effect on evolution and the focus of this work is on how the microstructure co-evolves with damage level. For these reasons, grain size is not explored further to resolve overestimation of void swelling.

7.2.2 Case Ref.0: Experimentally input network dislocations

Analysis of model cases will begin with the most fundamental system of dislocations and voids in the absence of other features. The simplest treatment in RIME is case Ref.0, which includes only the network at a constant density of 3×10^{14} m⁻², which was the measured value at 188 dpa. The next most complex case, and incidentally, more experimentally accurate, incorporates the increase in network sink strength from 3 to 4×10^{14} m⁻² at 550 dpa. This increase was shown experimentally in Figure 5.44 and the case is referred to as "Ref.0.N."

The resulting comparison of Ref.0 and Ref.0.N is shown in Figure 7.2. In Figure 7.2a, it is shown that a modest increase in network sink strength resulted in a small increase in void sink strength. The resulting increase in void sink strength was due to an increase in void diameter. By

650 dpa, the final diameter was 75.1 versus 74.3 nm in the Ref.0.N and Ref.0 case, respectively. The resulting increase in void sink strength is also reflected in Figure 7.2b, where the void swelling rate slightly increased with respect to the reference case beyond 550 dpa.

This comparison suggests two conclusions. First, the simplest case, Ref.0, results in a reasonable approximation for swelling, despite considering only the network behavior. To fully model the microstructure, loops must be taken into account so that the model reflects the most accurate representation of the dislocation network behavior. Second, increasing the network sink strength by 33% resulted in an observable inflection point in the swelling curve at 550 dpa, demonstrating that void growth rates are very responsive to small changes in biased sink strengths.

7.2.3 Case Ref.1: Experimentally input network and loops

A further increase in both complexity and accuracy in representation of the experimental behavior in the dislocation treatment is case Ref.1. Ref.1 is simply Ref.0.N with the addition of experimentally input loop evolution, previously described in Section 6.2.2. Figure 7.3a compares the network, loop and total dislocation sink strength for Ref.0 and Ref.1. The red dashed line matched the experimentally input initial network density of 3×10^{14} m⁻² and the increase to 4×10^{14} m⁻² at 550 dpa (as in Ref.0.N). Loops are shown with blue dashed lines. The total dislocation network and loop sink strength is shown in green, and increases as a function of dpa. Overall, Ref.1 represents the experimentally observed dislocation loop and network behavior from Figure 5.49.

The resulting swelling is compared in Figure 7.3b. With the addition of the network and loop sink strength, swelling increased relative to the constant network treatment (Ref.0) by about

15% (from 23 to 26%) by 650 dpa. The addition of loops appreciably alters void behavior by promoting void growth, indicating that a biased sink with a sink strength an order of magnitude lower than for voids can still alter void behavior.

The simpler Ref.0 case was shown to be a reasonable approximation for void swelling behavior. However, since the experimentally input network and loop treatment in case Ref.1 is most representative of the experimental data, it will be used as the primary reference case for comparison with more complex cases and microstructure treatments later in this chapter.

7.2.4 Case Ref.2: Dynamic Dislocation Treatment

The final dislocation treatment is the case of dynamic dislocation (DD) evolution (Ref.2). The DD case is compared to Ref.1 in Figure 7.4. Figure 7.4a presents the sink strength behavior as a function of dpa from 188 to 650 dpa. Network sink strength (in red) was similar in magnitude between Ref.1 and Ref.2; however, the loop sink strength (in green) was higher in the DD treatment by approximately an order of magnitude $(10^{13} \text{ to } 10^{14} \text{ m}^{-2})$. The higher sink strength resulted in higher total dislocation sink strength in Ref.2 relative to Ref.1. Nevertheless, the void sink strength was quite similar between cases, which resulted in almost identical swelling behavior shown in Figure 7.4b.

The discrepancy between dislocation sink strengths is due to the increased defect flow of both vacancies and interstitials to loops in spite of the biased nature of the sinks. Even though there was higher biased sink strength in Ref.2, there was also a higher sink strength able to absorb vacancies as well as interstitials, even though interstitials are preferred at dislocations due to the 1% bias. The loops and network then respond to the increase in absorbed vacancies and interstitials, which decreases the total biased sink strength. The larger sink strength of loops in Ref.2, relative to Ref.1, also limited the vacancies available to diffuse to voids, but the overall flux of vacancies relative to interstitials at the voids was very similar for both cases. Figure 7.5 demonstrates this by plotting the net vacancies absorbed at voids as well as the total dislocation sink strength for Ref.1 and Ref.2. Figure 7.5 also shows that the total biased sink strength, i.e. loops and network in Ref.2 is greater than that in Ref.1 by approximately 75%, but the net flux of vacancies absorbed at voids (measured as a percentage) is similar between Ref.1 and Ref.2 (0.4% versus 0.5%) prior to 450 dpa and virtually indistinguishable after 450 dpa. Net flux of vacancies drives void growth, which in turn determines the swelling value or void sink strength, which was shown to be nearly identical in Figure 7.4. In other words, a 75% increase in biased sink strength resulted in a 25% increase in net flux. The differing behavior between interstitial sink strength and net flux at voids demonstrates the subtle interaction between bias, sink strength of loops and sink strength of voids in the DD case. When the network or loops have prescribed increases in bias, swelling always increases, but when the system is allowed to respond, the higher sink strength does not always result in higher swelling, as loops and network respond.

Another way to interpret this data is that swelling response may be insensitive to dislocation microstructure, for certain ranges of sink strength. A range of initial dislocation densities input into the DD treatment in Figure 7.6a shows the insensitivity of the DD treatment to initial conditions. All three swelling curves were nearly identical regardless of whether 3×10^{13} m⁻², 3×10^{14} m⁻² or 3×10^{15} m⁻² was input as the dislocation microstructure responds to either grow or shrink the network to those observed in Ref.2, with a total dislocation network and loop density of $\sim 6-7 \times 10^{14}$ m⁻². In contrast, when a similar range of dislocation network density (3×10^{13} m⁻² to 3×10^{15} m⁻²) was into the experimentally input case, swelling is much more sensitive to the

combined network and loop sink strength. Loop sink strength was kept at experimental levels. Below 8×10^{13} m⁻², there was not a large enough biased sink strength to cause swelling. As dislocation density increased up to 3×14 m⁻², the swelling increased in response. However, the swelling behavior was relatively insensitive to network density from 3×10^{14} m⁻² to 1×10^{15} m⁻². By 3×10^{15} m⁻¹⁵, there was a decrease in swelling due to the dominance of the dislocation network. This is further evidence that it is reasonable that there was no change in swelling between experimentally input (Ref.1) and DD (Ref.2) treatments despite the increased network sink strength in Ref.2.

The similarity of the resulting swelling (Figure 7.4b) between the DD treatment (Ref.2) and the experimentally input (Ref.1) is significant for several reasons. First, the consistency of these two cases lends confidence to using either case. Second, DD is also necessary as a reference case in which the dislocations are allowed to respond to changes in microstructure, such as with the formation of precipitates, as Ref.1 does not have the capability.

7.2.5 Comparison of Model to Experiment

Ultimately, the goal is to achieve void and dislocation evolution in RIME similar to that which was observed experimentally. Rationalizing discrepancies between the observed dislocation and void behavior can lead to insights regarding interactions between various microstructure features. Figure 7.7 presents a comparison of Ref.1 and experimental data. (Ref.0 is not compared to experimental results here, as it does not include loop behavior). Figure 7.7a demonstrates the accuracy of the experimentally input dislocation treatment, which acts as the independent variable is this analysis. Voids are the only dependent variable. The resulting void diameter, number density

and swelling resulting from this dislocation treatment are presented in Figure 7.7b. (Results from Ref.1 were previously compared to Ref.0 in Figure 7.3 and Ref.2 in Figure 7.4.) The void number density from RIME matched the experiment reasonably well, but the void growth rate and diameter were much higher, resulting in swelling that was overestimated by 62% (26% swelling in model versus 16% swelling in experiment) by 650 dpa. This result suggests that the model is too simplistic in its current form. Rather, there must be another microstructure feature or mechanism diverting excess vacancy flow from the voids [34,82]. Thus, examining dislocation and void behavior may be too simplistic.

An alternative explanation is that the bias used in this case was too high. Bias directly impacts the number of vacancies free to migrate and then grow the void. In all reference cases considered to this point, the bias has been keep at 1% for loops and networks, regardless of dislocation treatment. Since swelling was overestimated by 62% in Figure 7.7, a decreased bias case (Ref.1.1.007: $z_i^{lp} = z_i^{net} = 1.007$) was run with the experimentally input network and loops to determine whether decreasing the bias would result in a better match of the void microstructure. A number of lower bias cases were run for comparison, but only 0.7% is presented here. (A bias of 0.7% was presented as it provided the best match of the swelling microstructure with the experimentally input dislocation treatment, in the absence of any other features.) Since the dislocation treatment was experimentally input, the dislocation behavior was identical to that in Figure 7.7a and so was not included again. The swelling resulting from bias factors of 1.01 and 1.007 is shown in Figure 7.8. With lower bias (0.7%), the void diameter and swelling were much more consistent with experimentally observed void behavior. In particular, the diameter growth rate from 188 to 650 dpa was 0.067 nm/dpa relative to 0.082 nm/dpa in Ref.1, whereas the number density did not change with bias. The excellent matching with lower bias suggests one of two

things; first, the actual bias of the dislocations was lower than expected from literature. Previously mentioned, measuring biases is extremely difficult, but most literature suggests that biases are somewhere between 1-5% for ferritic-martensitic alloys; no references were found with bias below 1% [41,48,114,115,137].

Assuming dislocation bias in the absence of any other effects remains at 1%, an alternative explanation is that there was another feature or mechanism that lowers the effective bias below the expected levels. One similar mechanism suggested in the literature by Little [121,122,141] was that interstitial solutes such as C and N may form Cottrell atmospheres around dislocation core. Cottrell atmospheres can relax the dislocation strain field, which thus decreased the dislocations' effective bias. In extreme cases, it was also hypothesized that eventually the bias would be reversed as interstitials were trapped at the dislocations [122,142] creating an artificial preference for vacancies. There is no mechanism in RIME to account for such a phenomenon and there is no experimental technique to confirm this interaction mechanism directly.

It was previously observed that void results from the experimentally input reference and the DD reference were very similar (Figure 7.4). For completeness, the DD reference (Ref.2) is also compared to experimental data in Figure 7.9. (Results from Ref.2 were also compared to Ref.1 in Figure 7.4) Figure 7.9a shows the resulting dislocation loop and network behavior. The dislocation network sink strength was quite reasonable (remains between 3 to 4×10^{14} m⁻²). The loop sink strength is overestimated, which was due to the higher than expected loop number density from RIME ($\sim 1 \times 10^{21}$ m⁻³ Figure 7.9b) compared to experiment ($\sim 2-3 \times 10^{20}$ m⁻³). The loop diameter reflects approximately the average of what was experimentally observed as a function of dpa either ~ 25 or 80 nm at low and high damage levels, respectively. Since the diameter is a direct result of

RIME inputs, this was deemed a reasonable assumption, but the consequences of this will be discussed further in Section 7.4.2.

The void results are plotted in Figure 7.9c. Similar to Ref.1 (Figure 7.7b), the number density was accurately captured but the diameter/diameter growth rate was too high (0.080 nm/dpa, which was consistent with Ref.1). Again, the resulting void swelling is higher than expected.

Table 7.3 compares the various treatments presented in Section 7.2 and how well they match observed experimental behavior. Both experimentally input Ref.1 and DD treatment (Ref.2) results in overestimation of void swelling in general. The high swelling was mitigated by lowering loop and network bias to 0.7% (Ref.1.1.007) to yield more realistic void results. However, 0.7% is below most suggested biases even for low swelling FM alloys.

The major conclusion of this analysis of dislocations and voids only is that there is a systemic overestimation of final swelling value at 650 dpa in the model relative to experiment by 63% (26% swelling was observed in model relative to 16% in the experiment), in both Ref.1 and Ref.2. Thus, it follows that there is some other mechanism inhibiting the effective bias of the system or acting as a sink to divert defect flow away from the voids. Although lowering the effective bias is an attractive option in matching the void swelling behavior, the bias required is below any reported in the literature and is therefore not convincing as a possible mechanism. Thus, the effect of other sinks is likely the cause. Since the other major features in the microstructure that are continuing to evolve at high damage are precipitates; precipitates will be analyzed next to determine if they provide a sufficiently effective alternate sink for defects.

7.3 Effect of Precipitates on Voids

For the purpose of this analysis, G phase and M_2X are treated separately. G phase and M_2X vary in terms of both their sink character (incoherent and coherent, respectively) and their evolution with dpa. First, G phase and its effect on voids will be addressed.

7.3.1 G Phase

G phase is analyzed first as the behavior of G phase in the irradiated microstructure is better understood as a result of being a commonly observed irradiation-induced precipitate [7,9,10,31,51,52]. In addition, incoherency [88,143] and that effect on precipitate-defect interactions [20] is better understood for G phase than for coherent M₂X.

G phase was confirmed to be an incoherent precipitate from HRTEM analysis presented in Section 5.3.1 in Figure 5.29, which is consistent with what is reported in the literature [88,143,144]. The evolution of G phase diameter and number density were presented in Figure 5.26, but a brief summary and comparison to voids is included here. The diameter increased at a nominally linear rate over this dpa interval, similar to voids, although the linear rate was nearly an order of magnitude lower than the void growth rate (~0.06 nm/dpa versus ~0.01nm/dpa for G phase and voids, respectively). G phase and voids had roughly constant number density from 188 to 650 dpa (Figure 5.9 and Figure 5.30) leading to an approximately linear volume fraction increase, which is reflected in Figure 5.26. Thus, G phase volume fraction tracked void swelling albeit at an order of magnitude lower, with a corresponding sink strength an order of magnitude lower (4 to $9 \times 10^{13} \text{ m}^{-2}$ relative to 3 to $4 \times 10^{14} \text{ m}^{-2}$ for voids). The correlation of the diameter and number density

behavior are additional supporting evidence that the interaction of both of these sinks with defects is identical i.e. they are both incoherent, unbiased sinks, which have no preference for either type of defects. For these reasons, G phase is treated as an unbiased sink in RIME.

The effect of G phase on void sink strength and swelling is compared to Ref.1 in Figure 7.10. With the addition of G phase, void sink strength decreased due to decreased void diameter. (Figure 7.10a) In the presence of G phase, void swelling reflected the lower void sink strength (Figure 7.10b). Although overall swelling/swelling rate decreased visibly with the addition of G phase, the overall effect was minimal. The final swelling at 650 dpa was 24.7% relative to 26.1% without G phase, which is a decrease of about 5%, which is not judged to be statistically significant, especially since the swelling was overestimated by 55% relative to experiment. The lack of effect is likely due to a combination of both the low sink strength and the fact that G phase is an unbiased sink unlike biased loops, which were still effective at a lower sink strength.

Figure 7.11 presents a comparison of the results of Ref.1.G with the experimental results. (The results from case Ref.1.G were also included in Figure 7.10.) Figure 7.11a shows the sink strength of the loops, network and G phase as a function of dpa. All sink strengths match experimental data as they are experimental inputs. Figure 7.11b presents the resulting void diameter, number density and swelling with the addition of the G phase treatment. The void number density is unaffected, but the diameter growth rate and swelling remained overpredicted relative to that observed in experiment. The combination of Figure 7.10b and Figure 7.11b show that although G phase decreases the final swelling value by ~5%, it is not a strong enough effect to resolve the overestimation of void swelling consistently observed in Ref.1.

Thus, G phase had a minimal effect in resolving the overestimation of swelling due to its low sink density. It was found to decrease overall swelling by 5% of the final swelling from 26.1% to 24.7%, which was insufficient to serve as an alternate sink in a meaningful capacity. Therefore, the effect of M_2X is now considered as a possible alternate sink to resolve the overestimation of void swelling.

$7.3.2 \underline{M_2 X}$

The formation and evolution of M_2X in this material is significant as irradiation-induced M_2X has been observed in only a few studies to date [38,53,90,145]. Furthermore, the interaction of coherent sinks or interfaces with irradiation induced defects is much less well understood than with incoherent sinks.

The evolution of M_2X with increasing dpa was previously presented in Figure 5.41 but is compared directly to void evolution in Figure 7.12. Voids demonstrated nearly linear growth from 188 to 650 dpa whereas M_2X grew rapidly up to 450 dpa then saturated. M_2X number density peaks at 450 dpa, then drops leading to a corresponding decrease in volume fraction. (Figure 7.12) The drop in number density has been attributed to loss of coherency leading to destabilization of the M_2X , which has been observed in the literature [38,52]. From 188 to 650 dpa, swelling rate appeared to be independent of the formation and growth of M_2X , which is consistent with some reports in the literature [126,127], despite the large sink strength (10^{14} m⁻²), which was the same order of magnitude as both void and dislocation network. M_2X was verified to be a semi-coherent sink up through 650 dpa, using HRTEM analysis presented in Section 5.3.2 (Figure 5.39), consistent with recent results from Wang *et al.* in a Fe-12Cr HT9 analogue [90] and from Borodin *et al.* in a Fe-13Cr FM alloy [38]. There are several competing theories regarding the behavior of semi-coherent or coherent sinks [20,122,146] in the microstructure. Having established the semi-coherency of M_2X , there are two possible precipitate treatments that are appropriate: as a variable biased sink or as a recombination center. The formalism for each of these treatments was compared in Section 6.2.4, but each will be summarized here.

The first treatment is that of a variable biased sink (MV). The bias for either vacancies (Y_v) or interstitials (Y_i) changes as a function of damage based upon d_ic_i and d_vc_v (Equation 6.39) and Y_v is calculated from Equation 6.40 using a first order approximation of recombination at the sink (δf) from Equation 6.41. Y_i , Y_v evolve as a function of dpa unlike the loop bias for interstitials (z_i^L). Thus, the sink strength for either vacancies or interstitials adjusts as a function of damage level; the M₂X sink strength has an affinity for whichever defect is dominant at any given time so that any given time. This formalism was developed from theoretical work performed by Brailsford and Bullough [127,146].

A more rigorous treatment of M_2X treats precipitate surfaces as partially or fully efficient recombination centers (MR) that form at the precipitate-matrix interface due to the strain at the interface, which traps vacancies that are then annihilate by the more mobile interstitials. M_2X has a slightly smaller lattice parameter than the matrix (0.279 versus 0.286 nm, respectively). This puts the matrix near the interface in a state of compressive stress, making a vacancy trap. Measurement of the strain energy in the ferrite due to M₂X ranges from 0.06 to 0.16 eV from [147,148]. Alternatively, the misfit strain energy, calculated from the strain and lattice parameter, for a semi-coherent precipitate is typically reported as 0.15 to 0.38 eV [149]. The misfit strain energy for a semi-coherent precipitate represents an upper bound on vacancy-trap emission energy for a coherent or semi-coherent precipitate. With these ranges providing context, a comparison of swelling with increasing emission energy for vacancy-trap complex ($E_b^{v,tr}$) is shown in Figure 7.13. With increasing trap binding energy, the swelling decreased as expected as the drive to emit vacancies decreases. Based primarily upon the results from the literature and also considering the results of Figure 7.13, a trap energy of $E_b^{v,tr}$ =0.1 eV was chosen as default energy for comparison to the variably biased treatment. Since the range reported in the literature of M₂X in ferrite is 0.06 to 0.16 eV and the upper bound imposed on coherent precipitates of the strain energy of a semi-coherent precipitate is from 0.15 to 0.38 eV, 0.1 eV is reasonable.

Using the chosen trap energy of $E_b^{v,tr}$ =0.1 eV, the recombination center treatment (Ref.1.MR) and variable biased treatment (Ref.1.MV) are compared in Figure 7.14 with an explicit dislocation network and loop treatment. The swelling behavior is nearly identical, indicating the reasonability of using either sink treatments, which was not unexpected as they have very similar underlying mechanisms with a recombination component. The Brailsford formalism that was incorporated into the MV treatment is based upon a combination of the balance between d_ic_i and d_vc_v , and the term f_v is a first order approximation for recombination expected at variable biased sink. Furthermore, both corrections are based upon the surface area and sink strength. So, the interaction mode is perhaps less important than the high sink strength of M₂X. Thus, the similarity of results lends confidence to 1) the chosen trap energy and 2) both precipitate treatments.

Since the recombination center and variable biased treatments are so similar for the $E_b^{\nu,tr}$ considered, Ref.1.MV treatment was chosen as the default M₂X precipitate treatment for continued analysis and is compared to the experimental results in Figure 7.15. (The case presented here was the same as that shown in Figure 7.14.) The sink strength for M₂X, loops and network is plotted in Figure 7.15a and the resulting void diameter, number density and swelling is plotted in Figure 7.15b. The void number density remains reasonable (10^{21} m⁻³) and the growth rate and swelling are still overpredicted with respect to swelling. However; compared to the Ref.1 case, the void behavior is trending in the correct direction with the addition of M₂X. For Ref.1, swelling was overpredicted by 62% (26.1% versus 16% observed in experiment) whereas for Ref.1.MV swelling was overpredicted by 25% (18.8% versus 16% observed in experiment), indicating that the M₂X precipitate is a significant feature in the overall defect partitioning.

Some studies suggest that coherent sinks should not have an effect on void growth at effective radii larger than 10 nm [128]. For comparison, the effective radius of M_2X is 18 nm at 250 dpa, where they are first observed. The results from the modeling are exactly the opposite; Ref.1.MV shows that M_2X does have an effect on void growth, which is proportional with precipitate size. In other words, there was no M_2X size observed above which the effect on void growth became negligible.

 M_2X was shown to have a strong impact on the overall void swelling by serving as a variable biased sink or recombination center, either of which have been result in very similar swelling behavior. The primary effect of M_2X was to serve as an alternate sink for vacancies which limited the amount of vacancies free to diffuse to and grow the void. The ultimate decrease in

swelling was from 26.1% to 18.8%, a 21% decrease in swelling relative to final swelling from Ref.1.

7.4 Effect of Precipitates on Dislocations

The effect of precipitates on dislocations will be discussed first for G phase followed by M_2X .

7.4.1 G Phase

G phase is treated as an unbiased sink and Ref.2 will be used as a reference case for this section. Ref.2 is used as dislocations are responsive to changes in microstructure unlike in the case of Ref.1. The evolution of G phase with dpa was previously presented in Figure 5.30 and the evolution of dislocation loops and network were shown in Figure 5.46, Figure 5.47 and Figure 5.49. G phase diameter exhibited nearly linear growth with dpa, whereas loop diameter exhibited sudden growth from 375 to 450 dpa (23 to 78 nm, respectively). G phase diameter was also considerably smaller (11 to 20 nm) than loop diameter (23-92 nm) at any given dpa. Number density of both G phase and loops was stable from 188 to 650 dpa, indicating that nucleation of new G phase or loops was minimal in this regime, which was consistent with the high damage levels considered. There was no correlation in diameter or volume fraction, indicating that there was likely no effect of G phase on dislocation network or loops, especially considering the low G phase sink strength.

Figure 7.16 shows the effect of G phase on dislocation loops with the dynamic dislocation treatment. There was a decrease in both loop and in network sink strength (Figure 7.16a) with the

addition of G phase as an alternate sink. The decrease in loop strength was a consequence of lower loop density (Figure 7.16b). Furthermore, the lower loop density provided a lower overall network source term, so there were fewer loops available to grow and join the network leading to the lower network sink strength shown in Figure 7.16a. Loop diameter was not affected as the loop diameter was set by the number of interstitial groups, the consequence of this will be discussed in Section 7.4.2. As was the case with the effect of G phase on voids (Figure 7.10), there was an insignificant impact on overall dislocation loop or network behavior, which was attributed to the low sink strength relative to the other features in the microstructure [20].

For completeness, Figure 7.17 compares the results of Ref.1.G (case previously presented in Figure 7.16) with the experimental observations. The overall network sink strength is very similar to that observed experimentally (Figure 7.17a), but the loop sink strength remained too high, which is a consequence of the overestimated loop density (Figure 7.17b). The loop sink strength but was marginally closer (5%) to the experimental observations than in the case of Ref.2 for both loop number density and sink strength. The improvement on loop sink strength was a decrease of 5%, which was especially insignificant considering that an improvement of 250% is required to match the results seen experimentally.

The addition of G phase had an insignificant impact (5% decrease) on loop and network sink strengths and was therefore not sufficient to resolve discrepancies between model and experiment. Furthermore, there is no observed correlation in terms of the experimental behavior i.e. loop and G phase growth behavior at the high dpa levels considered. Therefore, G phase has little effect on dislocation loop or network behavior, due to its low sink strength and it can be concluded that G phase has minimal effect on co-evolution of the microstructure.

7.4.2<u>M₂X</u>

A direct comparison of loop and M_2X diameter and length and number density from experiment are shown in Figure 7.18. The results are striking; the period of sudden growth in loop diameter corresponds with the period of large growth and nucleation of M_2X by 450 dpa, indicating there may be some correlation between the two features. After this sudden growth, both M_2X and loops saturated. Loop number density slowly decreased from 188 to 650 dpa, but M_2X number density peaked at 450 dpa before decreasing.

The correlation between loop growth and the increase in M_2X length and density suggests that they may be linked. If the formation of M_2X is considered from a microchemical perspective, precipitation results in both chromium and carbon being pulled out of solution. Both chromium and carbon have been observed to suppress loop growth relative to that in pure iron [122,150,151]. Suppressed growth is due to enrichment of either species at the dislocations pinning the loops limiting growth. To further explore linkages between the M_2X and dislocations, Ref.2.MV will be compared to Ref.2.

 M_2X is treated as a variable biased sink in this section (Ref.2.MV) and all dislocation behavior will be compared to Ref.2. The addition of the variable biased M_2X is compared to Ref.2. in Figure 7.19. By 450 dpa, the sink strength of M_2X is the same order of magnitude as the network and loops and remained similar to the total dislocation sink strength at its peak concentration at 450 dpa (Figure 7.19a). As M_2X grows in sink strength, a corresponding drop in network and loop sink strength was observed relative to the reference case, which was a consequence of the decreased loop number density shown in Figure 7.19b. M_2X and loop density are inversely proportional. Since network sink strength is a function of increasing loop sink strength as loops grow, there was also a decrease in network sink strength as a result of the high sink strength of M_2X .

Figure 7.19b showed that there was no effect of M₂X on the loop diameter. It was previously observed that a limitation of the RIME model is the insensitivity of loop diameter to either dpa or other microstructure interactions, after a period of initial loop and network instability from the beginning of the case run (Figure 7.17). This insensitivity is a consequence of the loop diameter being defined by the number of interstitial cluster groups and the maximum group size before loops "join" the network; both of which are model inputs. The reference number of interstitial cluster groups is 120, which resulted in an average loop diameter of 60 nm. The number of interstitial cluster groups cannot be changed mid irradiation without causing major instabilities in the loop, network and void behavior. As such, there was no way to include a mechanism such that precipitates could affect diameter, which was postulated earlier based upon experimental observations. As an alternative analysis, two different cases were compared to determine how changing diameter by changing number of interstitial cluster groups would affect the dislocation number density with the assumption that carbon precipitating into M₂X was the cause of the dislocation diameter increase. M₂X is still treated as a variable biased sink (Ref.2.MV) for these cases.

Figure 7.20a shows the corresponding change in loop and network density using 60 or 160 interstitial cluster groups. The number of groups was chosen to reflect the average diameter of the loops from 188 to 375 dpa (25 nm: 60 interstitial groups) and from 450 to 650 dpa (80 nm: 160 interstitial groups). Loop sink strength was much higher in the 160 group case (4×10^{14} m⁻² versus 5×10^{13} m⁻², respectively) and the network was comparable (3×10^{14} m⁻² versus 2×10^{14} m⁻² in 160

and 60 group cases, respectively). With 60 groups (Figure 7.20b), the loops had a smaller diameter (~25 nm) and a lower number density. With the increase in number of interstitial cluster groups, both the diameter and number density increases. Thus, diameter and number density of loops are strongly correlated.

Overall, Figure 7.20 demonstrates two significant limitations of the RIME model. First, dislocation diameter was more or less stagnant with increasing damage level. This assumption is consistent with literature results from FM alloys suggesting that there was little overall evolution in loops beyond 10 or 20 dpa [16,17]; however, this was not reflected in these new experimental results at very high damage levels. (Figure 5.46) As such, adding an additional treatment to model the loop diameter evolution is outside the scope of this thesis, but would improve the quality of dislocation modeling. Moreover, the loop growth at high dpa is one of the most significant findings of the ion irradiation experiments and is not captured in RIME.

The second limitation highlighted by these cases is the artificial interdependence of dislocation loop diameter, number density and network density. As diameter increases, the number density is forced to increase as a result of more loops growing before joining the network, since the maximum radius (r_{max}) before loops "join" the network is a function of the number of interstitial cluster groups. r_{max} is set by the number of interstitial groups (mil) and the group size (dri). Thus, as loops become larger, the radius/diameter at which they join the network is a function of this r_{max} since at r_{max} , the cluster group changes from being defined as an interstitial loop of radius r_{max} to being part of the network. Since the overall sink strength due to interstitial clusters is more or less the same regardless of r_{max} since the bias for loops or network is the same (minus an additional annihilation term for the network, shown in Equation 6.19), then r_{max} is the point at which

interstitial clusters change from being defined as loops or network. In general, as r_{max} increases the loop density, diameter and sink strength increases but the network sink strength decreases.

A more realistic view of dislocation evolution is that which was observed experimentally. Loop number density decreases slowly while loops grow to sizes large enough to join the network, evidenced by the increased network density at 550 dpa. This is consistent with the void behavior in the high damage regime; constant void number density with the growth of voids causing increased void sink strength/swelling.

Returning to the Ref.2.MV case with the reference number (120) of interstitial cluster groups for consistency (previously presented and compared to Ref .2 in Figure 7.19), Figure 7.21 compares results from the model to experimental results. Figure 7.21a presents the loop, network and M₂X sink strengths as a function of dpa. Similar to previous cases, the network behavior in both model and experiment were in reasonable agreement ($\sim 3 \times 10^{14} \text{ m}^{-2}$). With the addition of M₂X, the overall loop sink strength ($2 \times 10^{14} \text{ m}^{-2}$) was closer to the experimentally observed values ($\sim 3 \text{ to } 5 \times 10^{13} \text{ m}^{-2}$). The sink strength was an order of magnitude too high, but the loop sink strength decreased by a maximum of 75% from the Ref.2 case, relative to 250% decrease required to match experiment. The lowered loop sink strength was a result of the decreased loop number density with the addition of M₂X (Figure 7.21b). Again, the loop number density was closer to the experimentally observed values but remained too high ($9 \times 10^{20} \text{ m}^{-3} \text{ versus } 2-3 \times 10^{20} \text{ m}^{-3}$). Therefore, overall dislocation behavior is more realistic with M₂X, but exact matching with the experimental data was still not achievable.

The analysis of the effect of M_2X on dislocations has two overall conclusions. First, M_2X , when treated as a variably biased sink, has a measurable effect on loop and network behavior indicating that M_2X not only suppresses void swelling, but also dislocation loop formation. Second, the limitations of the RIME treatment of dislocations preclude development of a mechanism that explains the period of enhanced growth from 375 to 450 dpa on the basis of the variable biased treatment, but the experimental observations are strong evidence of an indirect effect of M_2X precipitation that pulls carbon out of solution, which will be discussed next.

7.5 Carbon Trapping

The behavior of carbon in the microstructure of FM alloys is one of the least well understood topics in radiation effects and presents a significant challenge. The precipitation of M₂X is intimately linked with carbon and its behavior both in solution and as a secondary phase. The precipitation of M₂X will pull carbon out of solution. Carbon can act as a solute trap for defects, and solute traps have been shown to inhibit swelling and loop growth [150,151]. Solute traps can also cause an indirect interaction mechanism between M₂X and voids/dislocations. Thus, M₂X can interact both directly, by acting as a sink or recombination center for defects, and indirectly, by removing carbon from solution and reducing the number of traps in the bulk. Both effects are incorporated into the overall model of the system through the addition of solute traps, modeled as a change in the effective vacancy migration energy in Section 6.2.3.

The removal of C from solution to form M_2X is predicated on the detrapping of C from Cottrell atmospheres i.e. the solutes that diffuse to the dislocation core, which inhibit dislocation movement [122]. The binding energy of a C atom to a dislocation was determined using a molecular statics approach by Veiga *et al.* to be approximately 0.41 or 0.65 eV for edge and screw type, respectively. Since it is difficult to determine the loop character in ferritic-martensitic alloys especially after irradiation, 0.5 eV was chosen as an approximate trap energy. A carbon-dislocation binding energy of 0.5 eV is very similar to the C vacancy trap energy, which has been estimated to range anywhere from 0.36 to 0.57 eV [123–125,152]. While the trap strength is the same, still lacking is a mechanism for removal of C from the loops.

An alternate interpretation of the system is that of dynamic dislocation nucleation and growth. Although number density of loops is slowly decreasing in the 188 to 650 dpa range, there are likely new loops nucleating and growing till they join the network at large enough sizes, characteristic of a pseudo steady state. As carbon is pulled out of solution that was not already formed into solute atmospheres, more of these newly nucleated loops are free to grow without the restraint of carbon to trap them. Thus, even if the C is unable to be de-trapped from the existing loops, the overall loop distribution expands in terms of length and the average diameter increases.

HT9 has 0.2 wt% C, which corresponds to 0.92 at%, or 9200 appm C. The solubility of carbon at 460°C is 855 appm C. A calculation was performed to account for the amount of carbon precipitated into M₂X at 450 dpa, where peak volume fraction of carbides was observed. M₂X has a hexagonal crystal structure with a=0.272 nm and c=0.452 nm. By calculating the number of unit cells contained in the observed M₂X, the C number density can be obtained (3.71x10²⁶ m⁻³) and compared to the number density of HT9 (8.34x10²⁸ m⁻³). This results in a maximum of C concentration of 3940 appm retained in M₂X. A comparison of the accounting for carbon in HT9 in the as-received condition and at 450 dpa is compared in Figure 7.22. Of the 9200 appm C total in the microstructure, a majority of the carbon is unaccounted for in the as

284

received condition and nearly half of the carbon is unaccounted for even at the peak volume fraction of M_2X at 450 dpa. The unaccounted carbon may be at grain boundaries, segregated to voids or other interfaces, in $M_{23}C_6$ carbides and also at small carbides at high density, such as vanadium carbides (MX) or small M_2X , which are more difficult to image or quantify. Furthermore, it is not possible to determine source of the C in the M_2X experimentally, so C may diffuse from any or all of these sources mentioned.

To determine the approximate amount of carbon removed from solution, the range 0 to 3940 appm was examined in Figure 7.23. But first, the effect of carbon on dislocation and swelling behavior must be determined by adding in its effect on vacancy mobility. Figure 7.23a reveals that increasing the amount of carbon in solution above 100 appm affects dislocation network and loop sink strength. It was assumed in the model that carbon was only allowed to trap vacancies causing decreased effective vacancy diffusion coefficient. Above 500 appm, the network sink strength remained constant or slightly increased, which was not consistent with results from Ref.2. Furthermore, above 500 appm, the simulation failed entirely at 380 and 260 dpa with 1000 and 3940 appm C, respectively. The simulation failure was due to a negative swelling rate which caused voids to shrink (Figure 7.23b), and was attributed to such a high trap strength that vacancy diffusion decreased to the point where voids began to shrink.

The effect of carbon in solution from 0 to 3940 appm on void swelling is presented in Figure 7.23b. There was no major effect on swelling until at least 100 appm C is included in the model. Beyond 100 appm, there was significant decrease in void swelling rate, by an order of magnitude from approximately 0.05 to 0.001%/dpa and even resulted in a negative swelling rate previously mentioned with 1000 and 3940 appm C.

While there is no way to directly measure or characterize the amount of carbon in solution contributing to vacancy trapping, the effect of C addition or removal can be modeled to assess its effect of vacancy mobility and therefore, dislocation and void evolution. The failure of the cases run with 1000 or more appm C means that these are not appropriate C amounts of carbon. With 500 appm C, the dislocation behavior diverges significantly from what is observed in the reference cases. Furthermore, the decrease in swelling rate is an order of magnitude, which is not consistent with experimental swelling results (Figure 7.23b). At 100 appm, there is only a minor effect on the network and loop behavior and a measurable effect on swelling. Below 100 appm, there is a negligible effect on the swelling behavior. Thus. 100 appm was chosen as an appropriate amount of C removed from solution by precipitation of M_2X .

Furthermore, an even more realistic treatment of carbon is to assume that the 100 appm decreases as a function of dpa until 450 dpa, at which point, the carbon is completely removed by the precipitation of M₂X. The resulting treatment is presented in Figure 7.24. Physically, this represents the case of carbon gradually removed from solution with the precipitation of M₂X. There was a modest decrease in swelling rate as expected, but after the gradual removal of C from the system, swelling rate increases to its nominal rate represented by Ref.2 in blue. Note that there is a clear parabolic shape of the curve as a result of removal of carbon from solution indicating a monotonic increase in swelling rate, that accelerates after the full removal of carbon from solution. For comparison, the instantaneous swelling at 300 dpa was 0.043%/dpa compared to the instantaneous swelling rate at 500 dpa, which was 0.055%/dpa (measured from 450 to 650 dpa). This can also be approximated as two regions of linear swelling: 0.042 (measured from 188 to 450 dpa) to 0.055%/dpa. As noted before in Figure 5.19, either linear regression or calculation of an

instantaneous swelling rate from the parabolic regression results in very similar swelling rate values.

A comparison between experimentally input and DD treatments with 100 appm carbon removed in a stepwise fashion from 188 to 450 dpa is given in Figure 7.25. The effect of carbon is much stronger in the case of the experimentally input case (Ref.1.C) resulting in final swelling of 21.2% versus 24.3% in the DD treatment (Ref.2), which is only a modest decrease from the reference case (26.1%). The suppression is mitigated in Ref.2 because the carbon also has a small impact on loop and network sink strength. The loop and network sink strength are actually 8 and 5% lower than the Ref.2, which effectively frees up more vacancies to diffuse to the voids. In contrast, the experimentally input case (Ref.1.C) does not respond to the changes in d_ic_i and d_vc_v , and the loop and network remains the same as in Ref.1. The carbon treatment is the only microstructure treatment that has a major difference in response between Ref.1 and Ref.2 unlike in precipitate treatments where the difference between treatments is negligible (below 5%), such as the case of G phase and M₂X. It can also be seen in Figure 7.25 that the parabolic shape is exaggerated.

Figure 7.24 demonstrated the effect of accounting for carbon in solution from 188 to 450 dpa, which suppressed void growth prior to the removal of the C in Ref.1.C consistent with mechanisms suggested in [122,141]. If carbon works to suppress swelling both as a solute trap and formed into a sink, this dynamic process could explain why no obvious decrease in void swelling with M₂X was observed in experiment. In other words, the suppression of swelling by M₂X was compensated by the loss of suppression of C in solution.

A more comprehensive description of M_2X in the microstructure is as both a sink and corresponding microchemical effect. Thus, M_2X should act as a sink for the entire growth-dominated regime as well as a consumer of carbon form solution; this interpretation is presented (Ref.1.MV.C) in Figure 7.26 and compared to the effect of M_2X alone (Ref.1.MV) and Ref.1. Compared to either Ref.1 or Ref.1.MV, accounting for the presence of carbon below 450 dpa suppresses swelling by an additional factor. The swelling rate is visibly reduced in the range of 188 to 450 dpa (0.025%/dpa measured instantaneously at 300 dpa); the swelling rate increased to 0.038%/dpa measured instantaneous at 500 dpa. However, the average swelling rate measured by linear regression from 188 to 650 dpa, is 0.03%/dpa, which is consistent with that observed experimentally in Figure 5.18. The agreement in overall swelling rate from 188 to 650 dpa between computational result and experiment provides confidence in the modeling that major interactions are being captured.

For completeness, the simple case of only carbon (Ref.2.C) is compared to experiment in Figure 7.27. (Results from this case were previously presented in Figure 7.25.) Network behavior remains reasonable $(3-4\times10^{14} \text{ m}^{-2})$ and the loop sink strength is still an order of magnitude too high (Figure 7.27a). Again, as with all cases analyzed, the loop sink strength is a consequence of the higher than experimentally observed loop number density in Figure 7.27b. Finally, void diameter and swelling are more consistent with experiment until 450 dpa (Figure 7.27c), but the swelling and growth rate increases once carbon is fully taken out of solution, leading to a final swelling values of 24.3% relative to the expected 16%, which represents a decrease in swelling from the reference case (Ref.2) of 7%.

The behavior of carbon has been linked to formation of M_2X as an indirect microchemical effect. Carbon in solution has been shown to have a strong effect on the swelling, decreasing the swelling from 26.1% to 21.1% for Ref.1 and 24.3% for Ref.2, when 100 appm of C in solution were accounted for up to 450 dpa. The discrepancy between cases was resolved by the observation of a modest decrease in dislocation loop and network sink strength, which decreased the amount of biased sink strength available in the system relative to Ref.2. The implementation of this mechanism was supported by experimental observations of the precipitation of large amount of M_2X , which was correlated with increased loop growth.

7.6 Combined Impact of Microstructure Features on Voids and Dislocations

Previous analyses in this discussion have shown the behavior of various microstructure features and treatments relative to the reference cases. On their own, no single interaction was able to completely resolve the discrepancy between the expected void behavior in experiment and model, regardless of whether dislocation microstructure was experimentally input (Ref.1) or was dynamically developed (Ref.2). Since void swelling was overestimated in all cases, it is reasonable to assume that there is a combination of interaction mechanisms in play. Both the precipitate (G phase + M_2X) and the carbon treatment will be included to determine whether the combined treatments can account for the dislocation/void discrepancy or if there is an additional process that was not captured in this version of the RIME model. G phase will continue to be treated as an unbiased sink. M_2X will be treated as a variable biased sink (MV) according to Brailsford formalism, since the recombination center treatment was shown (Figure 7.14) to be nearly identical for the trap energy considered.
A case with the full microstructure treatment and experimentally input dislocation (Ref.1.G.MV.C) is shown in Figure 7.28. Figure 7.28a shows the sink strength evolution of the network, loops, G phase and M₂X. There is a small discontinuity in the M₂X sink strength at 450 dpa due to the sudden increase in $d_v c_v$ when carbon in solution is removed as the effective sink strength responds to the change in defect kinetics. Figure 7.28b shows near perfect match of experimentally observed swelling, with 16.4% from the model case Ref.1.G.MV.C and 16% experimentally, indicating that M₂X, G phase and carbon in solution are all needed to resolve excess vacancy flux from the dislocation loops and network. Most importantly, this result indicates the robustness of this model; when all microstructure features are accounted for, the swelling behavior is nearly identical between experiment and computation.

Figure 7.28 demonstrated the excellent matching of void behavior when all alternate microstructure treatments are included. To confirm this result, and also to determine if the dislocation behavior can be likewise matched with all three treatments included, the full microstructure treatment was applied to Ref.2 in Figure 7.29 (Ref.2.G.MV.C). The network density, even with the addition of all microstructure treatments, remained similar to experiment, but the loop density was still too high by an order of magnitude relative to the experiment ($\sim 9 \times 10^{20}$ versus $2-3 \times 10^{20}$ m⁻³, respectively, shown in Figure 7.29b) leading to a loop sink strength that was still an order of magnitude too high ($\sim 1-2 \times 10^{14}$ m⁻² shown in Figure 7.29a). However, the addition of the other microstructure treatments was an improvement in terms of trends over the simpler Ref.2 reference case, which was shown in Figure 7.9. The resulting swelling at 650 dpa was 18.0%, which is within experimental error measured value of 16%, indicating that a combination of both the precipitate treatments along with the stepwise removal of carbon in solution from 188 to 450

dpa is capable of resolving the dislocation and void behavior, in the DD treatment as well as in the experimentally input case.

A summary of model cases is provided in Table 7.4, which also includes cases not explicitly presented here. The closest match for all conditions was from either the experimentally input network and loop or DD treatment with full precipitate treatment including carbon. Regardless of dislocation treatment, the addition of M₂X using either variable biased treatment is required to resolve the swelling to more appropriate levels, indicating that M₂X formation does influence swelling, despite the apparent linear swelling rate from 188 to 650 dpa. These results demonstrate the effectiveness of the RIME model as a method of deconvoluting the complex interactions inherent in the irradiated microstructure.

A direct comparison of the deconvolution of the four treatments including Ref.1 is shown in Figure 7.30. It is clearly demonstrated that M_2X and carbon in solution have the largest impact and the effect of G phase is negligible. To quantify the relative impact of the treatments, Table 7.5 presents the relative change in final swelling value with the addition of each microstructure treatment to either reference case. G phase has the most minor effect, a final swelling reduction of about 5% of the final swelling value, regardless of dislocation treatment. Carbon in solution and M_2X had the largest effect on final swelling. With the addition of M_2X only, the overall swelling was reduced by 21%. The stepwise removal of 100 appm of carbon from 188 to 450 dpa decreased the final swelling value by 19%, in the case of Ref.1 and 7% for Ref.2. (The difference in carbon response for each dislocation treatment was noted in Figure 7.25 and addressed in Section 7.5.) However, since carbon precipitation is considered as an indirect effect of M_2X . If M_2X is considered as the sum of its direct (as a sink) and indirect (microchemical) effects, M_2X has by far the most significant effect on void behavior.

7.7 Alternate Considerations Regarding Overall Microstructure Co-evolution

A strong case has been made for including the combined effects of the irradiated microstructure in modeling the void and dislocation evolution. The final section will discuss implications of these results.

7.7.1 Discussion of Other Possible Interaction Mechanisms

Figure 7.28 and Figure 7.29 offers convincing evidence that the primary interactions are between the dislocation and voids with M_2X , which served as both an alternate sink for defects and as a consumer of carbon out of solution. However, to support this statement, other alternative explanations and compelling evidence supporting the final chosen treatment are considered here.

7.7.1.1 Lower Effective Bias

The results of Figure 7.8 suggested that the swelling behavior could be explained in the absence of any features that were not dislocations, if a lower bias for interstitials with the experimentally input case were used (Ref.1.1.007). It was not pursued initially because this was a lower bias then those reported in the literature. However, disregarding this for the sake of argument, the case could be made that 0.7% bias is not unreasonable, as it is within 30% of 1% bias. Carrying this line of reasoning a step further, the lower biased case was run with the addition of the full microstructure treatment including G phase, M_2X and carbon in solution; results are presented in Figure 7.31a. Figure 7.31a is identical to Figure 7.24a, as bias does not change the experimentally input evolution, but a resulting decrease in void diameter and swelling is shown in Figure 7.31b. The addition of the precipitates decreased the void diameter enough to underpredicts swelling relative to the experiment by 43% (10 versus 16%, respectively). Thus, when all the possible microstructure interaction mechanisms are considered, including lowered effective bias (0.7% vs 1%) is not an appropriate treatment explaining the overall system's behavior. This demonstrates how the view of understanding void swelling as simply being influenced by dislocations is overly simplistic. A full understanding of void swelling needs to take into account other features that have sink strengths on the same order of magnitude. In fact, one of the strongest supports for this including all treatments is that it is unreasonable to assume a feature with sink strength 10^{14} m⁻² is not significant. Thus, lowered effective bias as a mechanism is not pursued further.

7.7.2 Reconsidering Swelling Rates from Experiment

The addition of, and subsequent removal of C in a stepwise fashion highlighted the slightly parabolic shape of the swelling curve, which was observed in cases with carbon only (Ref.1.C: Figure 7.24), carbon and M_2X as a variable sink (Ref.1.MV.C: Figure 7.26) and with the full microstructural treatment including G phase (Ref.1.G.MV.C: Figure 7.28). It was also demonstrated in Figure 7.28 that there was excellent matching of the overall swelling rate from 188 to 650 dpa from both the experimental data and model swelling curve. The question then becomes: can the slowly monotonically increasing swelling rate due to the parabolic shape be predicted in RIME be reasonably measured from the experimental data?

Figure 7.32 plots the swelling only as a function of damage from Ref.1.G.MV.C. Lines guiding the eye have been drawn to draw attention to the swelling rate which clearly increases with the removal of carbon and as a function of damage. The origin of this increase is that carbon suppresses void growth from 188 to 450 dpa, and then is removed from the model which, by its absence, promotes growth, despite M_2X acting as a sink for defects in the higher damage regime beyond 450 dpa.

To examine whether a case can be made experimentally for a slowly increasing swelling rate, the swelling rate was calculated at 300 dpa and at 500 dpa using the instantaneous swelling rate calculated from the parabolic regression least squares method described in Section 4.5.1. To make the analysis more thorough, it was also repeated using the fixed depth correction from Section 5.2.5, which gives an even more accurate swelling rate, taking into account void-induced extension of the ion damage curve. Furthermore, linear regression from 188 to 450 dpa and 450 to 650 dpa was used to confirm this as well. The results from all of these calculations are in Table 7.6 and Figure 7.33. The instantaneous swelling rate, calculated from the parabolic fit, increased from 0.025±0.004%/dpa to 0.032±0.005%/dpa at 300 and 500 dpa, respectively, which was an increase of 29%. For comparison, a linear regression was also calculated from 188 to 450 dpa and 450 to 650 dpa. Considering the first case with the nominal swelling calculation with no correction (Figure 7.33a), the swelling from 188 to 450 dpa is 0.025±0.004%/dpa whereas the swelling rate calculated from 450 to 650 dpa is 0.036±0.005%/dpa, which represents an increase of 44% that is outside the error bars.

Furthermore, considering the more accurate fixed depth corrected swelling (Figure 7.33b), the swelling rate increases from 0.027 ± 0.004 to $0.035\pm0.006\%$ /dpa, from 300 and 500 dpa,

respectively, which represents a swelling rate increase of 30% as well. This is comparable to the increase in swelling rate predicted from RIME of 44% from the lower (0.025%/dpa) to higher (0.036%/dpa) swelling rate. Thus, a strong case can be made for the observation of this slowly increasing swelling rate.

Practically speaking, the observation of the monotonically swelling increasing swelling rate demonstrates the fidelity of the experimental observations; the irradiation and characterization procedures were consistent enough to capture a swelling rate of change of less than a factor of 2. More importantly, this demonstrates the robustness of the model and is convincing evidence that the underlying mechanism treatments applied were appropriate.

The significance of this work is in that it highlights the importance of microstructure coevolution in terms of interactions between sinks in the microstructure, regardless of whether the precise co-evolution reflected in the model was that observed exactly. A case can always be made for other potential interaction mechanisms, but the overall shape and trajectory of the co-evolving microstructure is strong evidence of the suitability of this type of analysis for unfolding radiation damage interactions.

In a larger context, this has significant ramifications for how void swelling evolution is interpreted at very high damage levels in the void growth-dominated regime. Much emphasis has been placed on the concept of a "steady state" swelling rate and determining what that rate is; less emphasis has been on how the entire microstructure as a whole evolves and how this can influence swelling rates. This work demonstrates the necessity of considering the evolution of the entire microstructure, insofar as this is feasible, as the continual change in dislocation, precipitates and solutes that continue to affect void swelling at damage levels beyond any observed in the literature until now.

Furthermore, this work also demonstrates that the concept of "steady state" or linear swelling regime is likely overstated in the literature. A better interpretation of the void swelling evolution is that of a nucleation dominated regime, followed by a transition regime with both nucleation and growth followed by a growth-dominated regime, which can still be influenced by any changes in the microstructure. For the specific case examined here of HT9 irradiated with 5 MeV Fe⁺⁺, the swelling behavior in the void growth-dominated region is characterized by a nearly monotonically increasing linear swelling rate around ~0.03%/dpa for the damage levels examined. For the purposes of reactor design applications, taking the growth regime as a whole (188 to 650 dpa), 0.033%/dpa can serve as an excellent approximation. Reactor designs, in general, are limited to 10% swelling, which was within the swelling levels observed here. Beyond 10%, determining the swelling rate is more or less an academic exercise.

This work is particularly significant for the Gen IV reactor community as candidate materials are selected for the newest reactor design. As new reactor designs are proposed with more extreme environments in terms of high temperature, pressure or damage levels, the ability to understand how void swelling is expected to evolve beyond damage levels reached in reactor irradiations is very useful. More importantly, the continuous microstructure evolution at high damage levels provides a context for alloy developers working on improving the radiation tolerance of advanced materials, particularly in the area of void swelling. It also provides confidence for pursing alternate materials with high precipitate densities to mitigate void swelling, such as oxide dispersed steels, as a method of improving swelling resistance. Finally, the combined

approach of a set of systematic, well-controlled ion experiments with a rigorous modeling program demonstrates a powerful technique for understanding the fundamental mechanistic interactions between microstructure features.

Flag	Description of Microstructure/Treatment	Notes	
Ν	Network	Change network density from 3 to 4×10 ¹⁴ m ⁻² at 550 dpa	
'bias'	Changed bias from 1.01	Reflects any bias that is NOT 1.01. i.e. new bias is in flag '1.007'	
G	G phase	G phase always unbiased treatment	
MU	M ₂ X-Unbiased	M refers to M ₂ X; second letter refers to ppt treatment	
MB	M ₂ X-Biased	M refers to M ₂ X; second letter refers to ppt treatment	
MV	M ₂ X-Variable Biased	M refers to M ₂ X; second letter refers to ppt treatment	
MR	M ₂ X-Recombination Center	M refers to M ₂ X; second letter refers to ppt treatment	
С	Carbon in solution	Solute-vacancy traps in solution	

Table 7.1: Description of flags denoting modification of reference cases with various microstructure treatments.

Bias Range	Approach	Reference
1.01-1.25	Analytic Solutions	[48,137–139]
1.01-1.05	Rate Theory	[9,41,42,115,154]

Table 7.2: Dislocation biases for interstitials reported in literature using a variety of approaches.

Case	Bias	Void	Network	Loop	M ₂ X	G Phase	Carbon in Solution
Ref.0	1.01 network	Too high	Input	Not included	N/A	N/A	N/A
Ref.0.N	1.01 network	Too high	Input	Not included	N/A	N/A	N/A
Ref.1	1.01 network and loop	Too high	Input	Input	N/A	N/A	N/A
Ref.1.1.007	1.007 network and loop	Match	Input	Input	N/A	N/A	N/A
Ref.2	1.01 network and loop	Too high	Match	Too high	N/A	N/A	N/A
Ref.2.1.007	1.007 network and loop	Too high	Match	Too high	N/A	N/A	N/A

 Table 7.3: Description of reference cases with modifications used to match void and dislocation behavior to experiment.

Case	Bias	Void	Network	Loop	M ₂ X	G Phase	Carbon in Solution
Ref.1	1.01 network and loop	Too high	Input	Input	N/A	N/A	N/A
Ref.1.1.007	1.007 network and loop	Match	Input	Input	N/A	N/A	N/A
Ref.2	1.01 network and loop	Too high	Match	Too high	N/A	N/A	N/A
Ref.1.G.MV	1.01 network and loop	Too high	Input	Input	Input	Input	N/A
Ref.2.G.MV	1.01 network and loop	Too high	Match	Too high	Input	Input	N/A
Ref.1.G.MV.C	1.01 network and loop	Match	Match	Input	Input	Input	Stepwise decrease 100 appm from 188 to 450 dpa
Ref.2.G.MV.C	1.01 network and loop	Match	Match	Too high	Input	Input	Stepwise decrease 100 appm from 188 to 450 dpa
Ref.1.1.007.G.MV.C	1.007 network and loop	Too low	Input	Input	Input	Input	N/A

Table 7.4: Summary of attempts to match microstructure behavior with precipitate and carbon treatments.

	Swelli	ng (%)	% Change in Final Swelling		
Microstructure Treatment	Ref.1	Ref.2	Ref.1	Ref.2	
	26.1	26.1	N.A.	N.A.	
G	24.7	24.6	-5.4%	-5.7%	
MV	20.6	20.5	-21.1%	-21.5%	
C (100 appm removed stepwise from 188 to 450 dpa)	21.2	24.3	-18.8%	-6.9%	

Table 7.5: Comparison of relative effect on final swelling values at 650 dpa of each microstructure treatment.

	Nom	inal	Fixed Depth Correction				
Damage Range	Swelling Rate (%/dpa)	R ²	Swelling Rate (%/dpa)	R^2			
Parabolic Regression							
Instantaneous Swelling at 300 dpa	0.025±0.004	N/A	0.027±0.004	N/A			
Instantaneous Swelling at 500 dpa	0.032±0.005	N/A	0.035±0.006	N/A			
Linear Regression							
188-450 dpa	0.025±0.004	0.94	0.027±0.004	0.93			
450-650 dpa	0.036±0.005	0.98	0.042±0.006	0.98			
188-650 dpa	0.033±0.005	0.98	0.036±0.005	0.98			

Table 7.6: Comparison of swelling rates calculated in the range of 188 to 650 dpa using nominal or fixed depth method [85].



Figure 7.1: Schematic of relationships between precipitates, dislocations and voids explored in depth using RIME.



Figure 7.2: Comparison of Ref.0 (solid) and Ref.0.N (dashed) treatments (z_i^{net} =1.01) with experimental data in terms of a) void and network sink strength and b) void swelling.



Figure 7.3: Comparison of Ref.0 (solid) and Ref.1 (dashed) treatments ($z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) network, loop and total dislocation sink strength and b) void swelling.



Figure 7.4: Comparison of Ref.1 (solid) and Ref.2 (dashed) treatments ($z_i^{lp} = z_i^{net} = 1.01$) in terms of a) void, network, loop and total dislocation sink strength and b) void swelling.



Figure 7.5: Comparison of net vacancies absorbed at voids in Ref.1 (solid) and Ref.2 (dashed). Total dislocation sink strength is included in red. Discontinuity in Ref.1 case at 550 dpa is due to the manual increase in network sink strength which decreases d_ic_i and d_vc_v .



Figure 7.6: Comparison of swelling response to initial dislocation network density varied from 0.3 to 30×10^{14} m⁻² in a) Ref.2 and b) Ref.1.



Figure 7.7: Comparison of experimentally input loop and network treatment (Ref.1: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) network/loop sink strength and b) void diameter, number density and swelling.



Figure 7.8: Comparison of 1% (solid lines: Ref.1) and 0.7% biased (dashed lines: Ref.1.1.007) with experimental data in terms of void diameter, number density and swelling.



Figure 7.9: Comparison of DD treatment (Ref.2: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) loop and network sink strength b) loop diameter and number density and c) void diameter, number density and swelling.



Figure 7.10: Effect of G phase on void a) sink strength and b) swelling when included in experimentally determined levels as an unbiased sink. Dislocations are treated as experimentally input network and loops with (Ref.1.G: dashed lines) and without G phase (Ref.1: solid) with $z_i^{lp} = z_i^{net} = 1.01$.



Figure 7.11: Comparison of experimentally input loop and network treatment with G phase included (Ref.1G: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) G phase, loop and network sink strength and b) void diameter, number density and swelling.



Figure 7.12: Comparison of evolution of void and M_2X a) diameter and length and b) number density and volume fraction/swelling from 188 to 650 dpa. All irradiations performed with 5 MeV Fe⁺⁺ at 460°C with 10 appm He preimplanted. Lines guide the eye.



Figure 7.13: Comparison of swelling behavior with increasing $E_b^{\nu,tr}$ using Ref.1.MR with $z_i^{lp} = z_i^{net} = 1.01$.



Figure 7.14: Comparison of swelling with M_2X treated as either variable bias (red) or recombination centers (blue) with experimentally input network and loop with $z_i^{lp}=z_i^{net}=1.01$.



Figure 7.15: Comparison of Ref.1.MV ($z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) M₂X, loop and network sink strength and b) void diameter, number density and swelling. All irradiations performed with 5 MeV Fe⁺⁺ at 460°C with 10 appm He preimplanted.



Figure 7.16: Effect of G phase on network and loop a) sink strength and b) loop number density and diameter when included in experimentally determined levels as an unbiased sink. Dynamic dislocation treatment used both with (Ref.2.G: dashed lines) and without G phase (Ref.2: solid lines) with $z_i^{lp} = z_i^{net} = 1.01$.



Figure 7.17: Comparison of Ref.2.G ($z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) G phase, loop and network sink strength and b) dislocation loop diameter and number density.



Figure 7.18: Loop and M_2X diameter/length compared with number density as a function of damage. All irradiations performed with 5 MeV Fe⁺⁺ at 460°C with 10 appm He preimplanted. Lines guide the eye.



Figure 7.19: Effect of M_2X phase on network and loop a) sink strength and b) loop number density and diameter when included in experimentally determined levels as a variably biased sink. Dynamic dislocation treatment used with (Ref.2.MV: dashed lines) and without M_2X phase (Ref.2: solid lines) with $z_i^{lp} = z_i^{net} = 1.01$.



Figure 7.20: Effect of changing number of interstitial cluster groups from 60 (solid) to 160 (dashed) with DD treatment (Ref.2.MV: $z_i^{lp}=z_i^{net}=1.01$). M₂X treatment as variable bias sink was used.



Figure 7.21: Comparison of Ref.2.MV ($z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) M₂X, loop and network sink strength and b) dislocation loop diameter and number density.



Figure 7.22: Accounting for carbon in HT9 in the as-received condition and at 450 dpa.


Figure 7.23: Comparison of Ref.2 with Ref.2.C with 0 to 855 appm for a) network and loop sink strength and b) swelling. Case run with 3940 appm terminated at 400 dpa. 0 and 1 appm lines are indistinguishable in b).



Figure 7.24: Comparison of Ref.1 (blue), Ref.1.C with 100 appm in solution (red) and 100 appm in solution removed stepwise from 188 to 450 dpa (green) representing the precipitation of M₂X.



Figure 7.25: Comparison of Ref.1.C (blue) and Ref.2.C (red) with 100 appm of carbon in solution removed stepwise from 188 to 450 dpa representing the precipitation of M_2X .



Figure 7.26: Comparison of void swelling with M₂X plus 100 appm of carbon in solution removed stepwise from 188 to 450 dpa (Ref.1.MV.C: green), M₂X (Ref.1.MV: red) and Ref.1 (blue). All M₂X treated as variably biased with experimentally input dislocations.



Figure 7.27: Comparison of DD treatment (Ref.2.C: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) loop and network sink strength b) loop diameter and number density and c) void diameter, number density and swelling including 100 appm of carbon in solution removed stepwise from 188 to 450 dpa.



Figure 7.28: Comparison of experimentally input loop and network treatment (Ref.1.G.MV.C: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) network, loop, G phase and M₂X sink strength and b) void diameter, number density and swelling including M₂X (variable biased), G phase and stepwise removal of 100 appm of carbon in solution from 188 to 450 dpa.



Figure 7.29: Comparison of DD treatment (Ref.2.G.MV.C: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) network, loop, G phase and M₂X sink strength b) loop diameter and number density and c) void diameter, number density and swelling including M₂X (variable biased), G phase and stepwise removal of 100 appm of carbon in solution from 188 to 450 dpa.



Figure 7.30: Comparison of swelling curves with various microstructure treatments. All cases run with experimentally input dislocations (Ref.1: $z_i^{lp} = z_i^{net} = 1.01$).



Figure 7.31: Comparison of experimentally input loop and network treatment with lower bias (Ref.1.1.007.G.MV.C: $z_i^{lp} = z_i^{net} = 1.01$) with experimental data in terms of a) network, loop, G phase and M₂X sink strength and b) void diameter, number density and swelling including M₂X (variable biased), G phase and 100 appm C in solution removed stepwise from 188 to 450 dpa.



Figure 7.32: Comparison between swelling rate before and after 450 dpa (Ref.1.G.MV.C: $z_i^{lp} = z_i^{net} = 1.01$). Dashed lines guide the eye to approximate swelling rates calculated from RIME.



Figure 7.33: Comparison of instantaneous swelling rate calculated from experiment using parabolic regression before and after 450 dpa using a) uncorrected swelling and b) fixed depth method [85].

CHAPTER 8

CONCLUSIONS

The following conclusions have been reached regarding the interactions between voids, dislocations and precipitates in self-ion irradiated HT9 at very high damage levels.

A simple system of voids and dislocations was modeled using RIME in which the dislocations measured from experiment were used as input, or the dislocations were allowed to evolve dynamically. The result was that swelling was overestimated by 63% relative to that observed in experiment at 650 dpa for both treatments. The large discrepancy in measured vs. predicted swelling suggests that other sinks were acting to divert defect flow away from the voids. The consistency of the two dislocation treatments indicates the suitability of either method for analysis of more complex microstructure systems.

G phase had limited effect on the void or dislocation behavior. The addition of G phase decreased final swelling by about 5% from 26.1 to 24.7%, which was insufficient to serve as an alternate sink in a meaningful capacity. Thus, G phase was determined not to have a strong enough effect on voids as expected from its low sink density. G phase also had an insignificant impact (5% decrease) on loop and network sink strengths; it was not sufficient to resolve discrepancies between model and experiment. Therefore, G phase is minimal in terms of the co-evolution of the overall microstructure.

The behavior of M_2X within the microstructure was characterized by a direct effect as a coherent sink, and an indirect effect in consuming carbon from the matrix. The primary effect of M_2X was to serve as alternate sink for vacancies which limited the amount of vacancies free to diffuse and grow the voids, decreasing swelling from 26.1% to 20.7%. The growth of M_2X also resulted in the removal of carbon in solution from the matrix. Carbon trapping of vacancies was shown to have a strong effect on the swelling, decreasing the swelling from 26.1% to 21.1% for Ref.1 and to 24.3% for Ref.2, when 100 appm of C was removed is a stepwise fashion from 188 to 450 dpa. The removal of carbon due to growth of M_2X resulted in an increase in instantaneous swelling rate from approximately 0.029%/dpa to 0.056%/dpa before and after 450 dpa in the model.

Dislocation loops continued to evolve up through 650 dpa and underwent a step change in diameter between 375 and 450 dpa. M_2X had the largest impact on dislocation behavior. Loop growth beyond tens of dpa has not been observed to this point and this data set represents the most systematic data set at the highest damage levels. M_2X , when treated as a variably biased sink or recombination center, has a measurable effect (75% decrease) on loop and network behavior by suppressing the dislocation loop number density, and by extension, the loop and network sink strength.

An inflection point at 450 dpa was observed both experimentally and computationally, with instantaneous swelling rates measured at 300 dpa of ~0.025%/dpa and ~0.032%/dpa at 500 dpa. The inflection point, which occurred due to loss of matrix carbon by M₂X formation, demonstrates swelling cannot be at a true steady state as long as the surrounding microstructure features continue to evolve with dpa. Since microstructure evolution has been shown to occur out to several hundred dpa, "steady state" swelling will not be achieved. A better interpretation of the void swelling evolution is that of a nucleation dominated regime, a transition regime where both void nucleation and growth are important, and a growth-dominated regime characterized by a monotonic, slowly increasing swelling rate.

The agreement in void behavior between measurement and model when all microstructure effects (loops, network, G phase, M₂X formation and growth, and removal of carbon) are accounted for demonstrates the importance of characterizing the evolution of the full microstructure over the entire dpa range. The continuing evolution of the entire microstructure was a significant finding and was able to resolve the RIME model to better match experiment with wither Ref.1 or Ref.2.

CHAPTER 9

FUTURE WORK

The results from this study are significant, but there are some unanswered questions that merit further study.

Confining the analysis to the void-growth dominated regime limits the applicability of this methodology in understanding the nucleation-dominated void swelling regime.

Understanding when and how voids nucleate is an even more challenging question and arguably, a more useful analysis for reactor applications. The majority of ion irradiation data to this point has been in the nucleation dominated regime, but no modeling efforts to date have been able to satisfactorily explain the variations in the length of incubation period of swelling, as nucleation of voids is a much more complex phenomenon when compared to modeling of void growth-dominated behavior. Although the current treatment of void nucleation in RIME represents an improvement over previous nucleation modeling, it has yet to capture the variation in length of a nucleation period observed in different FM alloys.

The formation and growth mechanisms of precipitates in the high damage level regime have yet to be fully understood. The formation, growth and saturation of M₂X was observed, but not understood in a mechanistic way in this study. Neither experimental nor computation work was advanced enough to understand the full precipitate evolution from nucleation to growth. To fully integrate a precipitate model into RIME that could respond to defect flows would represent a large improvement in capability, and also an increase in complexity which could further explain or confirm the defect-precipitate mechanisms utilized in this version of the model. Furthermore, no satisfactory explanation for the 250 dpa incubation period before the appearance of M₂X.

The continuing evolution of dislocation loops and network at very high damage level was a significant result that was not captured by the model. A significant finding of the ion irradiations in this thesis was the continuing evolution of the loops and network at high damage levels, which greatly influenced void behavior. Neither the loop growth observed experimentally between 375 to 450 dpa nor the increase in loop network was observed. An interaction mechanism was proposed based upon the literature results, but further study is required to understand that complex interaction between precipitates, dislocations and carbon in solution in solution.

This study did not address the effect of helium implantation method on microstructure evolution. Dual ion irradiation is far more representative of damage in-reactor when compared to preimplanted helium, which was used in this study to approximate the effect of (n, α) reactors. Continuous helium implantation is expected to primarily affect void formation and growth, but the possible effect on other microstructure features cannot be discounted. In addition, this study has shown that microstructure continues to evolve as a function of dpa, therefore the continuing addition of helium is very likely to strongly influence the overall microstructure evolution either directly or indirectly. Highly heterogeneous void nucleation behavior was observed from grain to grain but was not explained by either the experiment or model. The heterogeneous void nucleation behavior has been well documented in FM alloys, and has not been sufficiently explained either using microscopy techniques or modeling, though some studies have suggested that retained δ ferrite may promote void swelling. For the purpose of this thesis, the average swelling of many grains was used in the final analysis. Results from this study suggest that the grain microchemistry, especially of C, may be important, but again, further work is needed to understand what grain environments promote or suppress void swelling. A study of this would be highly relevant to future alloy development programs.

APPENDICES

APPENDIX A - TEMPERATURE HISTOGRAMS

Temperature histograms are included for all irradiations presented in this thesis.



Figure A. 1: Temperature histograms for HT9 (heat 84425: ACO3) irradiated at 400°C: 250 dpa; 440°C: 25, 140, 188; 460°C: 188 dpa and 480°C:188 dpa



Figure A. 2: Temperature histograms for HT9 (heat 84425: ACO3) irradiated at 440°C: 50 dpa and 460°C: 75, 130, 250, 350, 375 dpa.



Figure A. 3: Temperature histograms for HT9 (heat 84425: ACO3) irradiated at 460°C: 450, 550, 650 dpa.

APPENDIX B - VOID IMAGES

The following are images for a liftout of each of the irradiated conditions.

ACO3-440C-140dpa-10.10He-032812-TEM-Grid A-071113





Figure B. 1: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 440°C up to 140 dpa with 10 appm He preimplanted.

ACO3-440C-25dpa-10.10He-081412-TEM-Grid B-050114



Figure B. 2: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 440°C up to 25 dpa with 10 appm He preimplanted.

ACO3-440C-188dpa-10.10He-091312-TEM-Grid B-101812



Figure B. 3: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 440°C up to 188 dpa with 10 appm He preimplanted.

ACO3-480C-188dpa-10.10He-111312-TEM-Grid B-012813



Figure B. 4: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 480°C up to 188 dpa with 10 appm He preimplanted.

ACO3-400C-250dpa-0He-011913-TEM-Grid C-052113



Figure B. 5: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 400°C up to 250 dpa with 0 appm He preimplanted.

ACO3-460C-188dpa-10.10He-062413-TEM-Grid C-072013



Figure B. 6: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 188 dpa with 10 appm He preimplanted.

ACO3-440C-50dpa-10.10He-090413-TEM-Grid C-050114



Figure B. 7: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 440°C up to 50 dpa with 10 appm He preimplanted.

ACO3-460C-375dpa-10.10He-111313-TEM-Grid B-120213



Figure B. 8: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 375 dpa with 10 appm He preimplanted.

ACO3-460C-130dpa-10.10He-092214-TEM-Grid C-100314



Figure B. 9: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 130 dpa with 10 appm He preimplanted.

ACO3-460C-75dpa-10.10He-102814-TEM-Grid C-033115



Figure B. 10: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 75 dpa with 10 appm He preimplanted.

ACO3-460C-250dpa-10.10He-120814-TEM-Grid A-121214





Figure B. 11: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 250 dpa with 10 appm He preimplanted.

ACO3-460C-350dpa-10.10He-011214-TEM-Grid B-011615





Figure B. 12: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 350 dpa with 10 appm He preimplanted.

ACO3-460C-450dpa-10He-021615-Grid B-021915





Figure B. 13: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 450 dpa with 10 appm He preimplanted.

ACO3-460C-550dpa-10.10He-030515-TEM-Grid B-031315



Figure B. 14: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 550 dpa with 10 appm He preimplanted.
ACO3-460C-650dpa-10.10He-050714-TEM-Grid B-051515



Figure B. 15: HT9 (ACO3) irradiated with 5 MeV Fe⁺⁺ at 460°C up to 650 dpa with 10 appm He preimplanted.

APPENDIX C - VOID DEPTH PROFILES AND DISTRIBUTIONS

The following are void depth profiles and distributions for all irradiation conditions considered

in this thesis.



440°C-140dpa-10He-032812

Figure C. 1: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 440°C, to 140 dpa with 10 appm He.



Figure C. 2: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 440°C, to 25 dpa with 10 appm He.



440°C-188dpa-10.10He-091312

Figure C. 3: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 440°C, to 188 dpa with 10 appm He.



480°C-188dpa-10.10He-111312

Figure C. 4: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 480°C, to 188 dpa with 10 appm He.

400°C-250dpa-0.0He-011913

No voids observed

No voids observed

No voids observed

No voids observed

Figure C. 5: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe^{++} (ACO3) at 400°C, to 250 dpa with 10 appm He.



460°C-188dpa-10.10He-062413

Figure C. 6: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 188 dpa with 10 appm He.



440°C-50dpa-10.10He-090413

Figure C. 7: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 440°C, to 50 dpa with 10 appm He.



460°C-375dpa-10.10He-111313

Figure C. 8: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 375 dpa with 10 appm He.



Figure C. 9: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 130 dpa with 10 appm He.



460°C-75dpa-10.10He-102814

Figure C. 10: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 75 dpa with 10 appm He.



Figure C. 11: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 250 dpa with 10 appm He.



460°C-350dpa-10.10He-011215

Figure C. 12 Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 350 dpa with 10 appm He.



460°C-450dpa-10.10He-021615

Figure C. 13: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 450 dpa with 10 appm He.



460°C-550dpa-10.10He-030515

Figure C. 14: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 550 dpa with 10 appm He.



Figure C. 15: Void diameter, number density and swelling depth profiles as well as void distribution in the 500 to 700 nm depth region of HT9 irradiated with 5 MeV Fe⁺⁺ (ACO3) at 460°C, to 650 dpa with 10 appm He.

REFERENCES

- T. Ellis, R. Petroski, P. Hejzlar, G. Zimmerman, D. Mcalees, C. Whitmer, et al., Traveling-wave reactors : A truly sustainable and full-scale resource for global energy needs, in: Int. Congr. Adv. Nucl. Power Plants, 2010.
- G.S. Was, Z. Jiao, E. Getto, K. Sun, A.M. Monterrosa, S.A. Maloy, et al., Emulation of reactor irradiation damage using ion beams, Scr. Mater. 88 (2014) 33–36. doi:10.1016/j.scriptamat.2014.06.003.
- [3] R.L. Klueh, D.R. Harries, High-Chromium Ferritic and Martensitic Steels for Nuclear Applications, 2001. doi:10.1520/MONO3-EB.
- [4] M.B. Toloczko, F.A. Garner, Variability of Irradiation Creep and Swelling of HT9
 Irradiated to High Neutron Fluence at 400-600C, Eff. Radiat. Mater. ASTM STP 1325.
 (1999).
- [5] M.B. Toloczko, F.A. Garner, C.R. Eiholzer, Irradiation creep and swelling of the US fusion heats of HT9 and 9Cr-1Mo to 208 dpa at 400C, J. Nucl. Mater. 215 (1994) 604–607.
- [6] M.B. Toloczko, F.A. Garner, Irradiation creep and void swelling of two LMR heats of HT9 at ~400 C and 165 dpa, J. Nucl. Mater. 237 (1996) 289–292.
- [7] D. Gelles, Microstructural examination of commercial ferritic alloys at 200 dpa, J. Nucl.
 Mater. 237 (1996) 293–298.

http://www.sciencedirect.com/science/article/pii/S002231159600222X (accessed August

19, 2011).

- [8] F. Garner, M.B. Toloczko, B.H. Sencer, Comparison of swelling and irradiation creep behavior of fcc-austenitic and bcc-ferritic/martensitic alloys at high neutron exposure, J. Nucl. Mater. 276 (2000) 123–142. doi:10.1016/S0022-3115(99)00225-1.
- [9] B.H. Sencer, J.R. Kennedy, J.I. Cole, S.A. Maloy, F.A. Garner, Microstructural analysis of an HT9 fuel assembly duct irradiated in FFTF to 155dpa at 443°C, J. Nucl. Mater. 393 (2009) 235–241. doi:10.1016/j.jnucmat.2009.06.010.
- B.H. Sencer, J.R. Kennedy, J.I. Cole, S.A. Maloy, F.A. Garner, Microstructural stability of an HT-9 fuel assembly duct irradiated in FFTF, J. Nucl. Mater. 414 (2011) 237–242. doi:10.1016/j.jnucmat.2011.03.050.
- [11] D.S. Gelles, Microstructural development in reduced activation ferritic alloys irradiated to 200 dpa at 420°C, J. Nucl. Mater. 212-215 (1994) 714–719. doi:10.1016/0022-3115(94)90150-3.
- [12] E. Getto, Z. Jiao, A.M. Monterrosa, K. Sun, G.S. Was, Effect of pre-implanted helium on void swelling evolution in self-ion irradiated HT9, J. Nucl. Mater. 462 (2015) 458–469. doi:10.1016/j.jnucmat.2015.01.045.
- [13] E. Getto, Z. Jiao, A.M. Monterrosa, K. Sun, G.S. Was, Effect of irradiation mode on the microstructure of self-ion irradiated ferritic-martensitic alloys, J. Nucl. Mater. 465 (2015) 116–126. doi:10.1016/j.jnucmat.2015.05.016.
- [14] F.A. Smidt, P.R. Malmberg, J.A. Sprague, J.E. Westmoreland, Swelling behavior of commercial alloys, EM-12 and HT-9, as assessed by heavy ion bombardment, Am. Soc.

Test. Mater. (1976) 227–241.

- [15] M.B. Toloczko, F.A. Garner, V.N. Voyevodin, V.V. Bryk, O.V. Borodin, V.V.
 Mel'nychenko, et al., Ion-induced swelling of ODS ferritic alloy MA957 tubing to 500
 dpa, J. Nucl. Mater. 453 (2014) 323–333. doi:10.1016/j.jnucmat.2014.06.011.
- [16] G. Gupta, Z. Jiao, A.N. Ham, J.T. Busby, G.S. Was, Microstructural evolution of proton irradiated T91, J. Nucl. Mater. 351 (2006) 162–173. doi:10.1016/j.jnucmat.2006.02.028.
- Z. Jiao, N. Ham, G.S. Was, Microstructure of helium-implanted and proton-irradiated T91 ferritic/martensitic steel, J. Nucl. Mater. 367-370 (2007) 440–445.
 doi:10.1016/j.jnucmat.2007.03.118.
- [18] R. Stoller, G.R. Odette, A Composite Model of Microstructural Evolution in Austenitic Stainless Steel Under Fast Neutron Irradiation, Am. Soc. Test. Mater. (1987) 371–392.
- [19] J.J. Kai, Effects of thermal annealing and ion irradiation on the microstructures of HT-9 ferritic steel (precipitates, cavities, TEM, dislocation Loops, cross-Section), 1986.
- [20] G.S. Was, Fundamentals of Radiation Materials Science, 2007.
- [21] R.E. Stoller, G.R. Odette, A comparison of the relative importance of helium and vacancy accumulation in void nucleation, Radiation-Induced Chang. Microstruct. Int. Symp. (1987) 358–370.
 http://books.google.com/books?hl=en&lr=&id=k5j2P1xKKqEC&oi=fnd&pg=PA358&dq =Zinkle+Helium+Void&ots=PLOM9BhLCV&sig=JiHIISfUYfJNTnSbouH8ihLkWAk.
- [22] A.S. Kalchenko, V.V. Bryk, N.P. Lazarev, I.M. Neklyudov, V.N. Voyevodin, F.A. Garner, Prediction of swelling of 18Cr10NiTi austenitic steel over a wide range of

displacement rates, J. Nucl. Mater. 399 (2010) 114–121. doi:10.1016/j.jnucmat.2010.01.010.

- [23] F.A. Garner, T. Okita, N. Sekimura, Swelling of pure vanadium and V-5Cr at ~430°C in response to variations in neutron flux-spectra in FFTF, J. Nucl. Mater. 417 (2011) 314–318. doi:10.1016/j.jnucmat.2010.12.072.
- [24] A.M. Dvoriashin, S.I. Porollo, Y. V Konobeev, F.A. Garner, Influence of cold work to increase swelling of pure iron irradiated in the BR-10 reactor to ~6 and ~25 dpa at ~ 400 °
 C, J. Nucl. Mater. 287 (2000) 157–160.
- [25] A. Kumar, F.A. Garner, Saturation of proton-induced swelling in AISI 316, J. Nucl. Mater. 117 (1983) 234–238.
- Y.V. Konobeev, a. M. Dvoriashin, S.I. Porollo, F. a. Garner, Swelling and microstructure of pure Fe and Fe–Cr alloys after neutron irradiation to ~26dpa at 400°C, J. Nucl. Mater. 355 (2006) 124–130. doi:10.1016/j.jnucmat.2006.04.011.
- [27] B.H. Sencer, F.A. Garner, Compositional and temperature dependence of void swelling in model Fe–Cr base alloys irradiated in the EBR-II fast reactor, J. Nucl. Mater. 283-287
 (2000) 164–168. doi:10.1016/S0022-3115(00)00338-X.
- [28] R. Viswanathan, W.T. Bakker, Materials for Boilers in Ultra Supercritical Power Plants, in: Int. Jt. Power Gener. Conf., 2000: pp. 1–22. http://www.scribd.com/doc/37295180/Boiler-Materials-for-USC-Plants-IJPGC-2000.
- [29] T.S. Byun, J.H. Baek, O. Anderoglu, S.A. Maloy, M.B. Toloczko, Thermal annealing recovery of fracture toughness in HT9 steel after irradiation to high doses, J. Nucl. Mater.

449 (2014) 263–272. doi:10.1016/j.jnucmat.2013.07.064.

- [30] J. Pešička, A. Aghajani, C. Somsen, A. Hartmaier, G. Eggeler, How dislocation substructures evolve during long-term creep of a 12% Cr tempered martensitic ferritic steel, Scr. Mater. 62 (2010) 353–356. doi:10.1016/j.scriptamat.2009.10.037.
- [31] O. Anderoglu, J. Van den Bosch, P. Hosemann, E. Stergar, B.H. Sencer, D.
 Bhattacharyya, et al., Phase stability of an HT-9 duct irradiated in FFTF, J. Nucl. Mater.
 430 (2012) 194–204. doi:10.1016/j.jnucmat.2012.06.038.
- [32] J.J. Penisten, The Mechanism of Radiation-Induced Segregation in Ferritic-Martensitic Steels, 2012.
- [33] D.S. Gelles, Void swelling in binary FeCr alloys at 200 dpa, J. Nucl. Mater. 225 (1995)
 163–174. doi:10.1016/0022-3115(95)00053-4.
- [34] L. Mansur, Theory and experimental background on dimensional changes in irradiated alloys☆, J. Nucl. Mater. 216 (1994) 97–123. doi:10.1016/0022-3115(94)90009-4.
- [35] J.J. Kai, G.L. Kulcinski, 14 MeV nickel-ion irradiated HT-9 ferritic steel with and without helium pre-implantation, J. Nucl. Mater. 175 (1990) 227–236.
- [36] D.L. Plumton, W.G. Wolfer, Supression of void nucleation by injected interstitials during heavy ion bombardment, J. Nucl. Mater. 120 (1984) 245–253.
- [37] G. Ayrault, Cavity formation during single and dual-ion 9Cr-1Mo ferritic alloy irradiation,J. Nucl. Mater. 114 (1983) 34–40.
- [38] O.V. Borodin, V.N. Voyevodin, V.F. Zelenskij, I.M. Neklyudov, P.V. Platonov, Radiation

damage studies of the 10 to 13% chromium-containing steels and alloys irradiated with heavy ions, in: Eff. Radiat. Mater. 15th Int. Symp., 1992: pp. 1157–1166. http://books.google.fi/books?id=SuRjaV0MVdEC.

- [39] A. Ward, S. Fisher, A comparison of heavy ion-irradiated ferritic and austenitic steels in the early stages of damage, in: Eff. Radiat. Mater. 15th Int. Symp., 1992: pp. 1167–1179.
- [40] M. Suzuki, N. Sekimura, N. Fukuya, H. Kusangi, H. Taguchi, M. Satake, et al.,
 Microstructural change in ferritic steels under heavy ion irradiation, in: Eff. Radiat. Mater.
 14th Annu. Symp. ASTM STP 1046, 1989: p. 160. doi:10.1017/CBO9781107415324.004.
- [41] G.R. Odette, On mechanisms controlling swelling in ferritic and martensitic alloys, J.Nucl. Mater. 157 (1988) 921–927.
- [42] G.P. Walters, The electron irradiation of pure FeCrNi alloys in the temperature range 400 to 700C, J. Nucl. Mater. 136 (1985) 263–279. doi:10.1016/0022-3115(85)90014-5.
- [43] R. Bullough, R.C. Perrin, The Mechanism and Kinetics of Void Growth During Neutron Irradiation, ASTM STP 484. (n.d.) 317–331.
- [44] C. Xu, G.S. Was, Anisotropic dislocation loop distribution in alloy T91 during irradiation creep, J. Nucl. Mater. 454 (2014) 255–264. doi:10.1016/j.jnucmat.2014.07.062.
- [45] M.N. Batista, S. Hereñú, I. Alvarez-Armas, The Role of Microstructure in Fatigue Crack Initiation and Propagation in 9-12Cr Ferritic-martensitic Steels, Procedia Eng. 74 (2014) 228–231. doi:10.1016/j.proeng.2014.06.253.
- [46] M. Li, L. Wang, J.D. Almer, Dislocation evolution during tensile deformation in ferriticmartensitic steels revealed by high-energy X-rays, Acta Mater. 76 (2014) 381–393.

doi:10.1016/j.actamat.2014.05.026.

- [47] R.. Faulkner, S. Song, P.E.. Flewitt, Radiation-induced inter-granular segregation in first wall fusion reactor materials, J. Nucl. Mater. 283-287 (2000) 147–151.
 doi:10.1016/S0022-3115(00)00353-6.
- [48] Z. Chang, D. Terentyev, N. Sandberg, K. Samuelsson, P. Olsson, Anomalous bias factors of dislocations in bcc iron, J. Nucl. Mater. 461 (2015) 221–229.
 doi:10.1016/j.jnucmat.2015.03.025.
- [49] P. Dubuisson, D. Gilbon, J.L. Séran, Microstructural evolution of ferritic-martensitic steels irradiated in the fast breeder reactor Phénix, J. Nucl. Mater. 205 (1993) 178–189. doi:10.1016/0022-3115(93)90080-I.
- [50] A.F. Padilha, R.L. Plaut, Stainless steel heat treatment, in: Steel Heat Treat. Handb., 2006: pp. 695–735.
- [51] Z. Jiao, G.S. Was, Precipitate evolution in ion-irradiated HCM12A, J. Nucl. Mater. 425 (2012) 105–111. doi:10.1016/j.jnucmat.2011.12.017.
- [52] O.V. Borodin, V.V. Bryk, V.N. Voyevodin, I.M. Neklyudov, V.K. Shamardin, Investigation of microstructure of ferritic-martensitic steels containing 9 and 13% Cr irradiated with fast neutrons, J. Nucl. Mater. 207 (1993) 295–302. doi:10.1016/0022-3115(93)90272-Z.
- [53] P.J. Maziasz, Formation and stability of radiation-induced phases in neutron-irradiated austenitic and ferritic steels, J. Nucl. Mater. 169 (2008) 95–115.
- [54] Z. Jiao, G.S. Was, Segregation behavior in proton- and heavy-ion-irradiated ferritic-

martensitic alloys, Acta Mater. 59 (2011) 4467–4481. doi:10.1016/j.actamat.2011.03.070.

- [55] J.P. Wharry, G.S. Was, A systematic study of radiation-induced segregation in ferritic– martensitic alloys, J. Nucl. Mater. 442 (2013) 7–16. doi:10.1016/j.jnucmat.2013.07.071.
- [56] S.A. Maloy, M.R. James, G. Willcutt, W.F. Sommer, M. Sokolov, L.L. Snead, et al., The mechanical properties of 316L / 304L stainless steels, Alloy 718 and Mod 9Cr ± 1Mo after irradiation in a spallation environment, J. Nucl. Mater. 296 (2001) 119–128.
- [57] J.T. Busby, M.C. Hash, G.S. Was, The relationship between hardness and yield stress in irradiated austenitic and ferritic steels, J. Nucl. Mater. 336 (2005) 267–278. doi:10.1016/j.jnucmat.2004.09.024.
- [58] D.S. Gelles, R. Schaublin, Examination of postirradiation deformation microstructures in F82H, in: Eff. Radiat. Mater. 21st Int. Symp., 2004: pp. 401–407.
- [59] Y. de Carlan, X. Avery, J.-C. Brachet, J.-L. Bertin, F. Rozenblum, O. Rabouille, et al., Post-irradiation tensile behavior and residual activity of several ferritic/martensitic and austenitic steels irradiated in Osiris reactor at 325C up to 9 dpa, in: Eff. Radiat. Mater. 14th Annu. Symp. ASTM STP 1475, 2006: pp. 67–85.
- [60] S.A. Maloy, M. Toloczko, J. Cole, T.S. Byun, Core materials development for the fuel cycle R&D program, J. Nucl. Mater. 415 (2011) 302–305.
 doi:10.1016/j.jnucmat.2011.04.027.
- [61] T.S. Byun, W. Daniel Lewis, M.B. Toloczko, S.A. Maloy, Impact properties of irradiated HT9 from the fuel duct of FFTF, J. Nucl. Mater. 421 (2012) 104–111. doi:10.1016/j.jnucmat.2011.11.059.

- [62] T.S. Byun, M.B. Toloczko, T.A. Saleh, S.A. Maloy, Irradiation dose and temperature dependence of fracture toughness in high dose HT9 steel from the fuel duct of FFTF, J. Nucl. Mater. 432 (2013) 1–8. doi:10.1016/j.jnucmat.2012.07.019.
- [63] M.J. Hackett, Personal communication, 2015.
- [64] J.F. Ziegler, M.D. Ziegler, J.P. Biersack, SRIM The stopping and range of ions in matter (2010), Nucl. Instruments Methods Phys. Res. Sect. B Beam Interact. with Mater. Atoms. 268 (2010) 1818–1823. doi:10.1016/j.nimb.2010.02.091.
- [65] R.E. Stoller, M.B. Toloczko, G.S. Was, a. G. Certain, S. Dwaraknath, F. a. Garner, On the use of SRIM for computing radiation damage exposure, Nucl. Instruments Methods Phys. Res. Sect. B Beam Interact. with Mater. Atoms. 310 (2013) 75–80. doi:10.1016/j.nimb.2013.05.008.
- [66] M.J. Norgett, M.T. Robinson, I.M. Torrens, A proposed method of calculating displacement dose rates, Nucl. Eng. Des. 33 (1975) 50–54. doi:10.1016/0029-5493(75)90035-7.
- [67] ASTM E521, Standard practice for neutron radiation damage simulation by chargedparticle, Annu. B. ASTM Stand. 12.02 (2009) 1–21. doi:10.1520/E0521-96R09E01.
- [68] W.K. T. Csörgô, S. Hegyi, From e+e- to Heavy Ion Collisions, in: 30th Int. Symp.Multiparticle Dyn., 2001: p. 241.
- [69] G.S. Was, J.T. Busby, T. Allen, E.A. Kenik, A. Jenssen, S.M. Bruemmer, et al., Emulation of neutron irradiation effects with protons: validation of principle, J. Nucl. Mater. 300 (2002) 198–216. doi:10.1016/S0022-3115(01)00751-6.

- [70] C. Xu, In-Situ Proton Irradiation Creep of FM Steel T91, 2014.
- [71] T. Malis, S.C. Cheng, R.F. Egerton, EELS log-ratio technique for specimen-thickness measurement in the TEM, J. Electron Microsc. Tech. 193-200 (1988).
- [72] L. Shao, C.-C. Wei, J. Gigax, A. Aitkaliyeva, D. Chen, B.H. Sencer, et al., Effect of defect imbalance on void swelling distributions produced in pure iron irradiated with 3.5MeV self-ions, J. Nucl. Mater. 453 (2014) 176–181. doi:10.1016/j.jnucmat.2014.06.002.
- [73] A.S. Kumar, F.A. Garner, Dual-ion irradiation: Impact of the conflicting roles of helium on void nucleation, Eff. Radiat. Mater. ASTM STP 870. (1985) 493–506.
- [74] C.S. Smith, L. Guttman, Measurement of Internal Boundaries in Three Dimensional Structures by Random Sectioning, J. Met. Trans. (1953) 81–87.
- [75] W.L. Fink, E.D. Campbell, Campbell and Campbell, Am. Soc. Heat. Treat. 1926 (1926) 717–752.
- [76] O.D. Sherby, J. Wadsworth, D.R. Lesuer, C.K. Syn, The c/a Ratio in Quenched Fe-C and Fe-N Steels - A Heuristic Story, Mater. Sci. Forum. 539-543 (2007) 215–222. doi:10.4028/www.scientific.net/MSF.539-543.215.
- [77] O.D. Sherby, J. Wadsworth, D.R. Lesuer, C.K. Syn, Revisiting the Structure of Martensite in Iron-Carbon Steels, Mater. Trans. 49 (2008) 2016–2027. doi:10.2320/matertrans.MRA2007338.
- [78] D.-H. Ping, Understanding Solid–Solid (fcc $\rightarrow \omega$ + bcc) Transition at Atomic Scale, Acta Metall. Sin. (English Lett. 28 (2015) 663–670. doi:10.1007/s40195-015-0283-z.

- [79] D. Kaoumi, Personal communication, (2016).
- [80] D. Xu, B.D. Wirth, M. Li, M.A. Kirk, Combining in situ transmission electron microscopy irradiation experiments with cluster dynamics modeling to study nanoscale defect agglomeration in structural metals, Acta Mater. 60 (2012) 4286–4302. doi:10.1016/j.actamat.2012.03.055.
- [81] R.E. Stoller, The effect of free surfaces on cascade damage production in iron, J. Nucl. Mater. 311 (2008) 935–940.
- [82] A.D. Brailsford, L.K. Mansur, Effect of self-ion injection in simulation studies of void swelling, J. Nucl. Mater. 71 (1977) 110–116.
- [83] T. Yamamoto, Y. Wu, G. Robert Odette, K. Yabuuchi, S. Kondo, A. Kimura, A dual ion irradiation study of helium–dpa interactions on cavity evolution in tempered martensitic steels and nanostructured ferritic alloys, J. Nucl. Mater. 449 (2014) 190–199. doi:10.1016/j.jnucmat.2014.01.040.
- [84] T. Chen, E. Aydogan, J.G. Gigax, D. Chen, J. Wang, X. Wang, et al., Microstructural changes and void swelling of a 12Cr ODS ferritic-martensitic alloy after high-dpa self-ion irradiation, J. Nucl. Mater. 467 (2015) 42–49. doi:10.1016/j.jnucmat.2015.09.016.
- [85] E. Getto, K. Sun, S. Taller, A.M. Monterrosa, Z. Jiao, G.S. Was, Methodology for determining void swelling at very high damage under ion irradiation, J. Nucl. Mater. 477 (2016) 273–279. doi:10.1016/j.jnucmat.2016.05.026.
- [86] G.R. Odette, D.M. Schwartz, A.G. Ardell, Particle Range and Energy Deposition in Materials Containing Voids, Radiat. Eff. 22 (1974) 217–223.

- [87] W.G. Johnston, J.H. Rosolowski, A.M. Turkalo, T. Lauritzen, The depth distribution of void swelling produced by 5 MeV Ni ions, J. Nucl. Mater. 62 (1976) 167–180.
 doi:10.1016/0022-3115(76)90014-3.
- [88] A. Mateo, L. Llanes, M. Anglada, A. Redjaimia, G. Metauer, Characterization of the intermetallic G-phase in an AISI 329 duplex stainless steel, J. Mater. Sci. 32 (1997) 4533– 4540. doi:10.1023/A:1018669217124.
- [89] J.M. Vitek, S.A. David, D.J. Alexander, J.R. Keiser, R.K. Nanstad, Low temperature aging behavior of type 308 stainless steel weld metal, Acta Metall. Mater. 39 (1991) 503– 516. doi:10.1016/0956-7151(91)90118-K.
- [90] X. Wang, Q. Yan, G.S. Was, L. Wang, Void swelling in ferritic-martensitic steels under high dose ion irradiation: Exploring possible contributions to swelling resistance, Scr. Mater. 112 (2016) 9–14. doi:10.1016/j.scriptamat.2015.08.032.
- [91] T.R. Allen, J.I. Cole, E.A. Kenik, G.S. Was, Analyzing the effect of displacement rate on radiation-induced segregation in 304 and 316 stainless steels by examining irradiated EBR-II components and samples irradiated with protons, J. Nucl. Mater. 376 (2008) 169–173. doi:10.1016/j.jnucmat.2008.01.025.
- [92] T.R. Allen, G.S. Was, E. a. Kenik, The effect of alloy composition on radiation-induced segregation in Fe-Cr-Ni alloys, J. Nucl. Mater. 244 (1997) 278–294. doi:10.1016/S0022-3115(96)00744-1.
- [93] X. Wang, Q. Yan, G.S. Was, L. Wang, Void swelling in ferritic-martensitic steels under high dose ion irradiation: Exploring possible contributions to swelling resistance, Scr.

Mater. (2015) 6–11. doi:10.1016/j.scriptamat.2015.08.032.

- [94] D.S. Gelles, Neutron Irradiation Damage in Ferritic Fe-Cr Alloys, in: Eff. Radiat. Mater.
 14th Int. Symp. Vol. 1, ASTM STP 1046, 1989: pp. 73–97.
 doi:10.1017/CBO9781107415324.004.
- [95] B.L. Eyre, R. Bullough, On the formation of interstitial loops in b.c.c. metals, Philos.Mag. 12 (1965) 31–39. doi:10.1080/14786436508224943.
- [96] Y. Katoh, D.S. Gelles, Swelling and dislocation evolution in simple ferritic alloys irradiated to high fluence in FFTF / MOTA Fe-3Cr I Fe-12Cr Fe-15Cr, J. Nucl. Mater. 225 (1995) 154–162.
- [97] S.I. Golubov, R.E. Stoller, S.J. Zinkle, A.M. Ovcharenko, Kinetics of coarsening of helium bubbles during implantation and post-implantation annealing, J. Nucl. Mater. 361 (2007) 149–159. doi:10.1016/j.jnucmat.2006.12.032.
- [98] S.I. Golubov, A. V. Barashev, R.E. Stoller, Radiation damage theory, 1st ed., Elsevier Inc., 2012. doi:10.1016/B978-0-08-056033-5.00029-X.
- [99] M. Kiritani, Analysis of the clustering process of supersaturated lattice vacancies, J. Phys.
 Soc. Japan. 35 (1973) 95–107. doi:10.1143/JPSJ.37.1532.
- [100] R.E. Stoller, Ph.D. Thesis, 1987.
- [101] A.C. Hindmarsh, LSODE and LSODI, Two new initial value ordinary differential equation solvers, ACM SIGNUM Newsl. 15 (1980) 10. doi:10.1017/CBO9781107415324.004.

- [102] B.N. Singh, A.J. Foreman, Production bias and void swelling in the transient regime under cascade damage conditions., Philos. Mag. A. 66 (1992) 975–990.
- [103] A.V. Barashev, S.I. Golubov, H. Trinkaus, Reaction kinetics of glissile interstitial clusters in a crystal containing voids and dislocations, Philos. Mag. A. 81 (2001) 2515–2532. doi:10.1080/01418610108217161.
- [104] A. V Barashev, Y.N. Osetsky, D.J. Bacon, A. V Barashevt, A Mechanism of onedimensional glide of self-interstitial atom clusters in α-iron, Philos. Mag. a. 80 (2000) 2709–2720. doi:10.1080/01418610008216500.
- [105] R.S. Nelson, D.J. Mazey, J.A. Hudson, The use of ion accelerators to simulate fast neutron-induced voidage in metals, J. Nucl. Mater. 37 (1970) 1–12. doi:10.1016/0022-3115(70)90176-5.
- [106] C.-C. Fu, J.D. Torre, F. Willaime, J.-L. Bocquet, A. Barbu, Multiscale modelling of defect kinetics in irradiated iron, Nat. Mater. 4 (2005) 68–74. doi:10.1038/nmat1286.
- [107] E. Del Rio, J.M. Sampedro, H. Dogo, M.J. Caturla, M. Caro, A. Caro, et al., Formation energy of vacancies in FeCr alloys: Dependence on Cr concentration, J. Nucl. Mater. 408 (2011) 18–24. doi:10.1016/j.jnucmat.2010.10.021.
- [108] D. Terentyev, N. Juslin, K. Nordlund, N. Sandberg, Fast three dimensional migration of He clusters in bcc Fe and Fe-Cr alloys, J. Appl. Phys. 105 (2009). doi:10.1063/1.3126709.
- [109] J.R.G. da Silva, R.B. McLellan, Diffusion of carbon and nitrogen in B.C.C. iron, Mater.
 Sci. Eng. 26 (1976) 83–87. doi:10.1016/0025-5416(76)90229-9.
- [110] R.E. Stoller, Role of cascade energy and temperature in primary defect formation in iron,

J. Nucl. Mater. 276 (2000) 22-32. doi:10.1016/S0022-3115(99)00204-4.

- [111] R.E. Stoller, G.R. Odette, B.D. Wirth, Primary damage formation in bcc iron, J. Nucl.
 Mater. 251 (1997) 49–60. doi:10.1016/S0022-3115(97)00256-0.
- [112] H. Xu, Y.N. Osetsky, R.E. Stoller, Cascade annealing simulations of bcc iron using object kinetic Monte Carlo, J. Nucl. Mater. 423 (2012) 102–109. doi:10.1016/j.jnucmat.2012.01.020.
- [113] H. Xu, R.E. Stoller, Y.N. Osetsky, Cascade defect evolution processes: Comparison of atomistic methods, J. Nucl. Mater. 443 (2013) 66–70. doi:10.1016/j.jnucmat.2013.07.001.
- [114] D. Brimbal, L. Fournier, A. Barbu, Cluster dynamics modeling of the effect of high dose irradiation and helium on the microstructure of austenitic stainless steels, J. Nucl. Mater. 468 (2015) 124–139. doi:10.1016/j.jnucmat.2015.11.007.
- [115] S. I. Golubov, B. N. Singh, H. Trinkau, On recoil-energy-dependent defect accumulation in pure copper Part II. Theoretical treatment, Philos. Mag. A. 81 (2001) 2533–2552. doi:10.1080/01418610110043163.
- [116] R.M. Mayer, L.M. Brown, Nucleation and growth of voids by radiation VI. Role of alloying atoms, J. Nucl. Mater. 95 (1980) 92–99. doi:10.1016/0022-3115(80)90078-1.
- [117] F.A. Smidt, J.A. Sprague, Suppression of void nucleation by a vacancy trapping mechanism, Scr. Metall. 7 (1973) 495–501. doi:10.1016/0036-9748(73)90102-6.
- [118] L.K. Mansur, M.H. Yoo, The effects of impurity trapping on irradiation-induced swelling and creep, J. Nucl. Mater. 74 (1978) 228–241.

- [119] D. Jiang, E. Carter, Carbon dissolution and diffusion in ferrite and austenite from first principles, Phys. Rev. B. 67 (2003) 214103. doi:10.1103/PhysRevB.67.214103.
- [120] P.R. Okamoto, N.. Lam, H. Wierdersich, R.. Johnson, Effects of defect trapping and solute segregation on defect recombination rates and void swelling in irradiated alloys, J. Nucl. Mater. 70 (1978) 821–824.
- [121] E.A. Little, Microstructural evolution in irradiated transitions to high dose behaviour steels :, J. Nucl. Mater. 206 (1993) 324–334.
- [122] E.A. Little, Void swelling in irons and ferritic steels I. Mechanisms of swelling suppression, J. Nucl. Mater. 87 (1979) 11–24.
- [123] A. Bakaev, D. Terentyev, X. He, E.E. Zhurkin, D. Van Neck, Interaction of carbon–vacancy complex with minor alloying elements of ferritic steels, J. Nucl. Mater. 451 (2014) 82–87. doi:10.1016/j.jnucmat.2014.03.031.
- [124] N. Anento, A. Serra, Carbon–vacancy complexes as traps for self-interstitial clusters in Fe–C alloys, J. Nucl. Mater. 440 (2013) 236–242. doi:10.1016/j.jnucmat.2013.04.087.
- [125] A.B. Lidiard, The influence of solutes on self-diffusion in metals, Philos. Mag. 5 (1960)1171–1180. doi:10.1080/14786436008238325.
- [126] A.D. Brailsford, L.K. Mansur, The effect of precipitate-matrix interface sinks on the growth of voids in the matrix, J. Nucl. Mater. 104 (1981) 1403–1408. doi:10.1016/0022-3115(82)90796-6.
- [127] A.D. Brailsford, R. Bullough, The rate theory of swelling in irradiated metals, J. Nucl. Mater. 44 (1972) 121–135.

- [128] A.D. Brailsford, Point defect trapping and void growth, J. Nucl. Mater. 78 (1978) 354–361. doi:10.1016/0022-3115(78)90457-9.
- [129] C.-G. Lee, Y. Iijima, T. Hiratani, K. Hirano, Diffusion of Chromium in alpha-Iron, Mater.
 Trans. JIM. 31 (1990) 255–261. doi:10.2320/matertrans1989.31.255.
- [130] K. Hirano, M. Cohen, B.L. Averbach, Diffusion of Nickel into Iron, Acta Metall. 9 (1961)440–445.
- [131] A. Galerie, G. Dearnaley, Radiation enhanced diffusion of silicon into iron for high temperature oxidation improvement, Nucl. Instruments Methods Phys. Res. 210 (1983) 823–829.
- [132] V. Irmer, M. Feller-Kniepmeier, Diffusion of manganese in alpha-iron single crystals of different purity, J. Phys. Chem. Solids. 33 (1972) 2141–2148. doi:10.1016/S0022-3697(72)80244-0.
- [133] H. Nitta, K. Miura, Y. Iijima, Self-diffusion in iron-based Fe-Mo alloys, Acta Mater. 54 (2006) 2833–2847. doi:10.1016/j.actamat.2006.02.020.
- [134] H. Oikama, Review of Lattice Diffusion of Substitutional Impurities in Iron, Summ. Rep. Tech Reports. 47 (1982) 1982.
- [135] S. Takemoto[†], H. Nitta[‡], Y. Iijima[§], Y. Yamazaki, Diffusion of tungsten in α-iron, Philos.
 Mag. 87 (2007) 1619–1629. doi:10.1080/14786430600732093.
- [136] A.W. Bowen, G.M. Leak, Solute diffusion in alpha- and gamma-iron, Metall. Trans. 1 (1970) 1695–1700. doi:10.1007/BF02642019.

- [137] T. Jourdan, Influence of dislocation and dislocation loop biases on microstructures simulated by rate equation cluster dynamics, J. Nucl. Mater. 467 (2015) 286–301. doi:10.1016/j.jnucmat.2015.09.046.
- [138] W.G. Wolfer, The dislocation bias, J. Comput. Mater. Des. 14 (2007) 403–417.
 doi:10.1007/s10820-007-9051-3.
- [139] F.S. Ham, Stress-assisted precipitation on dislocations, J. Appl. Phys. 30 (1959) 915–926.
 doi:10.1063/1.1735262.
- [140] J.J. Sniegowski, W.G. Wolfer, Sniegowski, J.J. Wolfer, Proc. Top. Conf. Ferritic Alloy. Use Nucl. Energy Technol. (1984) 1984.
- [141] E. Little, D. Stow, Void-swelling in irons and ferritic steels II. An experimental survey of materials irradiated in a fast reactor, J. Nucl. Mater. 87 (1979) 25–39.
 http://www.sciencedirect.com/science/article/pii/0022311579901235 (accessed August 4, 2011).
- [142] J. Weertman, W.V. Green, Irradiation Effects on the Microstructure and Properties of Metals, Irradiat. Eff. Microstruct. Prop. Met. ASTM STP 6 (1976) 256.
- [143] V.. Voyevodin, I.. Neklyudov, V.V. Bryk, O.V. Borodin, Microstructural evolution and radiation stability of steels and alloys, J. Nucl. Mater. 271-272 (1999) 290–295. doi:10.1016/S0022-3115(98)00785-5.
- [144] J. Van Den Bosch, O. Anderoglu, R. Dickerson, M. Hartl, P. Dickerson, J.A. Aguiar, et al., SANS and TEM of ferritic-martensitic steel T91 irradiated in FFTF up to 184 dpa at 413 °C, J. Nucl. Mater. 440 (2013) 91–97. doi:10.1016/j.jnucmat.2013.04.025.

- [145] E. Getto, K. Sun, A.M. Monterrosa, Z. Jiao, G.S. Was, Void swelling and microstructure evolution at very high damage level in self-ion irradiated ferritic-martensitic steels, J. Nucl. Mater. (2016) accepted.
- [146] A.D. Brailsford, R. Bullough, Void growth and its relation to intrinsic point defect properties, J. Nucl. Mater. 70 (1978) 434–450.
- [147] K.A. Bywater, D.J. Dyson, The Precipitation of Cr 2 N in 17%Cr Steels, Met. Sci. 9
 (1975) 155–162. doi:10.1179/030634575790444685.
- [148] R. Lagneborg, Metallography of the 475 C embrittlement in an Iron-30% chromium alloy, Trans. Am. Soc. Met. 60 (1967).
- [149] D.A. Porter, K.E. Easterling, M.Y. Sherif, Phase Transformations in Metals and Alloys, 2008. doi:10.1017/CBO9781107415324.004.
- [150] A. Bhattacharya, E. Meslin, J. Henry, C. Pareige, B. Décamps, C. Genevois, et al., Chromium enrichment on the habit plane of dislocation loops in ion-irradiated high-purity Fe–Cr alloys, Acta Mater. 78 (2014) 394–403. doi:10.1016/j.actamat.2014.06.050.
- [151] K. Arakawa, M. Hatanaka, H. Mori, K. Ono, Effects of chromium on the one-dimensional motion of interstitial-type dislocation loops in iron, J. Nucl. Mater. 329-333 (2004) 1194– 1198. doi:10.1016/j.jnucmat.2004.04.263.
- [152] D. Terentyev, K. Heinola, a. Bakaev, E.E. Zhurkin, Carbon-vacancy interaction controls lattice damage recovery in Iron, Scr. Mater. (2014). doi:10.1016/j.scriptamat.2014.04.003.
- [153] W.D. Callister, Materials Science and Engineering An Introduction, 2007. doi:10.1126/science.1213003.
- [154] J.L. Brimhall, L.A. Charlot, E.P. Simonen, Effect of Pulsed Irradiation on Void Swelling in Nickel, J. Nucl. Mater. 104 (1981) 1147–1150.
- [155] J.M. Vitek, R.L. Klueh, Microstructure of 9 Cr-1 MoVNb steel irradiated to 36 dpa at elevated temperatures in HFIR, J. Nucl. Mater. 122 (1984) 254–259. doi:10.1016/0022-3115(84)90606-8.
- [156] J.J. Kai, R.L. Klueh, Microstructural analysis of neutron-irradiated martensitic steels, J.
 Nucl. Mater. 230 (1996) 116–123. doi:10.1016/0022-3115(96)00165-1.